MAINTENANCE SERVICE MANUAL FT-901DM



YAESU MUSEN CO., LTD.

C.P.O. BOX 1500 TOKYO, JAPAN

YAESU ELECTRONICS CORP.

P.O. BOX 49

PARAMOUNT, CALIFORNIA, 90723

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FOREWORD

The purpose of this manual is to provide the reader with the information required to keep his or her FT-901 transceiver in top operating condition. While we have made every effort to provide an in-depth technical analysis of the workings of this equipment, we have attempted to tailor this manual toward the technician or owner, rather than the design engineer. To this end, we have relied heavily on drawings and diagrams.

Use of this manual is entirely at the owner's risk. While we believe that the information presented herein is correct and factual, we assume no responsibility for damage to your equipment when this manual is used as reference.

Moreover, if your test equipment is not equal to the task of performing alignments the right way, we would strongly urge you to refer the unit to a qualified service center.

We truly hope that the test information, parts location data, and modification information presented herein will be sufficient to your needs.

The author wishes to express his gratitude to the engineering and service staffs of Yaesu Musen Co., Ltd. and Yaesu Electronics Corporation, whose skill and insights have contributed significantly to the completion of this manual. Special thanks go to Mr. Y. Morii for his help in assembling the technical materials presented herein.

Chip Margelli, K7JA

Public Relations Manager

Yaesu Musen Company, Ltd.

Ctup Mayell.

Tokyo, Japan

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Printed in Japan.

A BRIEF HISTORY OF THE FT-901 SERIES

The FT-901 transceiver first appeared in the USA early in 1978 and immediately established a position of pre-eminence among "top-of-the-line" transceivers on the market. The FT-901 series has brought a number of never-before-possible technical features to the amateur community, along with traditional Yaesu quality design and purity of emissions.

The receiver section, in particular, has impressive credentials. A dual-filter variable IF bandwidth control allows continuous variation of the IF passband, from 2.4 kHz down to 300 Hz. Also included is a rejection tuning control, for nulling out of any interfering signal within the remaining IF passband. For CW, and audio peak filter (APF) provides a significant reduction in background noise, in addition to razor-sharp selectivity. The receiver dynamic range — typically well in excess of 85 dB in CW bandwidth — is the best ever achieved in a production-line amateur solid-state receiver.

The transmit side includes RF negative feedback for purity of emissions. A Curtis 8043 IC keyer is built-in on the FT-901DM/DE models, providing high reliability and immunity to RF interference. Another innovation is the 10-second TUNE button, which activates the transmitter for 10 seconds for tuning purposes, then returns the rig to receive, thus saving the final tubes from excessive key-down time.

The most exciting feature of the FT-901 series is the memory system, which provides for storage and recall of any frequency for control on transmit, receive, or transceive. This one feature largely eliminates the need for an external VFO in the traditional sense. That the FV-901DM synthesized scanning external VFO is hardly traditional bears this point out.

With coverage on all modes (SSB, CW, AM, FSK, and FM) on all bands from 160 through 10 meters, the FT-901 series is destined to maintain its position of dominance among top transceivers on the market. With some 2800 components assembled in one box, for a finite price tag, the FT-901 offers more performance per dollar than any other piece or collection of equipment on the market.

ALL MODE HF TRANSCEIVER FT-901DM



GENERAL DESCRIPTION

The FT-901DM is a precision engineered, high-performance HF transceiver of advanced design, providing all band coverage (160 - 10 meters) on all modes of operation: LSB, USB, CW, FSK, AM, and FM. This transceiver operates at an input power of 180 watts SSB/CW and 80 watts on AM, FM, and FSK.

Advanced features include PLL (Phase Locked Loop) frequency derivation, digital plus analog frequency readout with large display LED digits, a built-in Curtis 8043 IC electronic keyer, and memory frequency control circuitry. State-of-the-art receiver performance features include rejection tuning, dual-filter variable IF bandwidth tuning, and, for CW, an audio peak filter (APF) for unsurpassed rejection of unwanted signals. Other built-in features include VOX, semi-break-in CW with sidetone, 25 kHz calibrator, advanced noise blanker, RF speech processor, and a 20 dB RF attenuator for protection against receiver overload.

All circuits, except the transmitter driver and final amplifier stages, are solid state, utilizing modern plug-in printed circuit boards, thus permitting easy maintenance.

The FT-901DM transceiver is entirely self-contained, requiring only an antenna and power source for operation. For base station operation, AC power voltages of 100/110/117/200/220/234 VAC may be chosen, though the unit normally is supplied with 117 volt capability. A DC-DC converter unit provides for mobile or portable operation. Selection of AC or DC power source is automatically made when the proper line cord is inserted.

For mobile operation a separate switch is provided on the front panel to turn off the tube heaters while in the receive mode. With the heaters off, current consumption is only 1.1 amp.

Among the available options on economy models FT901D/SD/DE are the memory unit, the keyer unit, the DC-DC converter, the FM unit, and the cooling fan. Optional equipment on all models are the 600 Hz CW filter and the 6 kHz AM filter.

The entire FT-901DM transceiver weighs approximately 18 kg., and is 342 mm wide, 154 mm high, and 324 mm deep. A diecast front panel and heavy-duty case provide maximum protection against damage from shock and vibration during travel use.

SPECIFICATIONS

GENERAL

Frequency coverage:

160m 1.8 - 2.0 MHz 80m 3.5 - 4.0 MHz 40m 7.0 - 7.5 MHz 20m 14.0 - 14.5 MHz 21.0 - 21.5 MHz 15m 28.0 - 28.5 MHz 10mA28.5 - 29.0 MHz 10mB10mC 29.0 - 29.5 MHz 29.5 - 29.9 MHz 10mD WWV/JJY 15.0 - 15.5 MHz, RX only

Power requirements:

AC 100/110/117/200/220/234 V, 50/60 Hz DC 13.5 V, negative ground (DC option FT-901D/SD/DE)

Power consumption:

(FT-901DM/D/DE)

AC 117 V: 70 VA receive

(45 VA HEATER OFF) 320 VA transmit (max)

DC 13.5 V: 55 VA receive

(45 VA HEATER OFF)

105 VA transmit (max)

(FT-901S)

AC 117V: 55 watts receive

(45 watts HEATER OFF)

105 watts transmit (max)

DC 13.5 V: 3.8 A receive

(0.8 A HEATER OFF)
7.5 A transmit (max)

Size:

342 (W) x 154 (H) x 324 (D) mm

Weight:

18 kg

TRANSMITTER

Emission:

LSB, USB (A3j), CW (A1), AM (A3h), FM (F3) (option FT-901SD/DE), FSK (F1)

PA input power:

FT-901DM/D/DE

SSB/CW: 180 watts DC AM/FSK/FM: 80 watts DC

FT-901SD

SSB/CW/FSK/FM: 20 watts DC AM: 5 watts DC

Carrier suppression:

Better than 40 dB

Unwanted sideband suppression:

Better than 40 dB @ 1000 Hz

Spurious radiation:

Better than 40 dB below rated output

Transmitter frequency response:

300 - 2700 Hz (-6 dB)

Third order distortion products:

Better than 31 dB below rated output

Stability:

Less than 300 Hz drift from a cold start; less than 100 Hz drift over a 30 minute period after warm-up

Negative feedback:

6 dB at 14 MHz

Modulation:

A3J: Balanced modulator

A3h: Amplitude modulation of a low power

stage

F3: Variable-reactance frequency modulation, max. deviation ±5 kHz (F3 feature optional on FT-901SD/DE)

Antenna output impedance:

50 - 75 Ohms, unbalanced

Microphone input impedance:

500 - 600 Ohms

RECEIVER

Sensitivity:

SSB/CW/FSK $0.25 \mu V$ for S/N 10 dB

AM

 $1 \mu V$ for S/N 10 dB

FM

 $0.3 \mu V$ for 20 dB quieting

Image rejection:

1.8 - 21 MHz - - Better than 60 dB 28 MHz - - Better than 50 dB

IF rejection:

Better than 70 dB

Selectivity, WIDTH control at "0"

SSB: -6 dB/2.4 kHz -60 dB/4.0 kHz

*CW: -6 dB/0.6 kHz -60 dB/1.2 kHz

*AM: -6 dB/6.0 kHz -60 dB/12.0 kHz

**FM: -6 dB/12.0 kHz -60 dB/24.0 kHz

*AM and CW filters are optional, all models

**FM UNIT optional on FT-901SD/DE

Passband tuning:

Continuous from 2.4 kHz to 300 Hz

Two-tone dynamic range:

Typically well in excess of 85 dB (20 kHz spacing, 14 MHz, 600 Hz bandwidth)

APF response:

Within 3 dB from 400 - 900 Hz

Audio output:

Better than 3 watts @ 10% THD

Audio output impedance:

4 - 16 Ohms

FT-901D/SD/DE/DM MODEL DIFFERENCES

○ = Built-in feature

X = Available option

FEATURE	FT-901D	FT-901SD	FT-901DE	FT-901DM
BAND CRYSTAL 160m	0	0	0	0
BAND CRYSTAL 80m	0	0	0	0
BAND CRYSTAL 40m	0	0	0	0
BAND CRYSTAL 15m	0	0	0	0
BAND CRYSTAL 10mA	0	0	0	0
BAND CRYSTAL 10mB	0	0	0	` O
BAND CRYSTAL 10mC	0	0	0	0
BAND CRYSTAL 10mD	0	0	0 1	0
BAND CRYSTAL WWV/JJY RCV	0	0	0	0
VOX/MARKER UNIT	0	0	0	0
FM UNIT	0	×	×	0
RF SPEECH PROCESSOR	0	0	0	0
AM FILTER	×	×	×	×
CW FILTER	×	×	×	×
KEYER UNIT	×	×	0	0
MEMORY UNIT	×	×	×	0
DC-DC CONVERTER	×	×	×	0
COOLING FAN	0	×	0	0
POWER OUTPUT	100 W	10 W	100 W	100 W

TUBES AND SEMICONDUCTORS

TUBE COMPLEM	IENT	FET:		MSM5501	1	Varactor diodes:	
		2SK 19GR	15	MSM5562	1	1S2209	2
12BY7A	1	2SK19BL	8	MSM5564	1	1S2236	1
6146B	2	2SK34E	1	SN75450B	1	FC63	1
		3SK40M	14	SN76514N	1	MV104	10
SEMICONDUCTOR		3SK59Y	1	SN74LS00N	2	a	
COMPLEMENT		3SK59GR	1	SN74L04N	3	Silicon varistor o	liodes:
		JF1033B	5	SN74LS90N	1	MV13	I
Germanium trans	istors:	10		SN74LS123N	1	Zener diodes:	
T20A6	2	IC:	1	SN74LS192N	5	WZ050	2
Silicon transistors		8043	1	TA7060P	1	WZ090	4
2SA564A	2	μPC78L05	2 5	TA7061AP	2	WZ110	2
2SA639		μPC78L08		TA7063P	2		
2SA733	1	μPC14305	2	TA7089M	1	Light-emitting d	
2SC372Y	4 3	μPC14308	2	TA7205AP	1	GD4-203SRD	11
2SC3721 2SC373	10	μPC14312 F4024CP	l			Light-emitting d	isplay:
2SC535A	10	F4024CF F40192	2	TC5032P	1	HP5082-7740	6
2SC735Y	3	LM308	2			1110002	
2SC7850	5	MC1416P	l	Germanium diod			*
2SC945		MC3403P	1	IN60	17		
2SC1000GR	3 5	MC4044P	1 2	1S188FM	6		
2SC1815GR	2	MC4044P (μPC1008C)	2	1S1007 (GB) (1N270)	22		
2SC1815Y	49	MC14011B	3	(111270)			
2N4427	1	MC14042B	5	Silicon diodes:			
MPSA13	1	MM74C90	1	1S1555	89		
WII SAIS	1	MSL980Y7	1	10D1	7	,	
		MSL980Y4	1	10D10	8		
		MSM561	3	VO6B	2		
				-			

Specifications subject to change without notice.

RECOMMENDED ACCESSORIES





FV-901DM

FTV-901R

FV-901DM SYNTHESIZED, SCANNING REMOTE VFO

The FV-901DM external VFO provides a PLL-synthesized control system for your FT-901DM station. A three-speed scanner will take you anywhere in the band instantly, and the autoscan feature will sweep the band until it finds a signal, then it will halt.

PLL synthesis in 100 Hz steps is coupled to a 40-frequency memory bank, allowing wide versatility for contest, DX, or net operation. The TX/RX clarifier allows offset from either dial or memory frequencies, for precise tuning.

For the CW operator, the use of the FV-901DM, along with the FT-901DM audio peak filter, means that one step of the synthesizer will eliminate a signal from the passband.

FTV-901R VHF/UHF TRANSVERTER

In another Yaesu "first", the FTV-901R brings three bands in the UHF and VHF regions together in one compact case. The basic FTV-901R comes equipped for 144–148 MHz, and the 6 meter and 70 cm modules can be added as options.

The satellite 1-3 bands provide operation on OSCAR Modes A/B/J, on full duplex, when an external receiver is used. Of course, the FT-225RD or FT-221R transceivers can also be used for transmission on the OSCAR 145 MHz uplink. In this case, your FTV-901R can be used for instant QSY between 29 MHz, 145 MHz, and 435 MHz.

Repeater split is provided on 50 and 144 MHz. This means that you can use the FM capability of your FT-901DM to full advantage on these bands.



YO-901



SP-901P

SP-901P SPEAKER/HYBRID PHONE PATCH

The SP-901P features a shaped-response loud-speaker, and the hybrid phone patch allows easy, efficient operation during patches. Styling and size match the rest of the 901 series.



The YO-901 Multiscope provides superb monitoring capability, with instant interface to your FT-901DM station. Both wide and narrow band IF monitoring can be performed, as well as transmitter trapezoidal and two-tone tests. The two-tone generating capability is built in.

A panoramic adapter, known as the Bandscope, is an available option for the YO-901, allowing quick examination of the band for activity.

For a variety of test and measurement purposes, the YO-901 meets your requirements with ease.



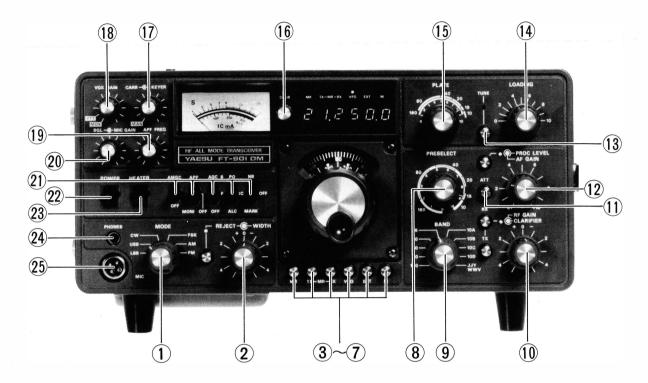
FC-901

FC-901 ANTENNA COUPLER

Present a 50 ohm load for your FT-901DM transceiver all across the band with the FC-901 antenna coupler. You may select three coax-fed and 1 random wire antenna. Included are an SWR bridge and power output meter. Maximum power handling capability is 500 watts.

CONTROLS AND SWITCHES

This transceiver has been specifically designed for ease of operation and versatility. The operator may, however, be unfamiliar with the operation of the controls, and improper adjustment thereof may result in poor transceiver performance. Thus, be certain that you understand the function of every control before operating the transceiver. The various front panel controls and switches are described in the following section.



(1) MODE

The MODE switch has six positions for selection of the operating mode desired: LSB, USB, CW, FSK, AM, or FM.

(2) REJECT-WIDTH

The REJECT and WIDTH controls are mounted on concentric shafts. The rejection tuning control (REJECT), when activated by pressing the small silver pushbutton to the left of the REJECT knob, provides a variable IF notch filter action for nulling out a particular interfering signal.

The WIDTH control varies the signal across the passband of one of the two IF 8-pole crystal bandpass filters used in this circuit, thus providing a variable IF bandwidth for rejection of signals above or below the desired signal.

(3) M

The M button is pressed to store a frequency in the memory circuitry. Whatever frequency is being read out on the digital display will be the frequency stored when the M button is pushed.

(4) EXT

When pushed, the EXT button transfers frequency control from the FT-901DM to an external VFO, such as the FV-901 fully synthesized scanning VFO.

(5) VFO

When the VFO button is pushed, frequency control is transferred from EXT or memory control to the FT-901DM internal VFO.

(6) TX-MR-RX

Once a frequency has been stored by the memory (M) button, that frequency may be recalled for control of either the transmit or receive frequency by pushing either the TX or RX MR button. respectively.

(7) MR

Once a frequency has been stored by the memory (M) button, that frequency may be recalled for control of the transceive frequency by pushing the MR button.

(8) PRESELECT

This control pretunes the signal circuits for both transmit and receive. The PRESELECT circuit provides continuous permeability tuning throughout the frequency range of the transceiver.

(9) **BAND**

The BAND switch provides selection of the band desired, 160 through 10 meters plus WWV/JJY (receive only).

(10) RF GAIN/CLARIFIER

The RF GAIN and CLARIFIER controls are mounted on concentric shafts. The RF GAIN control provides manual control of the gain levels of the RF and IF amplifiers on receive.

The CLARIFIER control allows manual offset of ±2.5 kHz of either the transmit or receive frequency. Selection of transmit or receive clarifier is made by the two silver pushbuttons to the left of the CLARIFIER control.

(11) ATT

The ATT (RF attenuator) button provides insertion of a 20 dB attenuator in the incoming signal path to minimize receiver cross modulation caused by extremely strong local signals.

(12) PROC LEVEL/AF GAIN

The PROC LEVEL and AF GAIN controls are mounted on concentric shafts. The PROC LEVEL control allows manual control of the output level of the RF speech processor. The processor is actuated by pressing the silver pushbutton to the left of the PROC LEVEL control.

The AF GAIN control adjusts the audio output level at the speaker and phone jack. Clockwise rotation increases the audio output.

(13) TUNE

This pushbutton, when depressed, places the transmitter in the "tune" condition for ten seconds for tuning purposes. After ten seconds, the transceiver is returned to the receive mode so as to prevent damage to the final amplifier tubes caused by excessive "key down" time during tune-up.

(14) LOADING

This control tunes the output circuit of the pi network to match the antenna/feedline impedance.

(15) PLATE

This control tunes the plate circuit of the final amplifier.

(16) **CALIB**

When the MARK switch is activated, the CALIB knob provides manual control for zeroing the calibration of the digital display with the calibrator signal.

(17) CARR/KEYER

The CARR and KEYER controls are mounted on concentric shafts. The CARR control varies the amount of carrier in the CW, AM, FSK, and FM models of operation.

The KEYER control varies the speed of the built-in Curtis 8043 IC electronic keyer.

(18) VOX GAIN

This control selects MOX/PTT/VOX transmitter relay control as well as adjusting the sensitivity of the VOX circuitry. The PTT position provides push-to-talk operation from a microphone PTT switch or a footswitch. The MOX position provides manual transmit. It must be returned to the PTT position for receiver recovery.

(19) APF FREQ

This knob, when actuated by turning on the APF switch, provides manual control for peaking the audio peak frequency (APF) circuit on the desired signal. This control will find its chief usefulness on CW, because its bandwidth is much too narrow for normal SSB reception.

(20) SQL/MIC GAIN

The SQL and MIC GAIN controls are mounted on concentric shafts. The SQL control sets the squelch threshold level for FM reception.

The MIC GAIN control varies the audio level from the microphone amplifier stage. The control has sufficient range to permit the use of any low impedance (500 - 600 Ohm) crystal or dynamic microphone. Clockwise rotation increases the level of output from the microphone amplifier stage.

(21) FUNCTION SWITCHES: AMGC, APF/MONI, AGC, PO/IC/ALC, and NB/MARK

The AMGC switch activates a microphone gain threshold circuit which requires a particular

minimum input level from the microphone to trigger the microphone amplifier. Low-level background noise will not activate the transmitter with the AMGC in operation. This circuit may be considered a "microphone squelch" system. The M GAIN control functions normally with the AMGC system in operation.

When the APF/MONI switch is in the APF position, the audio peak filter (APF) circuitry is activated. The exact frequency of the audio peak is set by the APF FREQ knob. When this switch is placed in the MONI position, monitoring of the microphone level may be accomplished for operator convenience or tape recording both sides of a QSO. In the CW mode, CW sidetone will be heard regardless of the position of the APF/MONI switch.

The AGC switch controls the length of the recovery time for the receiver AGC circuitry. This switch provides slow or fast recovery, and will also turn off the AGC if desired.

The PO/IC/ALC switch will hereafter be referred to as the METER switch. In the PO position, relative transmitter output power can be observed. In the IC position, transmitter final amplifier cathode current may be measured. In the ALC position, transmitter ALC voltage may be read. When the FT-901DM is in the receive mode, the meter functions as an "S" meter.

The NB/MARK switch provides for actuation of either the Noise Blanker (NB) or crystal calibrator (MARK). The marker oscillator can produce calibration signals at intervals of either 25 kHz or 100 kHz by proper positioning of a switch inside the cabinet.

(22) POWER

This is the main on/off switch for the transceiver. In the OFF position, the memory circuits are disabled, so that when the transceiver is turned to ON again, the memory circuits will have to be reset.

(23) HEATER

With the HEATER switch in the down position, the transmitter tube heaters are turned off. This reduces battery drain to 1.1 amp and thus permits long periods of listening without excessive battery drain. Placing this switch in the up position provides supply voltage to the tube heaters, and after 30 seconds of warmup the transmitter is

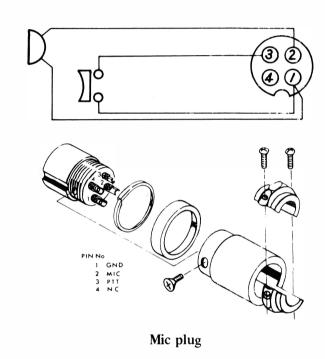
ready for operation. This switch operates in both the AC and DC modes.

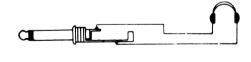
(24) PHONES

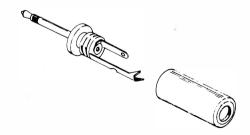
This is a standard 1/4" phone jack for accommodation of headphones. The internal speaker is disabled when headphones are plugged into this jack.

(25) MIC

This four-conductor jack accommodates the microphone plug for microphone input as well as for PTT actuation.

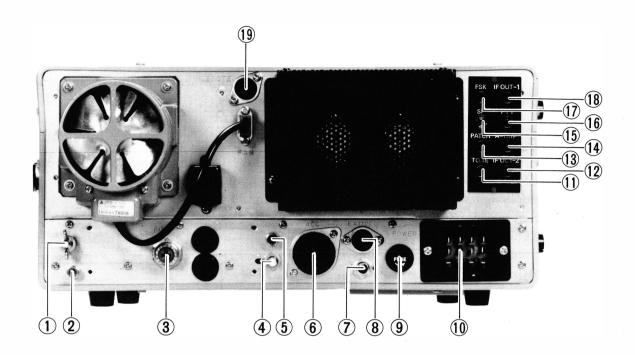






Headphone plug

REAR APRON CONNECTIONS



(1) **GND**

Threaded lug for ground connection.

(2) RF OUT

Signal frequency output from the driver stage may be obtained at this jack for use with optional equipment, such as the FTV-901R VHF/UHF transverter.

(3) ANT

Coaxial connection for antenna.

(4) PO ADJ

Sets PO meter sensitivity.

(5) RCV ANT

A second receiver receives its antenna connection through this jack.

(6) ACC

Accessory socket. Provides access to transceiver operating voltages and relay contacts.

(7) **KEY**

Three-conductor jack for connection to keyer paddle or external key.

(8) EXT VFO

Connections for external VFO.

(9) **FUSE**

Fuse holder requires 5 amp fuse for 117 volt or 3 amp fuse for 220 volt operation. For 12 volt DC operation, a 20 amp fuse is installed in the power cable. When replacing fuses, be certain to install a fuse of the proper rating. The warranty does not cover damage caused by improper fuse replacement.

(10) POWER

Power receptacle. Both AC and DC cables are supplied.

(11) **TONE**

Sidetone output for second receiver (if used).

(12) IF OUT 2

Wide-bandwidth 8.9 MHz IF signal for connection to a spectrum analyzer, etc.

(13) PATCH

Speech input terminal for phone patch connection. Impedance is 500 ohms.

(14) A-TRIP

Antitrip input from second receiver (if used).

(15) SP

Audio output is provided at this jack for an external speaker. Output impedance is 4 ohms, and

the internal speaker will be disabled when plug is inserted.

(16) PTT

This jack may be used for external actuation of the transmitter. As an example, a footswitch may be connected to this jack to provide remote control of the transmitter relay, leaving the operator's hands free for writing and tuning purposes.

(17) FSK

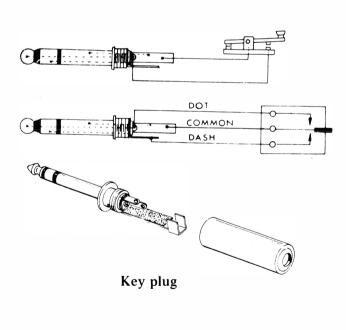
Input from the FSK terminal may be made through this jack. The FT-901DM is set up for 170 Hz shift.

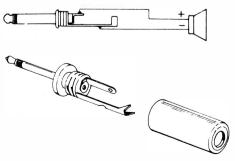
(18) IF OUT 1

Narrow bandwidth 8.9 MHz IF output is available for use with an IF monitorscope, etc.

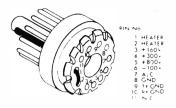
(19) REMOTE

Provides switched 13.5 VDC for relay control for external low-pass filter units, etc. As the band-switch is rotated, 13.5 VDC will appear at various pins on the REMOTE jack. Use a VOM to determine the proper pin for the band in use.



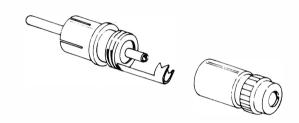


External speaker

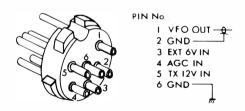


ACC plug



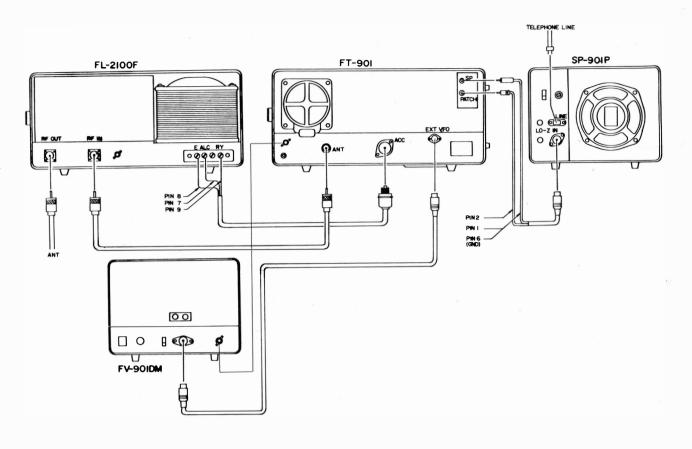


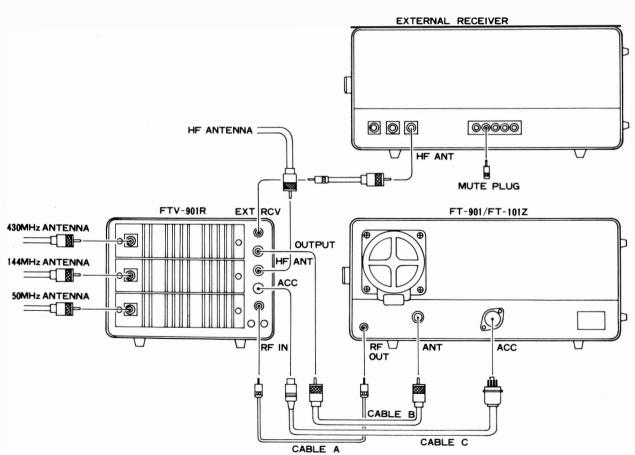
Pin plug

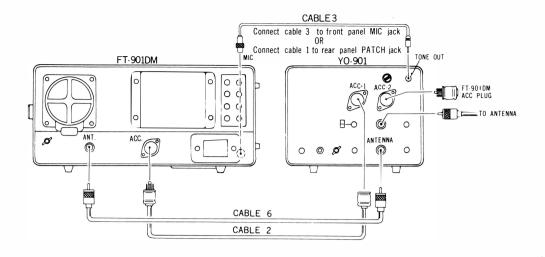


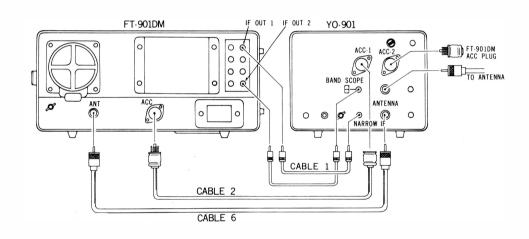
VFO plug

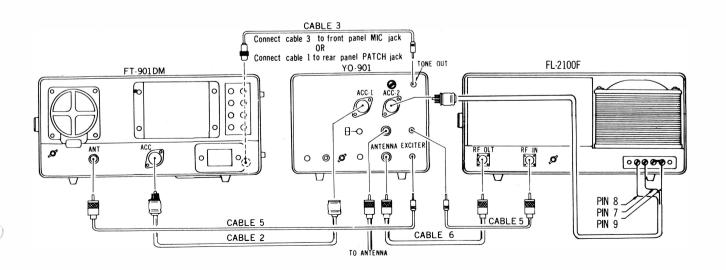
INTERCONNECTIONS











INSTALLATION

This transceiver is designed to be a single-unit station for fixed, portable, or mobile operation. Consequently, power supply connections providing for operation from a variety of source voltages are available. This system provides the flexibility required for changing locations or quick moves from fixed to mobile operation.

BASE STATION INSTALLATION

The FT-901DM is designed for use in many areas of the world using supply voltages that may differ from the operator's local supply voltage. For this reason, be sure that the voltage marked on the rear of the transceiver agrees with the local AC supply voltage. THIS INSPECTION MUST BE MADE BEFORE CONNECTING THE AC POWER CORD TO THE POWER OUTLET.

CAUTION

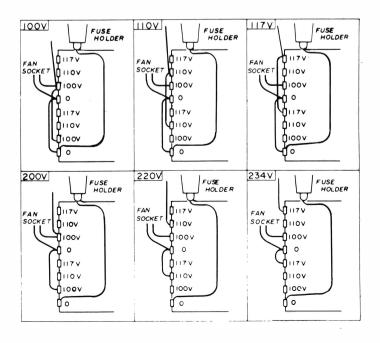
PERMANENT DAMAGE WILL RESULT IF IMPROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER.

The transceiver should be connected to a good earth ground. The ground lead should be made with a heavy braid wire and should be connected to the GND terminal on the rear apron of the transceiver.

We do not recommend the use of power connectors other than the ones supplied by Yaesu. If a rig brought in for servicing is blowing fuses every time you plug it in, check to make sure that no "improvements" have been made to the power cord through substitution of or modification to the power connector.

For base station installation, the only important consideration that need be made is to ensure adequate circulation around the unit. Do not place books or papers on or around the cabinet, nor should the unit be placed on top of another heat-generating device such as a linear amplifier. Avoid heat ducts and window locations which are exposed to the hot sun, and you will keep your transceiver running at full speed for a long, long time.

Be certain to ground the transceiver through a heavy, braided cable less than 10 feet long. Cold water pipes in newer houses probably are unsatisfactory as grounding posts; it is much better practice to use a system of one or more ground rods, with the ground line securely bonded to the ground system.



MOBILE INSTALLATION

(Note: The DC-DC converter described herein is built-in on the FT-901DM, and is an available option on the FT-901D/SD/DE models)

The FT-901DM will operate satisfactorily from any 13.5 Volt DC negative-ground battery source by connecting the DC power cord to the rear panel receptacle. For under-dash mounting, a special mobile mounting bracket is available from your dealer. In mobile installations the transceiver should be suited away from heater ducts. No special precautions need be observed if adequate ventilation space is available. A minimum of two inches of air space above the cabinet top and on all sides is recommended to allow proper air flow around the cabinet. Never stack other units above or below the transceiver since the accumulated heat from both units could cause damage.

The transceiver requires an average of 14 amps on transmit, with 20 amps on voice peaks. The DC power cable comes equipped with a 20 amp fuse. When making connections to the car battery, be absolutely certain that the RED lead is connected to the positive (+) terminal and the BLACK lead is connected to the negative (-) terminal. Reversed connections could permanently damage the transceiver.

The BLACK lead should, preferably, run directly to the negative terminal of the battery. Using the car frame as a negative connection or connecting the RED lead to a positive point such as the ignition switch places the transceiver in the same current path as noise-creating devices, thus failing to take advantage of the filtering action of the battery. The power cable should be kept away from ignition wires and should be as short as possible to minimize voltage drop and to provide a low impedance path from the transceiver to the battery.

Before connecting the power cable to the transceiver, check the battery voltage with the engine running (battery charging). If the voltage exceeds 15 Volts DC, the regulator should be readjusted so that the highest charging rate does not exceed 15 Volts. The transceiver should always be switched OFF while the car engine is being started to prevent voltage transients from damaging power supply components.

ANTENNA CONSIDERATIONS

The FT-901 transceivers are designed for operation using an antenna system presenting a 50-75 ohm resistive load at the antenna jack. Amateur installations seldom meet this requirement over the entire spread of every band, but the final amplifier pi network is sufficiently forgiving to allow for minor deviations from the target figure. However, significant departures from the 50–75 ohm range will result in seriously degraded transceiver performance.

If an open-wire feedline is used, or if the input impedance of the antenna system presents a very high or very low impedance at the coaxial input, some sort of antenna tuner must be used to provide a 50 - 75 Ohm unbalanced feedpoint for the transceiver.

For mobile operation, most of the commercially-available antennas on the market will provide good results if care is taken to tune the antenna-for minimum SWR. The outer conductor of the coaxial cable should be securely grounded to the automobile chassis at the antenna mount.

OPERATION

The tuning procedure for this transceiver is not complicated. However, care should be exercised when tuning so that peak performance of the equipment is secured. The following paragraphs describe the procedure for receiver and transmitter operation.

INITIAL CHECK

Before connecting the transceiver to a power source, carefully examine the unit for any visible damage. Check that all modules are firmly in place and that the controls and switches are operating normally. Make sure that the voltage specification marked on the rear panel matches your supply voltage, and that the line fuse on the rear panel matches the supply voltage; for 117 VAC, use a 5 amp fuse, and for 220 VAC use a 3 amp fuse. For DC operation a fuse holder is installed in the DC cable, and a 20 amp fuse should be installed here.

FREQUENCY SELECTION

Frequency readout for the FT-901DM includes both analog and digital readout. The analog readout dial shows calibrations at the 100 kHz and 10 kHz points, and is marked, as well, in 1 kHz increments for fine tuning. The digital readout displays all digits of the operating frequency, with resolution down to 100 Hz accuracy.

RECEIVE OPERATION

(1) Preset the controls and switches as indicated:

POWER....OFF

HEATER....OFF

VFO Switch depressed

VOX GAIN . . . PTT position

RF GAINFully clockwise

AF GAIN Adjust subsequently for com-

fortable level

BAND.....Desired band

MODE......Desired mode

PRESELECT. . Desired band segment

- (2) Turn the POWER switch to ON. The meter will light up and the operating frequency will be displayed on the dial window. Adjust the AF GAIN control for a comfortable listening level, and adjust the PRESELECT control for maximum receiver noise or signal level. The PRESELECT control may require repeaking as the main tuning dial is tuned across the band.
- (3) The RX CLARIFIER may be utilized if the received signal is drifting. Pushing the RX button and rotating the CLARIFIER control will provide a means of offsetting the receiver frequency ±2.5 kHz without changing the transmitting frequency. A red LED indicator will light up when the CLARIFIER is in use.
- (4) When pulse-type noise is encountered, the NB (Noise Blanker) switch should be activated, providing effective suppression of this type of noise.
- Rejection of adjacent-channel interference may be accomplished by several means. The REJECT control may be utilized to place a steep-skirt 30 dB notch attenuation on any interfering signal within the IF passband. The WIDTH control varies the passband of one of two IF filters (the other is fixed and presents a boundary for narrowing the passband). Varying the WIDTH control varies the IF selectivity from approximately 300 Hz to 2.4 kHz (at 2.4 kHz the WIDTH control is at "0" and the two filters have the same passband). Clockwise rotation from the center ("0") position makes the passband narrow toward the high frequency side, while counter-clockwise rotation narrows the passband on the low-frequency side.
- (6) For CW reception, the APF (Audio Peak Filter) may be activated. This filter has a 100 Hz peak bandwidth with very steep skirts so as to provide single-signal reception for CW, with insertion loss of less than 1 dB when the APF control is tuned exactly to the signal frequency. The APF FREQ control varies the peak frequency from approximately 400 Hz to 900 Hz. The operator will observe that the APF system provides a significant

improvement in signal-to-noise ratio. The selectivity of the APF circuit may be varied by adjusting VR_{501} under the top cover.

(7) For extremely strong signals, the ATT (RF attenuator) switch may be pressed to activate a 20 dB attenuation of the incoming signal. This should prevent any chance of overload of the receiver front end.

TRANSMITTER TUNE-UP

The following tune-up procedure must be performed prior to commencing operation on the desired mode: LSB, USB, CW, FSK, AM, or FM. See the paragraphs relating to the specific mode after basic transmitter tune-up is described.

Connect a dummy load or matched antenna to the coaxial fitting on the rear apron. Preset the controls as follows:

POWER.....OFF HEATER....OFF

CARR.....Fully counter-clockwise position MIC GAIN.....Fully counter-clockwise position

AMGC....OFF

METER switch . .IC

SELECT VFO (Depressed)

BAND..... Desired band segment

MODE.....USB or LSB

PLATEDesired band segment

PRESELECT....Desired band segment

LOADING. To position shown in table

PROC OFF (Not depressed)

TUNE OFF (Not depressed)

('LAR TX OFF (Not depressed)

VOX GAIN PTT position

Turn the POWER and HEATER switches to ON. From a cold start, allow 60 seconds after the HEATER switch is turned on for warm-up of the transmitter tubes. Be certain that the accessory plug is inserted in the accessory plug is inserted in the accessory socket; without this plug being so connected, there will be no power applied to the tube heaters. Heater voltage is supplied through pins 1 and 2 of the accessory socket.

LOADING POSITIONS

BAND	POSITION
160	5
80	4
40	3.5
20	3
15	2.5
10A	. 3
10B	3
10C	3
10D	3

Note: LOADING positions are nominal. Minor variations from positions shown are to be expected.

Set the VOX GAIN control to MOX. The meter will now read final amplifier resting cathode current. This should read .05 (50 mA).* If it is not, adjust the bias control located under the top cover near the rear of the set. Set the METER switch to ALC and adjust the ALC control under the top cover for full scale deflection of the meter. Return the meter switch to IC and the VOX GAIN control to PTT.

*Note: On the FT-901SD, resting cathode current should be .025 (25 mA).

PRE-TUNING

(IMPORTANT NOTE: Subsequent transmitter tuning utilizes the TUNE button instead of MOX for actuating the transmitter. When pressed, the TUNE button causes the transmitter to be activated for ten seconds, after which time the FT-901DM returns to the receive condition. This is a protective feature that should not be nullified by use of the MOX control.)

- (1) Adjust the PRESELECT control for maximum receiver noise level.
- (2) Depress the TUNE button. Rotate the CARR control until the meter reading rises just above the normal idling current of .05 (50 mA).
- (3) Adjust the PRESELECT control for a maximum meter indication.

Caution: if the meter reading exceeds .1 (100 mA) reduce the setting of the CARR control.

- (4) Rotate the PLATE control for a minimum meter reading ("dip" in final amplifier cathode current).
- (5) Push the TUNE button again to return the transceiver to the receive condition.

FINAL TUNING

Final peak tuning utilizes the relative power output position of the METER switch. At full rated power into a 50 Ohm load, the meter will read approximately 1/2 to 2/3 full scale. If the PO reading is too high (off scale) or too low (1/4 scale or less) and the load impedance is very close to 50 Ohms, the PO ADJ control on the rear apron may be adjusted so as to provide 1/2 to 2/3 scale deflection at full power. Once the PO meter is calibrated, off-scale meter deflections are the result of reflected power due to high SWR, and corrective action may be required in the antenna system.

Final transmitter peaking is described below:

- (1) Set the METER switch to the PO position and rotate the CARR control to the 11 o'clock position.
- (2) Press the TUNE button and rotate the PRE-SELECT control for a maximum meter reading. Press the TUNE button again to return to the receive condition.
- (3) Press the TUNE button and rotate the LOAD-ING control for a maximum meter reading. Press the TUNE button again to return to the receive condition.
- (4) Press the TUNE button and rotate the PLATE control for a maximum meter reading. Press the TUNE button again to return to the receive condition.
- (5) Repeat steps 2 through 4, advancing the CARR control approximately 2 units for each set of adjustments until the CARR control is fully clockwise. The transmitter is now tuned for maximum power output.
- (6) Return the CARR control to the fully counter-clockwise position. Return the METER switch to IC.

With familiarity, some of steps 2 - 4 may be performed within one press of the TUNE button, taking advantage of the 10-second timer. The operator is discouraged, through, from exceeding the 10-second limitation imposed by the timer through use of the MOX position or the microphone PTT switch.

SSB OPERATION

After completion of the above tuning procedure, set the MODE switch to USB or 1 SB as desired. Set the VOX GAIN control to PTT and activate the transmitter by pushing the microphone PTT switch or the footswitch, if used. While speaking in a normal voice into the microphone, advance the MIC GAIN control until the meter kicks down to the midscale of the green-colored portion of the meter scale.

Note: When the METER switch is set to IC, voice modulation peaks will indicate 150 - 200 mA. Actual peak current however, is approximately 2 times the indicated value.

To set the sensitivity of the VOX system, begin with the VOX GAIN control in the PTT position. Advance the VOX GAIN and speak in a normal voice. The VOX GAIN control should be advanced until the voice actuates the transmitter (do not press the microphone PTT switch or footswitch, if used, during this adjustment).

Set the antitrip potentiometer under the top cover to the minimum point which prevents the speaker output from tripping the VOX. Do not use more VOX GAIN nor antitrip than necessary Adjust the delay potentiometer under the top cover for the desired release time.

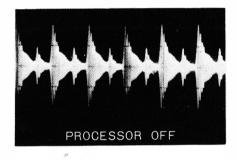
If desired, the AMGC circuit may be activated. This circuit acts as a "microphone squelch;" that is, it initiates a threshold for microphone input which must be exceeded before output from the microphone amplifier will occur. This feature permits minor noises such as a TV in the operating room to be present without going out over the air. Adjustment of the AMGC delay time is made by a control under the top cover.

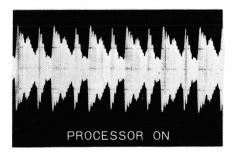
RF SPEECH PROCESSOR ADJUSTMENT (All models)

The FT-901DM speech processor, when properly adjusted, is designed to improve the intelligibility threshold at the receiving end by increasing the average SSB power output. RF clipping is applied to the IF signal, which is then filtered to remove harmonics and out of band intermodulation products.

The distortion produced by RF envelope clipping and filtering is less objectionable than that caused by an equivalent amount of audio clipping. RF clipping causes no increase in the peak power output, but it does clip the peaks of the voice waveform so as to increase the average power output.

With the processor switch (located immediately to the left of the PROC LEVEL control) in the OFF position (not depressed), set the METER switch to the ALC position. Speaking at a normal level, set the MIC GAIN control to the level where the meter indication stays in the green portion of the meter scale. Press the processor switch and adjust the PROC LEVEL control to the position where the ALC indication stays in the green portion of the meter scale while speaking in a normal voice. Optimum setting of the MIC GAIN and PROC LEVEL controls may require observation of the transmitted signal using an oscilloscope.





CW OPERATION

Note: The Curtis 8043 IC Keyer Unit is built-in on the FT-901DM/DE, and is an available option on the FT-901D/SD models.

For electronic keyer operation, insert a three conductor plug attached to a keyer paddle into the KEY jack on the rear apron. Keyer speed may then be adjusted by varying the KEYER control on the front panel.

For straight key, bug, or external electronic keyer use, rotate the KEYER control fully counter-clockwise into the click-stop. The desired key line may then be inserted into the KEY jack. Refer to the drawings on page 9 for details of the proper key line plug wiring.

The transmitter may be activated on CW by MOX, PTT, or by VOX (semi-break-in) as desired. The key-up voltage across the key terminals is 7 volts, while the key-down current is 1.5 mA, so most external electronic keyers may be used with the FT-901DM without modification.

The operator may select any power output desired by advancing the CARR control as desired.

NOTE: Insertion of the key plug automatically disconnects the bias supply to the PA tubes. Therefore, bias current will not be indicated when the METER switch is in the IC position.

AM OPERATION

AM operation of the transmitter is accomplished by setting the MODE switch to the AM position and inserting the proper amount of carrier with the CARR control.

After completing basic transmitter tune-up, place the MODE switch in the AM position. Activate the transmitter, and rotate the CARR control until the meter reads .10 (100 mA) in the IC position of the METER switch. While speaking into the microphone in a normal voice, increase the MIC GAIN control until the meter indicates very slight movement with voice peaks. Care must be exercised that the CARR control is not advanced too far. Do not exceed .10 (100 mA) meter indication during AM operation or damage to the transmitter final amplifier tubes may result.

For AM reception, an AM filter is available as an option.

FSK OPERATION

After completing basic transmitter tune-up, place the MODE switch in the FSK position. The FSK terminal input may be connected to the FSK jack on the rear panel. The FT-901DM is set up for 170 Hz shift, and the shift frequency may be adjusted somewhat by means of the trimmer capacitors located under the top cover. The CARR control must be adjusted in the TUNE position for not more than 100 mA. Excessive cathode current may result in damage to the final amplifier tubes.

Audio output from the transceiver may be taken from the SP jack in the rear apron.

FM OPERATION

Note: The FM Unit is built-in on the FT-901D/DM, and is an available accessory on the FT-901SD/DE models.

After completing the basic transmitter tune-up, set the CARR control for 100 mA carrier level in the FM mode. Speak into the microphone in a normal voice. The MIC GAIN and PROC LEVEL controls have no effect in the FM mode.

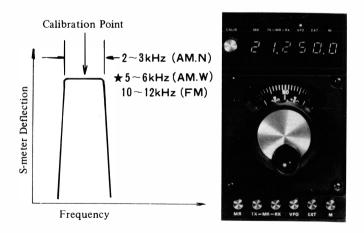
For FM reception, the SQL control on the front panel should be advanced only as far as required to silence background noise. When adjusted just past the silencing threshold, the squelch circuitry will provide noise-free reception with maximum sensitivity to weak FM signals.

DIAL CALIBRATION

The frequency readout of the FT-901DM is designed to indicate the carrier frequency. Consequently, there will be a 3 kHz difference between USB and LSB. When calibrating the dial and digital display, the CLARIFIER switch should always be OFF.

- (1) For SSB calibration, place the NB/MARK switch in the MARK position to activate the internal marker signal generator. The choice of 25 kHz or 100 kHz marker intervals may be made by changing the position of switch S₆₀₁, which is located on the VOX unit.
- (2) As the main tuning knob is turned, a beat note will be heard every 25 kHz or 100 kHz, depending on the position of S₆₀₁. Tune the dial and secure a zero beat (lowest pitch frequency) with the marker signal nearest the desired operating frequency.

- (3) Turn the ribbed calibration ring on the main tuning knob shaft to calibrate the analog scale precisely to the zero or 25 kHz point.
- (4) Adjust the CALIB control for a precisely correct reading in the digital window (for example, 14.225.0).
- (5) For CW calibration, secure a zero beat as above, then adjust the CALIB control until the digital display frequency indication is 700 Hz higher than the zero beat (for example, 14.000.7). Then rotate the main tuning dial to secure the zero or 25 kHz reading on the digital display (14.000.0); rotate the ribbed calibration ring on the main tuning knob shaft to align the analog dial precisely with the calibration mark and the digital display. In the CW mode, to repeat, the transmitter carrier frequency is the frequency being displayed.
- (6) In the AM and FM modes, the zero beat signal is not available. Place the WIDTH control in the "0" position, and tune the dial for maximum S-meter indication on the marker signal to establish the calibration point.



SELECT SWITCHES/MEMORY SYSTEM OPERATION

(Note: The memory unit is built-in on the DM model, optional on the D/SD/DE models)

Frequency control of the FT-901DM is by means of the internal VFO, the memory unit, an external VFO, or various combinations of the three.

Split-frequency control may be obtained with the memory system or the FV-901 synthesized scanning VFO. The switches involved in frequency control are as follows:

MR This button recalls the memorized frequency for control of the transceive frequency.

TX MR This button recalls the memorized frequency for control of the transmit frequency.

RX MR This button recalls the memorized frequency for control of the receive frequency.

VFO Frequency control is by means of the internal VFO as controlled by the main tuning knob.

EXT This switch selects the FV-901 synthesized scanning VFO for frequency control as follows: with the EXT and MR
buttons pushed, transceive frequency
control is by means of the external VFO.
With the EXT and TX MR buttons
pushed, the external VFO controls
the transmit frequency while the internal
VFO controls the receive frequency.
With the EXT and RX MR buttons
pushed, the external VFO controls the
receive frequency while the internal
VFO controls the transmit frequency.

M This button is used to store a frequency in memory. THE FREQUENCY DISPLAYED ON THE DIGITAL READOUT WILL BE THE FREQUENCY STORED WHEN THE M BUTTON IS PRESSED. When the M button is pressed, the frequency previously stored in memory will be destroyed. When the power is turned off, the frequency is lost from memory.

Note: Because of "round-off error" the digital display and memory system may exhibit a 100 Hz difference between the VFO condition and the memory recall condition.

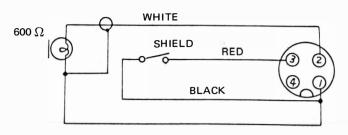
Operation of the memory system is perhaps best described by the use of some examples:

- (1) You are operating on a net on 3970 kHz and must QSY down 10 kHz to handle a piece of traffic. With the VFO button depressed and the main dial on 3970 kHz, press M; 3970 is now memorized. Move the main dial down to 3960 kHz to handle the message. When finished, press MR for instant return to 3970 kHz. The main dial may be left at 3960 kHz if further QSY to that frequency is anticipated. To return to 3960 kHz, simply press VFO.
- (2) You are operating split frequency on 40 meter phone, and you hear DX1DX on 7090 kHz, listening for calls on 7205 kHz. With the VFO button depressed and the main dial on 7090 kHz, press M to store 7090 kHz in memory, and press RX MR to lock the receiver on 7090 kHz. Turn the main tuning dial to 7205 kHz; you will now be transmitting on 7205 kHz and listening on 7090 kHz. To listen to the pile-up on 7205 kHz of stations calling DX1DX, push VFO; you will now be listening and transmitting on 7205 kHz, and another press of RX MR will return you to 7090 kHz for receive. If DX1DX should begin to drift slightly in frequency, push TX MR and M to store 7205 kHz in memory and lock the transmitter on that frequency. Place the main dial on 7090 kHz for precise tracking of the unstable DX1DX signal.
- (3) You find DX1DX on 21270 kHz, working stations by order of call area. By pressing the M button, 21270 kHz may be stored in memory and the operator may periodically check to see if his call area is being acknowledged by pressing MR or RX MR.

Note: After the M button is pushed, the VCO requires 10 seconds to stabilize on the memorized frequency. If one of the MR buttons is pushed during this 10-second period, some "drifting" of the memorized frequency may be observed.

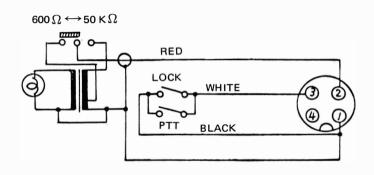
MICROPHONE CONNECTIONS





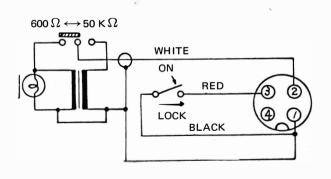
YE-7A Original Microphone





YD-844A





YD-148

PART DESIGNATIONS ON CIRCUIT BOARDS

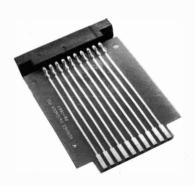
PLUG-IN MODULES

The FT-901DM utilizes computer-type plug-in modules, for ease of servicing. Extender boards of 10 pins (single and double face), 18 pins (single and double face), and 22 pins (single face) can be had from your Yaesu dealer to provide access to test points.

All parts used in the FT-901 transceivers have a part number (e.g. Q_{506}) assigned to them.

Part numbers 01-99 (e.g. R_{12}) are located on the main chassis. Other parts located on the printed circuit boards are assigned a three or four digit part number. The last two digits are the part number for that board; the first one or two figures are the code for the printed circuit board.

Thus, Q₃₀₁ is transistor number 01, located on circuit board #3, which is the FILTER unit. Refer to the chart below for a tabulation of the code numbers assigned to the various circuit boards used in the FT-901 trnsceivers.



10 Pin



18 Pin

Code #	Unit	Board designation
1	RF	PB-1702
2	NB	PB-1703
3	FILTER	PB-1716
4	IF	PB-1704
5	AF	PB-1705
6	VOX/MARK	PB-1846
7	CARRIER	PB-1706
8	VFO	PB-1440
9	FM	PB-1707
10	RECT A	PB-1708
11	PLL	PB-1709
12	VCO	PB-1710
13	XTAL	PB-1711
14	RECT HIGH B	PB-1708
15	CAPACITOR	PB-1713
16	DRIV	PB-1714
17	FINAL	PB-1715
18	RECT C	PB-1717
19	SELECT SW	PB-1718
20	SW	PB-1719
21	TUNE SW	PB-1720
22	LED A	PB-1721
23	REJ SW	PB-1722
24	TRIMMER A	PB-1723
25	TRIMMER B	PB-1724
26	TRIMMER C	PB-1092
27	KEYER	PB-1728
28	MEMORY	PB-1787
29	COUNTER	PB-1729
30	DISPLAY	PB-1730
31	DIODE SW	PB-1726
32	DC-DC CONVERTER	_



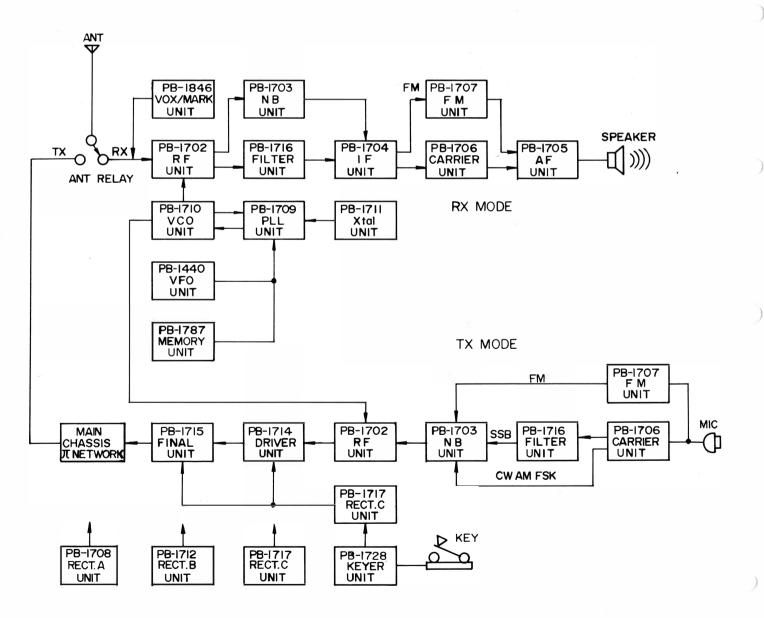
22 Pin

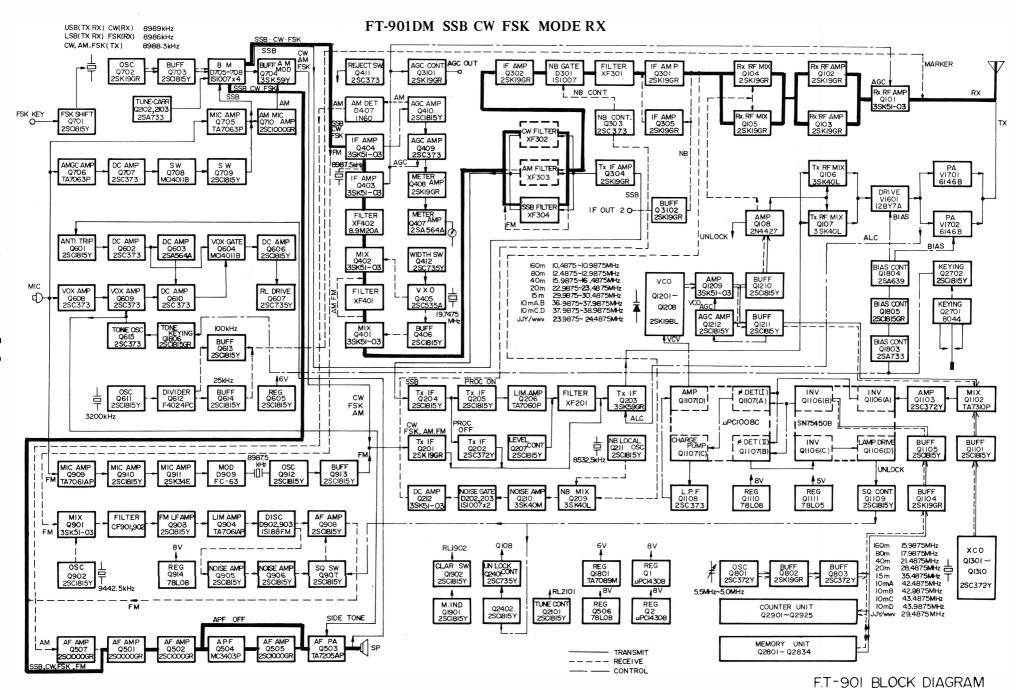
SIGNAL TRACING IN THE FT-901

Because the signal path may change considerably when the mode is changed, we have included augmented block diagrams on page 2-3 through 2-9, in order to assist you in understanding the function of the FT-901.

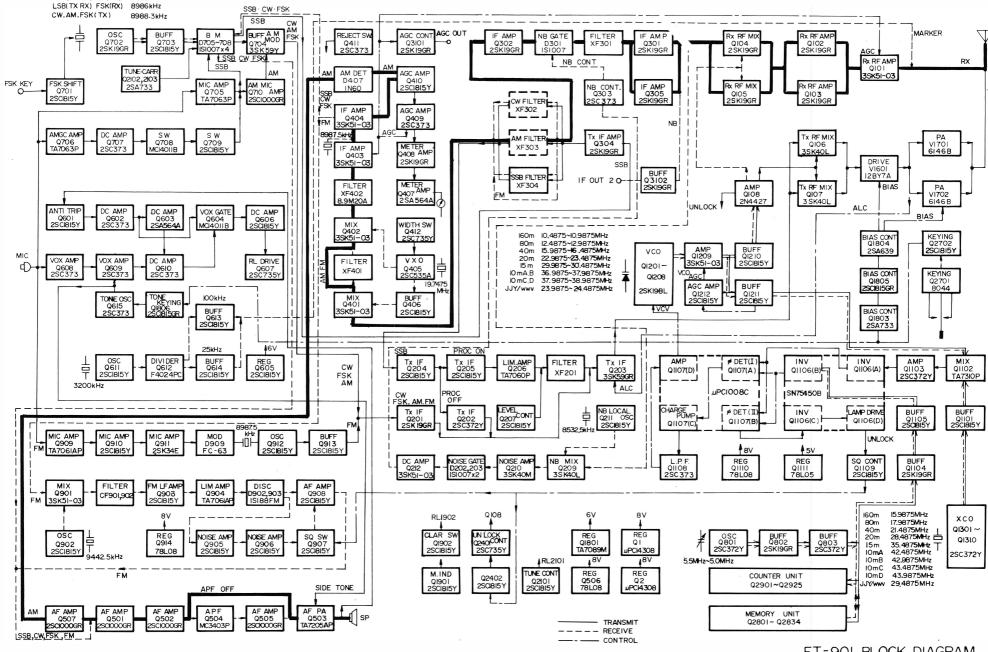
Below you will find a board-to-board block diagram, showing the TX and RX signal paths through the transceiver.

It should be noted that the internal calibrator (Marker) is an extremely useful signal for preliminary fault localization. In a properly functioning FT-901, the S-meter should read approximately S9 + 10 dB, when the preselector is peaked on 14.000 MHz SSB. Minor variations from this number are not unusual, but a blown RF amplifier FET will cause this indication to be practically nil. By using the internal calibrator, an experienced technician can peak practically all circuits on the receiver side, without the use of an external signal generator.

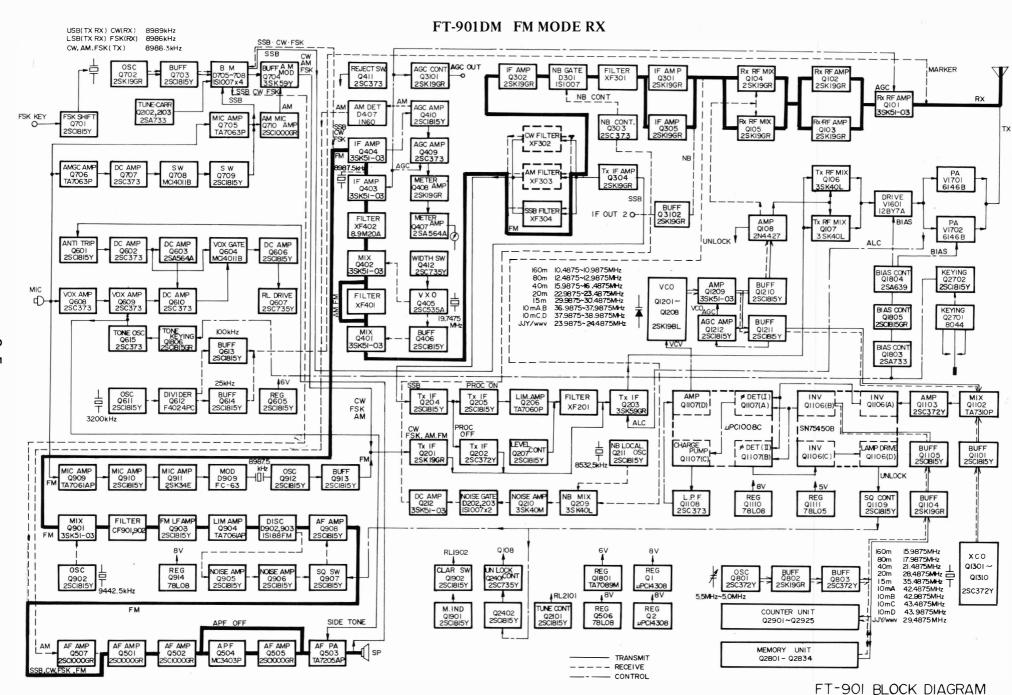


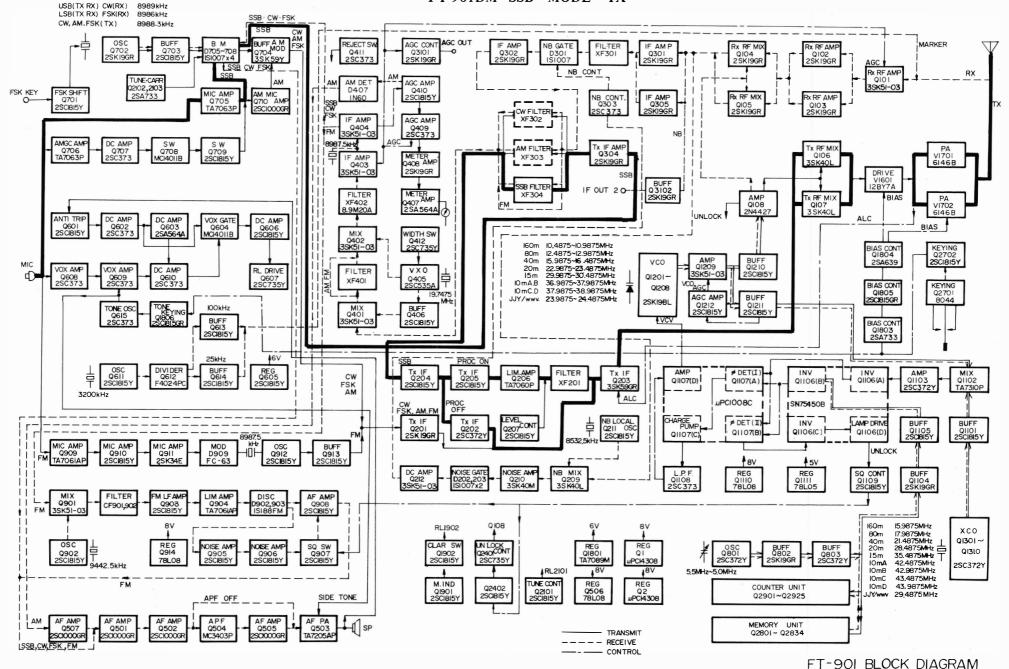


USB(TX RX) CW(RX) 8989kHz



FT-901 BLOCK DIAGRAM

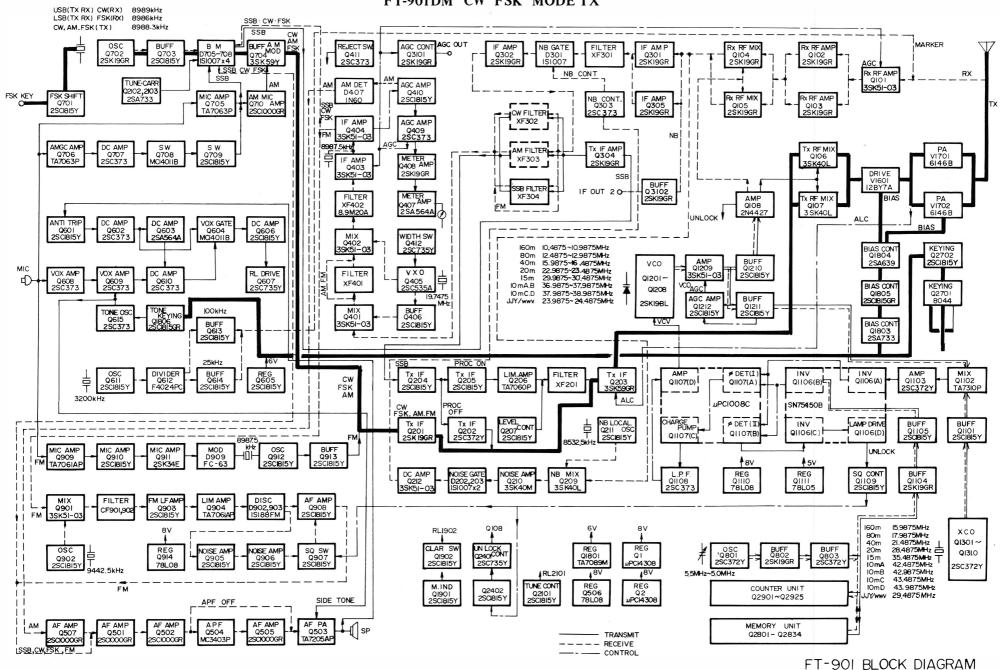




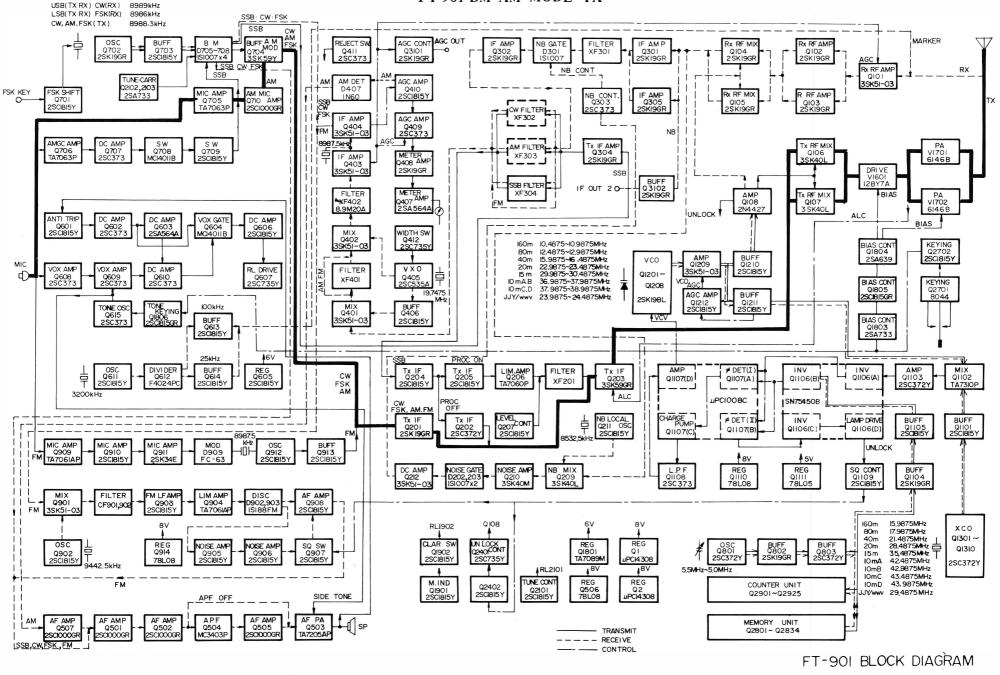
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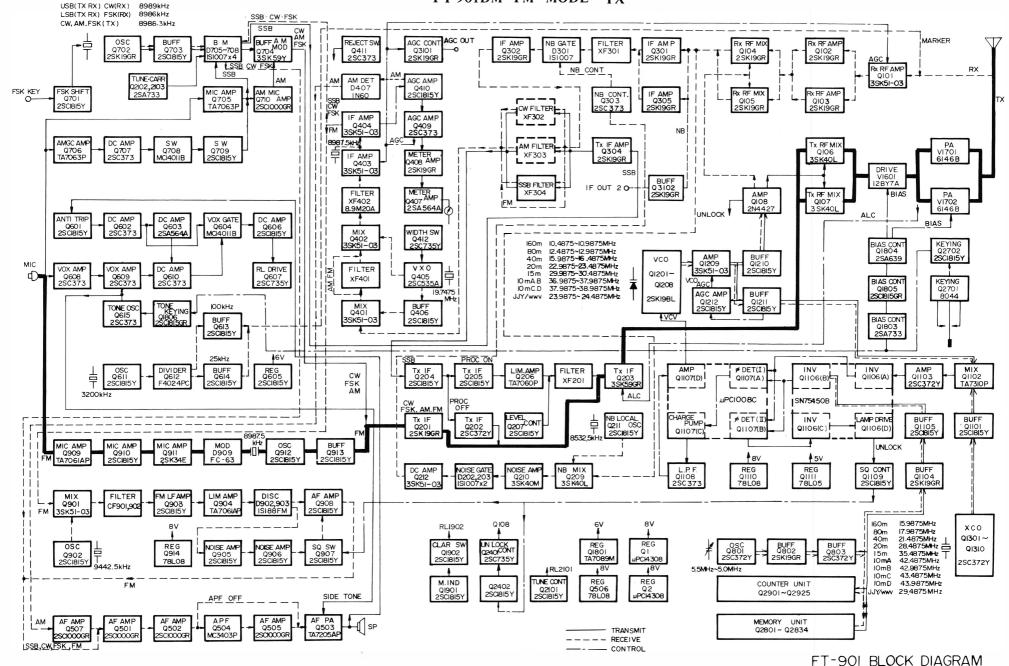
FT-901DM CW FSK MODE TX



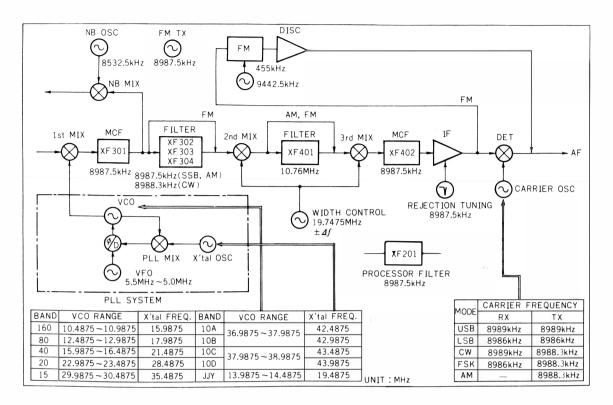
FT-901 DM AM MODE TX



FT-901DM FM MODE TX



FREQUENCY RELATIONS



CRYSTAL DATA FT-901DM

			·			·	
UNIT	FUNCTION	HOLDER	FREQUENCY (kHz)	MODE	LOAD C (pF)	EFFECTIVE RESISTANCE	DRIVE LEVEL
CRYSTAL	160m	HC-25/U	15987.5	3rd overtone	30	80 (2)	2mW
	89m	<i>,, ,,</i>	17987.5	"	"	60	"
	40m	<u> </u>	21487.5	"	" `	45	"
	20m	"	28487.5	"	"	40	"
	15m	"	35487.5	"	"	40	"
	10m (A)	"	42487.5	"	"	40	"
	10m(B)	"	42987.5	"	"	40	"
	10m(C)	"	43487.5	"	"	40	"
	10m(D)	"	43987.5	"	"	40	
	WWV(5MHz)	"	19487.5	"	"	40	"
	" (15MHz)	"	29487.5	"	"	40	"
CARRIER	LSB	HC-18/U	8986	Fundamental	35	30	10mW
	USB	"	8989	"	"	35	"
	CW·FSK·AM	"	8988.3	"	"	35	"
NB·PROC	Local	"	(1) 8532.5	11	"	35	"
IF	Reject	"	(2)cf. 8987.5	Resonate	"	35	"
	Width	11	(3)cf.19747.5	Fundamental	"	15	2mW
FM	Carrier	"	(4) 8987.5	. <i>11</i>	"	5	11
	Local	"	(5) 9442.5	"	30	35	
COUNTER	Local	"	18000	"	"	15	10mW
	Local	"	18500	"	"	15	"
	Clock	HC-14/W	655.36	"	23	7 K	2mW
VOX/MARK	Marker	HC-6/W	3200	"	"	50	5mW
MEMORY	Clock	HC-18/U	3276.8	"	"	200	3mW

NOTES

(1) ACTUAL FREQUENCY:

8534.5 kHz (2kHz up)

(2) ACTUAL FREQUENCY:

9017.5 kHz (30 kHz up)

(3) XCO FREQUENCY:

19743-19753 kHz

(4) Grounded case. (5) RESONATE FREQUENCY:8985.5-8989.5 kHz

Decided by circuit

THEORY OF OPERATION

This transceiver utilizes PLL (Phase Locked Loop) circuitry. The receiver is a single-conversion type with a 8.9875 MHz IF. The following circuit description is tailored to the full-feature FT-901DM, and some of the features and circuitry described below are optional on the FT-901D/SD/DE models.

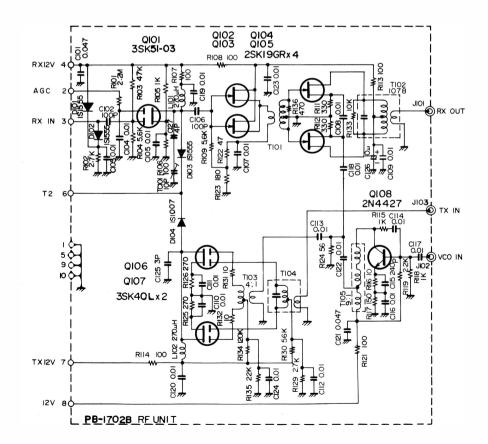
RECEIVER

The RF input signal from the antenna is fed to pin 3 of the RF UNIT (PB-1702) via antenna relay RL_2 , line fuse FH_1 , attenuator switch S_{2103} , input transformer T_1 , and 9 MHz trap coil T_{2402} .

RF UNIT (PB-1702)

The incoming signal is amplified by the RF amplifier Q_{101} (3SK40M), a dual-gate MOSFET which has superior rejection against cross modulation. The amplified signal is then fed through a source follower by parallel-connected Q_{102} and Q_{103} (both 2SK19GR) to the balanced mixer consisting of Q_{104} and Q_{105} (both 2SK19GR), where the input signal is heterodyned with a local signal delivered from buffer amplifier Q_{108} (2N4427), producing an IF signal of 8.9875 MHz at J_{101} .

The input and output of the RF amplifier are permeability tuned circuits, resulting in high sensitivity with excellent rejection of unwanted out-of-band signals.



FILTER UNIT (PB-1716C)

The IF signal received at pin 2 of the FILTER UNIT (PB-1716) is amplified by parallel-connected Q_{301} and Q_{305} (both 2SK19GR), and fed through a monolithic filter XF $_{301}$ (8.9M-20A), which has a ± 10 kHz bandwidth, providing additional selectivity and enough delay time to match the noise blanker gating pulses. The signal is then fed to the second IF amplifier, Q_{302} (2SK19GR).

The noise blanker diode D_{301} (1S1007) is placed between T_{302} and T_{303} , and it functions as an ON/OFF switch which is controlled by the noise blanker driver Q_{303} (2SC1815Y). The output from the source of Q_{302} is passed through the SSB filter XF_{304} (or the optional AM or CW filters). Selection of the filter to be used is performed by one of the diode switches D_{303} - D_{308} (1S1007), depending on the mode of operation. The IF signal is then transferred to the IF UNIT. In the FM mode, the IF signal is coupled directly through D_{310} (1S1555) to pin 5 of the IF UNIT.

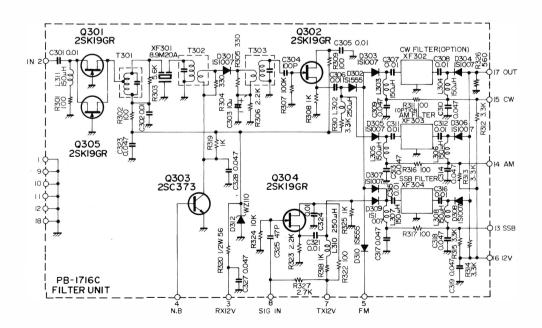
IF UNIT (PB-1704)

The IF signal from pin 14 is fed to the gate of the IF first mixer, Q_{401} (3SK51), where the IF signal is heterodyned with a 19.7475 MHz $\pm \Delta f$ local signal delivered from crystal oscillator Q_{405} (2SC535A) and buffer amplifier Q_{406} (2SC1815Y). resulting in a signal of 10.76 MHz $\pm \Delta f$.

The new $10.76\,\text{MHz} \pm \Delta f$ signal is fed through filter XF_{401} to the IF second mixer, Q_{402} (3SK51), where the filtered signal is heterodyned with a $19.7475\,\text{MHz} \pm \Delta f$ signal, producing an $8.9875\,\text{MHz}$ signal, the same as the original IF. This process moves the IF signal across the passband of XF_{401} . The combination of filters XF_{304} and XF_{401} provides continuously variable width of the IF passband.

The frequency of crystal oscillator Q_{405} is varied by varactor diode D_{401} (1S2209).

On the AM and FM modes, the IF signal is passed through diode switches D_{402} and D_{403} (1S1007), and does not pass through filter XF_{401} .



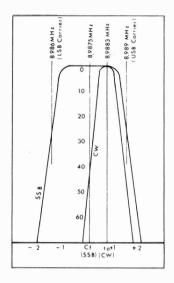
The output from the IF second mixer is fed through a monolithic filter XF_{402} to the two-stage IF amplifier consisting of Q_{403} and Q_{404} (both 3SK40M). The output from Q_{403} is coupled to the rejection tuning circuit which eliminates interference within the IF passband. This rejection function is accomplished by varying the resonant frequency of a crystal with varactor diode D_{406} (1S2209) on the SSB, CW, and FSK modes.

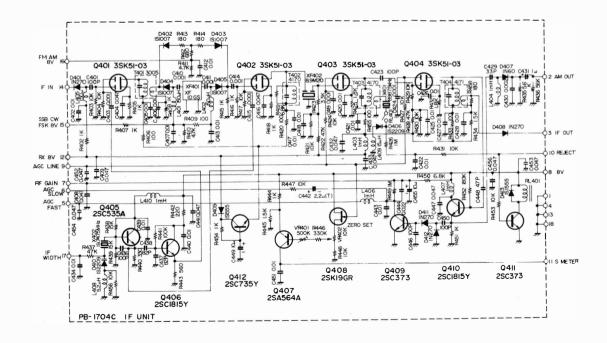
The amplified IF signal is fed to the CARRIER UNIT. In the AM mode, the signal is fed through a buffer amplifier Q_{410} (2SC1815Y) to the AM detector D_{407} (1N60). The signal is then fed to the AF UNIT.

A portion of the output from Q_{410} is rectified by D_{411} and D_{412} (1N60) to produce AGC voltage. The AGC voltage is amplified by DC amplifier Q_{409} (2SC373) and fed to the gate of RF amplifier Q_{101} and to IF amplifiers Q_{403} and Q_{404} to control the gain of these stages for AGC purposes. The time constant of the AGC voltage decay is selectable (FAST/SLOW) by switch S_{2003} . The AGC voltage is further amplified by Q_{408} (2SK19GR) and Q_{407} (2SA564A) for signal strength indication on the front panel S-meter.

The RF GAIN control on the front panel varies the AGC voltage level, providing manual control of the gain of the RF and IF stages.

 Q_{411} (2SC373) works as a relay driver for the IF rejection tuning circuit. Delay transistor Q_{412} (2SC735Y) supplies the voltage to the drain of Q_{401} and Q_{402} when the transceiver returns to the receive mode after transmission.





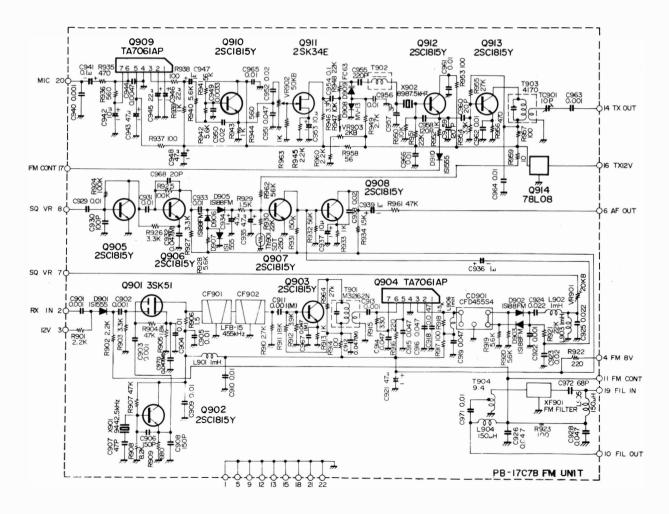
FM UNIT (PB-1707)

In the FM mode, the IF signal from the IF UNIT is fed to the gate of Q_{901} (3SK40M), where it is heterodyned with the 9442.5 kHz signal delivered from the FM oscillator Q_{902} (2SC1815Y), thus producing a 455 kHz IF signal. The 455 kHz IF signal passes through a two-stage ceramic filter consisting of CF_{901} and CF_{902} (LFB-15), and is amplified by an amplifier limiter consisting of Q_{903} (2SC1815Y) and Q_{904} (TA7061AP).

A ceramic discriminator consisting of CD_{901} (CFD455S4) and D_{902} and D_{903} (both 1S188FM) produces an audio output in response to a corresponding frequency shift in the 455 kHz IF signal. The discriminator output is amplified by Q_{908} (2SC1815Y) and fed to the AF UNIT at pin 6.

When no carrier is present in the 455 kHz IF, the noise at the discriminator output is amplified by Q_{905} and Q_{906} (both 2SC1815Y) and detected

by D_{905} and D_{906} (both 1S188FM) to produce a DC voltage. This voltage is applied to turn "on" Q_{907} (2SC1815Y). With Q_{907} "on," the base of Q_{908} is grounded to quiet the audio amplifier. When a carrier is present, the quieting action of the receiver removes noise from the discriminator output and Q_{907} is turned "off," permitting normal action of Q_{908} . The squelch control VR_{901} sets the squelch threshold level.

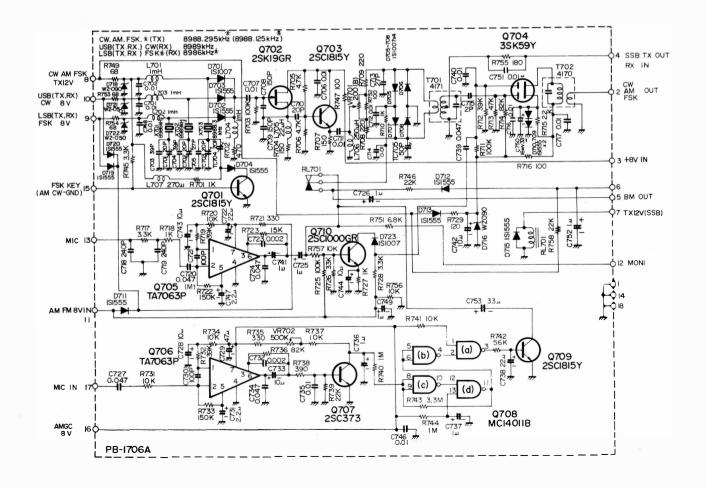


CARRIER UNIT (PB-1706)

The carrier oscillator Q_{702} (2SK19GR) is followed by a buffer amplifier Q_{703} (2SC1815Y). It oscillates at one of the following frequencies, depending on the mode of operation: 8989 kHz with X_{702} ; 8986 kHz with X_{701} ; or 8988.295 kHz with X_{703} . The crystal selection is made by diode switches D_{701} - D_{703} (1S1555).

Diode D_{701} conducts to activate X_{703} , which is used for the CW, FSK, AM, and TUNE transmit signal. Diode D_{702} conducts to activate X_{701} for LSB and FSK reception. Diode D_{703} conducts to activate X_{702} for USB and CW reception.

The carrier signal is fed to the ring demodulator consisting of D_{705} - D_{708} (all **1S1007**), which demodulates the IF signal into audio using the carrier signal applied from Q_{703} . The audio is then fed through relay contacts to the AF UNIT.

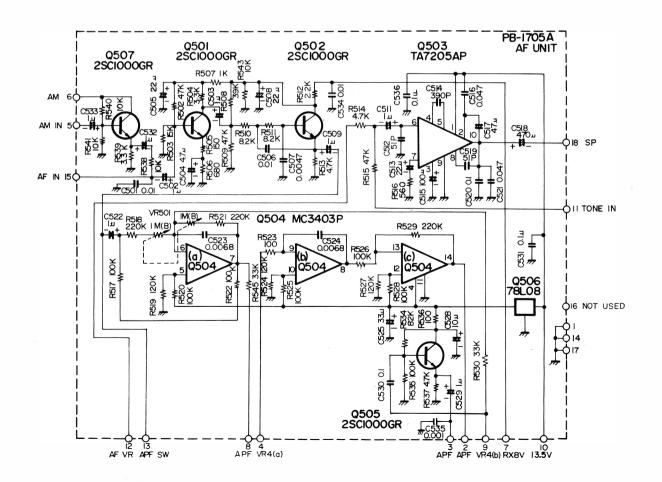


AF UNIT (PB-1705)

The audio signal from the AM detector is amplified by Q_{507} (2SC1000GR) and fed to the first audio amplifier Q_{501} (2SC1000GR). On SSB, CW, FM, and FSK, the audio signal is directly fed to Q_{501} from pin 15. The audio signal is amplified through Q_{501} and Q_{502} (both 2SC1000GR) and is then fed through the APF switch and audio volume control VR_5 a to the audio output amplifier Q_{503} (TA7205AP), which delivers 3 watts of audio output to the speaker.

The audio spectrum is shaped by an active lowpass filter of $f_0 = 2.7 \text{ kHz} - 12 \text{ dB/octave}$.

Operational amplifier $Q_{5\,04}$ (MC3403) and AF amplifier $Q_{5\,05}$ (2SC1000GR) are placed into the audio circuit by the APF switch on the front panel. The frequency of this selective amplifier is varied with the front panel APF control VR_4 a/b between 400 Hz and 900 Hz, providing single-signal, noise-free CW reception. $VR_{5\,01}$ provides adjustment of the selectivity of the APF circuit.



NB UNIT (PB-1703)

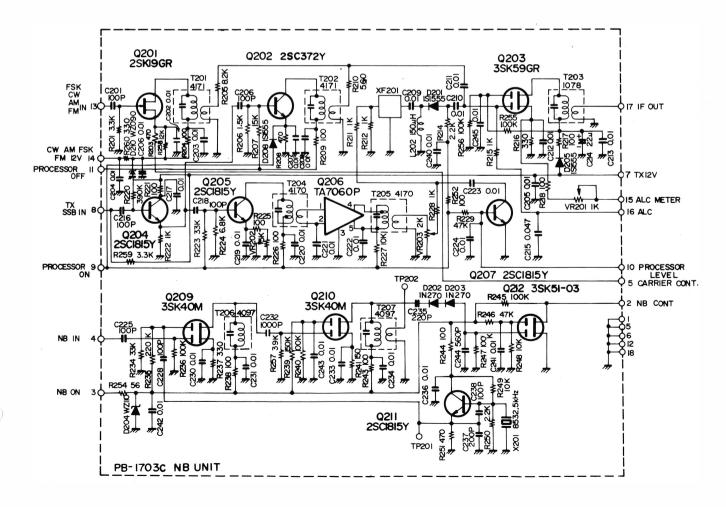
A portion of the 8987.5 kHz IF signal is fed to pin 4 of the noise blanker unit and appears at noise blanker mixer Q_{209} (3SK40M), where the 8532.5 kHz signal generated by Q_{211} (2SC1815Y) is mixed with the incoming signal to produce a 455 kHz signal. The 455 kHz signal is then amplified by Q_{210} (3SK40M).

When a carrier or a noise-free modulated signal is received, the 455 kHz signal (with its corresponding strength) is rectified by D_{202} and D_{203} (both 1N60) to charge C_{235} . There is no discharge loop for C_{235} ; therefore, signals which exceed the charged voltage established by the reference voltage on C_{235} will not pass through D_{202} and D_{203} . Accordingly, there will be no voltage drop across R_{247} , and Q_{212} (3SK40M) will conduct as the gate voltage approaches zero potential. When Q_{212} conducts, the drain voltage at pin 2 of the printed board will drop.

The drain of Q_{212} is directly connected to the base of Q_{303} (2SC1815Y) in the FILTER UNIT. As the drain voltage of Q_{212} drops, the base voltage of Q_{303} drops, turning off Q_{303} . The collector voltage will then increase, producing a forward bias to D_{301} (1S1007). As D_{301} conducts, the signals will pass normally through the circuit.

When pulse-type noise is received which exceeds the charged reference voltage established by C_{235} , D_{202} and D_{203} will permit negative-going pulses to turn Q_{212} off. The drain voltage will rapidly increase as it turns off.

As the drain voltage increases, Q_{303} will turn on and the collector voltage will decrease. Accordingly, D_{301} will be biased to block the signal. Thus, when pulse-type noise is received, the signal passage will be blanked off momentarily.



TRANSMIT CIRCUIT

SSB

The output from the MIC jack J_2 is fed through the MIC GAIN control VR_3a to pin 13 of the CARRIER UNIT.

CARRIER UNIT (PB-1706)

The microphone signal is amplified by microphone amplifier Q_{705} (TA-7063P) and fed through relay RL_{701} to the ring modulator, consisting of D_{705} – D_{708} (all 1S1007), where the signal modulates a carrier signal delivered from Q_{703} (2SC1815Y). The double sideband signal is fed through T_{701} to the FILTER UNIT.

FILTER UNIT (PB-1716)

The 8987.5 kHz signal fed to pin 8 of the FILTER UNIT is amplified by buffer amplifier Q_{304} (2SK 19GR) and is passed through sideband filter XF_{304} by diode switches D_{309} (1S1555) and D_{307} - D_{308} (both 1S1007) where the DSB signal is converted to an SSB signal by removing the unwanted sideband.

NB UNIT (PB-1703)

The SSB signal is fed through a buffer amplifier Q_{204} (2SC1815Y) to the bases of Q_{202} and Q_{205} (both 2SC1815Y). When the RF processor switch is "OFF," the SSB signal is amplified by Q_{202} and fed to Q_{203} (3SK59GR). When the processor switch is "ON," the SSB signal is amplified by Q_{205} (2SC1815Y) and is further amplified by the limiter Q_{206} (TA7060P), where the signals that exceed the preset clipping level are sliced out. VR_{203} is used to equalize the level of the clipped and unclipped signals.

This highly clipped SSB signal is passed through a selective filter XF_{201} to remove RF harmonics that result from signal clipping. The filtered output signal is amplified by Q_{203} and fed to the RF UNIT. The PROC LEVEL control VR_5 b, located on the front panel, varies the resistance

between the collector and emitter of Q_{207} (2SC 1815Y), thus changing the input signal level to the filter.

The CW, FSK, AM, and FM signals pass through Q_{201} (2SK19GR) and are fed to Q_{203} .

The ALC (Automatic Level Control) voltage detected at the grid circuit of the PA tube is fed to the first gate of Q_{203} to reduce the gain of the amplifier, thus preventing overloading and distortion.

RF UNIT (PB-1702)

The SSB signal from J_{102} of the printed board is fed to the balanced mixer consisting of Q_{106} and Q_{107} (both **3SK40M**), where the SSB signal is heterodyned to the desired RF frequency by mixing with the local signal which is supplied from the VCO UNIT. The mixer output is applied through diode switch D_{104} (**1S1555**) to the DRIVE UNIT.

DRIVE UNIT (PB-1714) PA UNIT (PB-1715)

The output from the RF UNIT is fed to the grid of the transmitter driver V_{1601} (12BY7A) where it is amplified to a level sufficient to drive the final amplifier tubes V_{1701} and V_{1702} (6146B). A portion of the RF signal is coupled through C_{16} to the cathode of the 12BY7A driver tube so as to improve the linearity of the final amplifier stage (RF negative feedback).

Neutralization of the power amplifier is accomplished by feeding back a small amount of the output through TC_1 to the cold end of the T_3/L_9 combination. The return of the grid circuit is connected to the REC A UNIT (PB1708) to produce ALC voltage to control the gain of the TX IF amplifier, thus preventing distortion caused by overdrive.

CW

In the CW, AM, and FSK modes, carrier oscillator Q_{702} (2SK19GR) on the CARR UNIT generates a crystal controlled carrier signal of 8988.2 kHz. The carrier is fed through buffer amplifier Q_{703} (2SC1815Y) to the ring modulator. Q_{702} also oscillates for TUNE operation.

DC voltage is applied through diode switch D_{912} (1S1555) and RL_{701} , to unbalance the ring modulator for CW, AM, and FSK operation; the resulting carrier signal is fed to T_{701} .

The output from T_{701} is amplified by Q_{704} (3SK59Y) and fed to Q_{201} (2SC1815Y) on the NB UNIT. The signal is then further amplified by Q_{203} (3SK59GR), and is fed to the transmitter mixer.

Keying of the transmitter is accomplished by changing the bias voltage to V_{1601} , V_{1701} , and V_{1702} . The tubes are cut off on "key up" by application of -35V for V_{1601} and -110V for V_{1701} and V_{1702} . These cutoff voltage are reduced to -0.1V and -60V, respectively, during "key down" conditions.

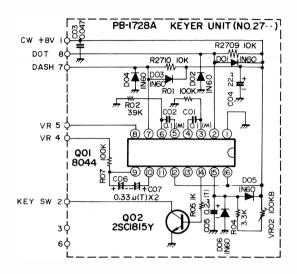
The key is connected to pin 13 of the REC C unit (PB1717). Under "key down" conditions, the base of Q_{1803} (2SA733) is grounded, causing Q_{1805} (2SC1815GR) and Q_{1804} (2SA639) to conduct. The voltage at pin 16 of PB-1717 reaches zero when Q_{1804} conducts. Since pin 16 of PB-1717 is connected to pin 2 of the RECT A UNIT (PB-1708), the bias voltage of V_{1601} , V_{1701} , and V_{1702} places these tubes in the normal operating condition.

On other modes, 12 volts is applied to pin 15, causing Q_{1804} to conduct, thus placing the operating bias on the tubes.

KEYER UNIT (PB-1728)

The built-in electronic keyer utilizes Q_{2701} (Curtis 8044 IC). The output of Q_{2701} is high during "key down" conditions; this output is connected to the base of Q_{2702} (2SC1815Y), the collector current of which is connected to the base of Q_{1803} , causing Q_{1803} to conduct during "key down" conditions.

Keyer speed is controlled by VR_2b on the front panel. VR_{2701} provides adjustment of the dot-space symmetry, while VR_{2702} adjusts the keying weight. VR_{2702} normally is set to minimum, providing a 1:1 dot: space weight.



AM

The microphone signal is amplified by Q_{705} (TA7063P) and Q_{710} (2SC1000GR) and fed to Q_{704} (3SK59Y), where it modulates the 8988.2 kHz carrier signal. The output from T_{702} is fed to the NB UNIT in the same manner as described in the CW section previously.

FSK

The carrier oscillator Q_{702} (2SK19GR) generates a crystal controlled carrier frequency of 8988.2 kHz. When keying is applied to the FSK jack J_{15} , the base voltage of Q_{701} (2SC1815Y) becomes zero, causing Q_{701} to cut off. In the "space" condition, Q_{701} conducts, placing TC_{704} in the circuit and lowering the carrier frequency to 8988.03 kHz.

AMGC circuit

The AMGC circuit is located in the CARRIER UNIT and is used to reduce the gain of the microphone amplifier when only low-level background noise is present (no speech input from the opera-

tor). The microphone signal is fed to pin 17 of the CARRIER UNIT, amplified by Q_{706} (TA 7063P), and fed to Q_{707} (2SC373). When a sufficient level of speech input is applied to the microphone, Q_{707} conducts, causing the output of NAND gate Q_{708} (MC14011B) to be "low." This condition cuts off AMGC controller Q_{709} (2SC1815Y). The collector circuit of Q_{709} is connected with the output circuit of the microphone amplifier Q_{705} .

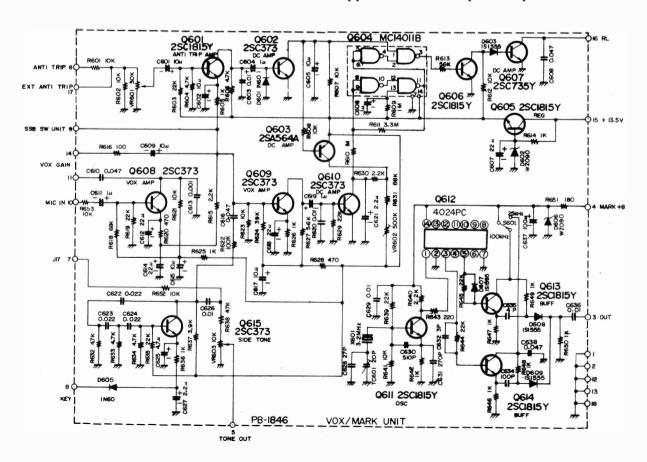
When the microphone input signal becomes significantly lower than the normal speech level (background noise only), Q_{707} turns OFF, causing the output of Q_{708} to be "high." This condition causes Q_{709} to conduct, grounding the output circuit of Q_{705} .

The gate holding time can be adjusted by means of VR_{702} , to allow for differences in operator preferences.

VOX UNIT PB-1846 (PB-1685-3330)

A portion of the microphone input is delivered to pin 10 of the VOX UNIT. The signal is amplified by Q_{608} and Q_{609} (2SC373) and fed to the base of Q_{610} (2SC373). When the signal is applied, Q_{610} conducts, causing C_{621} to discharge. The DC voltage of C_{621} is then fed to the gate circuit of Q_{604} (MC14011B). When pins 1 and 2 of Q_{604} are high, the output of the VOX gate of Q_{604} becomes low, causing Q_{606} (2SC1815Y) to cut off, thus turning relay driver Q_{607} (2SC735) ON to actuate the VOX relay RL_1 .

The antitrip circuit provides a bucking voltage to prevent the speaker output from tripping the transceiver into the transmit condition. The receiver audio output is fed through ANTITRIP control VR_{601} to amplifier Q_{601} (2SC1815Y) and is then rectified by D_{601} (1N60). The rectified DC voltage turns Q_{602} (2SC373) ON, placing its collector at a low level, thus preventing the gate circuit from activating the relay driver Q_{607} . The collector of Q_{602} is connected through R_{608} to the base of Q_{603} (2SA564A) which shorts the supply voltage for C_{621} ; thus, C_{621} is fully charged when the speaker output disappears, turning the gate into the transmit mode immediately with the appearance of microphone input.



The VOX GAIN control VR_1 on the front panel provides adjustment for relay sensitivity, and VR_{601} controls antitrip sensitivity. Relay hold time is determined by delay control VR_{602} .

The tone oscillator Q_{615} (2SC373) operates when the MODE switch is in the CW position. It is a phase shift oscillator operating at approximately 800 Hz. The sidetone level is adjusted by VR_{603} . The sidetone output is also coupled to the VOX circuit for semi-break-in operation.

Located on the VOX UNIT, the crystal marker generator Q_{611} (2SC1815Y) generates a basic 3200 kHz crystal controlled signal which is divided into 100 kHz multiples by frequency divider Q_{612} (4024PC). The voltage regulator Q_{605} (2SC 1815Y) regulates the supply voltage to the VOX circuit.

FM UNIT (PB-1707)

The speech signal from pin 20 of PB-1707 is fed to amplifier limiter Q_{909} (TA7061AP), which clips both positive and negative peaks when they exceed the level set for maximum deviation of the transmitter frequency. Q_{910} (2SC1815Y) acts as

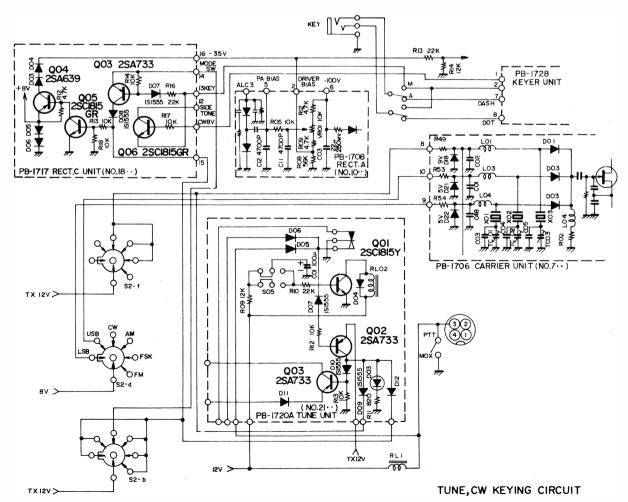
an active low pass filter to eliminate harmonics caused by the clipping. VR_{902} determines the maximum deviation.

The output from Q_{901} is amplified by Q_{911} (2SK34E) and then fed to the modulator D_{909} (FC63). Q_{912} (2SC1815Y) oscillates at a crystal frequency of 8987.5 kHz and is frequency modulated by varactor diode D_{909} . The output from Q_{912} is amplified by Q_{913} (2SC1815Y) and then fed to the NB UNIT.

TUNE UNIT (PB-1720)

When TUNE switch S_{2101} is pushed, the voltage across C_{2101} is applied to the base of Q_{2101} (2SC1815Y), causing Q_{2101} to turn ON; this activates RL_{2102} which grounds the cathodes of D_{2105} and D_{2106} (both 1S1555). As D_{2105} is connected in parallel with the PTT switch, the transceiver is placed in the transmit mode.

Diode D_{2106} grounds the common terminal of the MODE switch S_2g and S_2h , and the bias voltage of the PA stage is lowered from the cutoff condition to the normal operating level.



When D_{2107} is grounded, D_{2102} (2SA733) turns ON, and the voltage appearing at the collector of Q_{2102} is fed through D_{2109} (1S1555) to D_{701} on PB-1706 to activate the CW carrier oscillator. In the SSB mode, the SSB carrier oscillator is disabled by reverse voltage.

COMMON CIRCUITS

VFO UNIT (PB-1440A-3330)

A modified Colpitts-type oscillator is used to generate a 5.0 - 5.5 MHz signal, producing a 500 kHz tuning range. The frequency is varied by VC_{801} , which is geared to a precision-built dial tuning mechanism. VC_{801} consists of two sections. The sub-blades compensate for the capacitance variation of the main blades which may result from extreme temperature change.

Varactor diode D_{801} (1S2236) is in series with C_{807} , and the combination of the two is in parallel with TC_{801} . By closing the CLARIFIER switch, the VFO frequency may be varied ± 2.5 kHz with the CLARIFIER control on the front panel.

The oscillator output signal is fed through the amplifier/buffer stage Q_{802} (2SK19GR) and Q_{803} (2SC372Y), and then passes through the low-pass filter to the output terminal.

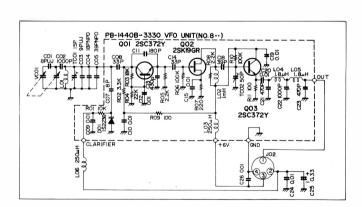
XTAL UNIT (PB-1711)

Crystal oscillator Q_{1301} - Q_{1310} (all 2SC1815Y) produces a heterodyne signal for the PLL (Phase Locked Loop) mixer. The oscillator frequency is selected by the BAND switch, and the output signal is fed through diode switch D_{1301} - D_{1310} (all 1S1555) to the PLL UNIT. The frequency of each crystal is shown in Table 1.

VCO UNIT (PB-1710)

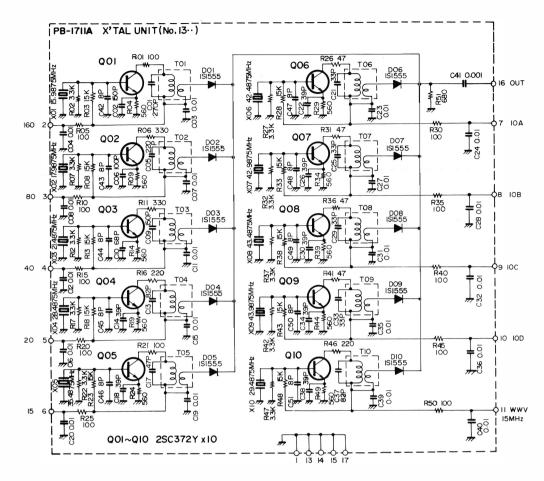
The VCO (Voltage Controlled Oscillator) generates a heterodyne signal which is 8.9875 kHz higher than the operating frequency. The frequency is locked by the voltage detected by the PLL UNIT.

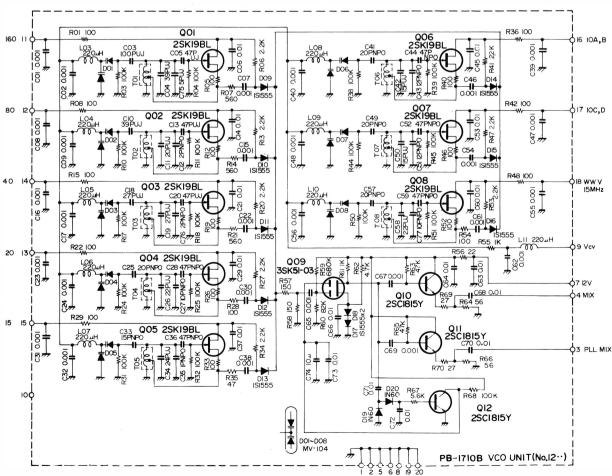
 Q_{1201} - Q_{1208} (all **2SK19BL**) oscillate at the frequency given in Table 1. The frequency is locked by varactor diodes D_{1201} - D_{1208} (all **MV104**), which are controlled by the VCV voltage supplied from the PLL UNIT. The oscillator output signal is amplified by Q_{1209} (**3SK40M**) and fed to the buffer/amplifier consisting of Q_{1210} and Q_{1211} (both **2SC1815Y**). The output from Q_{1210} is fed to the transceiver mixer in the RF UNIT; the output from Q_{1211} is fed to the PLL UNIT as a sample signal.



	Crystal Oscillator	V C O		
160m	15.9875(MHz)	10.4875~10.9875(MHz)		
80m	17.9875	12.4875~12.9875		
40m	21.4875	15.9875~16.4875		
20m	28.4875	22.9875 ~ 23.4875		
15m	35.4875	29.9875 ~ 30.4875		
10mA 42.4875		00.0005.00.0005		
10mB	42.9875	36.9875 ~ 37.9875		
10 m C	43.4875	37.9875~38.9875		
10mD	43.9875			
JJY/WWV	29.4875	23.9875~24.4875		

Table 1





A portion of the Q_{1209} output is rectified by D_{1219} and D_{1220} (both 1N60); this rectified DC voltage is amplified by DC amplifier Q_{1212} (2SC 1815Y) to generate AGC voltage which controls the gain of Q_{1209} , thus obtaining unity signal output when the band is changed.

PLL UNIT (PB-1709)

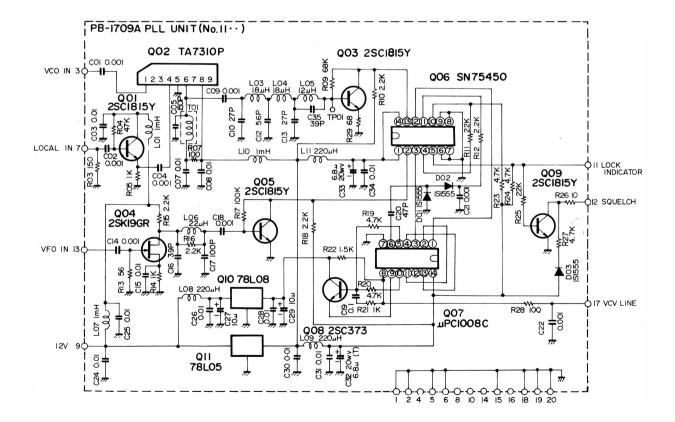
The sample signal from the VCO UNIT is fed to the PLL mixer Q_{1102} (TA7310P), where the sample signal is mixed with the heterodyne signal (at 5.0 - 5.5 MHz) delivered from the XTAL UNIT through buffer amplifier Q_{1101} (2SC 1815Y). The 5.0 - 5.5 MHz signal is fed through amplifier Q_{1103} (2SC1815Y) to Q_{1106} (SN 75450B), where the signal waveform is shaped

prior to being supplied to a phase detector Q_{1107} (MC4044P); here the phase of the signal is compared with the phase of the signal delivered through wave shaper Q_{1106} , buffer Q_{1105} (2SC 1815Y), and amplifier Q_{1104} (2SK19GR) from the VFO UNIT.

 Q_{1107} compares the phase of the two signals and converts the phase difference into the VCV voltage which controls the VCO frequency. Q_{1108} (2SC 373) acts as an active low pass filter to remove ripples from the VCV voltage.

When the VCO is unlocked, Q_{1109} (2SC1815Y) delivers the signal to prevent receive or transmit action of the transceiver.

 Q_{1110} (78L08) and Q_{1111} (78L05) are voltage regulators.



COUNTER UNIT (PB-1729)

DISPLAY UNIT (PB-1730)

The 5.0 - 5.5 MHz VFO signal is amplified by Q_{2901} (3SK40M) and fed through source follower Q_{2902} (2SK19GR) to a balanced mixer Q_{2903} (SN76514N), where the signal is heterodyned with either an 18.0 MHz or 18.5 MHz signal, producing either a 12.5 - 13.0 MHz or 13.0 - 13.5 MHz signal. The oscillator Q_{2907} (2SC945) generates an 18.0 MHz signal for the 160, 80, 10B, and 10D bands, and Q_{2906} (2SC945) generates an 18.5 MHz signal for the 40, 20, 15, 10A, 10C, and WWV/JJY (15 MHz) bands.

The oscillators are controlled by Q_{2908} (2SC945) and Q_{2909} (2SA733) in accordance with the band in use. The output from the balanced mixer is fed through amplifiers Q_{2904} and Q_{2905} (both 2SC785) to the counter gate Q_{2913} (SN74LS00N).

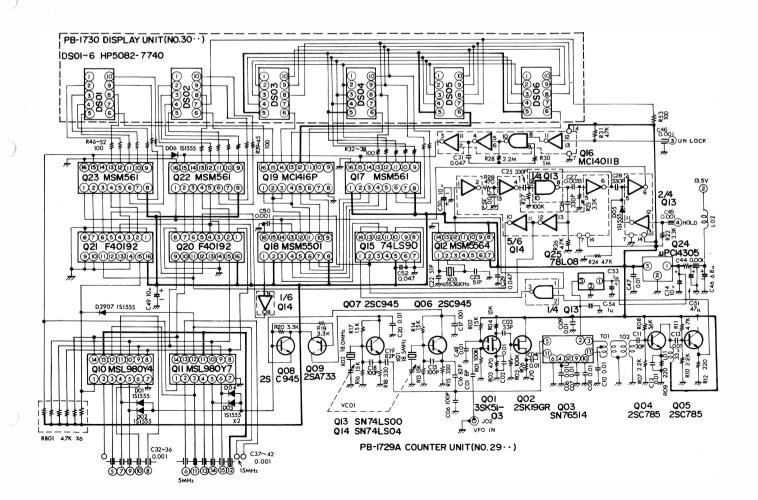
The MHz display is programmed by the diode matrix Q_{2910} (MSL980Y7) and Q_{2911} (MSL 980Y4). The output from Q_{2910} and Q_{2911} is

fed to the up/down counter Q_{2921} and Q_{2920} (both F40192); the output from the up/down counter is fed to drivers Q_{2923} and Q_{2922} (both MSM561) and then to the display LED's DS_{3001} and DS_{3002} (HP5082 - 7740).

The crystal oscillator/divider Q_{2912} (MM5564) generates a 655.36 kHz clock signal and produces 5 Hz gate pulses which are fed to the counter gate Q_{2913} .

The pulses which pass through the gate are fed to the decade counter Q_{2915} (SN74LS90N), which counts 10 Hz digits. The 10th pulse at pin 12 of Q_{2915} is fed to Q_{2918} (MM5501), which counts 100 Hz, 1 kHz, 10 kHz, and 100 kHz digits. The BCD output signal from Q_{2918} is fed through driver Q_{2917} (MSM561) to the display LED's DS_{3003} - DS_{3006} (HP-5082 - 7740).

 Q_{2919} (MC1416P) works as a series of switches operated by a timing signal delivered by Q_{2918} to select the output of Q_{2917} which drives the display LED's in a sequence of 100 Hz, 1 kHz, $10 \, \text{kHz}$, and $100 \, \text{kHz}$.



When the unlock signal is received from the PLL UNIT, Q_{2916} (MC14011B) generates a blanking signal which is fed to the LED drivers Q_{2917} . Q_{2922} , and Q_{2923} .

To calibrate the display, the heterodyne crystal frequency can be shifted by VC_{2901} from the front panel.

Voltage regulator Q_{2924} (uPC14305) stabilizes the supply voltage.

MEMORY UNIT (PB-1787)

The VFO signal delivered to pin 4 of PB-1787 is amplified by Q_{2809} (3SK40M) and Q_{2810} (2SC 785), and fed to counter gate Q_{2813} (SN74 LS00N). A clock signal generator Q_{2811} (MSM 5562) produces 50 Hz clock pulses from a crystal frequency of 3276.8 kHz. The pulses which passed through the gate are fed to a six digit decade counter Q_{2815} (TC5032P), which counts the VFO frequency. The BCD output from Q_{2815} is fed through Q_{2822} - Q_{2826} (all MC14042B) to up/down counter Q_{2827} - Q_{2831} (SN74LS192N), which presets the VFO frequency.

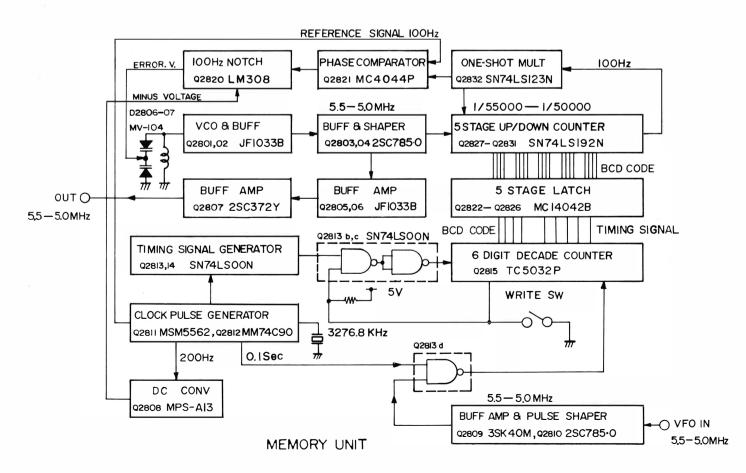
The 5.0 - 5.5 MHz signal generated by Q_{2801} (JF1033B) is fed through buffer/amplifier Q_{2802} (JF1033) and Q_{2803} (2SC785) to pulse shaper Q_{2804} (2SC785).

The switching pulse generated by Q_{2804} is also fed to Q_{2827} , where the signal is divided to 1/5000 to 1/55000 in accordance with the program preset by Q_{2827} - Q_{2831} . The output from Q_{2831} (approximately 100 Hz) is fed through a one-shot multivibrator Q_{2832} (SN74LS123N) to the phase comparator Q_{2821} (MC4044P) where the phase of the 100 Hz signal is compared with the phase of the 100 Hz signal which is delivered from Q_{2811} .

The DC output from Q_{2821} passes through a low pass filter, operational amplifier Q_{2820} (LM308), to remove the 100 Hz ripple. This DC voltage is applied to varactor diodes D_{2806} - D_{2807} (MV-104), thus locking the VCO frequency.

When the M (memory) switch is pushed, the counter output from Q_{2815} is latched and the VCO frequency is locked.

When the MR (memory recall) switch is pushed, the output from VCO buffer Q_{2802} (JF-1033B)



is amplified by Q_{2805} and Q_{2806} (both JF-1033B) and Q_{2807} (2SC372Y), and fed through a diode switch to the PLL UNIT (replacing the VFO signal).

 Q_{2813} (SN74LS00N) and Q_{2814} (SN74LS04N) generate timing pulses to set or reset the counter.

The 200 Hz signal delivered from Q_{2811} is amplified by Q_{2808} (MPSA13) and rectified by D_{2804} and D_{2805} (both 1S188FM) to produce a minus voltage to be used for operational amplifier Q_{2820} .

POWER SUPPLY

The power supply is designed to operate from either 100/110/117/200/220/234 Volts AC 50/60 Hz (all models) or 13.5 Volts DC with the DC-DC converter unit (built-in on the FT-901DM, optional on other models). Insertion of the appropriate power plug into the rear panel receptacle makes the necessary connections for operation from either AC or DC power sources.

When the transceiver is operated from a 13.5 Volt DC power source, transistors Q_{3201} and Q_{3202} (both **T20A6**) function as a low frequency oscillator to provide AC voltage at approximately 80 Hz to the power transformer. All of the tube heaters receive their power through the HEATER switch on the front panel. With the HEATER switch in the OFF position, voltage is still supplied to the receiver section, thus allowing continuous reception with reduced power consumption. The heaters of the two 6146B are connected in series to operate at 12 Volts DC.

(1) Low voltage supply

AC 11.5 Volt power delivered from the secondary winding of the transformer is rectified by D_{1001} and D_{1002} (V06B) in the RECTIFIER A UNIT (PB-1708) to provide the transistor supply voltage. The rectified DC voltage is supplied through pin 8 and pin 1 of the AC plug to pin 1 of the power receptacle which is connected to the DC power supply line. In the DC mode, the DC voltage from the power cord is directly supplied to pin 1 of the power receptacle. The DC voltage is filtered through CH_{1001} , C_{1001} , and C_{1002} , and fed to the voltage stabilizer Q_2 (uPC14308) (8V) and Q_3 (µPC14312) (+12V); 13.5 Volt power is also

supplied to the counter unit and accessory socket on the rear panel.

The stabilized 8 Volt supply from Q_2 is used for the VCO, XTAL and IF UNITS, and the stabilized 12 Volt supply is used for the FM, VOX, and AF UNITS, and other circuits as well. The 12 Volt supply is further stabilized by Q_1 (uPC14308) to be supplied to the AF and IF UNITS. A further portion of the 8 Volt supply from Q_2 is stabilized at 6 Volts by Q_{1801} (TA7089M) to be supplied to the VFO UNIT.

Independent voltage stabilizers are located in the MEMORY, COUNTER, AF, FM, and PLL UNITS.

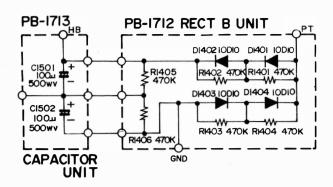
(2) High voltage supply

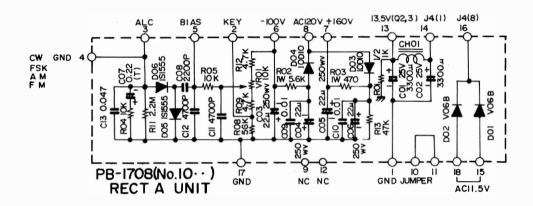
The power amplifier plate voltage of +800 Volts DC is supplied from the bridge-controlled doubler RECTIFIER UNIT B consisting of D_{1401} - D_{1414} (10D10) and C_{1501} and C_{1502} in PB-1712.

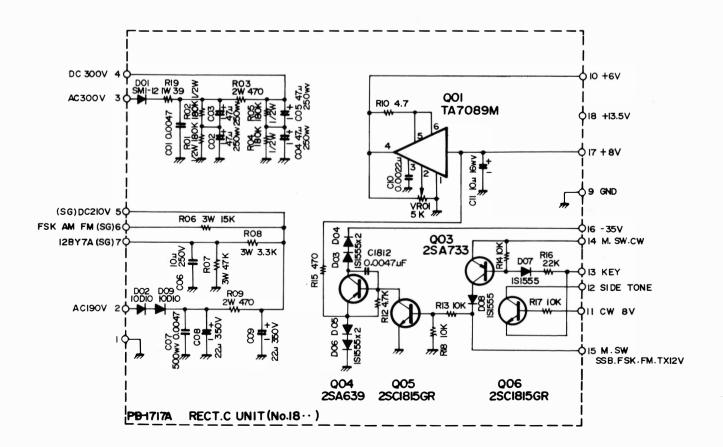
AC 190 Volts is rectified by D_{1802} (10D10) in RECTIFIER UNIT C to obtain 210 Volts for the screen grid supply of the power amplifier tubes. The screen grid voltage is reduced to 180 Volts for the FM, AM, and FSK modes.

The plate supply for the driver tube is obtained by rectifying 250 Volt AC by D_{1801} (10D10). The DC voltage obtained from the RECTIFIER C UNIT is dropped to 160 Volts by a resistor for the driver screen grid.

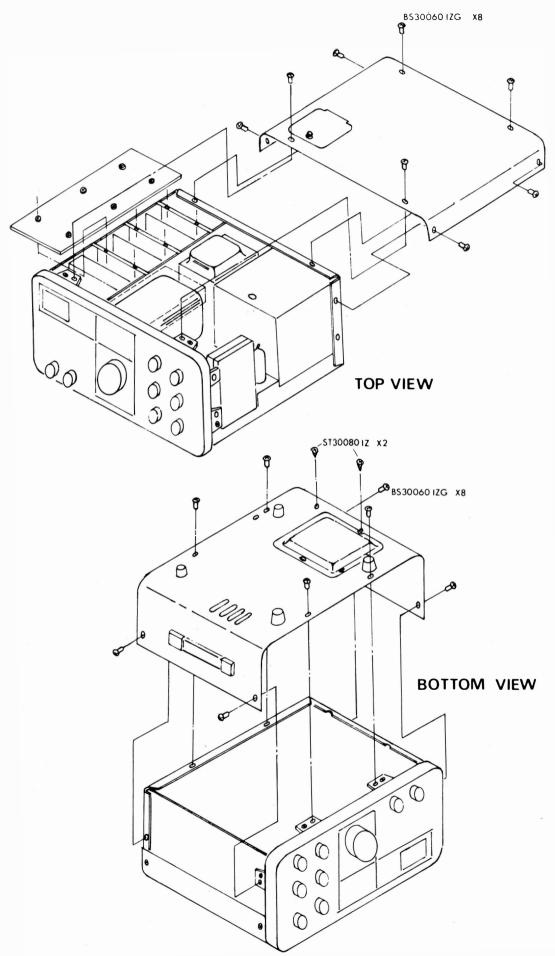
120 Volt AC from the transformer secondary winding is rectified by D_{1004} (10D10) in the RECTIFIER A UNIT (PB-1708) to obtain -140 Volts for the grid bias voltage for the driver and final amplifier tubes.





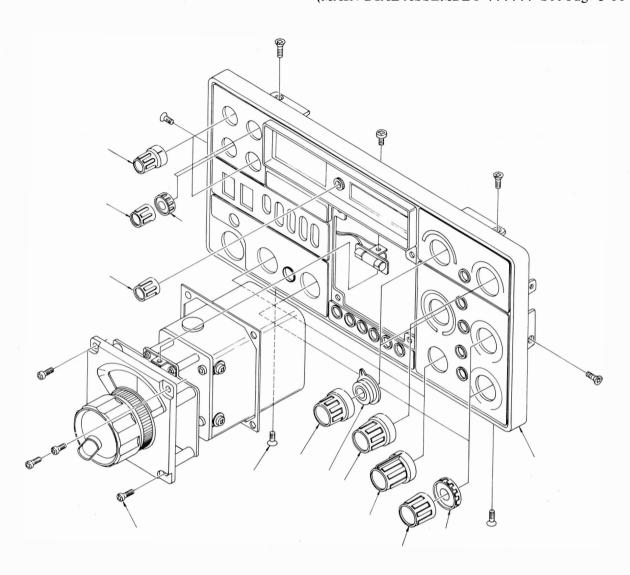


OUTER COVER REMOVAL



FRONT PANEL REMOVAL

(MAIN DIAL ASSEMBLY See Page 3-61.)

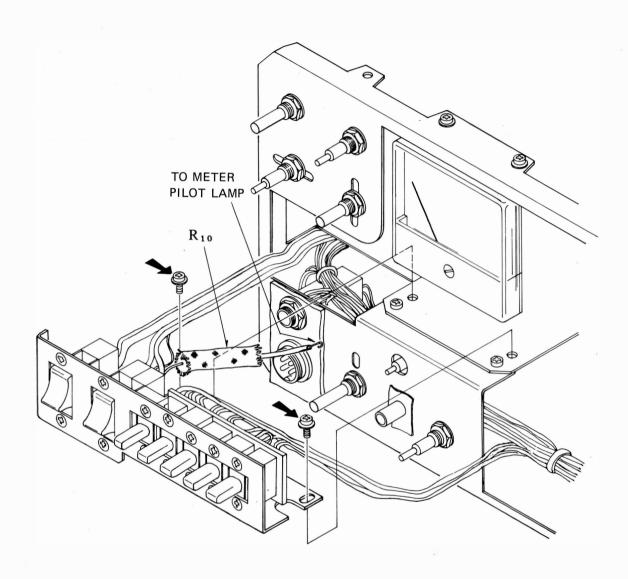


DISASSEMBLY PROCEDURE

- (1) Remove the knobs from all front panel controls, except the main tuning dial. If you must service the VFO unit, remove the main tuning dial, as well.
- (2) With the top cover of the transceiver removed, lift out the COUNTER UNIT, by removing its mounting screws. The purpose of this is to provide access to the connection cable for the VFO.
- (3) Disconnect the cable connected to the VFO compartment.

- (4) Now remove the four mounting screws from the front of the VFO compartment, and gently ease the compartment a short distance out of the front panel.
- (5) Remove the ground cable connected to the VFO compartment. The VFO can now be removed completely.
- (6) Remove the screws holding the front panel assembly to the chassis. The front panel may now be removed completely.

FRONT PANEL SWITCH ASSEMBLY



REMOVAL OF FUNCTION SWITCH STRIP

After you have removed the front panel, locate the yellow wire connected to the meter. This is the line that contains R_{10} . Disconnect this line from the meter, and be sure to note its position for reassembly purposes.

Now remove the two mounting screws which hold the switch strip to the chassis. These are the screws with the washers attached. With the two screws removed, carefully ease the switch strip away from the chassis. It will still be restrained by the cable harnesses, but service work can now be performed more easily.

SERVICING

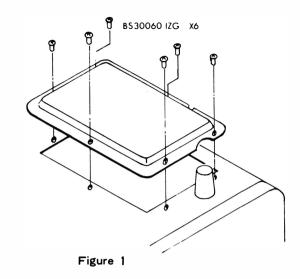
KEYER/MEMORY UNIT INSTALLATION

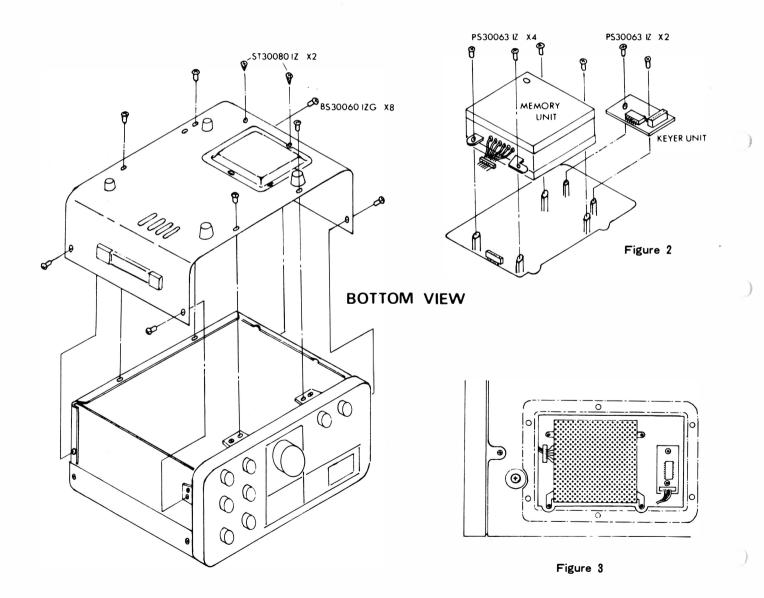
Remove the small cover from the bottom of the transceiver as shown in Fig. 1.

Install the MEMORY UNIT using the mounting screws supplied. Connect the 6-pin connector to the socket on the main chassis as shown.

Mount the KEYER UNIT as shown in Fig. 2, and connect the cable to the KEYER UNIT as shown in the drawing.

The completed installation may be viewed in Fig. 3.



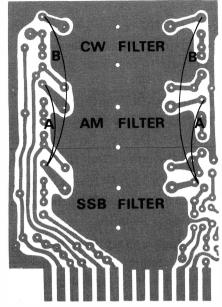


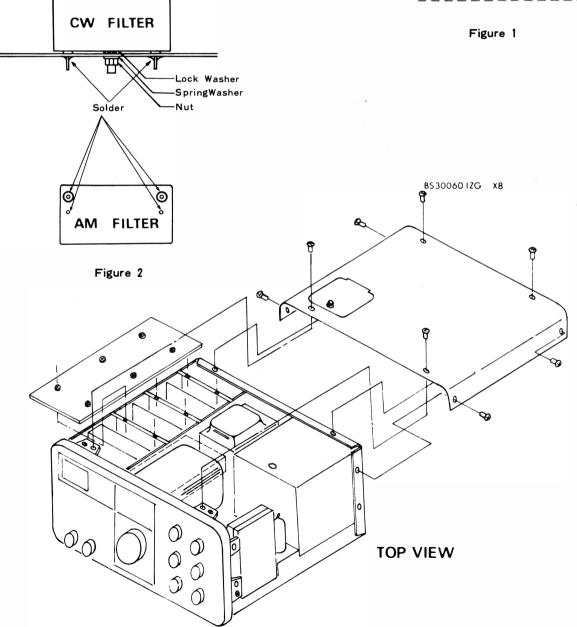
AM/CW FILTER INSTALLATION

Remove the top cover. Locate and remove PB-1716 (FILTER UNIT). Referring to Fig. 1, locate jumpers A and B on the printed board. If the AM filter is to be installed, the jumper marked A must be removed, and for CW filter installation the jumper marked B must be removed.

Referring to Figs. 1 and 2, install the desired filter in the appropriate holes. Make the fastening nuts snug (CW filter only), and solder the pins of the filter to the printed board.

Re-install PB-1716 in the chassis socket, and replace the cover of the transceiver.

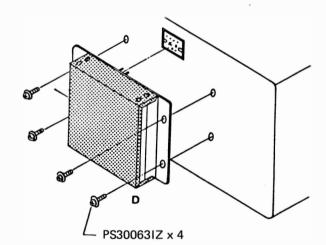


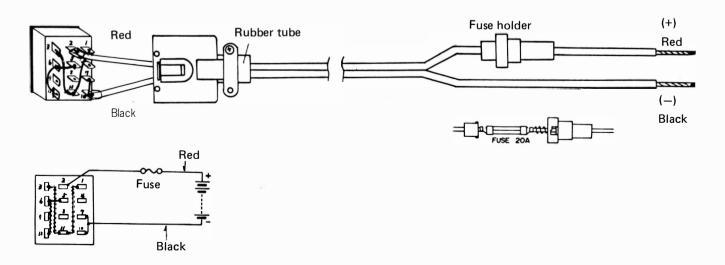


DC-DC CONVERTER INSTALLATION FOR FT-901D/DE/SD

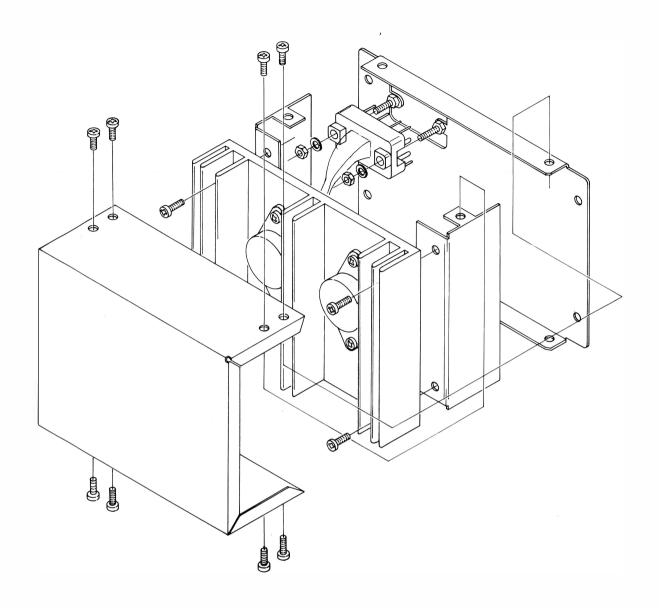
The optional DC-DC converter is easy to install in a matter of minutes. Please follow the instructions carefully, in order to make the proper connections.

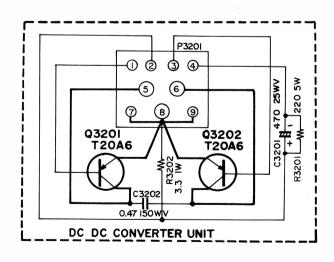
- (1) Install the DC-DC converter module as shown in the drawing. Use the four screws supplied with the kit. Do not force the plug into the socket, as the connection should be smooth.
- (2) Check the DC cable fuse socket, located in the positive (red) lead, to be certain that a 20 amp fuse is installed.
- (3) When making connections to the battery, be absolutely certain that the proper polarity is observed. The RED lead should be connected to the POSITIVE (+) battery terminal, and the BLACK lead should be connected to the NEGATIVE (-) terminal. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY REVERSED POLARITY CONNECTIONS.
- (4) Before connecting the DC power cable to the transceiver, check the automobile voltage regulator level with the engine running (battery charging). The maximum charging rate should be 15 volts or less. If the voltage is ihgher than this level, please adjust the voltage regulator for a maximum of 15 volts. This precaution applies, as well, to bench power supplies, which should be adjusted in the same fashion. Also, the transceiver should not be operated from a supply voltage of less than 12 volts.
- (5) Connect the DC cable to the transceiver. Power connections are made automatically when the DC cable is connected to the POWER jack.

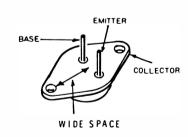




DC-DC CONVERTER (EXPLODED VIEW)







FM UNIT INSTALLATION FOR FT-901DE/SD

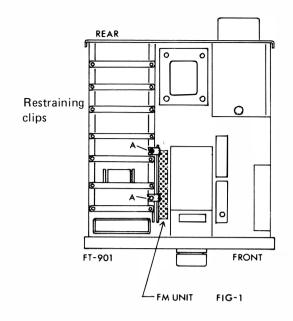
The FM Unit operation for the FT-901DE and SD models can be installed in a matter of minutes.

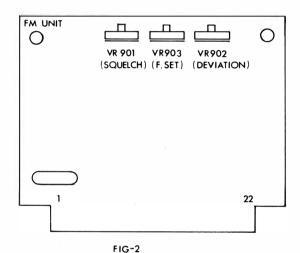
Remove the top cover of the transceiver, and remove the black cover of the circuit board rack (left-hand side of the transceiver).

Install the FM Unit in the 22-pin connector. The component side of the circuit board should be on the side facing the VFO enclosure. Use the two circuit board restraining clips to secure the board in place, securing the clips to the main circuit board rack with the two screws included with the kit.

The positions of the alignment potentiometers of interest can be found by referring to Fig. 2.

Replace the circuit board cover, and replace the top cover of the transceiver. Installation is now complete.



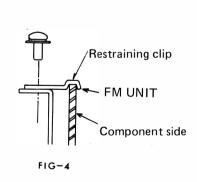


Alignment potentiometers

BS300601ZG X8 Circuit board cover (Remove) Top cover (Remove) TOP VIEW

FIG-3



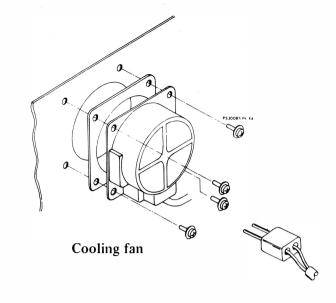


COOLING FAN INSTALLATION (OPTION for FT-901SD)

The FT-901SD cooling fan may be used with other models of Yaesu equipment. Installation is easily accomplished in minutes.

Hold the fan up to the rear panel in its proper location. Determine the proper length of the two-wire power lead to the motor. Solder the leads to the 2-pin plug supplied with the fan. The 4-pin plug is not needed for FT-901SD installation.

Install the fan onto the rear panel of the transceiver, as shown in the drawing. Insert the power lead from the fan into the fan socket on the rear panel.



SOLDERING AND DESOLDERING TECHNIQUE ON PRINTED CIRCUIT BOARDS

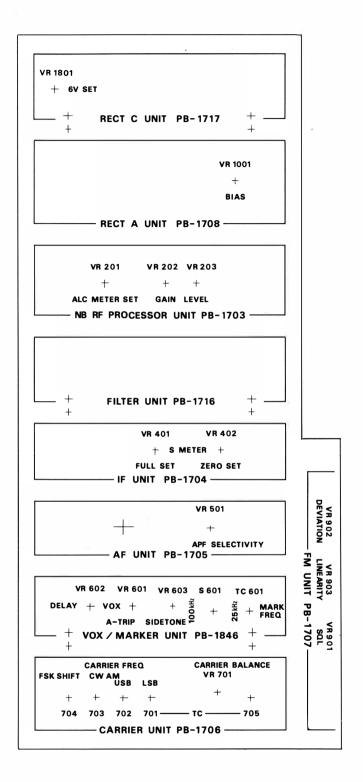
The FT-901 circuit boards are tough, but mishandling during soldering can cause circuit traces to "lift." While this does no permanent damage to the board, much servicing trouble can result, because of the tendency for this lifted trace to break. A few simple precautions will keep your circuit boards in A-1 condition.

- 1. Use only a 12 to 30 watt chisel-tip soldering iron. Yes, some "repairmen" have been known to use small blowtorches on cards.
- 2. Use only a soldering iron equipped with a three-wire cord, with the tip grounded. Also acceptable is a soldering iron isolated through a transformer. An old soldering iron or gun may have 117 volts on the tip, and will certainly cause more damage than it repairs!
- 3. USE ONLY 60/40 ROSIN CORE SOLDER. Acid core solder should be thrown away if you find it in your radio shop!
- 4. Use a solder sucker and solder tape to ensure a professional repair job.
- 5. If you do lift a trace, don't worry! Read on to find out how to repair traces like a pro.

IMPORTANT

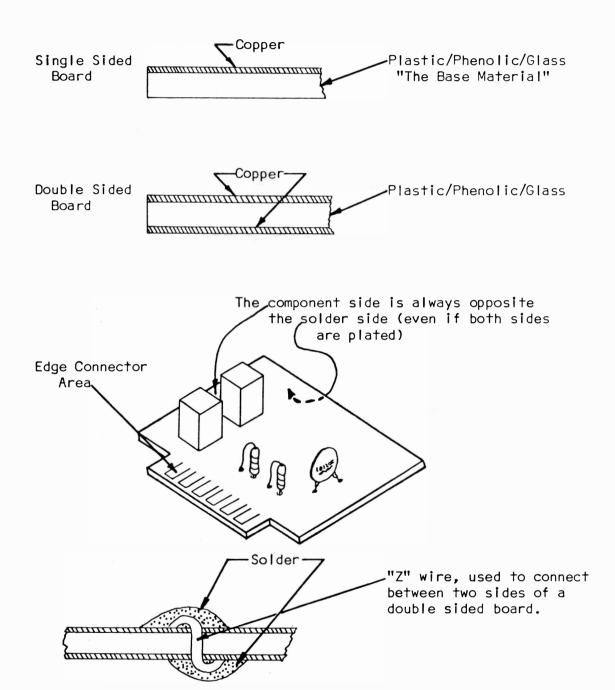
The circuit boards used in the FT-901 are not keyed, and it is possible to install a board backwards, or to install it in the wrong socket.

If you have several boards out of the chassis at any one time, be certain to install the boards correctly into their sockets. Use the reference plate which is installed above the circuit board rack.



CIRCUIT TRACE REPAIR

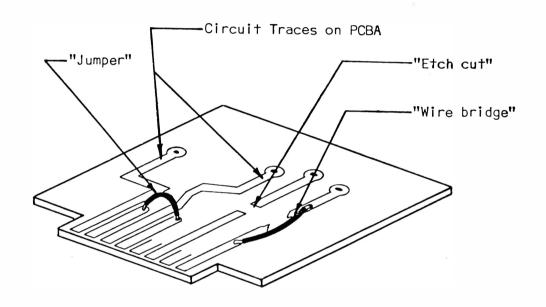
Most of the printed circuit boards used in the FT-901 are single sided boards. However, occasionally a double-sided board is used, in situations where high shielding is required. A comparison of the two types is shown below.

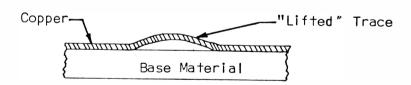


SERVICING

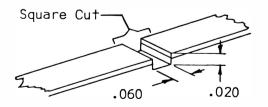
Sometimes, after the design and drafting of a board are completed, a board is produced with an error in it. Though non-technical managers sometimes suffer a stroke at hearing of this situation, it is not unheard of in engineering circles. Thus, should you encounter etch cuts and jumpers on a board, be assured that the modifications were made in the interest of securing optimum performance. Unless you consider your expertise to be superior to that of the design engineer, please leave these mods in place.

However, in service work the occasion does arise when a trace must be cut. Proceed as follows.





If you have previously lifted a trace, make an etch cut on each side of the lifted trace, and install a wire bridge as shown in the drawing.



Coat Cut Area With Eastman 910

MODIFICATIONS

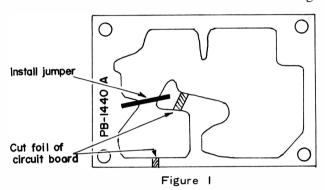
VFO DRIFT IN PRESENCE OF VHF TRANSMITTER

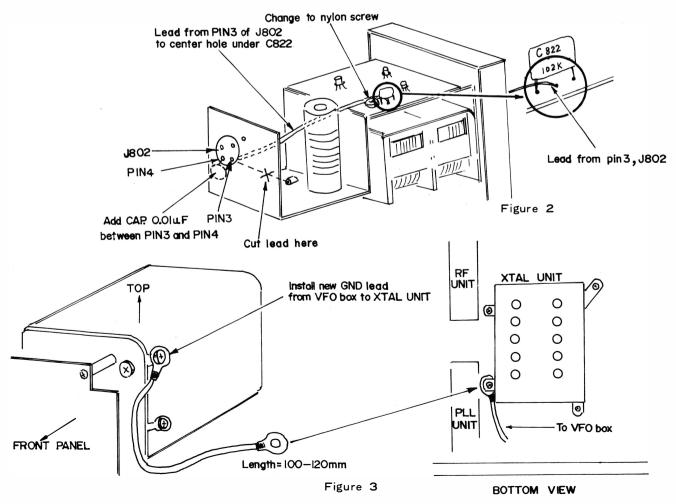
Some transceivers from the first and second production lots display a VFO drift problem in the presence of a nearby 2 meter transmitter. The problem is caused by a ground loop, and the modification below will eliminate the difficulty.

Modification Procedure:

(1) Refer to Fig. 1, and cut the foil on the VFO UNIT, PB-1440A, at the two points shown. Install the jumper wire shown in the drawing.

- (2) Refer to Fig. 2 , and remove the ground lead from pin 4 of J_{802} . Re-route the lead so that the connection is from pin 4 of J_{802} to the center hole under C_{822} .
- (3) Change the screw adjacent to C_{822} to a NYLON screw.
- (4) Ad a new 0.01 disc ceramic capacitor between pins 3 and 4 of J_{802} .
- (5) Install a new ground lead, made from a heavy braided wire of 100-120 mm length. This lead should run from the VFO compartment to the ground lug for the XTAL UNIT, as shown in Fig. 3.





SERVICING

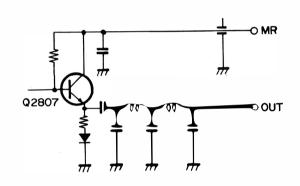
MEMORY UNIT HUM, MR MODE

In some FT-901DM sets, leakage from the memory circuitry could cause a low-level hum to be apparent when going to the MR mode. The following modification should eliminate this problem.

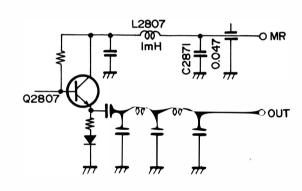
Modification Procedure:

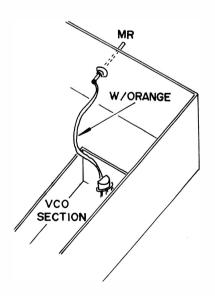
- (1) Refer to the drawings below, and install a two-lug terminal strip near the MR terminal on the MEMORY UNIT.
- (2) Remove the white/orange wire connected to the MR terminal, and connect it to the ungrounded lug of the new terminal. Connect a 1 mH mini-inductor in the collector lead of Q_{2807} . This new inductor is labeled L_{2807} in future productions.
- (3) Install a new 0.047 μ F disc ceramic capactitor between the MR terminal and ground, as shown in the drawing. Modification is now complete.

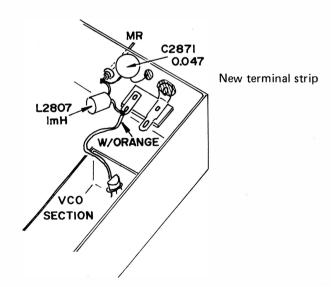




AFTER MODIFICATION





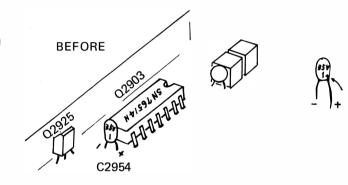


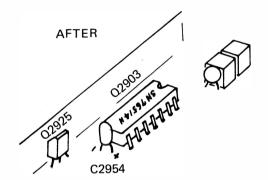
COUNTER UNIT CAPACITOR REVERSAL

In FT-901DM units bearing serial numbers 8F030001 through 8H059999, the markings on PB-1729 showed the polarity of C_{2954} incorrectly. As a result, the capacitor was installed correctly according to the marking, but **incorrectly** according to the intended purpose.

Modification Procedure:

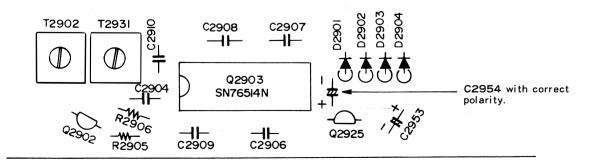
- (1) Remove the COUNTER UNIT, PB-1729, from the transceiver. Locate C₂₉₅₄, and observe the polarity. On sets bearing the above serial numbers, if the capacitor is installed with reversed polarity according to the circuit board making, your unit is already modified. If it is the same as the circuit board marking, remove and discard the capacitor. A correctly installed capacitor has its markings facing in the direction of Q₂₉₀₃.
- (2) Install a new C_{2954} (1 μ F, 35 WV, tantalum) as shown in the drawing below. Its markings should face Q_{2903} .
- (3) Replace the COUNTER UNIT. Modification is now complete.







Capacitor installed per PB marking (incorrect). Remove and reverse C_{2954} . Markings should face Q_{2903} . Capacitor reversed according to PB marking.



POWER SUPPLY PROTECTION MODIFICATION

Beginning with production lot No. 6, the following modification was adopted, in order to provide protection for the filter capacitors, screen grid supply, and mode switch. These might be subject to damage in the event of flashover between the electrodes inside the final amplifier tubes.

Modification Procedure:

- (1) Fix a three-terminal soldering post to the chassis, using a self-tapping screw, as illustrated in Fig. 1.
- (2) Solder a 10D10 diode to the post as shown, being careful to observe proper diode polarity.
- (3) Remove the yellow wire previously connected to the circuit board, as shown in Fig. 1. Solder it to the anode of the diode, as shown in the drawing.
- (4) Connect a lead from the cathode end of the diode to the circuit board, in the position previously occupied by the yellow wire.
- (5) The modified schematic is shown below.

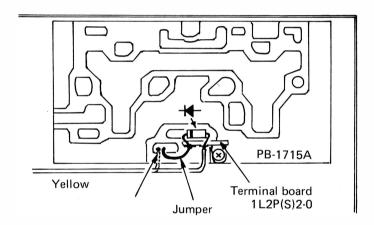


Figure I

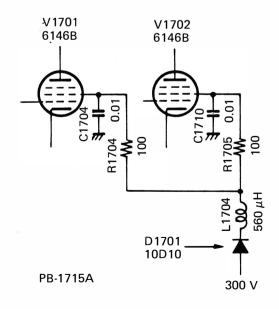


Figure 2

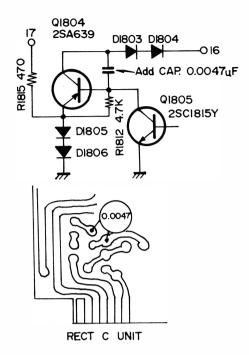
KEY CLICK MODIFICATION

In some FT-901 transceivers, when operating in the CW mode, the keying waveshape could become too "hard" if the drive control (CARR) were advanced too far. The following modification should eliminate this difficulty.

Modification Procedure:

(1) Connect a 500 WV 0.0047 μ F disc ceramic capacitor between the collector and base of Q_{1804} , as shown in the drawing.

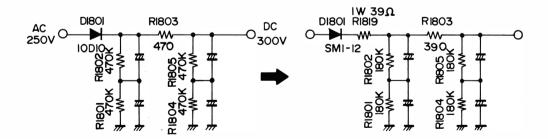
This modification was adopted in production runs beginning with serial numbers 080001.



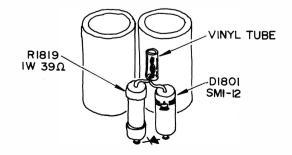
RECTIFIER C UNIT MODIFICATION

The FT-901 series has been modified, starting with the No. 8 production lot, as described below. The change was made in order to provide protection against the loss of R_{1803} caused by unbalance in C_{1802} and C_{1803} . While the problem was highly isolated, the failure of R_{1803} could cause the destruction of the filter capacitors. In order to catch this problem before it causes damage in the field, we recommend the following modification:

- 1) Change R_{1801} , R_{1802} , R_{1804} , and R_{1805} to 180 K ohms, ½ watt.
- 2) Change R_{1803} to 390 ohms, 2 watts.
- 3) Add a new R_{1819} (39 ohms, 1 watt) in series with D_{1801} , as shown.
- 4) D₁₈₀₁ is being changed in production to type SM1-12, but this change should not be necessary in the field. Modification is now complete.



Note: An easy alternative to the above is to add another 10D10 diode in series with D1801. No further modification is necessary. This was done in the 190 volt line from pin 2, shown on page 2-28, and this should be satisfactory. Modification of the 190 volt line is also recommended.

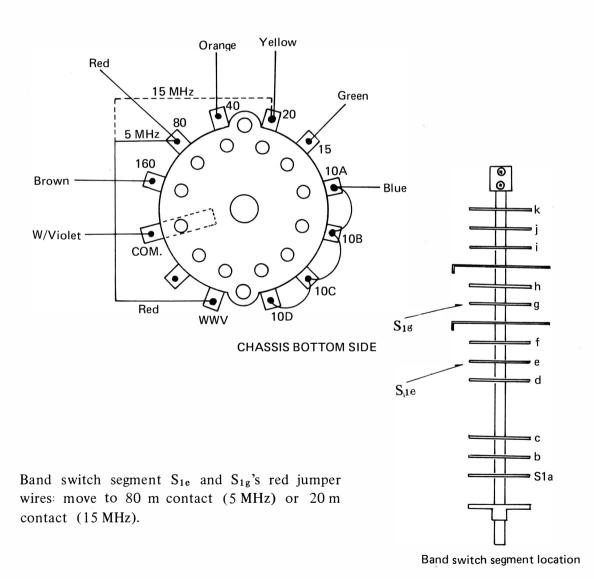


WWV/JJY MODIFICATIONS

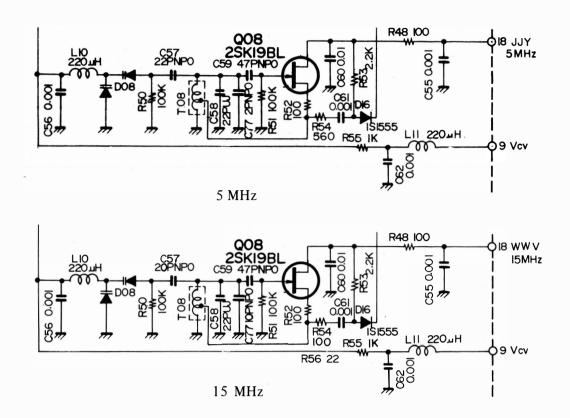
FT-901 transceivers for the first production lot were equipped with 5 MHz WWV coverage. From the second production lot, this was changed to 15 MHz. Units destined from the Japanese domestic market all are equipped for 5 MHz.

Modification Procedure:

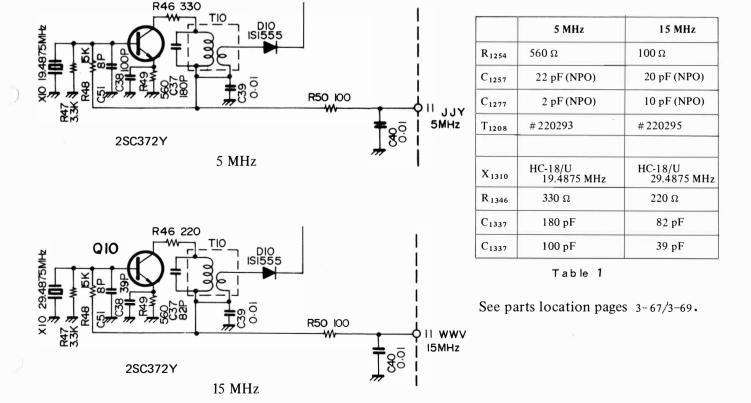
- (1) Locate bandswitch segments (e) and (g). Refer to the drawing for reference.
- (2) For WWV 5 MHz reception, the red jumper wires on these wafers must be connected between the WWV terminal and the 80 meter terminal.
- (3) For WWV 15 MHz reception, the red jumper wires must be connected between the WWV terminal and the 20 meter terminal.
- (4) Make the component changes as shown in Table 1. Peak T_{1310} for a reading of $80-150\,\text{MV}$ at the OUT terminal (pin 16) of the XTAL UNIT.



VCO UNIT



X'TAL UNIT



MOSFET CHANGES

Because of a potential parts availability problem, many of the 3SK40M MOSFET components were changed to 3SK51-03 types. There is no reason to make this change in the field, unless the 3SK40M types are not available in your parts inventory.

For replacement MOSFET servicing, please refer to the chart below.

CODE

- Replacement with this type OK without further change.
- △ When changing to this type, make resistor change at right.
- × Do not replace with this type.

Example:

PART	3SK40M	3SK40L (R/B)	3SK51-03	Change for
Q_{106}	0	\triangle	X	$R_{126}: 390 \rightarrow 270$

This means: when replacing Q_{106} , it may be replaced with type 3SK40M with no further changes; a 3SK40L(R/B) may be used by changing R_{126} from 390 ohms to 270 ohms; type 3SK51-03 should not be used.

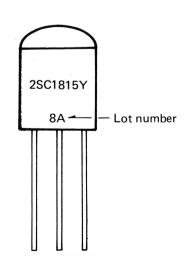
RF	PROCESSOR/XTAL	UNIT	TRANSISTOR
MOI	DIFICATION		

On the NB UNIT, transistor Q_{202} should bear a lot number . . . 7J, 7K, 7L, or earlier. If the transistor bears a lot number 8A, 8B, 8C, or later, the transistor should be changed from type 2SC1815Y to type 2SC372Y.

The same consideration applies to transistors $Q_{1301}-Q_{1310}$ on the XTAL UNIT.

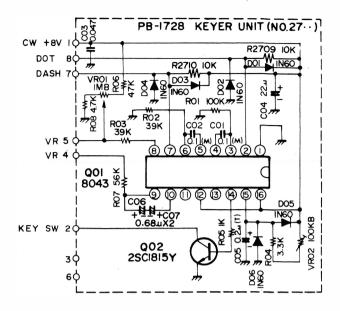
The new 2SC1815Y transistors exhibit higher noise than Yaesu specifications will allow, hence the change to the 2SC372Y.

PART	3SK40M	3SK40L (R/B)	3SK51-03	
Q101	0		Δ	R ₁₀₃ $39K \rightarrow 47K$
Q ₁₀₆	0	Δ	Х	$R_{126} = 390 \rightarrow 270$
Q ₁₀₇	0	Δ	Х	$R_{125} 390 \rightarrow 270$
Q 209	0	0		
Q ₂₁₀	0	0		
Q212	0		0	(3SK41M OK)
Q ₄₀₁	0		Δ	R ₄₀₅ 560 → 1K
Q402	0		Δ	$R_{418} 560 \rightarrow 1K$
Q ₄₀₃	0		Δ	$R_{425} = 560 \rightarrow 1.8K$
Q404	0		Δ	R_{432} 560 \rightarrow 1.8K
Q 901	0		Δ	R_{905} 56 \rightarrow 1.8K
Q ₁₂₀₉	0		Δ	$R_{1259} 470K \rightarrow 680K$
Q ₂₈₀₉	0 ,		0	
Q ₂₉₀₁	0		0	



KEYER UNIT MODIFICATIONS

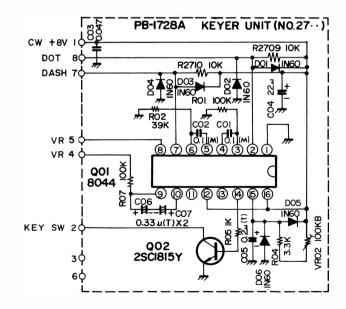
Several minor changes were made during the production of FT-901DM units using the Curtis 8043 IC. The diagram below represents the final version of the KEYER UNIT, and if you should have to perform service on this board, we recommend that the circuit be modified as shown here.



CURTIS 8044 IC CIRCUIT MODIFICATION

Beginning with the No. 8 production lot, the Curtis 8044 IC was used in the KEYER UNIT. The 8044 includes both dot and dash memories, and several changes were made in the circuit board to reflect the use of the new IC. Notable among these was the removal of the symmetry control.

The corrected schematic for the 8044 IC KEYER UNIT is shown below.

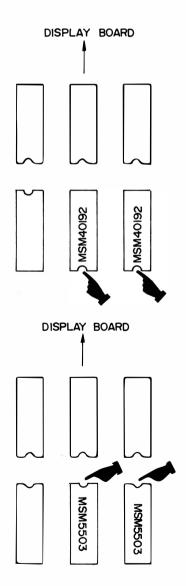


COUNTER UNIT IC INSTALLATION NOTE

In some FT-901 transceivers, Q_{2920} and Q_{2921} were changed from type MSM40192 to type MSM5503. The units are identical in operation, but the MSM5503 pin layout is the reverse of that of the MSM40192.

For this reason, if you have to replace Q_{2920} or Q_{2921} , be sure to observe the proper alignment of the key marking, as shown in the drawing below.

Note also that the circuit board is marked correctly only for installation of the MSM40192 IC. Install MSM5503's with the key mark at the opposite end, as shown below.



For models using MSM40192. Circuit board print is marked correctly.

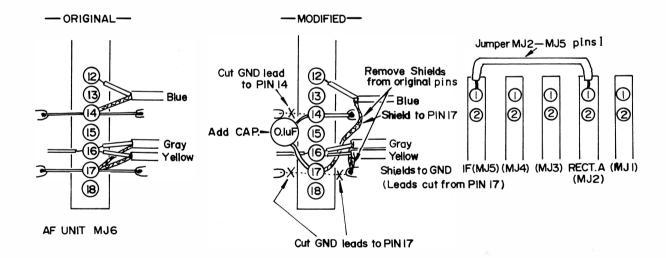
For models using MSM5503. Install reversed from PCB marking.

AUDIO HUM MODIFICATION

In some early models of the FT-901, a slight hum could be heard on receive; this is most easily observed by rotating the AF and RF gain controls to zero. The problem was a ground loop, and this bulletin will detail the simple modification to cure the problem.

- 1. Refer to the drawing. Locate MJ₆ on the bottom of the chassis.
- 2. Cut the ground leads from pin 17. Cut the ground lead from the left side of pin 14.

- 3. Locate the cable whose center conductor is connected to pin 12. Remove the **shield** of this cable from pin 14, and reconnect it to pin 17.
- 4. Locate the two cables whose center conductors are connected to pin 16. Their **shields** should be removed from pin 17, and connected to the ground point previously connected to pin 17 from the **right** side.
- 5. And the 0.1 μ F 25 WV capacitor between pins 14 and 17, as shown. A ceramic capacitor is OK in this application.
- 6. Connect a jumper between MJ_2 , pin 1, and MJ_5 , pin 1. This completes the modification.



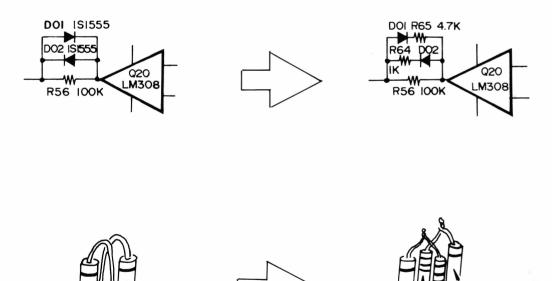
MEMORY LOCK MODIFICATION

In some FT-901 transceivers, it was not possible to obtain a memory lock through the entire range of the VFO, especially toward the high end. The following modification will allow a lock to be obtained, in these isolated situations.

Refer to the drawing below, and install a 4.7 K ohm resistor in series with D_{2801} . Install a 1 K ohm resistor in series with D_{2802} . These resistors should be $\frac{1}{4}$ watt rating, and should be installed on the cathode side of the diodes.

Use care in reinstalling the components in the circuit board, as the memory unit is extremely densely packed.

This completes the modification.



DOI R64 R65

MAINTENANCE AND ALIGNMENT

WARNING

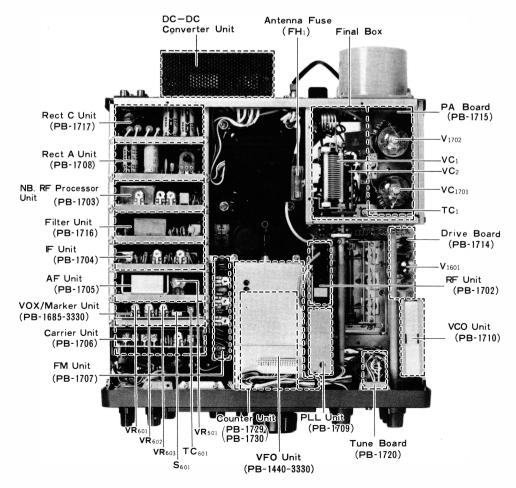
DANGEROUS VOLTAGES ARE PRESENT WITHIN THIS TRANSCEIVER. USE EXTREME CAUTION WHEN WORKING ON THE TRANSCEIVER WITH THE COVERS REMOVED. DISCHARGE ALL CAPACITORS BY SHORTING THEM TO GROUND WITH AN INSULATED SCREWDRIVER AFTER POWER HAS BEEN REMOVED, AND OBSERVE OTHER NORMAL SAFETY PRECAUTIONS.

CAUTION

Never operate this transceiver in the transmit mode without a matched antenna or dummy load connected to the antenna receptacle on the rear panel. It is possible to damage the final amplifier tubes and the pi network components if the transceiver is operated without the proper load termination.

GENERAL

This transceiver has been carefully aligned and tested at the factory and, with normal usage, should not require other than the usual attention given to electronic equipment. Service or realignment of a major component may require subsequent realignment; under no circumstances, though, should realignment be attempted unless the operation of the transceiver is fully understood, the malfunction has been carefully analyzed, and the fault has definitely been traced to misalignment. Service work should only be performed by experienced personnel using the proper test equipment.



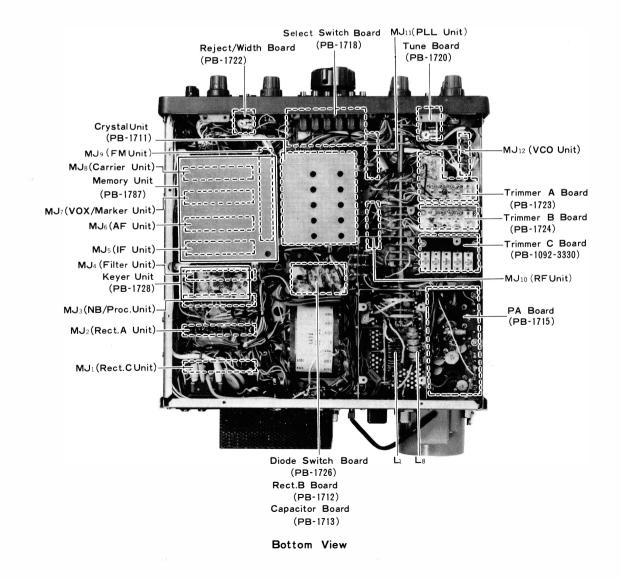
Top View

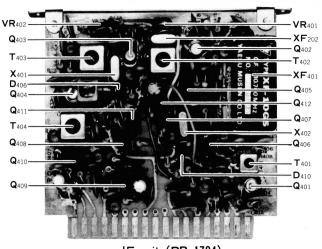
EQUIPMENT REQUIRED

- RF Signal Generator: Hewlett-Packard Model 606A or equivalent, with one volt output at 50 Ohms, and frequency coverage to 30 MHz.
- (2) Vacuum Tube Voltmeter (VTVM): Hewlett-Packard Model 410B or equivalent, with an RF probe good to 40 MHz.
- (3) Dummy Load: Yaesu model YP-150 or equivalent, with 50 Ohm non-reactive load impedance rated to 150 watts average power.
- (4) AF Signal Generator: Hewlett-Packard Model 200AB or equivalent.
- (5) A general coverage receiver covering the frequency range from 3 to 30 MHz with a 100 kHz calibrator.
- (6) A frequency counter, Yaesu Model YC-500 or equivalent, with resolution to .01 kHz and frequency coverage to 30 MHz.

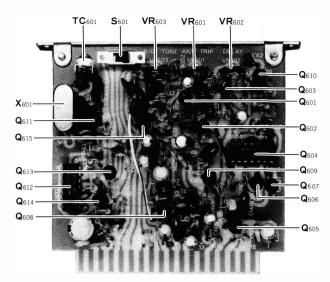
1. S-METER SENSITIVITY ADJUSTMENT

Place the transceiver in the receive mode and connect a signal generator to the antenna terminal of the transceiver. Set the signal generator to 14200 kHz with an output of 6 dB. Tune the transceiver to 14200 kHz for a maximum reading on the S-meter. The S-meter should just start to rise with a 6 dB input. If no deflection is observed, adjust VR_{402} to obtain a slight meter deflection. Apply 100 dB input to the antenna terminal; the S-meter should read S9 + 60 dB. If not, adjust VR_{401} . VR_{401} and VR_{402} are located on PB-1704.





IF unit (PB-1704)



VOX/Marker unit PB-1846 (PB-1685-3330)

2. VOX ADJUSTMENT

Tune in a signal and adjust the AF GAIN control for a normal listening level. With the microphone positioned near the speaker, increase the VOX GAIN control on the front panel until the speaker output causes the VOX relay to switch to the transmit mode. Set the ANTITRIP control VR₆₀₁ on PB-1685 to the point that will just prevent the speaker output from tripping the VOX relay. Speak into the microphone in a normal voice to see if one's voice will activate the VOX relay. If not, VR₆₀₁ may be advanced too far.

Adjust the DELAY control VR₆₀₂ for the desired release delay. Clockwise rotation of VR₆₀₂ will increase the delay time. For CW semi-break-in operation, VR₆₀₂ should likewise be adjusted to suit the operator's preferences. For CW operation with a footswitch for relay actuation, the VOX GAIN control may be rotated fully counterclockwise (but not to the click-stop, which is the MOX position) to disable the VOX system.

3. **CW SIDETONE LEVEL**

Adjustment of the CW sidetone level is made by adjustment of potentiometer VR₆₀₃, located on PB-1685, while the transceiver is being keyed.

CARRIER BALANCE 4.

The transceiver should be allowed to reach normal operating temperature before making carrier balance adjustments.

Tune up the transceiver for SSB operation using a matched antenna or dummy load. Turn the MIC GAIN control fully counterclockwise to remove all audio input from the modulator stage.

With the MODE switch set to either LSB or USB. turn the VOX GAIN control to MOX and adjust the carrier balance controls VR_{701} and TC_{705} on PB-1706 for a minimum meter reading with the METER switch in the PO position.

A more precise balance may be obtained by tuning a receiver which has an S meter to the transmitted frequency. Adjust VR₇₀₁ and TC₇₀₅ for a minimum S meter reading on the remote receiver while switching the MODE switch back and forth between the two SSB positions; this will help ensure good carrier suppression on both LSB and USB.



Carrier unit (PB-1706)

5. AMGC (Automatic Mic Gain Control)

The hold time of the AMGC system is adjusted by VR_{702} on PB-1706; clockwise rotation of VR_{702} will provide a longer hold time.

6. CARRIER FREQUENCY ADJUSTMENT

Tune up the transmitter on 20 meters in the USB mode, using a dummy load. Apply a 1 kHz audio signal to the microphone input and adjust the audio generator output for 30 watts output from the transmitter as measured by the dummy load wattmeter. Shift the audio generator output frequency to 300 Hz without changing its output level. Adjust TC₇₀₁ until the power output becomes 8 watts. Repeat this procedure for the LSB mode.

NOTE: Recheck the carrier balance after adjusting the carrier frequency.

Connect a frequency counter to pin 17 of the NB UNIT PB-1703. Transmit in the AM mode. Set TC_{703} for a reading of 8988.295 kHz on the frequency counter.

Transmit on the FSK mode. Set TC₇₀₄ a reading of 8988.125 kHz on the frequency counter. Repeat this procedure for AM and then FSK until both frequencies are indicated correctly on the counter. Ground the inner conductor of the FSK jack on the rear panel and confirm that the frequency shifts to 8988.295 kHz.

VR201 VR203 VR202 T 207 T 201 **Q**210 XF201 **Q**207 **T**206 **Q**206 **Q**212 T 204-**T**201 Q209 **Q**203 **Q**211 T 203 **Q**201 Q202

NB/PROC unit (PB-1703)

7. ALC LEVEL ADJUSTMENT

Set the METER switch to ALC, the MODE switch to USB or LSB, the MIC GAIN control counterclockwise, and the VOX GAIN control to MOX. If the meter reading is not fully deflected to the right, adjustment of the ALC level control VR₂₀₁ on PB-1703 will be required. Adjust VR₂₀₁ for a reading of 350 (full scale) and return the VOX GAIN control to PTT.

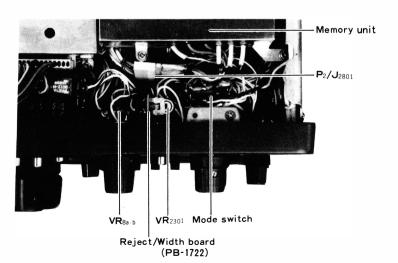
8. RF SPEECH PROCESSOR ADJUSTMENT

Tune up the transceiver on USB at 14.2 MHz. Set VR_{202} and the PROC LEVEL controls to the center of their range. Apply a 1 kHz audio signal to the microphone input and adjust its level to the point where power output levels off after reaching its maximum value; do not advance the input level past the saturation point. Adjust VR_{203} so as to obtain the same power output when the RF Processor switch is in the ON and OFF positions.

9. IF PASSBAND TUNING ADJUSTMENT

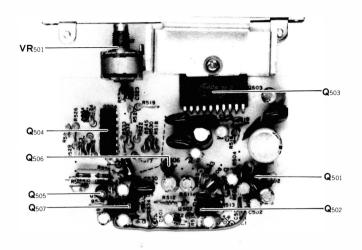
Tune the receiver to 14.2 MHz in the USB mode and set the WIDTH control to the 12 o'clock position. Set the RF GAIN control fully clockwise.

Change the MODE switch from USB to LSB. The receiver background noise at the speaker should not change in pitch. If there is any difference, adjust VR_{2301} located adjacent to the MODE switch below the chassis until the noise is of the same pitch when switching between USB and LSB.



10. APF SELECTIVITY

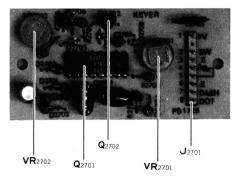
The selectivity of the APF (Audio Peak Filter) can be adjusted by varying VR_{501} , located on PB-1705. Clockwise rotation of VR_{501} will yield sharper selectivity of the filter.



AF unit (PB-1705)

11. KEYER ADJUSTMENT

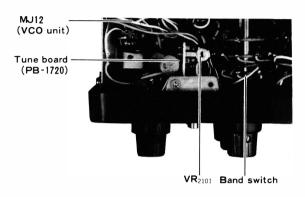
 VR_{2702} controls the dot-to-space ratio for the built-in electronic keyer; this is normally set to 1:1 at the factory. VR_{2701} adjusts the symmetry between dots and dashes. Once VR_{2701} is set, this setting is correct for all keying speeds. Adjustment of VR_{2702} will make both dots and dashes change uniformly with respect to the space. Both of these controls are located on PB-1728.



Keyer unit (PB-1728)

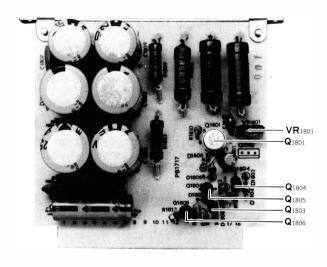
12. CLARIFIER ADJUSTMENT

With the transceiver in the receive mode, push the RX CLARIFIER button and set the CLARIFIER control to 0. Tune in the marker signal on any band and then switch the RX CLARIFIER button OFF. If the frequency changes at all, adjust potentiometer VR_{2101} , which is located inside the cabinet near the CLARIFIER control potentiometer.



13. VOLTAGE REGULATOR ADJUSTMENT

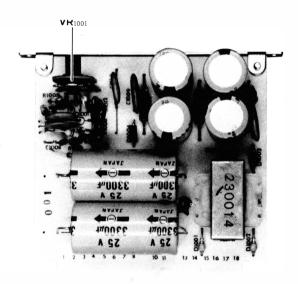
Connect a VTVM DC probe between pin 10 of MJ_1 (PB-1717) and ground. Adjust 6V SET potentiometer VR_{1801} for exactly 6 Volts as indicated on the VTVM.



Rectifier C unit (PB-1717)

14. BIAS ADJUSTMENT

The final amplifier bias must be checked to ensure linearity and normal operating plate dissipation for the final amplifier tubes. Adjust the BIAS control VR₁₀₀₁ on PB-1708 as follows: set the transceiver in the receive mode and allow the tubes to reach normal operating temperature. Set the MODE switch to USB, the METER switch to IC, and the VOX GAIN control to MOX, so as to activate the transmitter. The meter will then indicate cathode current for the PA tubes. The idling cathode current is 50 mA if the bias is correct (25 mA for the SD model). If the idling cathode current is other than 50 mA, adjust the BIAS control VR₁₀₀₁ for the correct value.



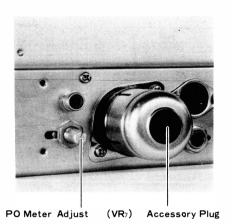
Rectifier A unit (PB-1708)

15. POWER OUTPUT METER ADJUSTMENT

VR₇, located on the transceiver rear panel adjacent to the RCV ANT jack, provides adjustment for the relative power output indication on the front panel meter.

With the transceiver tuned at full power into a 50 Ohm dummy load, VR_7 should be adjusted to indicate 1/2 to 2/3 full scale meter deflection, with the METER switch in the PO position.

It should be noted that the PO meter indicates relative power output, and it is not the basis for determining actual power output. VR_7 has been preset at the factory to read 1/2 to 2/3 full scale into a 50 Ohm dummy load. The operator should not indiscriminately adjust VR_7 while using an unknown load or antenna of possibly high VSWR.



16. FINAL AMPLIFIER NEUTRALIZATION

When replacing the final amplifier tubes, it may be necessary to reset the bias to give the correct idling current, and to check neutralization. Using the procedure outlined below will guarantee maximum output and long tube life.

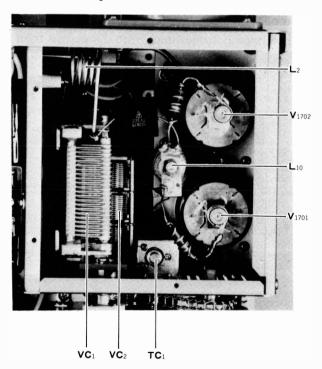
CAUTION

HIGH VOLTAGES ARE PRESENT ON THE UNDERSIDE OF THE CHASSIS AND INSIDE THE FINAL AMPLIFIER COMPARTMENT. USE GREAT CARE WHILE MAKING ADJUSTMENTS IN AREAS OF EXPOSED WIRING.

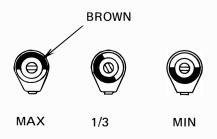
- (1) Connect a dummy load to the antenna receptacle, and set the METER switch to IC.
- (2) Locate TC₀₁, the neutralization variable capacitor shaft, on the inside wall of the final amplifier compartment.
- (3) Check the final amplifier idling current as described in part 14 of this section of the manual (BIAS ADJUSTMENT).
- (4) Tune up the transceiver at 29 MHz, using either the 10B or 10C band, and adjust the carrier level so that it is 150 mA. in the TUNE condition.

- (5) Rotate the PLATE tuning control and observe the point of minimum current ("dip") If the dip is not prominent, reduce the LOADING control slightly to get a better dip. As the PLATE control is rotated the meter should rise equally and smoothly on either side of the dip.
- (6) Determine which side of the dip rises abruptly. Set the PLATE control slightly to this side of the dip, keep the meter reading below 100 mA.
- (7) Using a nonmetallic tuning wand, rotate the neutralization capacitor shaft very slightly in the direction which reduces the current on the meter. Repeat steps 6 and 7 until the meter indicates a smooth and equal rise on either side of the dip.

NOTE: The final amplifier compartment cover must be in place to supply the RF shielding required during the neutralization procedure.



Final Amplifier Compartment



ALIGNMENT OF TRANSMITTER MIXER/ DRIVER AND RECEIVER FRONT END STAGE

- (1) Connect a dummy load/wattmeter to the rear panel ANT jack.
- (2) Set the RF/AF gain controls fully clockwise, set the MODE switch to FSK, and set TC_{2506} to the 1/3 capacitance setting, as shown in Fig. 1.
- (3) Set the BAND switch to 10D, set the main tuning dial for a reading of 30.000 MHz, and set the PRESELECT control to the upper end of the 10 meter band (fully clockwise). Set the LOAD control to 3, and dip the PLATE CONTROL while tuning
- (4) Set the CARR control to the 12 o'clock position. Set the VOX GAIN control to MOX (for not more than 10 seonds), and carefully adjust T₂ and T₃ for maximum IC reading on the meter. Be sure that the bonding agent has been removed before you adjust the cores.
- (5) While receiving, set the MARKER switch ON, and tune to the calibrator signal. Adjust T_1 for maximum S-meter deflection.
- (6) Now set the BAND switch to 10A, set the VFO for a display frequency of 28.000 MHz, and peak the PRESELECT control for maximum PO while tuning. Dip the PLATE control for minimum IC indication. Now set the VOX GAIN switch to MOX, and adjust TC₂₅₀₆ maximum IC indication on the meter (FSK mode, still).
- (7) Set the MARKER switch ON, and tune to the calibrator signal. Peak TC₂₄₀₆ for maximum S-meter deflection.
- (8) As there may be some interaction of adjustments, please repeat steps (3) through (7).
- (9) Adjust the final amplifier neutralization, as described on page 3-30.
- (10) Again repeat steps (3) through (8).
- (11) Now you are ready to align the other bands. Set the BAND switch to 15, set the main tuning dial for a reading of 21.000 MHz, and set the PRESELECT control at 8.6 on its scale. Dip the PLATE control for minimum IC indication while tuning. Set the VOX GAIN control to MOX, and adjust TC₂₆₀₅

and TC_{2505} for maximum PO indication on the meter. On receive, tune in the MARKER signal, and adjust TC_{2405} for maximum Smeter deflection.

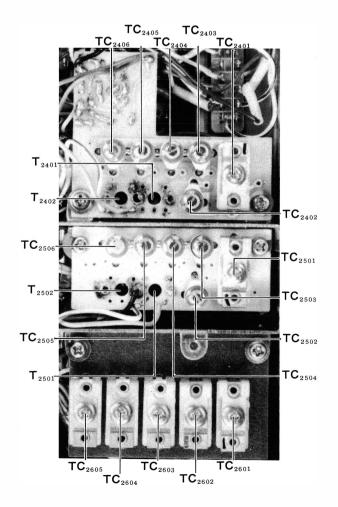
- (12) Set the BAND switch to 20, set the VFO for a frequency of 14.000 MHz, and set the PRE-SELECT control to 7.2 on its scale. Dip the PLATE control for minimum IC indication while tuning. Set the VOX GAIN control to MOX, and adjust TC₂₆₀₄ for maximum PO indication on the meter. On receive, tune in the MARKER signal, and adjust TC₂₄₀₄ for maximum S-meter deflection.
- (13) Set the BAND switch to 80, tune the main dial for a reading of 4.000 MHz, and set the PRESELECT control to 6 on its scale. Dip the PLATE control for minimum IC indication while tuning. Set the VOX GAIN control to MOX, and adjust L₉ and T₂₅₀₁ for maximum PO indication on the meter. On receive, tune in the MARKER signal, and adjust T₂₄₀₁ for maximum S-meter deflection.
- (14) Set the main tuning dial for a reading of 3.500 MHz, and set the PRESELECT control to 2 on its scale. Dip the PLATE control for minimum IC indication while tuning. Set the VOX GAIN control to MOX, and adjust TC₂₆₀₂ and TC₂₅₀₂ for maximum PO indication on the meter. On receive, tune in the MARKER signal, and adjust TC₂₄₀₂ for maximum S-meter deflection.
- (15) Because of possible interaction of adjustments, please repeat steps (13) and (14).
- (16) Set the BAND switch to 40, tune the main dial for a reading of 7.200 MHz, and set the PRESELECT control to 6.5 on its scale. Dip the PLATE control for a minimum IC reading while tuning. Set the VOX GAIN control to MOX, and adjust TC₂₆₀₃ and TC₂₅₀₃ for maximum PO indication on the meter. On receive, tune in the MARKER signal, and adjust TC₂₄₀₃ for maximum S-meter deflection.

ADVICE ON TROUBLESHOOTING THE DRIVER/FINAL STAGES

Three tubes are used in the FT-901DM: a 12BY7A and two 6146B's, run in parallel in the final.

Because not all service personnel are as familiar with tubes as they are with semiconductors, we would begin by cautioning you that tubes are voltage devices. To produce power in useful amounts, they require voltages well in excess of that needed for solid state devices. Take care, lest you quickly develop "serviceman's elbow," a malady well known to old timers. It occurs when your arm jerks back from the +800 volts right into some immovable object. Accompanied by a few colorful phrases, it is not an experience one knowingly encourages, though it is seldom fatal.

If you should come into contact with the high voltage, it is best to take a break from servicing. Alert your colleagues to what happened, and seek medical attention should any signs of shock (trauma) develop. Trauma following contact with high voltage is sometimes more dangerous than the high voltage itself. IT CAN BE FATAL!



FAULT IDENTIFICATION AND LOCALIZATION

The process of troubleshooting any electronic equipment is highly individualistic. Fundamentally, though, the process is one of logical elimination.

Begin with a visual inspection of the transceiver, looking for broken, discolored, or charred components. Smell the unit, as transformers smell differently than resistors, etc. If you do find a component that is cooked, remember that another fault may have caused the destruction of the part you have located.

Initially, turn on the receiver, and check out **only** the RX side. Any malfunctions you detect on the receiver side should be repaired before you check out the transmitter. In doing this, you may well cure the entire problem, as much circuitry is shared on TX and RX.

The logical process of fault identification is to determine the missing function (no RX on LSB), then the board at fault (CARRIER UNIT), then the bad circuit (LSB oscillator), then the malfunctioning part (X701).

If, after the receiver inspection is completed, all appears OK, switch to the transmit side, following the same logical procedure (function — board — circuit — component). Concentrate on those sections unique to the transmit side, as you have already performed a thorough checkout of all receiver and shared circuits (hopefully). Use only a dummy load. NEVER troubleshoot using an antenna.

In this manual, we will provide troubleshooting advice which leads you directly to suspect components. As there are some 2,800 parts in the FT-901DM, though, it obviously is impossible for us to trace the path of every possible malfunction in the radio. Therefore, if your tips do not lead to identification of the trouble, the logical elimination process is the way to go.

In all troubleshooting, an "extender board" is essential for quick and easy voltage testing. A major advantage of Yaesu equipment from a service standpoint is that you don't have to snake a probe into the innards of a rat's nest of wires to get to a critical test point. With the plug-in circuit boards, you can quickly examine a board and move on to another potential trouble area. But don't be without extender boards if you do any servicing. They're cheap, and they cut service time dramatically.

NOTES ON USE OF CMOS IC's:

As CMOS devices are extremely sensitive to damage from static electricity, special precautions must be observed.

In storage, use only a non-inductive sponge.

When installing a CMOS IC in a socket, or on a circuit board, be certain that the power is off. In addition, the technician should rest his hand on the chassis as the component is inserted, so as to place his hand at the same level as the chassis (better to discharge small amounts of static electricity through your fingers than through a \$5 IC!).

When soldering a CMOS IC onto a circuit board, use a low wattage iron, and be sure to ground the tip with a clip lead, if the tip is not grounded through a three-wire power cord.

TROUBLESHOOTING

A FUNDAMENTAL ANALYSIS OF THE TROUBLE

The failure may be caused by one of the following:

- 1) Mechanical defect
- 2) Electrical defect
- 3) Others (Murphy's Law, etc.)

1. MECHANICAL DEFECTS

Typical examples of mechanical defects encountered by the technician are:

- a) Damage from shock during transportation (remember the unit was probably subjected both to sea and truck shipment).
- b) Damage caused by vibration in service.
- c) Damage caused by forcing stubborn knobs or switches. This difficulty is usually preceded by one of the two above defects.

2. ELECTRICAL DEFECTS

Typical electrical defects encountered are:

- a) Part(s) failure caused by aging;
- b) Failures caused by improper application of supply voltage or by voltage spikes;
- c) Improper operation (e.g. transistors without load this usually points to a failure elsewhere, in addition to the damaged transistor or IC).
- d) Loose connections, at the power receptacle, caused by cold solder joints, etc.

3. OTHERS

Among the miscellaneous types of failures or difficulties encountered are:

- a) Antenna troubles be on the alert for antenna problems when the owner of the just-aligned transceiver complains of difficulty "when I switch to the antenna."
- b) Poor power source extremely high or low voltage, insufficient capacity, poor regulation, etc.
- c) Murphy's Law use of a non-Yaesu microphone with different connections, for example. (See page 1-22.)

TYPICAL PART FAILURES, CAUSES, AND SYMPTOMS

PARTS	CAUSE OF TROUBLE	SYMPTOMS
Semiconductors (IC, FET, TR)	High supply voltage Open circuit Excessive drive High temperature	Short or open circuit Output decreases to 1/2 at 80°C Internal noise Instability
MOS FET MOS IC	Static electricity	Total failure
Crystal Crystal filter	Shock High temperature	Crystal destroyed Frequency drift Filter bandpass change
Resistor	Excessive power Aging High temperature	Component burned Value changed Open circuit
Potentiometer	Excessive power Shock	Component burned Open circuit Noise Unsmooth rotation
Capacitor	Excess voltage High temperature Excess power	Shorted Leakage Open/decreased capacitance
Variable capacitor Trimmer capacitor	Ratings exceeded Dust between plates Shock, forced rotation	Shorted Leakage Unsmooth rotation
Coils	Ratings exceeded Variation	Open or short circuit Leakage or shorted turns Detuned
Switch	Ratings exceeded Aging	Poor contact Unsmooth operation Open circuit
Relay	Ratings exceeded Humidity	Poor contact Noise Coil open

RECEIVE MODE

Problem	Condition	Probable Cause(s)
(1) No AC power applied	(a) Fuse OK	* Defective power switch * Defective AC line cord * Cold solder joint to AC cord * Loose contact at power jack
	(b) Fuse blows	* Defective DC-DC Converter (check w/o DC-DC Converter) * Defective D ₁₄₀₁ -D ₁₄₀₄ * High voltage line shorted * Short in 6146B electrodes * Defective D ₁₀₀₁ -D ₁₀₀₂ in 13.6 VDC line * Defective D ₁₀₀₃ , D ₁₀₀₄ , D ₁₈₀₁ , D ₁₈₀₂ in DC 300 and 210 V line * Short in pilot lamp supply * Improper transformer connections
	(c) Fuse blows after tubes warm up	 * Defective 6146B * Defective R₁₀₀₅, R₁₇₀₃, L₁₇₀₁ * Cold solder joint to pin 5 of 6146B socket * Defective bypass capacitor in control grid circuit * Check for -130 volts bias on 6146B * Leakage or short at C₁₇₀₁ * Leakage or short at C₀₄
	(d) Tube heaters do not light up	* Defective heater switch * Cold soldering in heater supply line * Defective tube * ACC plug not installed * Loose connection at tube socket or ACC jack
	(e) No DC operation, OK on AC	* Defective DC cord
	(f) OK on AC, fuse blows on DC with heater switch on	* Defective T20A6 transistor in DC-DC Converter $ * \ \text{Defective } D_{1001} - D_{1004} , D_{1801} , D_{1802} $
	(g) OK on AC, fuse OK, but no DC operation	* Defective T20A6 transistor * Cold solder joint in DC-DC converter

(2) No reception	(a)	S-meter OK, but no audio output from speaker	* Defective speaker * Defective TA7205AP or 2SC1000GR on PB-1705 * Defective audio circuit around above transistor/IC * Defective EXT SP jack
	(b)	No audio output on some mode:	
-		LSB/FSK	* Defective X ₇₀₁
		USB/CW	* Defective X ₇₀₂
		AM	* Defective D ₄₀₇ (PB-1704) * Defective Q ₅₀₇ (PB-1705)
		FM	* Defective Q ₉₀₁ –Q ₉₀₄
		Some mode	* Defective mode switch or cold solder joint on switch
	(c)	No audio output, S-meter off scale	* Defective RF GAIN control * Defective Q ₄₀₇ , Q ₄₀₈
	(d)	Speaker appears OK, no S-meter deflection	* Defective RL ₁ , Q ₄₀₇ , VR ₂ * Defective 19.7475 MHz xtal * Defective Q ₄₀₅ , Q ₄₀₆ (PB-1704) * Defective Q ₃₀₃ (PB-1716) * Defective Q ₂₁₂ (PB-1703) * Defective Q ₁₀₁ -Q ₁₀₅ (PB-1702) * Defective Q ₃₀₁ , Q ₃₀₂ , Q ₃₀₅ (PB-1716) * Defective Q ₄₀₁ -Q ₄₀₄ , Q ₄₀₉ , Q ₄₁₉ (PB-1704)
4	(e)	MARKER ON, only slight S-meter deflection on the marker signal	* Low VCO output (see section on COMMON CIRCUITS) * Defective T ₁ , T ₂₄₀₂ , or C ₂₄₀₆ * Check tuning or T ₁₀₂ , T ₃₀₁ -T ₃₀₃ , T ₄₀₁ -T ₄₀₄ * Tracking error in RF coils * Defective XF ₃₀₂ -XF ₃₀₄ or XF ₄₀₁
	(f)	Normal S-meter deflection against marker signal (S9 +10 dB nominal)	* Defective FH-1 (lamp fuse) * Defective RL ₂ * Defective S ₂₁₀₃

(3) Partial reception	(a) Poor reception on one or more bands (some bands OK)	* Low VCO output or VCO unlocked (see section on COMMON CIRCUITS) * Defective band switch * Defective TC ₂₄₀₁ (160m)-TC ₂₄₀₆ (10m), C ₂₄₀₁ (160m)-C ₂₄₀₆ (10m)
(4) Self-oscillation on receive	(a) Oscillation with HEATER switch on	* Defective 6146B, R_{1005} , R_{1703} , L_{1701} * Defective L_{1701} , C_{04} * Defective R_{13} , R_{14} , R_{1601} , R_{1602} , C_{84} , C_{1101} * Defective Q_{1804} , Q_{1805} (PB-1717)
	(b) Oscillation with HEATER switch either on or off	* TX 12V line shorted to RX 12V line. Check at each board, TX/RX switching diodes and switches
(5) Marker inoperative	(a) RX OK, no marker signal heard	* Defective NB/MARK switch Check voltage at pin 4 of PB-1846 and PB-1685. Should be 12 volts nominally * Defective X ₆₀₁ * Defective Q ₆₁₂ * Defective D ₆₀₆
	(b) 25 kHz marker inoperative	* Defective S ₆₀₁
(6) REJECT inoperative	(a) No notch action	* Defective RL ₄₀₁ * Defective X ₄₀₁ * Defective D ₄₀₆ * Defective Q ₄₁₁ * Defective REJECT switch
(7) APF inoperative	(a) Low or no output, serious distortion	* Defective Q ₅₀₄ , Q ₅₀₅ , Q ₅₀₆

TRANSMITTER

Problem	Condition	Probable Cause(s)
(1) No power output	(a) IC OK, but no power output	* Defective L ₁ , L ₀₂ , L ₁₃ . * Shorted VC ₀₁ , VC ₂ . * Defective C ₇₀ , C ₄₇ * Low bands only: Defective C ₀₇ -C ₀₉ , C ₃₉ * Defective RL ₂ * Open D ₆
	(b) IC OK, but no output on a particular band	 * Cold solder joint between band switch and tank coil * Defective band switch
	(c) No IC indication	 Defective 6146B ACC plug not correctly wired or improperly seated No screen voltage at 6146B because of defective L₁₇₀₄, band switch, or mode switch
	(d) Idling IC OK, but no drive	 Defective 12BY7A No screen voltage because of defective R₁₆₀₃, C₁₈₀₆, R₁₈₀₇, or R₁₈₀₈ Defective Q₁₀₆, Q₁₀₇, or Q₂₀₃
(2) Poor TX performance	(a) No power output on LSB only	* Defective X ₇₀₁
	(b) No power output on USB only	* Defective X ₇₀₂
	(c) No power output on both USB/LSB	* Defective RL ₇₀₁ , Q ₇₀₅ * No vox operation: defective or grounded MIC or PATCH jack * Defective Q ₇₀₈ or Q ₇₀₉
	(d) No power output on CW/FSK/AM/TUNE	* Defective X ₇₀₃ , Q ₇₀₄ , Q ₂₀₁
D.	(e) Keyer OK, but no CW keying	 Defective mode switch, Q₁₈₀₃, and associated circuit Defective D₆₀₅ if carrier hangs up.

	(f) No modulation on AM	* Defective Q ₇₁₀
	(g) No output on FM	* Defective X_{902} , Q_{912} , Q_{913}
	(h) No modulation on FM	* Defective T ₉₀₂ , D ₉₀₈ , D ₉₁₄
	(i) No FSK shift	 Defective Q₇₀₁, defective or misaligned TC₇₀₃, TC₇₀₄ FSK jack grounded
(3) Abnormal meter operation	(a) Cannot set ALC meter to full scale	* Defective C_{1008} * Defective Q_{203} , VR_{201} * Defective meter switch or RL_1
13	(b) ALC meter does not function	 Defective 12BY7A ALC line shorted to ground Defective D₁₀₀₅, D₁₀₀₆ Driver, IF stages require realignment
	(c) Power output OK, no IC meter indication	* Defective R ₀₆ or meter switch * Defective RL ₁
	(d) Power output OK, PO meter does not function	* Improper setting of VR ₇ * Defective C ₁₁ , C ₁₉ , C ₂₄ , C ₄₁ , L ₁₁ , D ₁₁ , VR ₇ , or mode switch
(4) No changeover from RX to TX	(a) TX OK in MOX position	* Failure in MIC or PTT line * Loose MIC jack or plug connection
	(b) No TX in MOX position	* Defective VR_1 * Defective RL_1 , D_5
	(c) VOX inoperative	 If CW semi-break-in is OK, then Q₆₀₈ defective If no CW semi-break-in, check Q₆₀₁ - Q₆₀₇, Q₆₀₉, Q₆₁₀
(5) No return to RX from TX		* PTT line grounded * Defective Q ₆₀₇ * Defective Q ₆₀₂ -Q ₆₀₄ , Q ₆₀₆ * Defective keyer unit (CW)

(6) Fuse blows on transmit	(a) OK on RX	* TX 12V or TX 8V line grounded * Insufficient bias voltage on 6146B * Defective D ₅ or D ₇
(7) TX self-oscillation	(a) OK on receive	* Neutralization of final tubes required * Defective C ₁₆ , C ₃₀ , C ₈₇ , C ₁₆₀₅ * RX 12V line shorted to TX 12V or TX 8V line only on TX
(8) RF processor trouble	(a) Low or no output with processor on	* Processor switch defective * Defective XF ₂₀₁ * Defective Q ₂₀₅ , Q ₂₀₆ , Q ₂₀₇
(9) Monitor trouble	(a) Inoperative	* Defective APF/MONI switch or loose contact * Defective R515
(10) Keyer trouble	(a) Keyer not functioning	* Defective Q ₂₇₀₁ , Q ₂₇₀₂
	(b) Key-down all the time or string of dots, etc.	 * Key line shorted to ground * Latch-up of 8043 IC. Replace IC and replace leaky C₂₇₀₆ (use 0.33 μf mylar or 2 back-to-back tantalum of 0.68 μf each).
	(c) Side tone normal, but carrier hangs on for 2–3 seconds.	* Defective D ₆₀₅

COMMON CIRCUITS

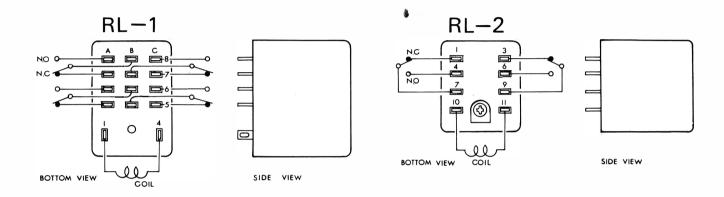
Problem	Condition	Probable Cause(s)
(1) Counter circuit	(a) Digital display does not work	* Defective Q ₂₉₂₄ * 5V line in Counter Unit grounded * Defective display LED * Defective Q ₂₉₁₇ , Q ₂₉₁₉ , Q ₂₉₂₂ , Q ₂₉₂₃ * Defective R ₂₉₃₂ -R ₂₉₅₂
	(b) Four digits to the right read "000.0"	 * VFO input not connected or is grounded * Defective Q₂₉₀₁ -Q₂₉₀₅, Q₂₉₁₃, Q₂₉₁₅, Q₂₉₁₈, Q₂₉₂₅ * Defective 18.0 or 18.5 MHz crystal in counter * Defective 655.36 kHz crystal * Defective Q₂₉₁₂
	(c) Display unstable, all digits working OK	 * PLL unlock. Refer to section on PLL trouble. * Defective 655.36 MHz crystal * Low VFO input (80–120 mV OK)
	(d) MHz display incorrect	 * Check wiring between P₁₀/J₂₉₀₂ and band switch . * Defective Q₂₉₁₀, Q₂₉₁₁, D₂₉₀₁ -D₂₉₀₄, D₂₉₂₀ -D₂₉₂₃
	(e) Display flickers	 Defective Q₂₉₁₆. PLL or VCO problems. Refer to appropriate sections of this guide
(2) PLL, VCO circuits	(a) Display flickers	* T ₁₂₀₁ -T ₁₂₀₈ require alignment * Loose connection on band switch * VCO not oscillating
	(b) No VCO output, all bands	 Defective Q₁₂₀₉ -Q₁₂₁₂ VCO output cable grounded or cut
	(c) No input signal— local, VCO, VFO— to PLL unit	 * If no VCO signal, refer to (b), above * If no local signal, check local crystal and band switch * If no VFO signal and VFO LED is not lighted, check SELECT switch and

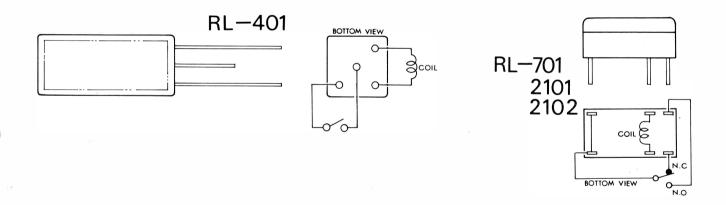
		select relay; check wiring to pin 3 of P7 for short to ground; check Q ₁₈₀₁ * If no VFO signal, but VFO LED lights up, check PB-1726 and VFO unit
(3) Indicators	(a) APF LED does not work	* Defective D ₈ , R ₂₀₀₁ , or APF switch
	(b) REJECT LED does not work	* Defective LED D_{2301} , or R_{2301} , S_{2301}
	(c) CLARIFIER LED does not work	* Defective LED D_{2101} or S_{2104} , S_{2105} , R_{2104}
	(d) PROCESSOR LED does not work	* Defective LED D_{2101} , or R_{2108} , S_{2102}
	(e) TUNE LED does not work	 * If TUNE relay does not operate, check RL₂₁₀₁, R₂₁₁₀, C₂₁₀₁, D₂₁₆₄, S₂₁₆₁ * If TUNE relay is working, check Q₂₁₀₂, R₂₁₁₁, R₂₁₁₂, D₂₁₀₃, D₂₁₀₇
	(f) MR LED does not work	* Defective LED or S ₁₉₀₁ –S ₁₉₀₅
	(g) TX MR LED does not work	* Defective LED or RL ₁₉₀₁ , S ₁₉₀₂
	(h) RX MR LED does not work	* Defective LED or RL ₁₉₀₁ , S ₁₉₀₃
	(i) VFO LED does not work	* Defective LED or S ₂₁₀₃ –S ₂₁₀₄ , RL ₁₉₀₁
	(j) EXT LED does not work	* Defective LED or S ₁₉₀₅
,	(k) M LED does not work	* Defective LED or R ₂₂₀₃ , or memory unit.

(4) Clarifier	(a) Frequency jumps with clarifier on	* Defective VR_{06} , R_6 , R_{2103} , S_{2104} , S_{2105} , RL_{2102}				
	(b) OFF and "0" condition do not coincide in frequency	* Defective VR_{2101} , R_{2101} , R_{2102} , RL_{2101}				
	(c) Frequency jumps with clarifier off, OK with clarifier on	* Defective VR ₂₁₀₁ , R ₂₁₀₁ , R ₂₁₀₂ , S ₂₁₀₅				
	(d) Frequency jumps regardless of clarifier position	 * Unstable 6V REG supply, check Q₁₈₀₁ and VR₁₈₀₁ * Check VFO unit * Check VCO unit 				

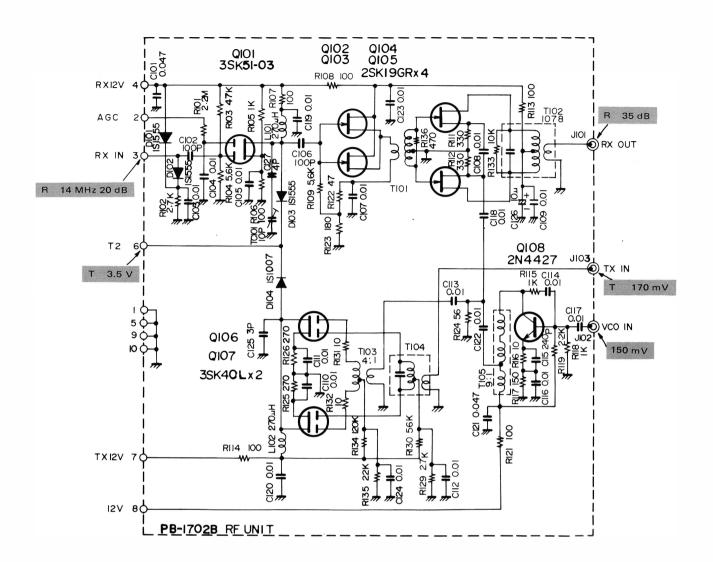
RELAY CONNECTION INFORMATION

Should the need for replacement of relays become necessary, or if you are trying to verify proper relay operation, the diagrams below should help you.





RF UNIT (PB-1702B)



SIGNAL LEVEL

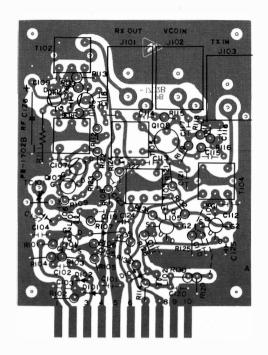
Tx: USB 14.0 MHz
1 kHz 5 mV MIC INPUT

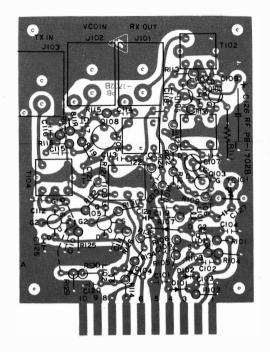
Rx: USB 14.0 MHz
S-9 Level

ANT: 18 dB

	DC	DC VOLTAGES						(V)
	E(S)		C(D)		B(G1)		(G ₂)	
	R	Т	R	Т	R	Т	R	T
Q 101	1.5	0	10.6	0	1.3	0	2.5	2.5
Q102	2.0	0	10.2	0	1.6	0	_	-
Q103	2.0	0	10.2	0	1.6	0	_	-
Q104	1.4	0	9.5	0	0	0	_	-
Q105	1.4	0	9.5	0	0	0		
Q106	0	0.9	0	10.3	0	0.5	0	1.6
Q107	0	0.9	0	10.3	0	0.5	0	1.6
Q108	2	2	8.7	8.7	2.7	2.7	_	_

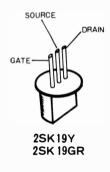
RF UNIT PARTS LAYOUT

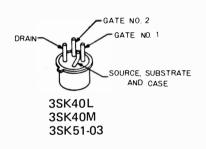




Viewed from component side

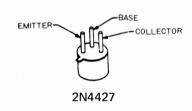
Viewed from solder side

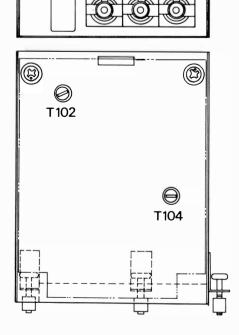




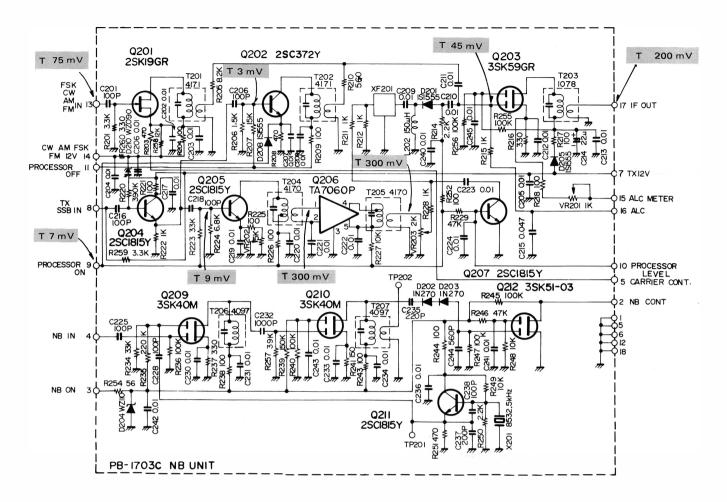
J 101

J102 J103





NB/PROC UNIT (PB-1703C)



	DC VOLTAGES					(V)		
	E(\$	E(S) C((D) B		G1)	(G ₂)	
	R	Т	R	Т	R	Т	R	Т
Q201	0	4	0	8.9	0	0.7	_	_
Q 202	0	0.3	0	10.9	0.	1.0	_	-
Q 203	0	0.6	0	11	0	2.5	0	5.5
Q204	0	3.2	0	11.9	0	3.9	_	_
Q 205	0	1.1	0	10.3	0	1.8	_	_
Q 207	0	0	0	0	0	0.5	_	_
Q 209	0.5	0.5	10.5	10.5	0	0	1.4	1.4
Q210	0.5	0.5	10.3	10.3	0	0	4.1	4.1
Q211	3.5	3.5	9.7	9.7	1.8	1.8	_	_
Q212	0	0	0	0	0	0	0	0

.4	NB	ON	
l.1	NB	ON	
_	NB	ON	
)			
	_		
5			
		2222	~

SSB

CW, AM, FSK, FM SSB, PROC OFF

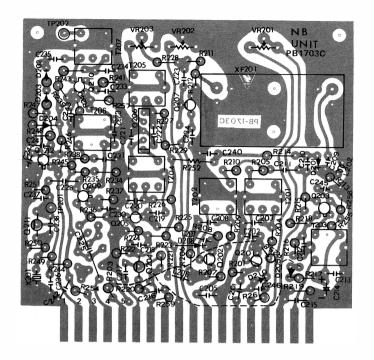
SSB, PROC ON

SSB, PROC ON

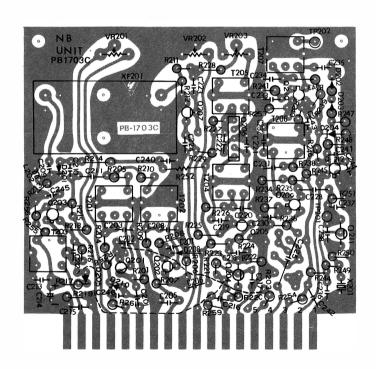
		. 1	2	3	4	5
Q206	R	0	0	0	0	0
	Т	1.4	1.4	0	2.3	2.3

SSB, PROC ON

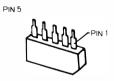
NB/PROC UNIT PARTS LAYOUT



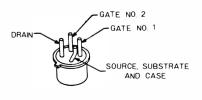
Viewed from component side



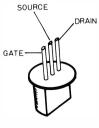




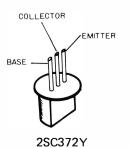
TA7060P

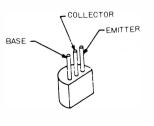


3SK40M 3SK59GR 3SK51-03



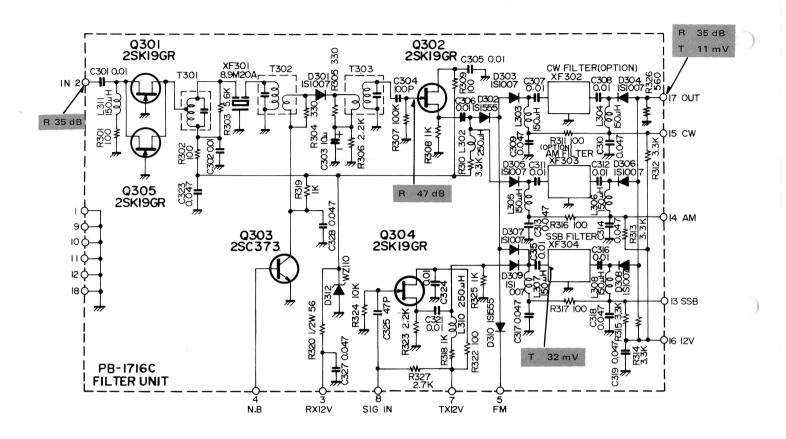
2SK19GR





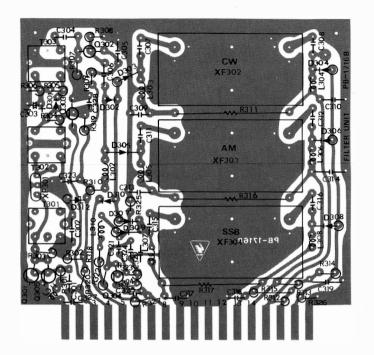
2SC1815Y

FILTER UNIT (PB-1716C)

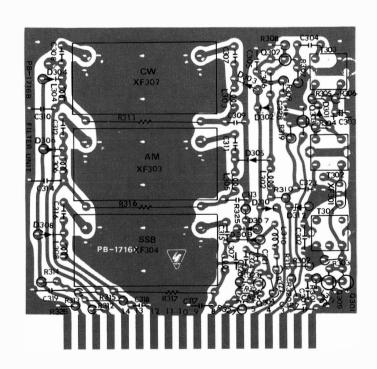


		(V)					
	E(S)		C(I)	B(G1)		
			R	Т	R	Т	
Q301	8.0	0	9.8	0	0	0	
Q302	1.7	0	10.6	0	0	0	
Q303	0	0	7.5	0	0	0	
Q304	0	1.8	0	11.9	0	0	
Q305	0.8	0	9.8	0	0	0	

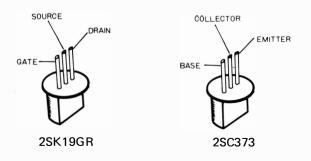
FILTER UNIT PARTS LAYOUT



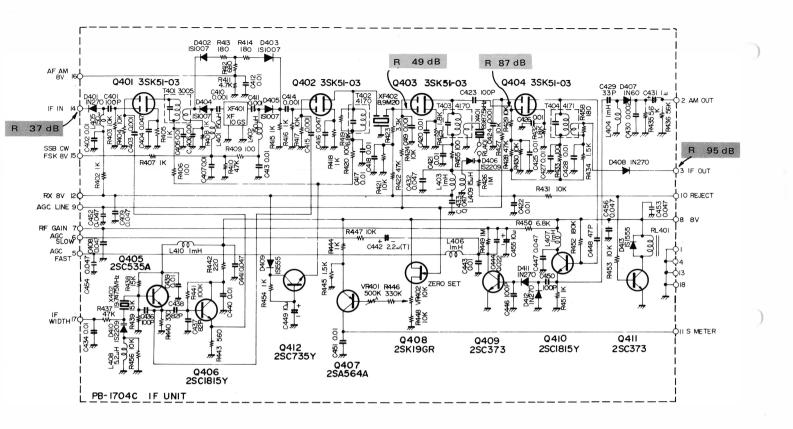
Viewed from component side



Viewed from solder side



IF UNIT (PB-1704C)

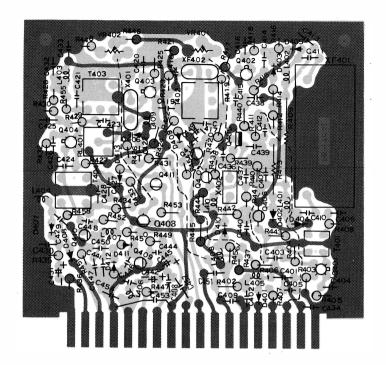


	DC	VOLTAGES						(V)
	E(\$	S)	C(E))	В(С	31)	(G	i2)
a.	R	Т	R	Т	R	Т	R	Т
Q401	0.5	0	6.8	0	0	0	0	0
Q402	0.5	0	6.8	0	0	0	0	0
Q403	2.0	0	8.0	0	1.7	0	2.9	2.9
Q404	2.0	0	8.0	0	1.4	0	2.9	2.9
Q405	2.4	2.4	8.0	8.0	2.4	2.4	_	_
Q4,06	3.2	3.2	7.0	7.0	3.8	3.8	_	-
Q 407	5.0	5.0	0	3.9	4.3	4.3	_	_
Q403	5.2	5.2	8.2	8.2	3.0	3.0	_	-
Q409	0	0	3.0	3.0	0	0	_	_
Q410	3.8	3.8	8.0	8.0	4.5	4.5	_	_
Q211	0	0	0.15*	0.15	0.7	0.7	_	
Q412	6.8	0	7.5	0.3	7.5	0.3	_	_

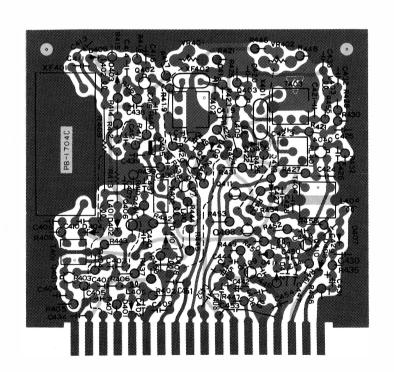
REJECT ON

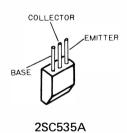
^{*} REJECT OFF 8.0 V

IF UNIT PARTS LAYOUT

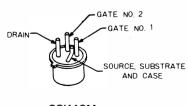


Viewed from component side

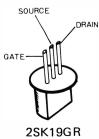




Viewed from solder side



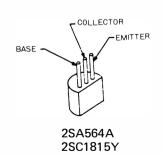
3SK40M 3SK51-03



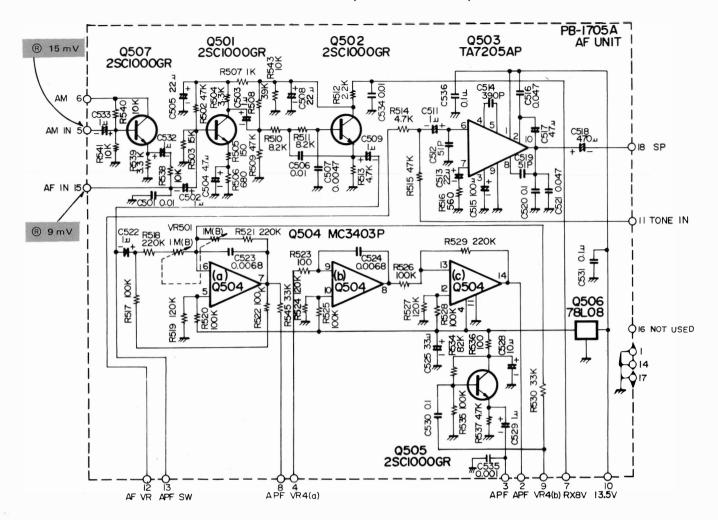
DRAIN

BASE

2SC373
2SC735Y



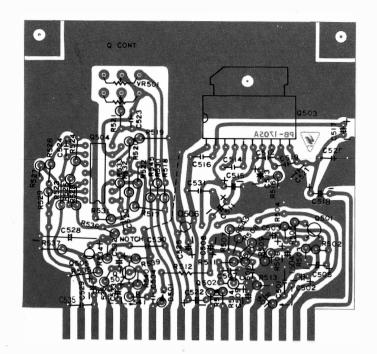
AF UNIT (PB-1705A)



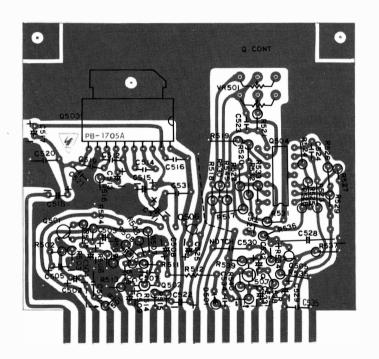
	DC	VO	LTAG	ES		(V)	
	E		C	;	E	3	
	R	Т	R	Т	R	Т	
Q501	0.7	0	2.8	0	1.4	0	
Q502	3.0	0	6.9	0	3.6	0	
Q505	3.6	3.6	8.0	8.0	4.3	4.3	
Q507	3.3	3.3	7.9	7.9	3.9	3.9	AN

38		DC	VOLT	AGES	;										(V)
		1	2	3	4	5	6	7	8	9	10	11	12	13	14
	R	14.9	13.8	4.2	8.6	1.5	3.6	3.6	1.2	0	7.3		-	_	_
Q503	Т	14.9	13.8	4.2	8.6	1.5	3.6	3.6	1.2	0	7.3	-	-	-	_
	R	6.9	4.4	0.3	8.2	4.4	4.5	4.5	4.4	4.5	4.4	0	4.4	4.4	4.4
Q504	Т	6.9	4.4	0.3	8.2	4.4	4.5	4.5	4.4	4.5	4.4	0	4.4	4.4	4.4
		IN	OUT												
Q506		15	8.0												

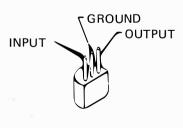
AF UNIT PARTS LAYOUT



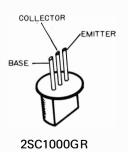
Viewed from component side

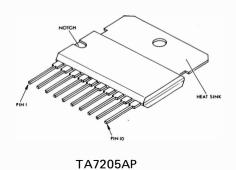


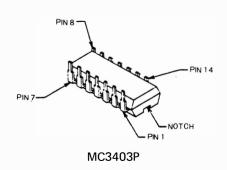
Viewed from solder side



78L08

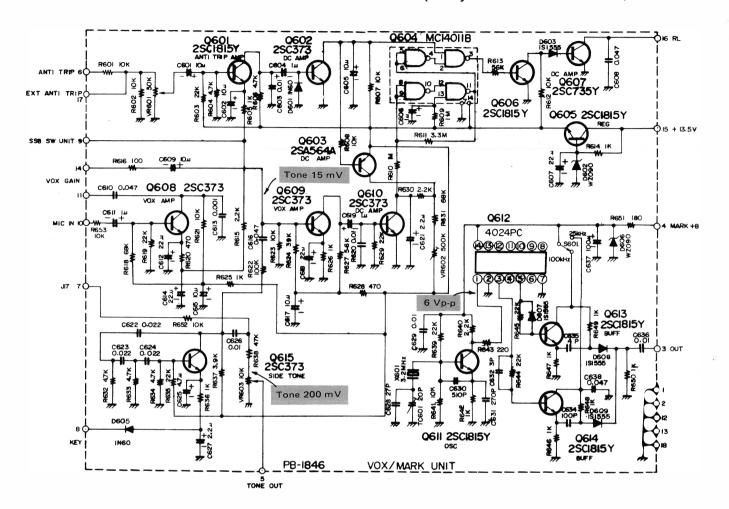






VOX/MARKER UNIT (PB-1846)

(Early model PB-1685-3330)



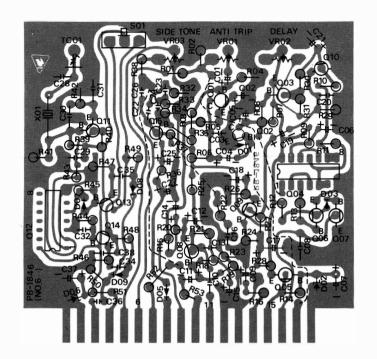
		DC VOLTAGES						
		E	(ı	В		
	R	Т	R	Т	R	Т		
Q601	0.7	0.7	4.6	4.6	1.4	1.4		
Q602	0	0	8.3	8.3	0	0		
Q603	8.3	8.3	8.2	8.2	8.3	8.3		
Q605	8.9	8.9	12.0	12.0	8.3	8.3		
Q606	0	0	0.03	0.03	0.7	0.7		
Q607	0	0	12.0	0	0.14	0.11		
Q608	1.2	1.2	3.4	3.4	1.8	1.8		

	DC	VOL	TAGE	S		(V)
	E	Ē	C	;	E	3
	R	Т	R	Т	R	Т
Q609	0.9	0.9	2.6	2.6	1.6	1.6
Q610	0	0	8.2	8.2	0	0
Q611	1.8	1.8	4.5	4.5	2.4	2.4
Q613	3.7	3.7	9.0	9.0	2.9	2.9
Q614	3.6	3.6	9.0	9.0	4.0	4.0
Q615	0.9	0.9	8.3	8.3	1.5	1.5

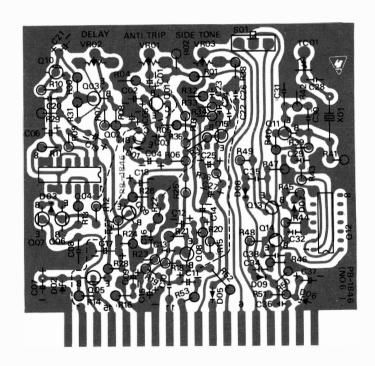
MARK ON 25 kHz ON 100 kHz ON

		DC	VOL	TAGE	S										(V)
		1	2	3	4	5	6	7	8	9	10	11	12	13	14
Q604	R	8.3	0	8.2	0	8.3	8.3	0	7.6	7.6	0	8.3	0	7.4	8.3
Q604	Т	8.3	0	8.2	0	8.3	8.3	0	7.6	7.6	0	8.3	0	7.4	8.3
0010	R	4.5	0	4.5	4.5	4.5	4.5	0	0	4.5	0	4.5	4.4	0	8.9
Q612	Т	4.5	0	4.5	4.5	4.5	4.5	0	0	4.5	0	4.5	4.4	0	8.9

VOX/MARKER UNIT PARTS LAYOUT

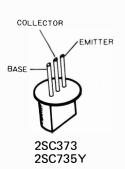


Viewed from component side

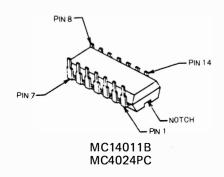


BASE EMITTER 25 A FG 4 A

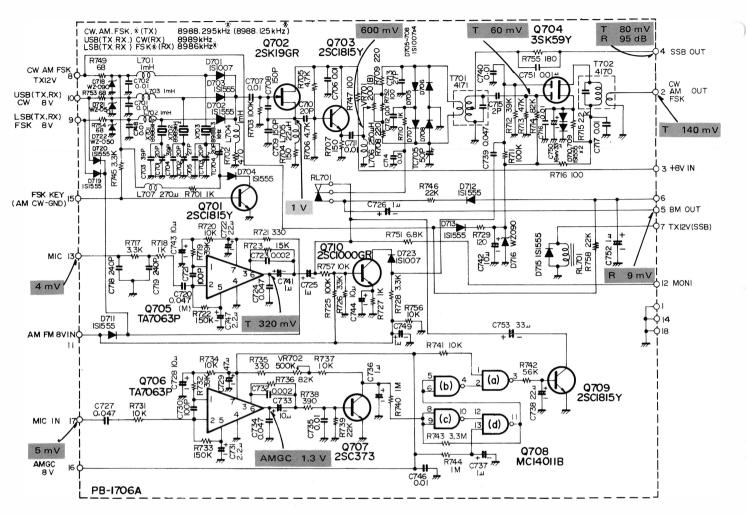
2SA564A 2SC1815Y



Viewed from solder side



CARRIER UNIT (PB-1706A)



	DC	DC VOLTAGES						(V)
	E(S)	C(D)	В(G 1)	(0	32)
	R	Т	R	Т	R	Т	R	Т
Q701	0	0.2	0	14.3	0	0.6	_	_
Q702	0.7	0.7	6.2	6.2	0	0	_	_
Q708	2.2	2.2	6.2	6.2	2.9	2.9	-	
Q704	0	1.4	0	7.4	0	3.2	0	2.5
Q707	0	0	0.4	0.4	0	0	_	-
4707	0	0	8.0	8.0	0	0	-	_
Q709	0	0	0	0	0	0	_	_
Q709	0	0	0	0	0.6	0.6	-	_
Q710	1.3	1.3	3.7	3.7	1.9	1.9	-	_
		1	2	3	4	5	6	7
Q705	R	1.4	0.6	0	0	0.7	4.4	7.0
Q705	Т	1.4	0.6	0	0	0.7	4.4	7.0
	R	0.4	0	0	0	0	0	0.4
0.700	Т	0.4	0	0	0	0	0	0.4
Q 706	R	1.2	0.6	0	0	0.6	5.2	7.7
	Т	1.2	0.6	0	0	0.6	5.2	7.7

AMGC OFF

" ON

" OFF

AM

AMGC OFF

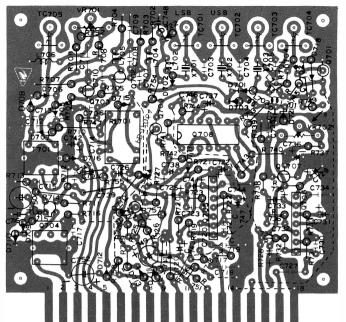
AMGC ON

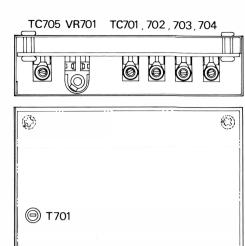
		1	2	3	4	5	6	7	8	9	10	11	12	13	14
	R	0.4	0	0.3	0	0.3	0.3	0	0.3	0.3	0	0.3	0	0.4	0
0	Т	0.4	0	0.3	0	0.3	0.3	0	0.3	0.3	0	0.3	0	0.4	0
Q ₇₀₈	R	8.2	0	8.2	0	8.2	8.2	0	7.5	7.5	0	8.2	0	7.4	8.2
	Т	8.2	0	8.2	0	8.2	8.2	0	7.5	7.5	0	8.2	0	7.4	8.2

AMGC OFF

AMGC ON

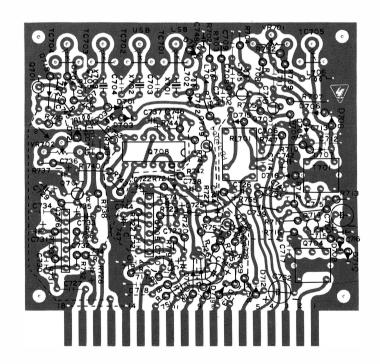
CARRIER UNIT PARTS LAYOUT

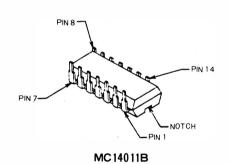


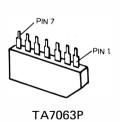


Viewed from component side

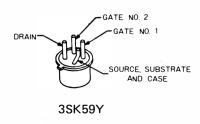
⑤ T702

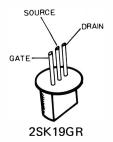


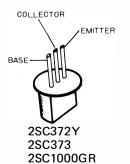


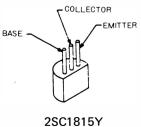


Viewed from solder side

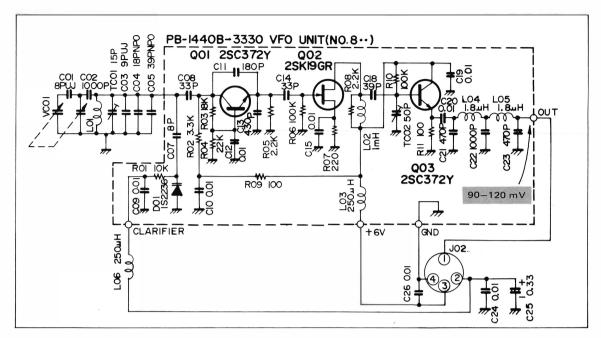


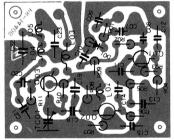


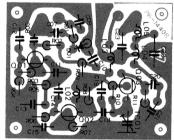




VFO ASSEMBLY VFO BOARD (PB-1440B-3330)

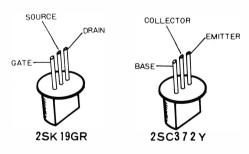




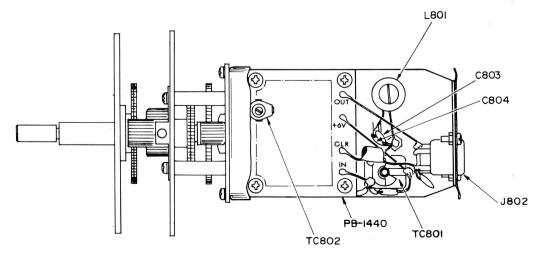


Viewed from component side

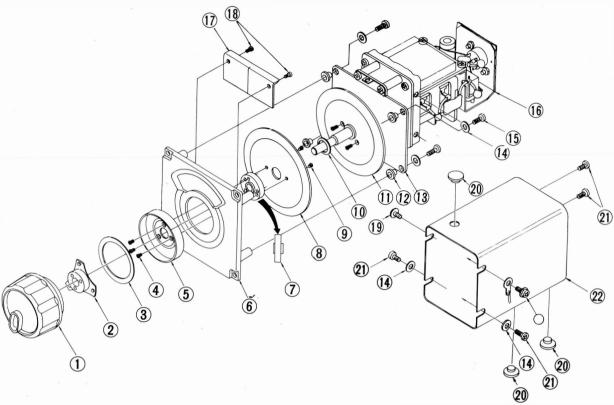
Viewed from solder side



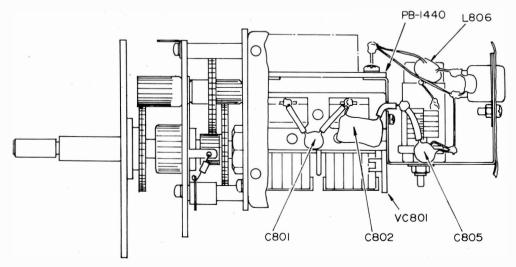
	DC	VOLTAGE	S			(V)
		E(S)		C(D)		B(G)
	DC	RF	DC	RF	DC	RF
Q801	1.3	(120 mV)	3.8	(1.4 V)	2.0	_
Q802	0.7	_	6.2	(400mV)	0	(100 mV)
Q803	0.8	(200 mV)	6.3	_	1.6	(200 mV)



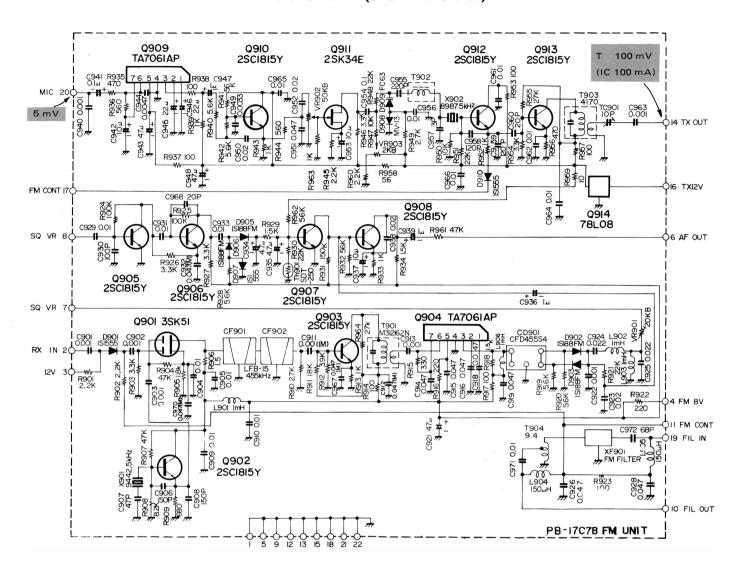
VFO UNIT EXPLODED VIEW



					•
Fig. & Index No.	Q'ty	Name & Description	Fig. & Index No.	Q'ty	Name & Description
1-1	1	Knob: Tuning	1-12	4	Bushing: Sleeve
		Set Screw: M4 x 6, mm, Steel	1-13	1	Gear Assembly
1-2	1		1-14	6	Fiber Washer: Flat
1-3	1	Washer:	1-15	4	Screw: Pan Head with washer,
1-4	3	Screw: Flat Head, M2 x 4, mm,			M3 x 6, mm, Steel
		Steel	1-16	1	Insulator: Sheet
1-5	1	Calibration Ring	1-17	1	Cursol
1-6	1	Escutcheon	1-18	2	Screw: Pan Head, M2 x 4, mm
1-7	1	Holder: Aluminum			Steel
1-8	1	Sub Dial	1-19	2	Screw: Pan Head with spring
1-9	2	Screw: Flat Head, M2 x 4, mm,			washer and flat washer, Steel
		Steel	1-20	3	Grommet: Rubber
1-10	1	Washer: Flat, Steel	1-21	4	Screw: Pan Head, M3 x 6, mm,
1-11	1	Main Dial			Plastic



FM UNIT (PB-1707B)

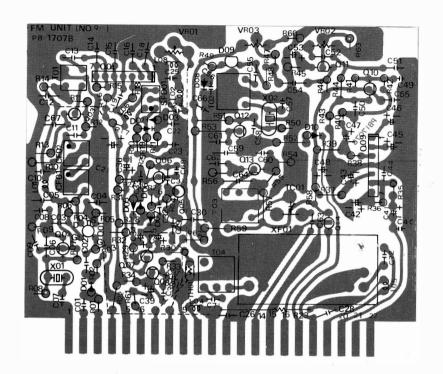


	DC VOLTAGES							(v)
	E	(S)	C(D)	В(G1)	(0	(2)
	R	Т	R	Т	R	Т	R	Т
Q 901	0.6	0.6	5.3	5.3	0	0	0.6	0.6
Q 902	0.3	0.3	5.5	5.5	0.8	0.8	_	_
Q 903	0.4	0.4	5.7	5.7	1.0	1.0	_	_
Q905	0	0	1.0	1.0	0.6	0.6	_	
Q 906	2.9	2.9	3.9	3.9	3.5	3.5	_	_
Q907	0	0	1.4	0	0.4	0.6	_	_
Q908	0.7	0	4.6	5.8	1.4	0	_	_
Q910	0	4.9	0	7.0	0	5.5	_	_
Q911	0	1.6	0	4.6	0	0	_	_
Q912	0	1.9	0	7.7	0	2.4		
Q ₉₁₃	0	0.2	0	6.3	0	0.8		

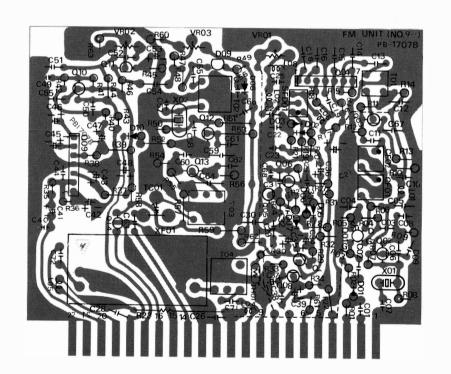
	DC VOLTAGES								
	\	1	2	3	4	5	6	7	
0	R	1.6	1.6	5.6	0	4.5	1.6	1.6	
Q904	Т	1.6	1.6	5.6	0	4.5	1.6	1.6	
Q909	R	0	0	0	0	0 -	0	0	
Q909	Т	1.8	1.9	4.4	0	6.4	1.9	1.9	
		IN	OUT						
0011	R	0	0						
Q914	Т	12.0	8.0						

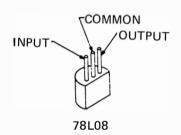
SQ: OFF SQ: OFF

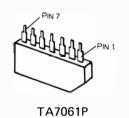
FM UNIT PARTS LAYOUT



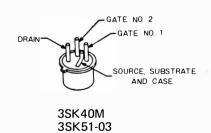
Viewed from component side

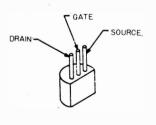


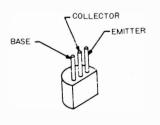


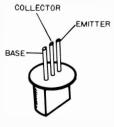


Viewed from solder side





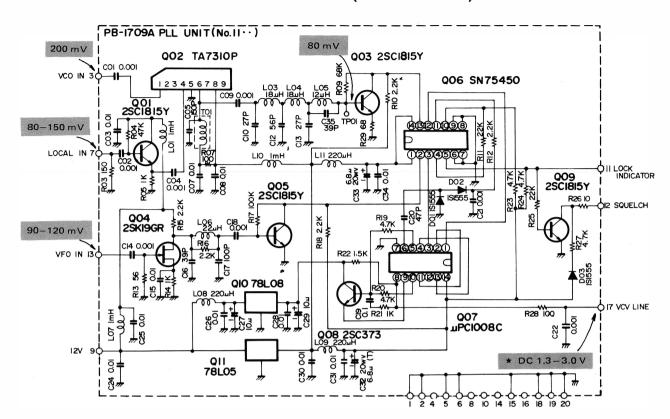




2SK34E 2SC1815Y

2SC372Y

PLL UNIT (PB-1709A)

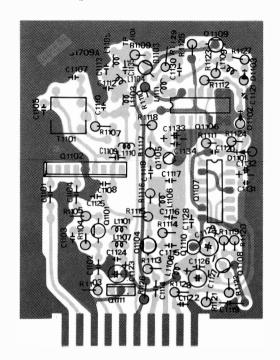


	DC	DC VOLTAGES										
	E	(S)	C(D)	B(G)							
	R	Т	R	Т	R	Т						
Q 1101	8.4	8.4	11.1	11.1	9.0	9.0						
Q1103	0.1	0.1	1.5	1.5	0.8	0.8						
Q 1104	2.0	2.0	6.7	6.7	0	0						
Q1105	0	0	1.7	1.7	0.6	0.6						
Q1108	1.3	1.3	8.0	8.0	1.8	1.8						
Q1109	0	0	0	0	0.6	0.6						

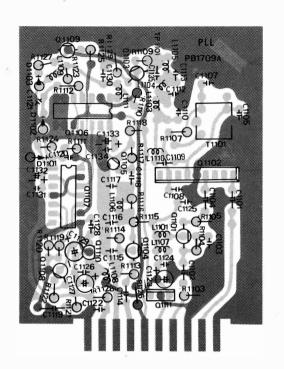
	IN	OUT
Q1110	11.2	8.0
Q1111	11.3	5.0

		DC	VOL	TAGE	S										(V)
	_	1	2	3	4	5	6	7	8	9	10	11	12	13	14
Q1102	R	2.6	1.9	1.2	2.6	0	4.4	2.0	4.7	1.3	_	_	_	-	-
41102	Т	2.6	1.9	1.2	2.6	0	4.4	2.0	4.7	1.3	_	_	_		_
Q1106	R	4.9	1.7	1.2	0	4.2	0	0	0	0	0.07	0.6	1.2	1.5	4.9
21100	Т	4.9	1.7	1.2	0	4.2	0	0	0	0	0.07	0.6	1.2	1.5	4.9
Q1107	R	1.2	3.7	1.2	3.6	1.9	2.5	0	*VCV	1.4	1.8	3.7	3.9	3.6	4.9
21107	Т	1.2	3.7	1.2	3.6	1.9	2.5	0	*VCV	1.4	1.8	3.7	3.9	3.6	4.9

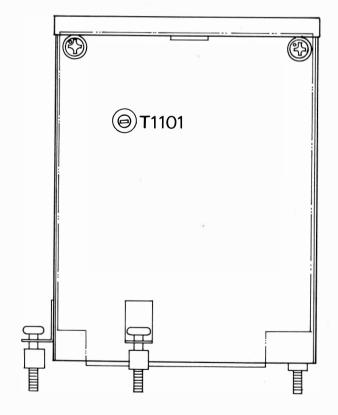
PLL UNIT PARTS LAYOUT

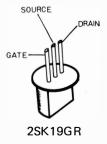


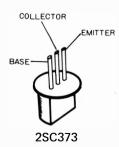


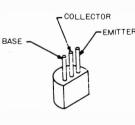


Viewed from solder side

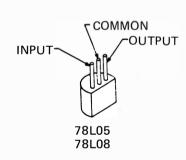


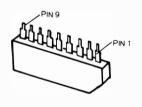




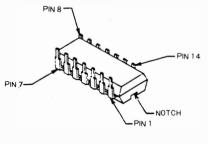


2SC1815Y



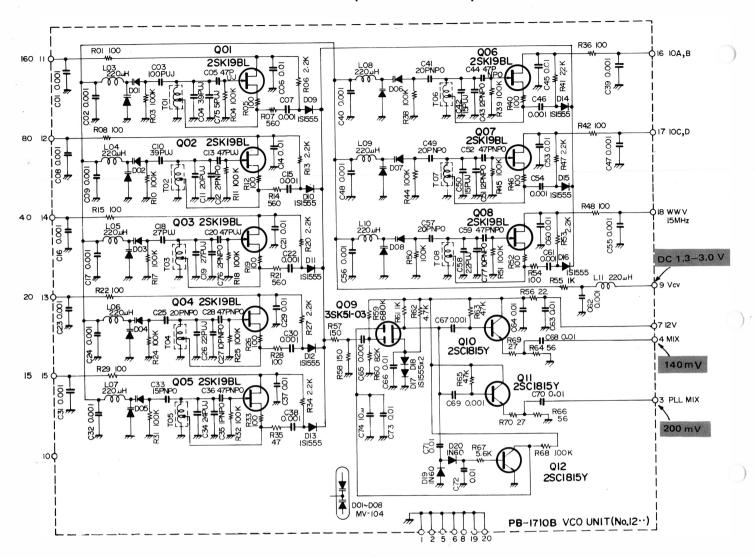


TA7310P

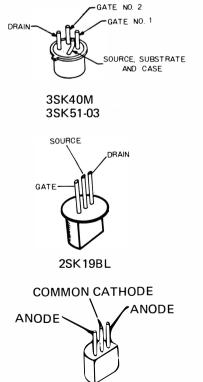


SN75450B MC4044P μ PC1008C

VCO UNIT (PB-1710B)

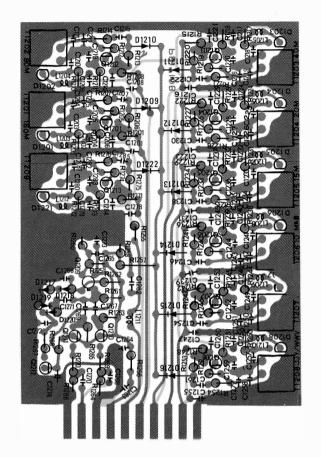


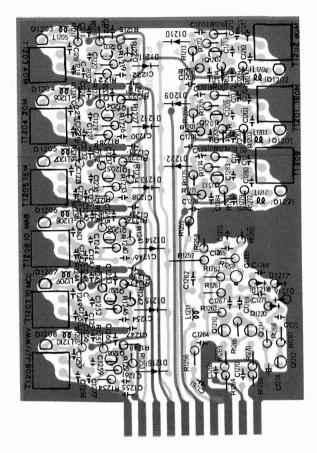
	DC	(V)							
	E((S)	C(I)	В(G1)	(G ₂)		
	R	Т	R	Т	R	Т	R	Т_	
Q1201	0.7	0.7	7.1	7.1	0	0	_	-	
Q1202	0.9	0.9	6.9	6.9	0	0	_	-	
Q1203	0.9	0.9	7.0	7.0	0	0	_	-	
Q1204	0.9	0.9	7.0	7.0	0	0	_	-	
Q ₁₂₀₅	0.9	0.9	7.0	7.0	0	0	_	_	
Q1206	0.9	0.9	6.4	6.4	0	0	_	_	
Q1207	0.8	0.8	6.4	6.4	0	0	_	_	
Q1208	0.7	0.7	7.2	7.2	0	0	-	_	
Q 1209	1.3	1.3	3.5	3.5	0.8	8.0	1.5	1.5	
Q1210	1.3	1.3	7.3	7.3	2.0	2.0	_	_	
Q1211	1.7	1.7	7.3	7.3	2.4	2.4	_		
Q1212	0	0	1.5	1.5	0.6	0.6	_	_	



MV104

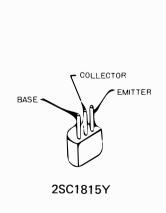
VCO UNIT PARTS LAYOUT

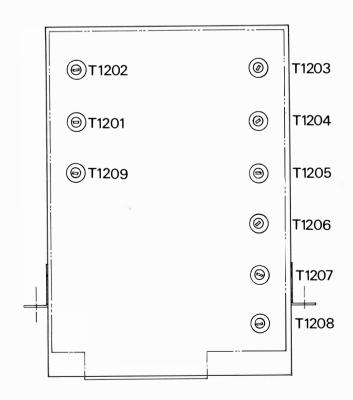




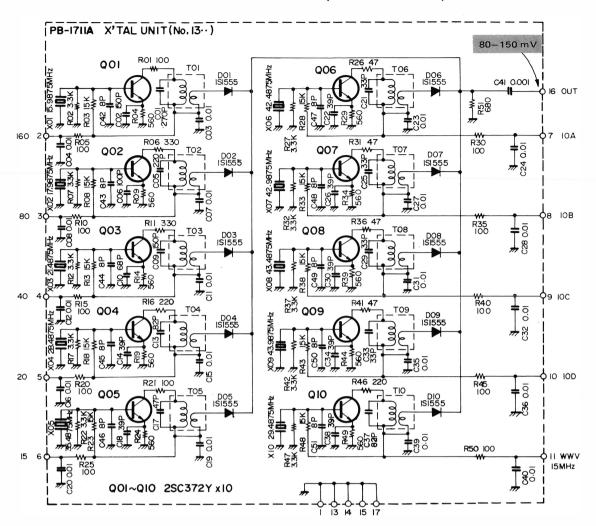
Viewed from component side

Viewed from solder side



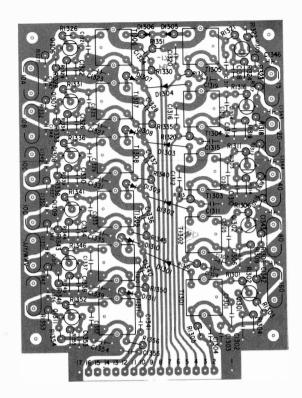


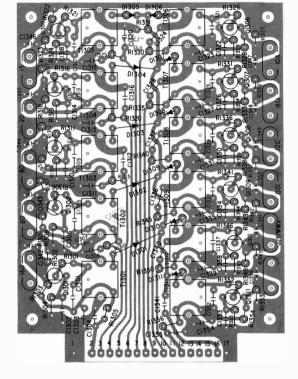
XTAL UNIT (PB-1711A)



	DC	DC VOLTAGES										
	E	1	(2	В							
	R	Т	R	Т	R	Т						
Q1301	0.7	0.7	6.9	6.9	1.3	1.3						
Q1302	0.6	0.6	6.7	6.7	1.2	1.2						
Q ₁₃₀₃	0.7	0.7	6.7	6.7	1.2	1.2						
Q ₁₃₀₄	0.7	0.7	6.8	6.8	1.3	1.3						
Q ₁₃₀₅	0.7	0.7	6.9	6.9	1.3	1.3						
Q 1306	0.7	0.7	7.0	7.0	1.3	1.3						
Q1307	0.7	0.7	7.0	7.0	1.3	1.3						
Q1308	0.7	0.7	7.0	7.0	1.3	1.3						
Q ₁₃₀₉	0.7	0.7	7.0	7.0	1.3	1.3						
Q1310	0.7	0.7	6.8	6.8	1.3	1.3						

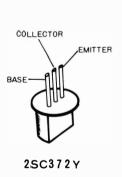
XTAL UNIT PARTS LAYOUT

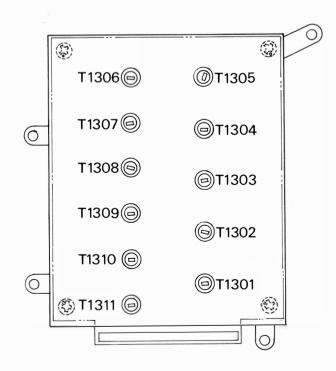




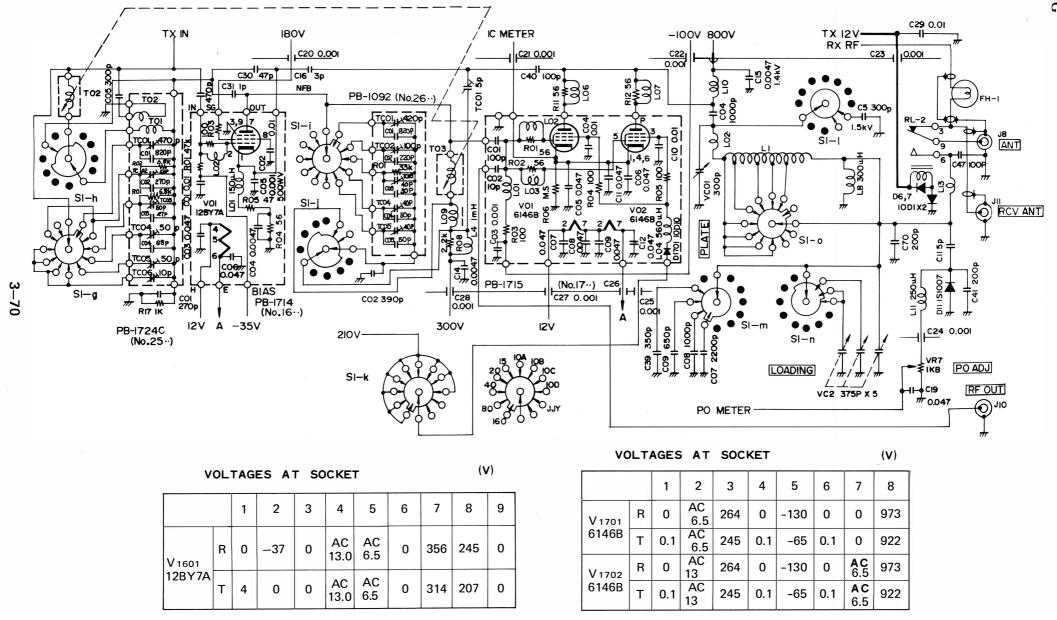
Viewed from component side

Viewed from solder side

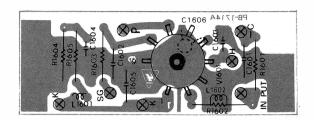


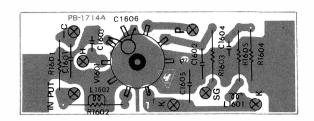


DRIVER/FINAL AMPLIFIER STAGES



DRIVER BOARD (PB-1714A)

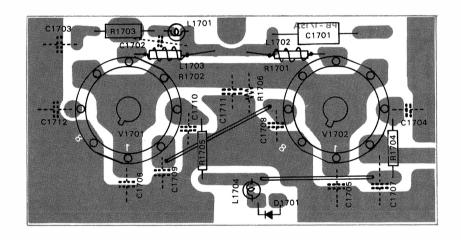




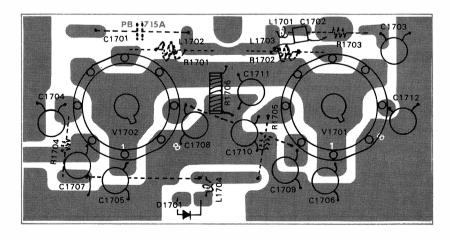
Viewed from component side

Viewed from solder side

FINAL BOARD (PB-1715A)

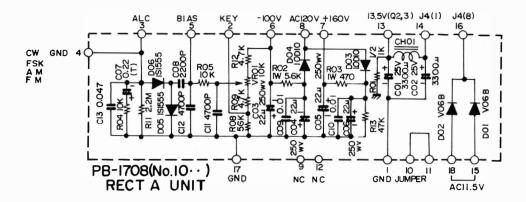


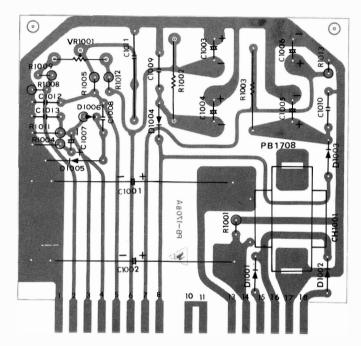
Viewed from component side

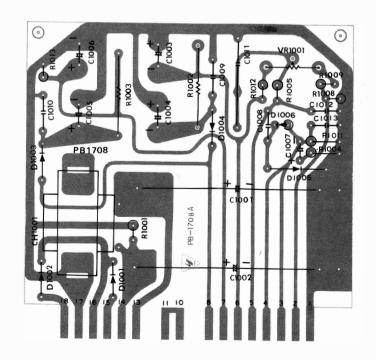


Viewed from solder side

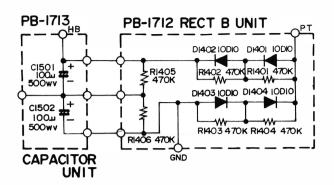
RECT A UNIT (PB-1708A)

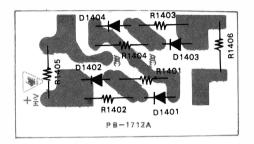




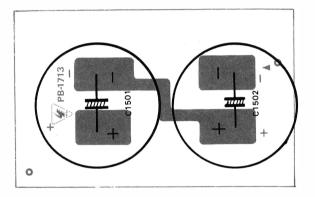


RECT B BOARD/CAPACITOR BOARD

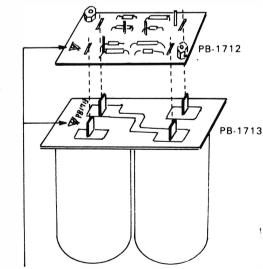




Viewed from component side

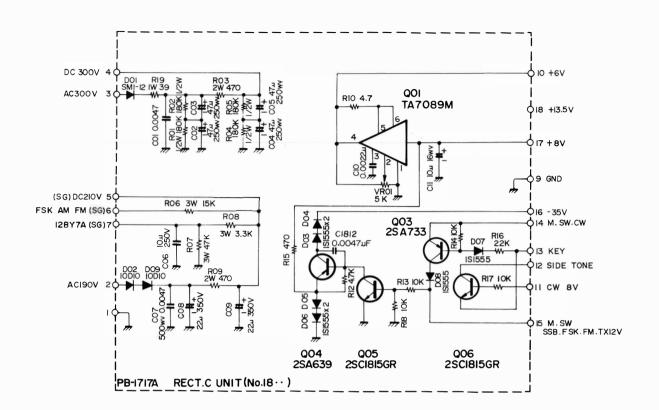


Viewed from solder side



Please align with YAESU gemblems together.

RECT C UNIT (PB-1717A)

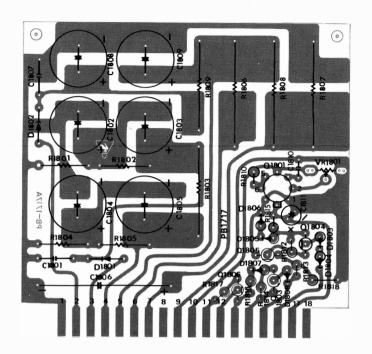


	DC	VOL	TAGES	5		(V)	
	E	Ē	С		Е	3	
	R	Т	R	Т	R	Т	
Q1803	0	0.1	-0.1	0	0	0.1	
Q1804	1.5	0.8	-88.8	0.6	1.5	0	SS
Q1805	0	0	1.5	0	0	0.7	
	7.6	11.6	7.8	7.8	8.2	8.2	CV
Q1806	0	0	0	0	0.7	0.7	K

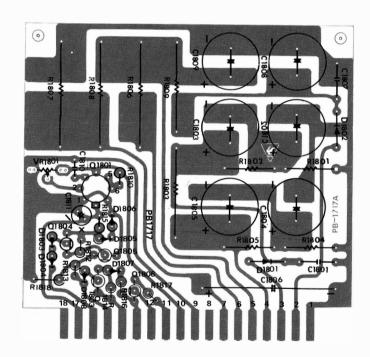
	22R
4	
	CW
	KEY DOWN

		1	2	3	4	5	6	7	8
Q1801	R	Е	3.0	7.8	6.0	6.5	6.5	0	8.2

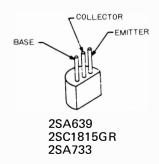
RECT C UNIT PARTS LAYOUT

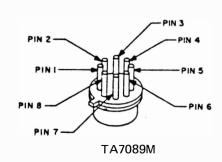


Viewed from component side



Viewed from solder side



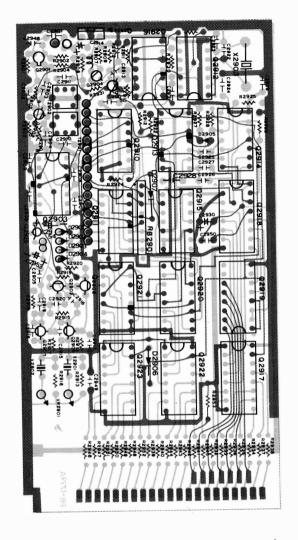


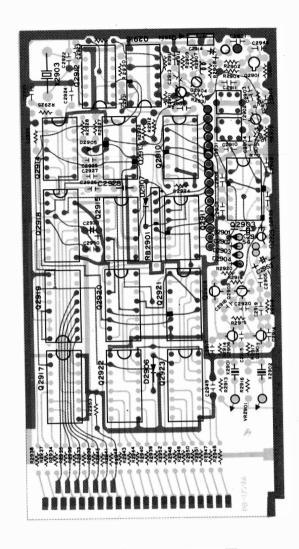
(1)

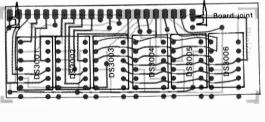
(1)

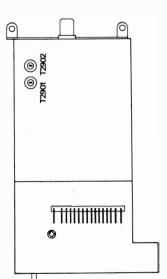
(K)

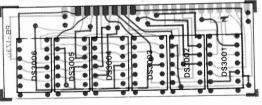
COUNTER/DISPLAY UNIT PARTS LAYOUT

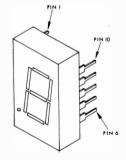








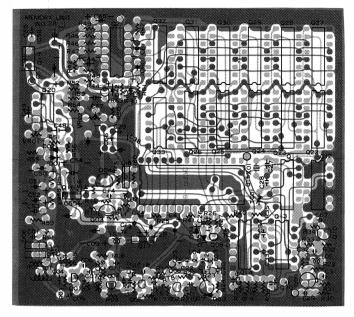




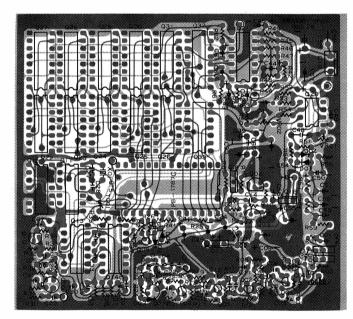
HP5082-7740

Other semi-conductor connections: see page 3 - 79.

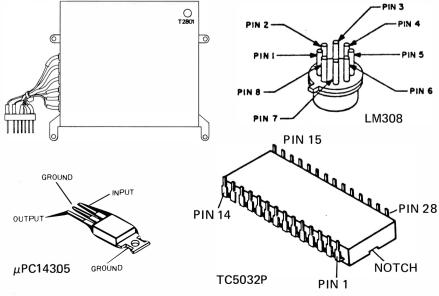
MEMORY UNIT PARTS LAYOUT

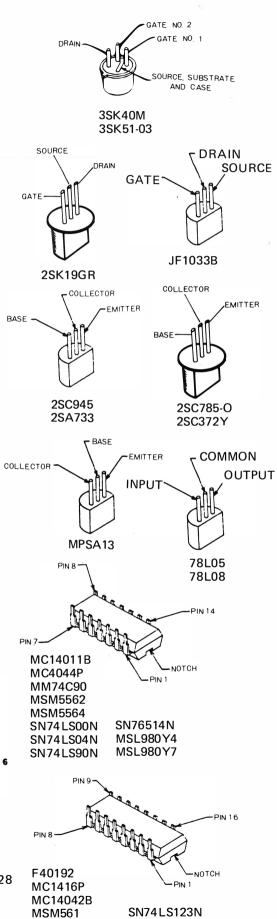


Viewed from component side



Viewed from component side



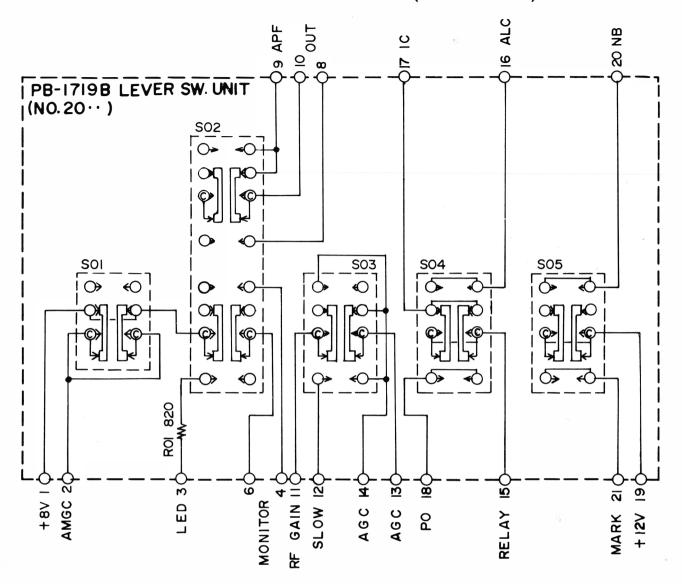


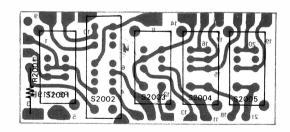
SN74LS192N

MSM5501

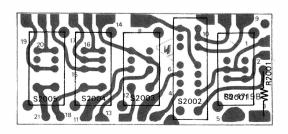
3-79

LEVER SWITCH BOARD (PB-1719B)



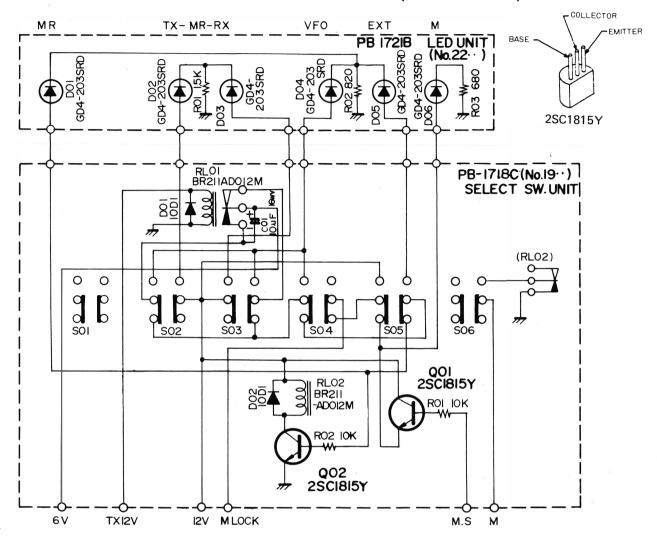


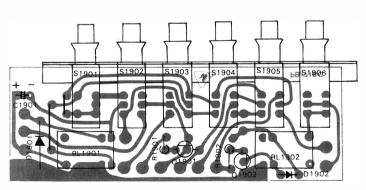
Viewed from component side



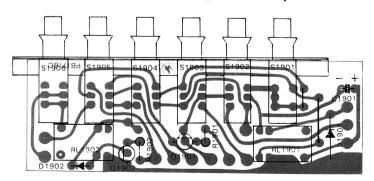
Viewed from solder side

LED A BOARD (PB-1721B) SELECT SWITCH BOARD (PB-1718C)





Viewed from component side



Viewed from solder side

	Е	С	В
0	3.2	12	3.9
Q1901	0	12	0
0	0	0.2	0.8
Q1902	0	12	0

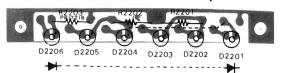
MR OFF

MR ON

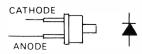
ON OFF

Viewed from component side

D2203 D2204 D2205 D2206

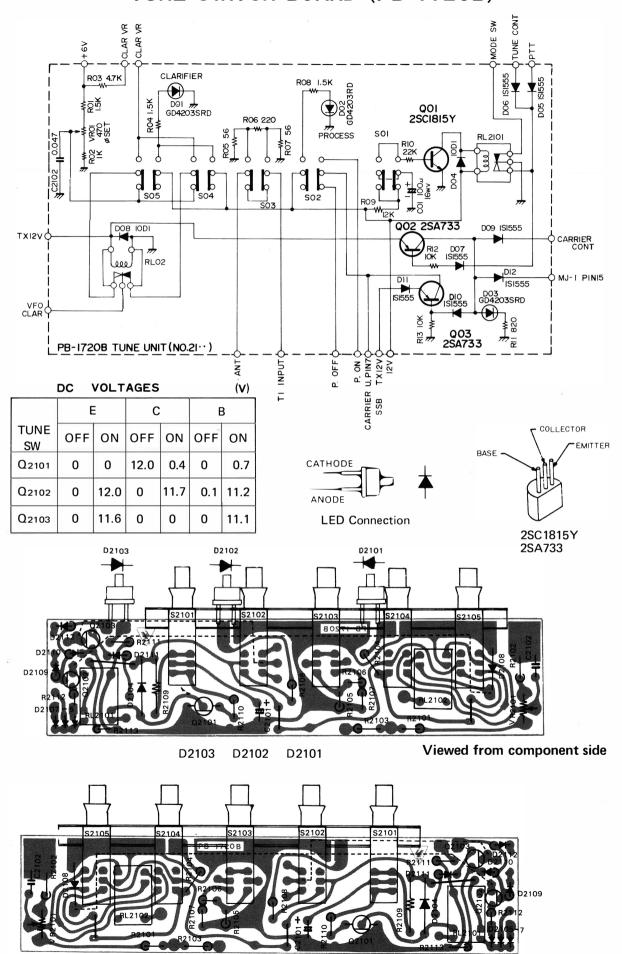


Viewed from solder side



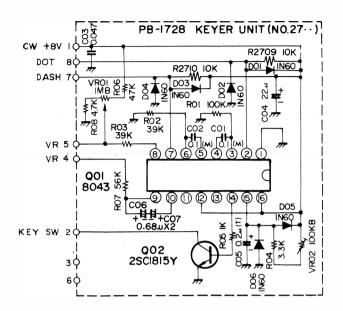
LED Connection

TUNE SWITCH BOARD (PB-1720B)

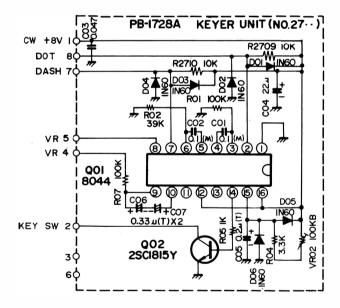


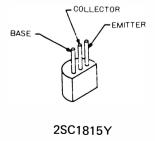
Viewed from solder side

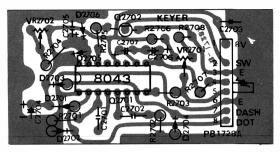
KEYER UNIT (PB-1728A)



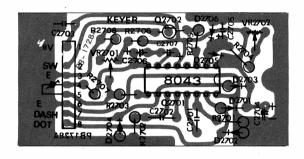
		DC	VOL:	TAGE	s												(V)	
		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
_	R	0	8.2	0	0	0	0	8.2	0	1.7	8.2	8.2	8.2	0	0	8.2	8.2	
Q ₂₇₀₁	Т	0	0	8.1	8.2	8.2	8.1	0	4-5	4-5	4-5	1-5	8.2	4-8	3-5	2-5	8.2	MODE C





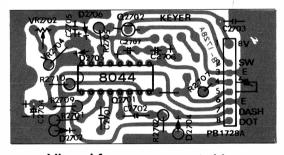


Viewed from component side

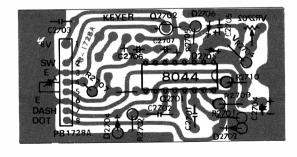


Viewed from solder side

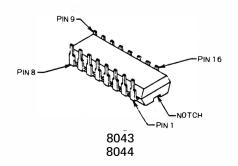
		DC	VOL	TAGE	S		(V)	
ì			E	(0		В	
		R	т	R	т	R	т	
	Q2702	0	0	7.7	-	0	0.4-0.9	MODE CW KEYERON



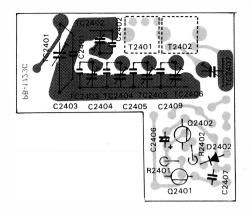
Viewed from component side

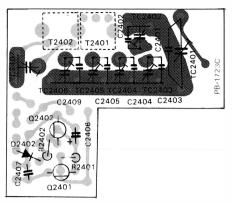


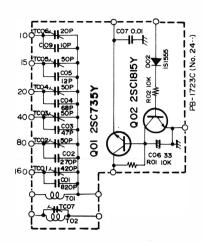
Viewed from solder side



TRIMMER A BOARD (PB-1723C)





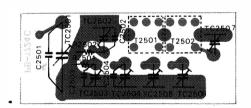


Viewed from trimmer side

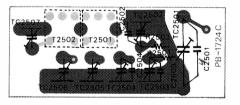
Viewed from component side

	DC	VOLT	AGES	5		(V)			
		LOCK		UNLOCK					
	Е	С	В	E	В				
Q2401	10.2	12	10.9	0	12	0			
Q2402	Ò	10.9	0.2	0	0	0.7			

TRIMMER B BOARD (PB-1724C)



Viewed from trimmer side

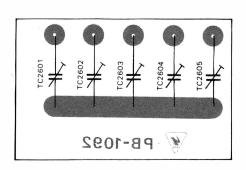


Viewed from component side

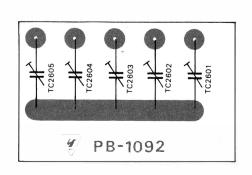
160 420P 1701 | 1820P | 180 0 TC02 1 150P | 180 0 TC02 1 150P | 180 0 TC03 1 150P | 180 0 TC04 1 150P | 15 0 TC04 1 150P | 15 0 TC05 1 150P | 16 0

PB-1724C

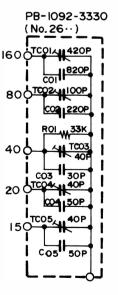
TRIMMER C BOARD (PB-1092-3330)



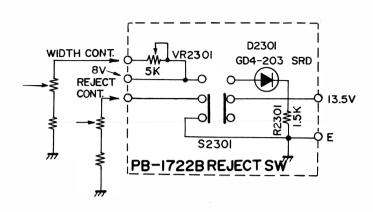
Viewed from trimmer side

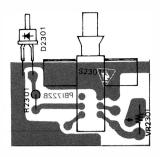


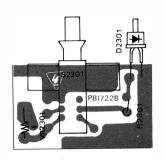
Viewed from component side



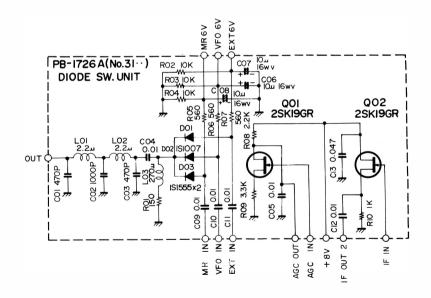
REJECT SWITCH BOARD

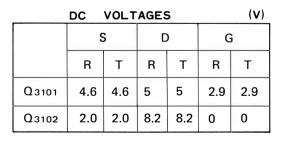


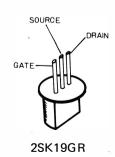


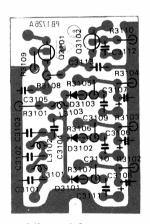


DIODE SWITCH BOARD (PB-1726A)

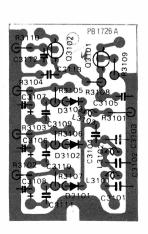








Viewed from component side



Viewed from solder side

SERVICING

PARTS LIST AND ORDERING FORMS

If you live in the United States, you may order parts from Yaesu Electronics Corporation. In other countries, you should order parts from the Yaesu agent for your country. In countries where Yaesu is not currently represented, you may order spare parts directly from Yaesu Musen Company, Ltd. in Tokyo.

When ordering, please specify the exact model number of the transceiver that the part is for. Many parts are standard, such as resistors and disc ceramic capacitors, but you should use particular care when ordering such items as electrolytics, tantalum capacitors, and the like.

The parts list to follow identifies the board that the parts belong to, as well as the circuit designation and part description. A "Part Number" is also specified, and this number will allow immediate identification by our parts department of the item you require. (**See note below.)

Shipment of parts from Yaesu USA is usually made by UPS, COD. Allow at least a week for the parts department to process your order. You will receive prompt notification that your order has been received, and if parts are back ordered, or if additional information is required, you will be so informed.

PARTS ORDER EXAMPLE

QUANTITY	TRANSCEIVER IDENTIFICATION	LOCATION	**PART NUMBER	CIRCUIT DESIGNATION
1	FT901DM	PB-1702B	23800513	Q ₁₀₁ 3SK 51-03

**Note: In earlier transceivers, no part numbering system was used in the manual. For this reason,

a part number for each component.

Country:

the nomenclature "3SK51" will suffice for the part number. All FT-901DM transceivers have

		(cut here)					
YAESU MUSEN COMPANY, LTD. — C.P.O. BOX 1500, TOKYO, JAPAN YAESU ELECTRONICS CORPORATION — 6851 Walthall Way, Paramount, CA90723 YAESU ELECTRONICS CORPORATION — 9812 Princeton-Glendale Rd., Cincinnati, OH 45246 ORDER BLANK							
QUANTITY	TRANSCEIVER IDENTIFICATION	LOCATION	PART NUMBER	CIRCUIT DESIGNATION			
	,						
	I authorize shipment via: ☐ Best Way ☐ UPS		☐ Parcel Post☐ Other				
Ship To:	Name:						
(Print or Type)							
	City:		State:	_ Zip:			

REPAIR PARTS

YAESU MUSEN COMPANY, LTD. - C.P.O. BOX 1500, TOKYO, JAPAN YAESU ELECTRONICS CORPORATION - 6851 Walthall Way, Paramount, CA90723

YAESU ELECTRONICS CORPORATION - 9812 Princeton-Glendale Rd., Cincinnati, OH 45246

ORDER BLANK

QUANTITY	TRANSCEIVER IDENTIFICATION	LOCATION	PART NUMBER	CIRCUIT DESIGNATION
*				
				1
•				
	I authorize shipment	via: Best Way UPS	□ Parcel Post □ Other	
Ship To:	Name:			
(Print or Type)	Address:			
	City: Country:	·	State:	_ Zip:
YAESU ELECTR	ONICS CORPORATION	N – 9812 Princeto ORDER BLANK	n-Glendale Rd., Cinci	nnati, OH 45246
QUANTITY	TRANSCEIVER IDENTIFICATION	LOCATION	PART NUMBER	CIRCUIT DESIGNATION
-		-		
	I authorize shipment	 via: □ Best Way □ UPS	☐ Parcel Post☐ Other	
		_ 515	- Other	
Shin To:	Name			
Ship To: (Print or Type)	Name: Address:			
-	Name: Address: City: Country:		State:	Zip:

REPAIR PARTS

	MAI	N CHASSIS	52~56,	30820473	Ceramic disc 50WV	0.047µF
Symbol No.	Part No.	Description	58,62~68,	30020473	Ceranic disc 50WV	0.047μι
		ic	71~73,75,81,			
Q1, 2	25000116	μPC 14308	82,88,91,96.			
Q3	25000068	μPC 14312	98, 99, 0101,			
			0102			
			C35, 36	30830472		0.0047μI ²
			C77,79,80,83,0106			0.01µF
		DIODE	C40, 47	30840101		100PF
D10, 16, 18,	21010070	Germanium 1S1007	C14, 15	30240472		0.0047μF
19			C12, 13, 44,	30240103	" " "	0.01μF
D1~3, 9,	21015550	Silicon 1S1555	78, 92			
11~15, 17	ļ	·	Č41	33821201		200PF
D5~7	21090011	" 10D1	C31	33824020	,	1PF 5PF
			C11	33834050		10PF
			C87	33834100		
			C1, 42	33834271		270PF
		RESISTOR	C39	33834351		350PF 470PF
R5	41143821	Carbon film 1/4W TJ 820Ω	C3	33834471		
	40143102	" " " VJ 1 kΩ	C9	33834651		650PF
R6	41143332	" " " TJ 3.3kΩ	C8	33834102		1000PF
R19	41143472	" " " 4.7kΩ	C2	33844391		390PF
R2	40143273	" " VJ 27kΩ	C7	33844222		2200PF 100PF
R1	41143104	" " TJ 100kΩ	C70	33147101	Modified filled	
R4, 16	42124100	" composition 1/2W GK 10Ω	C70	33147201		200PF 1000PF
R11, 12	42124560	" " 1W " 56Ω	C4	33197102	OR V	$\frac{1000FF}{0.047\mu F}$
(L6, 7)	1212122		C84	36835473	1.1) Idi	$\frac{0.047 \mu \text{F}}{0.001 \mu \text{F}}$
R34	42104222	" " 2.2kΩ	C20~28, 51	32830102	T cou till a coom t	0.001μF 1μF
R3, 18, 30	42124101	" " 1/2W GK 100Ω	0(1	34220105	Electrolytic 16WV	10μΕ
R22	42124221	22011	C61	34220106	" "	33μF
R20	42124561	00000	C57	34220336		100μF
R7, 9, 17	42124102	" " " 1kΩ " " " 2.2kΩ	C34, 43	35220107 34220227	" "	220µF
R8, 36	42124222	$^{\prime\prime}$ $^{\prime\prime}$ $^{\prime\prime}$ $^{\prime\prime}$ $^{\prime\prime}$ $^{\prime\prime}$ 2.7k Ω	C34, 43			470μF
R33	42124272	" " " 10ks.		34320477	25111	- 170μ1
R14	42124123	" " 12kΩ			-	
R13, 29	42124223	" " " 22kΩ			VARIABLE CAPACITOR	
R26	43204220	Metallic film 2W 22Ω	VC1	39000058	RT-18-300VC	*
R10	43304240	" " 3W · 24Ω	VC2	39000061	C134E125	
		-				
					TRIMMER CAPACITOR	
			TC1	39000072	120C 10x2 1.5KV 5	PF
		POTENTIOMETER	TC2	39000016		00PF
VR1	49800085	VM11A5M 1112: 10kΩA				
VR2	49800086	DM11A5M 1222 10kΩB/500kΩC				
VR3, 6	49800087	DM10A $5k\Omega B/5k\Omega B$				
VR4	49800088	GM70A 50kΩB/50kΩB			INDUCTOR	
VR5	49800089	DM70A 5kΩB/5kΩA	L1	55003214	#2203041	3
VR7	49800091	VM10A 1kΩB	L2	55003215	#2203054	4
VR8	49800092	DM10E $5k\Omega B/5k\Omega B$	L4	53020001	Microindicator FL-5H 1	mH
			L11, 12, 14	53010003	" 2	50μH
				53040001	250µH #220100	
			L8	54000040	300µH #220064	
		CAPACITOR	L6, 7	55003216	#220308	
C69	31820200	Ceramic disc 50WV 20PF CH	(R11, R12)			
C30	31820470	" " " 47PF "	L9	55000490	#220009	
C5	31249301	" " 1.5KV 300PF	L10	54000050	500µH #220065	
C16	31249030	" " 3KV 3PF	L13		#220349	
C0103	30320104	" " 25WV 0.1μF				
C29,59,60,89,90	4	" " 50WV 0.01μF				
0104, 0105,0107					TRANSFORMER	
C17,18.19.37,	30820473	" " 0.047μF	T1	55000450	#220073	
(17,10.17.57,			T2	55000460	#220011	

T3	55000500	#220074	J9	68110001	SA602B00
		METER			MULTI JACK
M1 (with	75000350	500μA #250007	MJ1~8	68180003	121S-18B-105A
R 1706,PL3,4)			МЈ9	68220003	121S-22B-105A
			MJ10	68100009	121S-10B-105A
1 1			MJ11, 12	68200002	220D-20B-205A
		SPEAKER			
SP1	75000018	SA-77K-Y 4Ω 3W			
					COOLING FAN
			FAN1	75000004	2SB10A
		POWER TRANSFORMER			
PT1	52000051	#230013A			
			,		FUSE
			F1	73000004	5A (100~117V)
				73000003	3A (200~234V)
		RELAY			
RL1	70000013	AE 3244			
RL2	70000002	MX2P 12V			
		*			FUSE HOLDER
			FH1, 3	69030007	F3265
		DEL AV COOKET	FH2	69030001	SN1001 #2
DC1	69000006	AE3840			
RS1 RS2	69000003	PX08			
K32	09000003	1 700			PILOT LAMP
			PL1	14000027	BF 311-04071A 14V 0.12A
			PL2	14000028	BF 311-03011A 8V 0.15A
		SWITCH	PL3, 4 (M1)		Meter lamp 8V 0.055A
S1	61000450	RS-14-14-11			*
S2	61000460	GS-4-8-6A			
S3	64000007	WD9216	PB-1390	60413900	LED B BOARD
S4	64000006	WD92231	D8	21090140	LED GD4-203-SRD
		DI LIO			
P1 (with Wire)	68080007	PLUG 5047-08 #240032A			
P2 (with Wire)	68070028	5047-08 #240052B		R	FUNIT
P3 (with Wire)	68170001	5047-17 #240034A	Symbol No.	Part No.	Description
P8 (with Wire	68160002	5047-16 #240035D	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	017022AZ	RF unit with Components
P4, 5, 6	67020007	SQ4052	PB-1702B	60417022	P.C. Board
P10	67020014	SQ4152			
P7	67040002	SI5908 4P			
P9	67020009	SI7502 2P		1	
				-	FET & TRANSISTOR
			Q102~105	22800195	FET 2SK19GR
			Q106, 107	23800402	MOS FET 3SK40L
T.1	(0000001	CONNECTOR	Q101 Q108	23800513	MOS FET 3SK51-03
J1	68030001	SG-7701	Q108	22390000	Transistor 2N4427
J2 J3	68040003 68030002	FM-144-S SG-7814		+	
J10, 11	68030002	CN-7017		+	DIODE
J10, 11 J12~1'8	80040622	Jack Ass'y Board	D104	21010070	Germanium 1S1007
J19	68020012	SG-8050	D101~103	21015550	Silicon 1S1555
J4	67120009	QS-A-DB12ML	2101 103	+	
J5	67060006	D6-701B00			
J6	68070027	D7-701B00			
J8	68000011	M-BR-06B (D)			RESISTOR
J20	67090003	AC9-PF	R116, 131,	40143100	Carbon film 1/4W VJ 10Ω
J7	68020010	SI-7501-I	132	1	

		,			
R122	40143470	Carbon film 1/4W VJ 47Ω			
R124	40143560	" " " 56Ω			
R 106, 107,	40143101	" " " 100Ω			
108, 113,					
114, 121					
R117	40143151	" " " 150Ω			
R123	40143181	" " " 180Ω			
R 125, 126	40143271	" " " 270Ω			
R112	40143331	" " " 330Ω			NB UNIT
R111	41143331	" " TJ 330Ω	Symbol No.	Part No.	Description
R 136	40143471	" " " VJ 470Ω		019940AZ	NB unit with components
R105,115,118	40143102	" "" " 1kΩ	PB-1994	60419940	P.C. Board
R119	40143222	" " " 2.2kΩ			
R 102, 129	40143272	" " " 2.7kΩ			
R104, 109	40143562	" " " 5.6kΩ			
R133	40143103	" " " 10kΩ			IC, FET & TRANSISTOR
R135	40143223	" " " 22kΩ	Q 206	25000105	IC TA7060P
R103	40143473	" " " 47kΩ	Q 201,	22800195	FET 2SK19GR
R130	40143563	" " " 56kΩ	Q 209, 210,212	23800401	FET 3SK40M
R134	40143124	" " " 120kΩ	Q212	23800513	FET 3SK51-03
R101	42144225	" composition 1/4W GK 2.2MΩ	Q 203	23800595	FET 3SK59GR
			Q202	22303724	Transistor 2SC372Y
			Q 204,205,207,	22318154	2SC1815Y
			211	2231010.	25010191
			211		DIODE
		CAPACITOR	D202, 203	2109 07	Germanium 1N270
C102, 106	31829101	Ceramic disc 50WV 100PF SL	D202, 203		Silicon 1S1555
C102, 100	30821103	" " " 0.01µF YY	D201, 203, 208	21090034	Zener WZ090
109,112,119,	30821103	0.01μΓ 11	D204	21090034	Zener WZ110
120,123,124		1	D 204	21090030	Zeller WZ110
	30820103	" " " 0.01μF			
C105, 107,	30820103	$^{\prime\prime}$ $^{\prime\prime}$ $^{\prime\prime}$ 0.01 μ F			
108,110,111,		1			0000000
113,114,116			W201	71000000	CRYSTAL W210042
~118, 122	20020472	" " " 0.047µF	X201	71800088	HC-18/U 8532.5kHz #210043
C101, 121	30820473	0.017 μ1			
C125	33821030	Dipped mica " 3PF	,		+
C127 C115	33821040	111			
C113					ODVOTAL ELLTED
0106	33820241		V.DOO.	71000029	CRYSTAL FILTER
C126	34220106	Electrolytic 16WV TT 10μF	XF201	. 71000028	CRYSTAL FILTER XF-8.9HP #210089
C126			XF201	71000028	<u> </u>
C126			XF201	71000028	XF-8.9HP #210089
C126					XF-8.9HP #210089 RESISTOR
C126			R254	40143560	XF-8.9HP #210089 RESISTOR Carbon film 1/4W VJ 56Ω
C126		Electrolytic 16WV TT 10μF	R254 R204, 209,		XF-8.9HP #210089 RESISTOR
	34220106	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR	R254 R204, 209, 217,218,221,	40143560	XF-8.9HP #210089 RESISTOR Carbon film 1/4W VJ 56Ω
TC101		Electrolytic 16WV TT 10μF	R254 R204, 209, 217,218,221, 225,226,238,	40143560	XF-8.9HP #210089 RESISTOR Carbon film 1/4W VJ 56Ω
	34220106	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244	40143560 40143101	XF-8.9HP #210089 RESISTOR Carbon film 1/4W VJ 56Ω " " " 100Ω
	34220106	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252	40143560 40143101 41143101	XF-8.9HP #210089 RESISTOR Carbon film 1/4W VJ 56Ω " " " 100Ω
	34220106	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241	40143560 40143101 41143101 40143151	XF-8.9HP
TC101	34220106 39000006	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF INDUCTOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260	40143560 40143101 41143101 40143151 40143331	XF-8.9HP
	34220106	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251	40143560 40143101 41143101 40143151 40143331 40143471	XF-8.9HP
TC101	34220106 39000006	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF INDUCTOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210	40143560 40143101 41143101 40143151 40143331 40143471 40143561	XF-8.9HP
TC101	34220106 39000006	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF INDUCTOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212,	40143560 40143101 41143101 40143151 40143331 40143471	XF-8.9HP
TC101	34220106 39000006	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10×40 10PF INDUCTOR	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102	RESISTOR
TC101 L101, 102	34220106 39000006	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212,	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143152	RESISTOR
TC101	34220106 39000006	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102	RESISTOR
TC101 L101, 102	34220106 39000006 53020027	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143152	RESISTOR
TC101 L101, 102 T101, 103	34220106 39000006 53020027	Electrolytic 16WV TT 10µF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270µH TRANSFORMER #220209	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143152 40143152	XF-8.9HP
TC101 L101, 102 T101, 103 T102, 104	39000006 53020027 55003174 55003175	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250 R201, 259	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143152 40143152 40143332	RESISTOR
TC101 L101, 102 T101, 103 T102, 104	39000006 53020027 55003174 55003175	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250 R201, 259 R224	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143122 40143322 40143682 40143822	RESISTOR
TC101 L101, 102 T101, 103 T102, 104	39000006 53020027 55003174 55003175	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250 R201, 259 R224 R205	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143122 40143322 40143682 40143822	RESISTOR
TC101 L101, 102 T101, 103 T102, 104	39000006 53020027 55003174 55003175	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250 R201, 259 R224 R205 R227, 248, 249	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143122 40143322 40143682 40143822 40143103	RESISTOR
TC101 L101, 102 T101, 103 T102, 104	39000006 53020027 55003174 55003175	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221 #220210	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R201, 259 R224 R205 R227, 248, 249 R258 R207	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143122 40143322 40143822 40143822 40143103 40143123	RESISTOR
TC101 L101, 102 T101, 103 T102, 104 T105	39000006 39000006 53020027 55003174 55003175 55003176	Electrolytic 16WV TT 10μF TRIMMER CAPACITOR ECV1ZW 10x40 10PF INDUCTOR Micro inductor FL-5H 270μH TRANSFORMER #220209 #220221 #220210	R254 R204, 209, 217,218,221, 225,226,238, 243,244 R252 R241 R216, 237, 260 R203, 208, 251 R210 R211, 212, 215,222,228 R206 R214, 250 R201, 259 R224 R205 R227, 248, 249 R258	40143560 40143101 41143101 40143151 40143331 40143471 40143561 40143102 40143122 40143332 40143682 40143822 40143103 40143123 40143153	RESISTOR

					
R236, 240,	40143104	Carbon film 1/4W VJ 100kΩ			
245, 247,					
255, 256					DIODE
R239	40143154	" " " 150kΩ	D301.303~	21010070	Germanium 1S1007
R235	40143224	" " " 220kΩ	309		
R220	40143394	" " " 390kΩ	D302, 310,	21015550	Silicon 1S1555
K220	40143374	370832	+		
			D312	21090036	Zener WZ110
	A-11-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-		-		
					CRYSTAL FILTER
		POTENTIOMETER	XF301	71200017	8.9M-20A #210047
VR201	49912102	V10K-8-1-2 1kΩB	XF304	71000023	XF-8.9HS #210086
VR 203	49912202	" 2kΩB	XF303	71000029	XF-8.9GA #210087 (OPTION
VR202	49912502	" 5kΩB	XF302	71000021	XF-8.9HC '#210088 (OPTION
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		111.002	71000021	111 SIJITE #210000 (011101
		1		*	<u> </u>
					RESISTOR
				10110000	
		CAPACITOR	R323	40143220	Carbon film 1/4W VJ 22Ω
C201, 206,	31829101	Ceramic disc 50WV 100PF SL	R 301, 302,	40143101	" " " 100Ω
216,218,225,			309,		
228,238			R311, 316, 317	41143101	" " TJ 100Ω
C237	31829201	" " " 200PF SL	R304, 305	40143331	" " " VJ 330Ω
C235	31829221	" " 220PF SL	R322, 326,	40143561	" " " 560Ω
C244	31829561	" " 560PF SL	R308, 318,	40143102	" " " 1kΩ
C202, 203,	30820103	" " " 0.01µF	319, 325		
205, 208~213,	2020103	υ.υιμι	R306	40143222	" " " 2.2kΩ
203, 208~213, 217, 219~224,		2		40143272	" " " 2.7kΩ
1			R327		
230,231,233,			R310, 312~	40143332	" " " 3.3kΩ
234,236,240			315		
~243, 245.			R303	40143562	" " " 5.6kΩ
246			R324	40143103	" " " 10kΩ
C215	30820473	" " " 0.047μF	R307	40143104	" " " 100kΩ
C232	33824102	Dipped mica 50WV 0.001µF	R320	42124560	" composition 1/2W GK 565
C214	34220226	Electrolytic 16WV TW 22μF	†		
		Districtly the 10 to 1 to 22 to	<u> </u>		
		INDUCTOR	+		
L202	53020013	Micro inductor 150µH	1	,	CAPACITOR
1202	33020013	Micro inductor 130µm	C304	31829101	Ceramic Disc 50WV 100PF SL
			C302, 305, 324		" " " 0.01µF YY
		TRANSFORMER			
		TRANSFORMER	C301, 306,	30820103	" " $0.01\mu\text{F}$
T206, 207	54140970	R12-4097 #220101	307, 308, 311,		
T201, 202,	54141700	R12-4170 #220140	312, 315, 316,		
204, 205			321		
T203	55003177	R12-1078 #220221	C309, 310,	30820473	" " " 0.047μF
			313,314,317,		
			318,319,323,		
	91100008	Wrapping Terminal C	318,319,323,		
	71100000	"Tapping Tellillial C		21920 101	" " " 100pF NPO
			C325	31820-101	
			C303	34220106	Electrolytic 16WV TW 10μF
		· ·			
	FI	LTER UNIT			
Symbol No.	Part No.	Description			INDUCTOR
-	019950AZ	Filter unit with components	L312		Micro inductor FL5H 33µH
PB-1995	60419950	P.C. Board	L303~308,	53020013	Micro inductor FL5H 150µH
1 D-1773	00417730	1.C. DUAIU	→	33020013	MICIO INDUCTOF FLOH 150µH
		-	311	52012555	
			L302, 310	53010003	" " 250μΗ
		FET & TRANSISTOR			
Q301, 302,	22800195	FET 2SK19GR			
					TRANSFORMER
304, 305					
304, 305 Q303	22303730	Transistor 2SC373	T301~303	54141710	R12-4171 #220141

			R438, 439	40143153	Carbon film 1/4W VJ	15kΩ
			R422, 428, 437	40143473	" " " "	47kΩ
			R436	40143563	" " " "	56kΩ
			R441	40143104	" " " "	100kΩ
		IF UNIT	R452	40143184	" " " "	180kΩ
Symbol No.	Part No.	Description	R446	40143334	" " " "	330kΩ
	017043AZ	IF unit with components	R426,449	40143105	" " " "	1MΩ
PB-1704C	60417043	P.C. Board		42144105	" composition 1/4W	
					POTENTIOMETER	
			VR402	49912103	V10K-8-1-2	10kΩB
		FET & TRANSISTOR	VR401	49912504	"	500kΩB
Q408	22800195	FET 2SK19GR				
Q401~404	23800513	" 3SK51-03			CAPACITOR	
Q407	22105641	Transistor 2SA564A	C401, 423, 446,	31829101	Ceramic disc 50WV	100PF SL
Q409, 411	22303730	" 2SC373	450	31023101	Columno disc 50 W V	TOOTT BE
Q405	22305351	" 2SC535A	C437, 438	31827820	" " "	82PF UJ
Q412	22307354	" 2SC735Y	C436	31827101	" " "	100PF UJ
Q406, 410	22318154	" 2SC1815Y	- i	31820330	" " "	33PF NPO
2100, 110	22310131	25010131	C448	31820470	, , , , , , , , , , , , , , , , , , ,	47PF NPC
		1	C448	30820103	" " "	0.01µF YY
			412, 413, 417,	30020103		υ.υιμΓ ΙΥ
-		DIODE	412, 413, 417, 418, 421, 425,			
D407	21090115	Germanium 1N60	427, 428			
D401, 408, 411,	21090113	" 1N270	C403, 410, 411,	30820102	" " "	0.001µF
412	2107010/	11/2/0	414, 415, 419,	30020102	, , , , , , , , , , , , , , , , , , , ,	υ.υυιμΓ
D402~405	21010070	" 1S1007	424	Į.		
D409, 413	21015550	Silicon	C430	30820222	" " "	0.002µF
D406, 410	21013330		C430 C420, 422, 426,	30820222	" " "	$0.002 \mu F$ $0.01 \mu F$
D400, 410	21022090	Varactor 1S2209		30820103	" " "	0.01μ F
			434, 439, 440,			
			443, 451	1 20020152		0.015.5
		ODVOTAL	C404, 408, 409,	30820473	" " "	$0.047\mu\mathrm{F}$
7/102		CRYSTAL	416, 432, 433,			
X402	71800111	HC-18/U 19.7475MHz #210043-2				
X401	71800091	" 8987.5MHz #210043-1				
			C444	36825223	Mylar 50WV	0.022μF
			C442	36226225	Tantalum 16WV	2.2μF
			C431	34220105	Electrolytic 16WV TW	•
		CRYSTAL FILTER	C445, 449	34220106	" " "	10μF
XF402	71200017	8.9M20A #210047				
XF401	71000024	XF-10GS #210090				
		*		1		
	101:2::	RESISTOR		ļ.,,	INDUCTOR	
R406, 409, 420,	40143101	Carbon film 1/4W V J 100Ω		53020020	Micro inductor FL5H	15μH
433, 455			L401, 402, 405	53020013	n n n	150µH
R413, 414, 458	40143181	" " " " 180Ω		53020001	" " .	l mH
R442	40143221	" " " 220Ω				
R440	40143331	" " " 330Ω	,	55003178	VXO coil 5.2μH	#220145
		" " " 560Ω				
R443	40143561					
R443 R412	40143681	" " " " 680Ω				
R443 R412 R402, 405, 407,						
R443 R412 R402, 405, 407, 408, 415, 416,	40143681	" " " " 680Ω			TRANSFORMER	
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454	40143681	" " " " 680Ω	T401	55003185	3005	#220187
R443 R412 R402, 405, 407, 408. 415, 416, 418, 444, 451, 454	40143681	" " " " 680Ω	T401	55003185 54141700		#220187 #220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445	40143681 40143102	" " " " 680Ω " " " " 1kΩ	T401 T402, 403		3005	
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432	40143681 40143102 40143152	" " " " 680Ω " " " " 1kΩ	T401 2 T402, 403 2 T404	54141700	3005 R12-4170	#220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423	40143681 40143102 40143152 40143182	" " " " 680Ω " " " " 1kΩ " " 1.5kΩ " " " " 1.8kΩ	T401 2 T402, 403 2 T404	54141700	3005 R12-4170	#220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423	401431681 40143102 40143152 40143182 40143332 40143472	" " " " 1.5kΩ " " " " 1.8kΩ " " " " 4.7kΩ	T401 2 T402, 403 2 T404	54141700	3005 R12-4170	#220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423 R410, 411	401431681 40143102 40143152 40143182 40143332	" " " " 1.5kΩ " " " " 1.5kΩ " " " " 3.3kΩ " " " " 4.7kΩ	T401 2 T402, 403 2 T404	54141700	3005 R12-4170	#220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423 R410, 411 R435 R419, 450	401431681 40143102 40143152 40143182 40143332 40143472 40143562	" " " " 1.5kΩ " " " " 1.8kΩ " " " " 4.7kΩ " " " " 5.6kΩ " " " " 6.8kΩ	T401 2 T402, 403 2 T404	54141700	3005 R12-4170 R12-4171	#220140
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423 R410, 411 R435 R419, 450 R403, 404, 417,	40143681 40143102 40143152 40143182 40143332 40143472 40143562 40143682	" " " " 1.5kΩ " " " " 1.8kΩ " " " " 4.7kΩ " " " " 5.6kΩ " " " " 6.8kΩ	T401 2 T402, 403 2 T404	54141700 54141710	3005 R12-4170 R12-4171	#220140 #220141
R443 R412 R402, 405, 407, 408, 415, 416, 418, 444, 451, 454 R434, 445 R425, 432 R423 R410, 411 R435 R419, 450	40143681 40143102 40143152 40143182 40143332 40143472 40143562 40143682	" " " " 1.5kΩ " " " " 1.8kΩ " " " " 4.7kΩ " " " " 5.6kΩ " " " " 6.8kΩ	T401 2 T402, 403 2 T404	54141700 54141710	3005 R12-4170 R12-4171	#220140 #220141

				C532, 533	34220105	Electrolytic 16WV TW 1µF
		,		C504	34220475	" " 4.7μF
	-	AF UNIT		C528	35220106	" " " 10μF
Symbol No.	Part No.	Description		C505, 508, 513	35220226	" " " 22μF
	017051AZ	AF unit with componen	ts	C525	34120336	" 10WV " 33μF
PB-1705A	60417051	P.C. Board		C517	34120476	" " 47μF
				C515	34120107	" " 100μF
	*			C518	34120477	" " 470μF
		IC & TRANSISTOR				
Q503	25000133	IC	TA7205AP			
Q504	25000125	IC	MC3403P		-	
Q506	25000128	IC	78L08			
Q501, 502, 505,	22310005	Transistor	2SC1000GR			HEAT SINK
507					80042802	(TA-7205)
						,
		RESISTOR				
R523, 536	40143101	Carbon film 1/4W VJ	100Ω			
R505	40143151	" " " "	150Ω			ARKER UNIT
R516	40143561	" " " "	560Ω	Symbol No.	Part No.	Description
R 506	40143681	" " " "	680Ω		018460AZ	VOX/Marker unit with componer
R507	40143102	" " " "	1kΩ	PB-1846	40618460	P.C. Board (=PB-1685-3330)
R512	40143222	" " " "	2.2kΩ			
R504, 539	40143332	и. и и и	3.3kΩ			
R513, 514, 537	40143472	" " " "	4.7kΩ			
R510, 511	40143822	" " " "	8.2kΩ			IC & TRANSISTOR
R538, 540, 541,	40143103	" " " "	$10k\Omega$	Q604	25000114	IC MC14011
543				Q612	25000177	IC 4024PC
R503	40143153	" " " "	15kΩ	Q603	22105641	Transistor 2SA564A
R530, 545	40143333	" " " "	33kΩ	Q602, 608~610,	22303730	Transistor 2SC373
R508	40143393	" " " "	39kΩ	615		
R502, 509, 515	40413473	" " " "	47kΩ	Q607	22307354	Transistor 2SC735Y
R 534	40143823	" " " "	82kΩ	Q601, 605, 606,	22318154	Transistor 2SC1815
R517, 520, 522,	40143104	" " " "	100kΩ	611, 613, 614		
525, 526, 528,						
535						
R519, 524, 527,	40143124	" " "	120kΩ			
						DIODE
R518, 521, 529	40143224	" " "	220kΩ	D601, 605	21090115	Germanium 1N60
				D603, 607~609	21015550	Silicon 1S1555
		1		D602, 606	21090034	Zener WZ090
					ļ	
TVD CO1	400000000	POTENTIOMETER	1MoD 2	}	 	LODVOTAL .
VR501	49800078	GM-70R	1MΩBx2	V(01	71600022	CRYSTAL #210026
				X601	71600032	HC-6W 3200kHz #210026
		CAPACITOR				
C535;	32820102		0.001µF		-	PECICTOR
C501, 534	30820102	1	0.001µF	D616	40142101	RESISTOR Carbon film 1/4W VJ 100
C501, 334	30820103	1	$\frac{0.01 \mu F}{0.047 \mu F}$	R616 R643	40143101	" " " " 220
C521 C512, 519			51PF SL	R620, 628	40143221	" " " 220
C512, 519 C514	31829510		390PF SL	R620, 628 R605, 614, 625,	40143471	" " " 4/0
C314	33824391 36825102		0.001µF	4	40143102	" " " " IK3.
C507	36825102		$\frac{0.001 \mu F}{0.0047 \mu F}$	626, 636, 642, 646~650		
C507	1		$\frac{0.0047 \mu F}{0.0068 \mu F}$		40142222	" " " 2.21
C523, 524 C506	36825682 36825103		$\frac{0.0068 \mu F}{0.01 \mu F}$	R615, 630, 640 R637	40143222 40143392	" " " 3.91
C516,	36825103		$\frac{0.01 \mu F}{0.047 \mu F}$		40143392	
C520, 530, 531,	36825104		0.047μF 0.1μF	R604, 606, 632~634	40143472	" " " 4.71
536	30023104		υ. 1μ1	R627	40143562	5.61
C502, 503, 509,	34220105	Electrolytic 16WV TW	1µF	R627 R601, 602, 607,	40143362	" " " " 3.61 " " " 10k
511, 522, 529,	1	Liectiony iie 10 w v 1 w	1μ1	608, 612, 621,	70143103	10k
311, 322, 329,	L	1		1 000, 012, 621,	L	

R623, 641, 652,	40143103	Carbon film 1/4W VJ	10kΩ		CAR	RIER UNIT	
653				Symbol No.	Part No.	Descripti	on
R603, 619, 629,	40143223	" " " "	22kΩ		017061AZ	Carrier unit with con	nponents
635, 639, 644,				PB-1706A	60417061	P.C. Board	
645				1			
R624	40143393	" " " "	39kΩ				
R 638	40143473	" " " "	47kΩ				
R613	40143563	, , , , , , , , , , , , , , , , , , , ,	56kΩ			IC, FET & TRANSIST	
R618, 631	140143683.	" " " "	68kΩ	Q705, 706	25000134	IC	TA7063P
R622	40143104	" " " "	100kΩ	Q708	25000114	IC	MC14011B
R609, 610	40143105	" " " "	1MΩ	Q702	22800195	FET	2SK19GR
R651	42124181	" composition 1/2W		Q704	23800594	FET	3SK59Y
R611	42144335	" " 1/4W	" 3.3MΩ	Q707	22303730	Transistor	2SC373
				Q710	22310005	Transistor	2SC1000GR
				Q701, 703, 709	22318154	Transistor	2SC1815Y
VR603	49912103	V10K-8-1-2	10kΩΒ	1		21025	
VR601	49912103	V10K-8-1-2	10kΩB	D701 705 700	21010070	DIODE	101007
VR602	49912303	"	500kΩB	D701, 705~708,	21010070	Germanium	1S1007
, 1002	17712307		2008770	D702~704, 709	21015550	Silicon	1S1555
				~713, 715,	21013330	Silicon	131333
				719, 720, 724			
		CAPACITOR		D716, 718	21090034	Zener	WZ090
C632	31829030	Ceramic disc 50WV	3PF SL	D710, 718	21090111	Zener	WZ050
C635	31829040	" " "	4PF SL		31070111		
C634	31829101	" " "	100PF SL	<u> </u>			
C628	31820270	" " "	27PF CH				
C631	31820271	n n n	270PF CH			CRYSTAL	
C630	31820511	" " "	510PF CH	X701	71800085	HC-18/U 8986kHz	#210042-1
C613	30820102	" " "	0.001µF	X703	71800087	" 8988.3kH	z #210042-3
C603, 620, 626, 629, 636	30820103	" " "	0.01µF	X702	71800086	" 8989kHz	#210042-2
C638	30820473	" " "	$0.047 \mu F$				
C622~624	36825223	Mylar "	0.022μF				
C608, 610, 616	36825473	" "	0.047µF	†	1	RESISTOR	
C606	36226105	Tantalum 16WV	1μF	R749,753,754	40143680	Carbon film 1/4W V.	J 68Ω
C621	36226225	" "	2.2μF		41143680	" " T.	J 68Ω
C602, 605	36226106	. " "	10μF	R716, 747,752	40143101	" " V	J 100Ω
C612, 618	36226226	" "	22μF		41143101	" " T.	J 100Ω
C604, 611, 619	34220105	Electrolytic 16WV TW	1μF	R729	40143121	" " " V	J 120Ω
C627	34220225	" " "	2.2μF	R704, 707	40143151	" " " #	10000
C625	34220475	11 11 11	4.7μF	R755	40143181	" " " "	180Ω
C601, 609, 615,	34220106	" " "	10μF	R708, 709	40143221	" " " "	22002
617				R721, 735	40143331	" " " "	33042
C607, 614	34220226	n n	22μF	R710, 738	40143391	" " " "	37042
C637	34220107	" " "	100μF	R702	40143471	" " " "	17002
				R701, 718, 727	40143681	" " " "	00012
					40143102		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
				R715	40143222	" " " "	Z.ZKUD
				R717, 728, 745	40143332	" " " "	3.5KU
		TRIMMER CAPACITOR		R705, 706	40143472	" " " "	1.7 RGB
TC601	39000007	ECV-1ZW 20x40	20PF	R751	40143682	" " " "	
				R720, 731, 734, 737, 741, 756,	40143103	" " "	10kΩ
		SWITCH		757	40142152	" " " "	151-0
\$601	63000008	SWITCH SS 12 L06		R723	40143153	" " " "	10100
S601	03000008	SS-12-L06		R739, 746, 758 R726	40143223	" " " "	
				R712, 719, 732	40143333	" " " "	
				R712, 719, 732	40143393	" " " "	
		+		R742	-	" " " "	
			Access to the second second		40143563	" " " "	
				R714, 736	40143823	<u> </u>	82kΩ

R703, 711, 725	40143104	Carbon film 1/4W VJ	100kΩ				
R722, 733	40143154	" " " "	150kΩ				
R740, 744	40143105	" " " "	lMΩ			RELAY	
R743	42144335	" composition 1/4V	V GK 3.3MΩ	RL701	70000031	FBR-211AD012M	12V
					·		
		POTENTIOMETER			V	FO UNIT	
VR701	49910201	EVL SOAA 00B22	200ΩΒ	Symbol No.	Part No.	Descriptio	n
VR702	49910504	EVL SOAA 00B55	500kΩB			VFO assembly 3330	
					014402BZ	PCB with components	
				PB-1440B-3330	60414402	P.C. Board	
07.15	21020020	CAPACITOR	and or				
C715	31829020	Ceramic disc 50WV	2PF SL			FFT 9 TDANGISTOD	
C721, 730 C718, 719	31829101 31829241	" " "	100PF SL 240PF SL	Q802	22800195	FET & TRANSISTOR FET	2SK19GR
C718, 719 C705	31829241	" " "	27PF CH	Q802 Q801, 803	22800193	Transistor	2SC372Y
C713	31820270	" " "	27PF CH*	1 2001, 003	22303/24	11411515101	2303721
C703, 704	31820270	" " "	39PF CH	1			
C708, 709	31820350	" " "	150PF CH				
C701, 702, 706,	30820103	n n n	0.01µF			DIODE	
707, 711, 712,				D801	21022360	Varactor	1S2236
714, 716, 717,							
735, 740, 746,							
748, 751							
C739	30820473	" " "	0.047µF			RESISTOR	
C710	33824200	Dipped mica "	20PF	R809, 811	40143101	Carbon film 1/4W VJ	100Ω
C723, 732	36825202	Mylar "	0.002µF	R807	40143221	" " " "	220Ω
C720, 724, 727,	36825473	" "	$0.047 \mu F$	R805, 808	40143222	n n n n	$2.2k\Omega$
734				R802	40143332	п п п п	3.3kΩ
C725, 726, 736,	34220105	Electrolytic 16WV TW	′ 1μF	R801	40143103	" " " "	10kΩ
737, 741, 749,				R803	40143183	" " " "	18kΩ
752				R804	40143223	" " " "	22kΩ
C731, 747	34220225	" " "	2.2μF	R806, 810	40143104	" " " "	100kΩ
C728, 733, 742	34220106	" " "	10μF		-	+	
~744 C722, 738	34220226	" " "	22μF	<u> </u>		+	
C750, 753	34220226		33μF	<u>I</u>			
C729	34220336	n n n		<u> </u>	1		
0,2,	31220170		17μ1			CAPACITOR	
				-C807	31820080	Ceramic disc 50WV	8PF CH
				C801	31827080	" " "	8PF UJ
			·	C803	31827090	" " "	9PF UJ
		70.0		C804	31820180	" " "	18PF CH
		TRIMMER CAPACITO	R	C808, 814	31820330	" " "	33PF CH
TC701~704	39000007	ECV-1ZW 20x40	20PF	C805, 818	31820390	11 ft 11	39PF CH
TC705	39000009	ECV-1ZW 50x40	50PF	C809, 810, 812, 815, 819, 820, 824, 826	30820103	11 11 11	0.01μF
				C811	33824181	Dipped mica "	180PF
		INDUCTOR		C813	33824431	" " "	430PF
L705	53020007	Micro inductor FL-5H	22μΗ	C821, 823	33824471	" " "	470PF
L706	53010003	" "	250μΗ	C802, 822	33824102	" " "	1000PF
L707	53020027	" "	270µH	C825	36226334	Tantalum 10WV	0.33μF
L701~704	53020001	" " FL-5H	1mH				
				†			
		TDANIOSOSICS		1,000	20000000	VARIABLE CAPACIT	UR
T701	54141710	TRANSFORMER	#220141	VC801	39000027	C521	
1 / 11 1	54141710	R12-4171	#220141	1	1		
T702	54141700	R12-4170	#220140				

		TRIMMER CAPACITOR	1			CERAM	C DI	SCR	MIN	ATOR
TC801	39000070	TSN-100D 15	15PF	CFD901	70900001	SFD-45		0011		41011
TC802	39000076	ECV-1ZW 50x32	50PF	01 2701	70700001	1				
10002	37000003	BCV 12W 30X32	3011			 				
						1				
						RESIST	OR			
		INDUCTOR		R959	41143100	Carbon	film	1/4W	TJ	10Ω
L801	55003184		#220268	R958	40143560	"	"	"	VJ	56Ω
L804, 805	53020014	Micro inductor FL-4H	1.8μΗ	R914, 917, 937,	40143101	"	"	"	"	100Ω
L803, 806	53010003	" "	250µH	938, 953, 957						
L802	53030001	" " S4 102	K 1mH	R923	41143101	"	"	"	TJ	100Ω
				R916, 922	40143221	"	"	"	VJ	220Ω
				R915	40143331	"	"	"	"	330Ω
				R935, 956	40143471	"	"	"	"	470Ω
		RECEPTACLE		R936, 944	40143561	"	"	"	"	560Ω
J802	68040001	SI-6303-1		R909	40143681	"	"	"	"	680Ω
				R913, 933, 939,	40143102	"	"	"	"	lkΩ
			_	943, 952, 963						
				R906, 918, 929,	40143152	"	"	"	"	1.5kΩ
		TERMINAL		934		1				
	90000000	Lighthouse type		R905	40143182	- "	"	"	,,	1.8kΩ
	91100008	Wrapping terminal C		R901, 902, 945,	40143222	"	"	"	"	2.2kΩ
	, 110000			960	10113222					2.2836
+		-		R910, 949	40143272	- "		"		2.7kΩ
				R903, 926, 927,	40143332	,,	-,,	"	"	3.3kΩ
				946, 954	10143332					J.JK42
				R912	40143392	- "	,,		"	3.9kΩ
		FM UNIT		R919, 920, 928,	40143562	"	"		"	5.6kΩ
Symbol No.	Part No.	Description		940, 942	40143302					J.0K32
- Cymbol 140.	017072AZ	FM unit with compone		R908	40143822		"	"	"	8.2kΩ
PB-1707B	60417072 60417072	P.C. Board		R947, 950	40143103	- "				0.2k32
FD-1/U/D	60417072	r.c. boald		R911	40143103	- "				
		+				- "				18kΩ
		 		R921, 930, 948,	40143223	"	"	"	"	22kΩ
		IC FET 9 TRANSISTO		951	40142272	+	"			271.0
Q904, 909	25000099	IC, FET & TRANSISTO		R955, 964	40143273	"		"	"	27kΩ
Q904, 909 Q914	25000099	IC	TA7061AP	R904, 907, 961	40143473	- "	"	"	"	47kΩ
Q914 Q911			78L08 ±10%	R932, 941, 962	40143563	"	"			56kΩ
Q901	22800345 23800513	FET FET	2SK34E 3SK51-03	R924, 925	40143104	"	"	."		100kΩ
Q902, 903, 905,		Transistor		R931	40143154	"	"	"	"	150kΩ
906, 907, 908, 910, 912, 913	22318154	Transistor	2SC1815Y							
					ļ	1				
				l myyood		THERM)R		
		21005		TH901	29090001	SDT-25	50			
D002 002 005	21001880	DIODE Germanium	1S188FM	,		+			-	
D902, 903, 905,	21001880	Germanium	15188FM		-					
906	21015550	Ciliana	101555	ļ		DC====	T10:			
D901, 907, 910 D908	21015550	Silicon	1S1555	VD002	40012222	POTEN			K	AVE.
LIMITA	29090007	Varistor	MV-13 FC-63	VR903	49912202	V10-K	8-1-2			2KB
1				L V/D 0.01	140013302	"				20kΩB
D909	21090137	Varactor	FC-03	VR901	49912203			_		
1		Varactor	FC-03	VR901 VR902	49912203	"				50kΩB
1		Varactor	rc-03							50kΩB
1			FC-03							50kΩB
D909	21090137	CRYSTAL	FC-03			"				50kΩB
D909	71800091	CRYSTAL HC-18/U 8987.5kHz	FC-03	VR902	49912503	CAPAC				
D909	21090137	CRYSTAL	FC-03	VR902 C901, 902, 903, 913, 963	49912503 30820102	CAPAC Cerami	c dis	c 50V		0.001µF
D909	71800091	CRYSTAL HC-18/U 8987.5kHz HC-18/U 9442.5kHz	FC-03	VR902 C901, 902, 903, 913, 963 C904, 905, 909, 910, 956, 961, 962, 964, 966	49912503	CAPAC		c 50V		
X902 X901	71800091 71800092	CRYSTAL HC-18/U 8987.5kHz HC-18/U 9442.5kHz CERAMIC FILTER	FC-03	C901, 902, 903, 913, 963 C904, 905, 909, 910, 956, 961, 962, 964, 966 971	30820102 30820103	CAPAC Cerami	c dis	c 50V		0.001μF 0.01μF
D909	71800091	CRYSTAL HC-18/U 8987.5kHz HC-18/U 9442.5kHz	FC-03	C901, 902, 903, 913, 963 C904, 905, 909, 910, 956, 961, 962, 964, 966 971 C926, 928,	30820102 30820103 30820473	CAPAC Cerami	c dis	c 50V		0.001μF 0.01μF 0.047μF
X902 X901	71800091 71800092	CRYSTAL HC-18/U 8987.5kHz HC-18/U 9442.5kHz CERAMIC FILTER	FC-03	C901, 902, 903, 913, 963 C904, 905, 909, 910, 956, 961, 962, 964, 966 971	30820102 30820103	CAPACI Cerami	c dis	e 50v		0.001μF 0.01μF

C960	33824200	Dipped mica 50WV	V 20PF			RESISTOR	
C907	33824470	" " "	47PF	R1009, 1012	40143472	Carbon film 1/4W VJ	4.7kΩ
C927	33824500	" " "	50PF	R1004, 1005	40143103	п п п п	10kΩ
C930	33824101	" " "	100PF	R1001	42124102	" composition 1/2	WGK 1kΩ
C958, 959	33824121	" " "	120PF		42124473	" " "	" 47kΩ
C906, 908	33824151	" " "	150PF	R1008	40143563	" film 1/4W VJ	56kΩ
C955	33824221	" " "	220PF	R1011	42144225	" composition 1/4	W GK 2.2MΩ
C911, 922, 940	36825102	Mylar "	$0.001 \mu F$	R1003	43104471	Metallic film 1W	470Ω
C949	36825332	. " "	0.0033µF	R1002	43104562	" " "	5.6kΩ
C944	36825472	" "	0.0047µF	R1013	43204473	" " 2W	47kΩ
C929, 931, 933,	36825103	" "	0.01µF				
965							
C923, 924, 925,	36825223	" "	0.02µF				
938, 950, 952							
C912, 914, 915,	36825473	" "	0.047μF			POTENTIOMETER	
916, 918, 919, 932, 951, 967,				VR1001	49910103	V18K-3-2	10kΩB
970						, , ,	
C954	36825104	" "	0.1µF				
C941	36526104	Tantalum 35WV	0.1µF	Ì			
C936, 939, 947	34220105	Electrolytic 16WV	TW 1μF			CAPACITOR	
C934, 935	34220475	" "	$4.7\mu F$	C1011, 1012	30830472	Ceramic disc 500WV	0.0047μF
C937, 942, 953	34220106	" "	10µF	C1009, 1010	30830103	" "	0.01µF
C945, 946	34220226	" "	22μF	C1013	30820473	" 50WV	0.047µF
C921, 943, 948	34220476	" "	47μF	C1008	30834222	Dipped mica 500WV	
			· · · · · · · · · · · · · · · · · · ·	C1007	36526224	Tantalum 35WV	0.22μF
				C1003~1006	35330226	Electrolytic250WV T	
				C1001, 1002	34329901		T 3300μF
,				<u> </u>			
,							
		TRIMMER CAPACI	TOR	1	1		
TC901	39000006	ECV-1ZW 10x40					
					1	AF CHOKE	
				CH1001	55000011		#230014
		INDUCTOR		+			,, 20 3 3 1 .
L904, 905	53020013	Micro inductor	150µH				
L901, 902, 903,		" " FL	-5H 1mH	1	1		
	33020001						
906	33020001						
	33020001						
	33020001				P	LL UNIT	
	33020001			Symbol No.		LL UNIT	in.
	33020001			Symbol No.	Part No.	Descriptio	
906		TRANSFORMER	#220188		Part No. 017091AZ	Description PLL unit with components	
906 T901	55003084		#220188 #221024	Symbol No. PB-1709A	Part No.	Descriptio	
906 T901 T902	55003084 55003028	TRANSFORMER	#221024		Part No. 017091AZ	Description PLL unit with components	
906 T901 T902 T903	55003084 55003028 54141700		#221024 #220140		Part No. 017091AZ	Description PLL unit with components	
906 T901 T902	55003084 55003028	TRANSFORMER	#221024		Part No. 017091AZ	PLL unit with compose P.C. Board	nents
906 T901 T902 T903	55003084 55003028 54141700	TRANSFORMER	#221024 #220140	PB-1709A	Part No. 017091AZ 60417091	PLL unit with compose P.C. Board	nents OR
906 T901 T902 T903	55003084 55003028 54141700	TRANSFORMER	#221024 #220140	PB-1709A Q1102	Part No. 017091AZ 60417091 25000129	PLL unit with compose P.C. Board IC, FET & TRANSIST	OR TA7310P
906 T901 T902 T903	55003084 55003028 54141700	TRANSFORMER	#221024 #220140	PB-1709A Q1102 Q1106	Part No. 017091AZ 60417091 25000129 25000130	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC	OR TA7310P SN75450B
906 T901 T902 T903	55003084 55003028 54141700 55003176	TRANSFORMER R12-4170	#221024 #220140	PB-1709A Q1102	Part No. 017091AZ 60417091 25000129	PLL unit with compose P.C. Board IC, FET & TRANSIST	OR TA7310P SN75450B MC4044P
906 T901 T902 T903 T904	55003084 55003028 54141700 55003176	TRANSFORMER R12-4170 CT. A UNIT	#221024 #220140 #220210	PB-1709A Q1102 Q1106 Q1107	Part No. 017091AZ 60417091 25000129 25000130 25000135	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC	OR TA7310P SN75450B MC4044P (µPC10080
906 T901 T902 T903	55003084 55003028 54141700 55003176 REC Part No.	TRANSFORMER R12-4170 CT. A UNIT Descrip	#221024 #220140 #220210	Q1102 Q1106 Q1107	Part No. 017091AZ 60417091 25000129 25000130 25000135	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5%
906 T901 T902 T903 T904 Symbol No.	55003084 55003028 54141700 55003176 REC Part No. 017080AZ	TRANSFORMER R12-4170 CT. A UNIT Descript Rect. A unit with of	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5% 78L08±10%
906 T901 T902 T903 T904 Symbol No.	55003084 55003028 54141700 55003176 REC Part No.	TRANSFORMER R12-4170 CT. A UNIT Descrip	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC IC IC IC IC FET	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5% 78L08±10% 2SK19GR
906 T901 T902 T903 T904 Symbol No.	55003084 55003028 54141700 55003176 REC Part No. 017080AZ	TRANSFORMER R12-4170 CT. A UNIT Descript Rect. A unit with of	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC	OR TA7310P SN75450B MC4044P (µPC1008C) 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No.	55003084 55003028 54141700 55003176 REC Part No. 017080AZ	TRANSFORMER R12-4170 CT. A UNIT Descript Rect. A unit with of	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103,	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC IC IC IC IC FET	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5% 78L08±10% 2SK19GR
906 T901 T902 T903 T904 Symbol No.	55003084 55003028 54141700 55003176 REC Part No. 017080AZ	TRANSFORMER R12-4170 CT. A UNIT Descript Rect. A unit with a P.C. Board	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No. PB-1708	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080	TRANSFORMER R12-4170 CT. A UNIT Descript Rect. A unit with the P.C. Board DIODE	#221024 #220140 #220210	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103,	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC	OR TA7310P SN75450B MC4044P (µPC10080 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No. PB-1708	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080	TRANSFORMER R12-4170 CT. A UNIT Descrip Rect. A unit with of P.C. Board DIODE Silicon	#221024 #220140 #220210 potion components	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103,	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC	OR TA7310P SN75450B MC4044P (µPC1008C) 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No. PB-1708 D1001, 1002 D1003, 1004	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080 21090022 21090019	TRANSFORMER R12-4170 CT. A UNIT Descrip Rect. A unit with of P.C. Board DIODE Silicon "	#221024 #220140 #220210 potion components V06B 10D10	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103,	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC TC TC Transistor Transistor	OR TA7310P SN75450B MC4044P (µPC1008C 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No.	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080	TRANSFORMER R12-4170 CT. A UNIT Descrip Rect. A unit with of P.C. Board DIODE Silicon	#221024 #220140 #220210 potion components	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103, 1105, 1109	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730 22318154	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC IC	OR TA7310P SN75450B MC4044P (μPC1008C 78L05±5% 78L08±10% 2SK19GR 2SC373 2SC1815Υ
906 T901 T902 T903 T904 Symbol No. PB-1708 D1001, 1002 D1003, 1004	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080 21090022 21090019	TRANSFORMER R12-4170 CT. A UNIT Descrip Rect. A unit with of P.C. Board DIODE Silicon "	#221024 #220140 #220210 potion components V06B 10D10	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103,	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC TC TC Transistor Transistor	OR TA7310P SN75450B MC4044P (µPC1008C 78L05±5% 78L08±10% 2SK19GR 2SC373
906 T901 T902 T903 T904 Symbol No. PB-1708 D1001, 1002 D1003, 1004	\$5003084 \$5003028 \$4141700 \$5003176 REC Part No. 017080AZ 60417080 21090022 21090019	TRANSFORMER R12-4170 CT. A UNIT Descrip Rect. A unit with of P.C. Board DIODE Silicon "	#221024 #220140 #220210 potion components V06B 10D10	Q1102 Q1106 Q1107 Q1111 Q1110 Q1104 Q1108 Q1101, 1103, 1105, 1109	Part No. 017091AZ 60417091 25000129 25000130 25000135 25000132 25000128 22800195 22303730 22318154	Description PLL unit with compose P.C. Board IC, FET & TRANSIST IC IC IC IC IC TC IC	OR TA7310P SN75450B MC4044P (μPC1008C 78L05±5% 78L08±10% 2SK19GR 2SC373 2SC1815Υ

		RESISTOR				
R1 126	40143100	Carbon film 1/4W VJ 10Ω			,	
RI 113	40143560	" " " 56Ω				
R1129	40143680	" " " 68Ω				
R1107, 1128	40143101	" " " 100Ω		V	CO UNIT	
R1 103	40143151	" " " 150Ω	Symbol No.	Part No.	Description	
R1105, 1114,	40143102	" " " 1kΩ		017102AZ	VCO unit with components	
1121			PB-1710B	60417102	P.C. Board	i
R1122	40143152	" " " 1.5kΩ		00.17.102		
R1110, 1112,	40143222	" " " 2.2kΩ				
1115, 1116,						
1118					FET & TRANSISTOR	
R1119, 1120,	40143472	" " " 4.7kΩ	Q1201~1208	22800196		19BL
1123, 1124,			Q1209	23800513		51-03
1127	14		Q1210~1212	22318154		1815Y
R1111, 1125	40143223	" " " 22kΩ	(250	10101
R1 104	40143473	" " " 47kΩ				
R1109	40143683	" " " 68kΩ				
R1117	40143104	" " " 100kΩ			DIODE	
	111.0107	1 30832	D1219, 1220	21090115	Germanium 1N6	$\frac{1}{100}$
			D1209~1218	21015550	Silicon 1S1	
1			D1201~1208	21090138	Varactor MV	
			21201 1200	210,0100	in v	
	İ	1				
	<u> </u>	CAPACITOR			RESISTOR	
C1110, 1113	31829270	Ceramic disc 50WV 27PF SL	R1256	40143220	Carbon film 1/4W VJ	22Ω
C1116, 1135	31829390	" " 39PF SL	R1269, 1270	40143270	" " " "	27Ω
C1120	31829470	" " 47PF SL	R1235	40143470	" " " "	47Ω
C1112	31829560	" " " 56PF SL	R1264, 1266	40143560	" " " "	56Ω
C1117	31829101	" " 100PF SL	R1201, 1205,	40143101	" " " "	100Ω
C1105	31829151	" " 150PF SL	1208, 1212,	.01.0101		10011
C1101, 1102,	30820102	" " 0.001μF	1215, 1219,			,
1104, 1109,			1222, 1226,		İ	
1114, 1118,			1228, 1229,			
1121, 1122			1233, 1236,			
C1103, 1107,	30820103	" " " 0.01μF	1240, 1242,			
1108, 1115,			1246, 1248,			
1124~1126,			1252, 1254*			
1128, 1130,			1271		1	
1131, 1134	İ		R1257, 1258	40143151	" " " "	150Ω
C1119	36825104	Mylar " 0.1μF	R1207, 1214,	40143561	и и и и	560Ω
C1132, 1133	36326685	Noise limiter 20WV 6.8µF	1221, 1254		1	
C1127, 1129	34220106	Electrolytic 16WV TW 10µF	R1255, 1261	40143102	" " " "	lkΩ
,			R1206, 1213,	40143222	" " " "	2.2kΩ
			1220, 1227,	.01.0000		
			1234, 1241,			
			1247, 1253			
			R1262	40143472	, n n n n	4.7kΩ
		INDUCTOR	R1267	40143562	" " " "	5.6kΩ
L1105		Micro inductor FL4H J 12µH	R1263, 1265	40143473	" " " "	47kΩ
L1103,1104	53020028	" " FL5H 18μH	R1260	40143823	" " " "	82kΩ
L1 106	53020019	" " 22μΗ	R1203, 1204,	40143104	n n n n	100kΩ
L1108, 1109,	53020013	" " 220µН	1210, 1211,	101.5107		
1111		220,000	1217~1218,			
L1101, 1107,	53020001	" " " 1mH	1224, 1225,			
1110	1	1	1231, 1232,			
			1238, 1239,			
			1244, 1245,			
	-	TRANSFORMER	1250, 1251,			
T1101	54141840	R12-4184 #220169	1268, 1272 ^A			
	2.1.1010	#22010J	R1259	40143684	. " " " "	680kΩ
	†		111207	70173004		COOKSE
	†		†			
TP1101	91100008	Wrapping terminal C	▲ 5MHz WWV			
	1	<u> </u>	★ 15MHz WWV			
					1	

		, in the second				TRANSISTOR
			~~~~	Q1301~1310	22303724	Transistor 2SC372
	× 1 100	CAPACITOR				
C1275	- 31827050	Ceramic disc 50WV	5PF UJ			
C1242, 1250	31827150	" " "	15PF UJ			
C1211,	31827200	" " "	20PF UJ			DIODE
C1226, 1258	31827220	" " "	22PF UJ		21010070	Germanium 1S1007
C1234	31827240	" " "	24PF UJ	D1201~1210	21010070	
C1234 C1218, 1219	31827270	" " "	27PF UJ	D1301~1310	21013330	Silicon 1S1555
C1218, 1219 C1204, 1210		, , , , , , , , , , , , , , , , , , , ,	39PF UJ			
	31827390 31827470	" " "	47PF UJ			
C1205, 1213,	3102/4/0		4/FF UJ			
1220, 1259	21927101	11 11 11	100DE III			CDVCTAL
C1203	31827101	" " "	100PF UJ	V1201	71500164	CRYSTAL (160 ) 15 0075MHz (210041
C1235	31820010	" " "	1PF CH	X1301	71500164	(160m) 15.9875MHz #210041
C1212,1276,1277	31820020	" " "	2PF CH	X1302	71500165	(80m) 17.9875MHz #210041
C1227, 1277*	31820100		10PF CH	X1303	71500166	(40m) 21.4875MHz #210041
C1243, 1251	31820120		12PF CH	X1304	71500167	(20m) 28.4875MHz #210041
C1233	31820150	" " "	15PF CH	X1305	71500168	(15m) 35.4875MHz #210041
C1225, 1241,	31820200	" " "	20PF CH	X1306	71500169	(10A) 42.4875MHz #210041
1249, 1257*				X1307	71500170	(10B) 42.9875MHz #210041
C1228, 1236,	31820470	" " "	47PF CH	X1308	71500171	(10C) 43.4875MHz #210041
1244, 1252				X1309	71500172	(10D) 43.9875MHz #210041
C1201, 1202, 1207~1209,	30820102	" " "	0.001µF	X1310*	71500183	(*15MHz WWV) 29.4875MHz #210078-11
1215~1217,				X1310 A	71500173	(▲5MHz WWV) 19.4875MHz
1222~1224,						#210078-10
1230~1232,						
1238~1240,						CRYSTAL SOCKET
1246~1248				XS1301~1310	69010012	SD0105 1P
1254~1256,						
1261, 1262,						
1265, 1267,						
1269						RESISTOR
C1206, 1214,	30820103	" " "	0.01µF	R1326, 1331,	40143470	Carbon film 1/4W VJ 47Ω
1221, 1229,	30020103		0.01μ1	1336, 1341	, , , , , , , , , , , , , , , , , , , ,	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
1237, 1245,				R1301, 1305,	40143101	" " " 100
1253, 1260,				1310, 1315,		
1263, 1264,				1320, 1321,		
1266, 1268,				1325, 1330,		
1270~1273				1335, 1340,		
C1274	34220106	Electrolytic 1 6WV TW	10μF	1345, 1350		,
01271	31220100	Electrolytic 10W V 1W	10µ1	R1316, 1346*	40143221	" " 220
		INDUCTOR		R1306, 1311,	40143331	" " " 330
L1203~1211	53020021	Micro inductor FL5H	220Ц	1346▲	40143331	330
L1203~1211	33020021	MICIO IIIductoi FLSH	220μπ		40143561	" " " 560
*				R1304, 1309, 1314, 1319,	40143301	" " " 560
				1314, 1319,		
		TRANSFORMER		1324, 1329,		
T1201 1202	55002170		<b>#220204</b>	•		
T1201, 1202	55003179		#220294	1344, 1349	40142601	" " " 680
T1203	55003180		#220297	R1351	40143681	000
T1204, 1308*	55003181		#220295	R1302, 1307,	40143332	" " " 3.31
T1205~1207	55003182		#220296	1312, 1317,		
T1308▲	55003183	,	#220293	1322, 1327,		
				1332, 1337,		
				1342, 1347		
				R1303, 1308,	40143153	" " " 15k
				1313, 1318,		
	X	TAL UNIT		1323, 1328,		
Symbol No.	Part No.	Description		1333, 1338,		
-	017111AZ	Xtal unit with compone	nts	1343, 1348		Ĭ
PB-1711A	60417111	P.C. Board				

	T	CAPACITOR	T	1	
C1342~1351	31820080	Ceramic disc 50WV 8PF C	Н		-
C1321, 1325,	31820330	" " " 33PF C		CAPA	CITOR BOARD
1329, 1333	1		Symbol No.	Part No.	Description
C1314, 1318,	31820390	" " 39PF C		017130AZ	Capacitor board with components
1322, 1326,			PB-1713	60417130	P.C. Board
1330, 1334		1			
1338*					
C1317	31820470	" " " 47PF C	н		
C1310	31820680	" " " 68PF C			CAPACITOR
C1313, 1337*	31820820	" " 82PF C		34839902	Electrolytic 500WV 100µF
C1306, 1338 ⁴	31820101	" " " 100PF C		1 1007702	(CE-62L)
· C1302, 1309	31820151	" " " 150PF C		<u> </u>	(65 022)
C1337▲	31820181	" " 180PF C		<b>†</b>	
C1305	31820221	" " 220PF C		<u> </u>	
C1301	31820271	" " 270PF C		<del> </del>	
C1341	30820102	" " " 0.001µF		<b>†</b>	
C1303, 1304,	30820102	" " " 0.01μΓ		DRI	VER BOARD
1307, 1308,	30020103	0.01#1	Symbol No.	Part No.	Description
1311, 1312,			Symbol No.	017140AZ	Driver board with components
1311, 1312,				01/140AZ	(without vacuum tube)
1315, 1316, 1319, 1320,		1	PB-1714A	60417141	P.C. Board
			1D-1/14A	0041/141	1.C. DUATU
1323, 1324,				1	
1327, 1328,				-	
1331, 1332,				<b>†</b>	V/A OLUMA TUDE
1335, 1336,	ļ		1/1/01	10000000	VACUUM TUBE
1339, 1340			V1601	10000020	12BY7A
	<b>+</b>				
	ļ	-			
					VACILIM TURE COCKET
		TRANSFORMER	VS1601	68090006	SB-9403
T1301~1310	55002217			68090006	SB-9403
11301~1310	55003217	#220017			
	<b>_</b>				
	<b>+</b>			<u> </u>	RESISTOR
		MINI CONNECTOR	R1605	42124470	Carbon composition $1/2W$ GK $47\Omega$
T1201	68170001	5048-17A	R1602(L1602),160		" " " $56\Omega$
J1301	08170001	3046-17A	R1603		
				42124101	" " " 100Ω " " 47kΩ
	ļ		R1601	42124473	" " 4/K32
	-			<u> </u>	
				+	
				-	
		T. B BOARD		<b>_</b>	
Symbol No.	Part No.	Description		1	
DD 12121	017121AZ	Rect. B board with components	01601 1602	20020102	CAPACITOR
PB-1712A	60417121	P.C. Board	C1601, 1602	30820103	Ceramic disc 500WV 0.01µF
			C1603, 1604,	30820473	" " 50WV 0.047μF
			1606	1	
			C1605	33834102	Dipped mica 500WV 1000PF
		DIODE			
D1401~1404	21090019	Silicon 10D10	,		
		RESISTOR			INDUCTOR
R1401~1406	42124474	Carbon composition 1/2W GK	L1601	53020013	Micro inductor FL5H 150µH
		470k	$\Omega \qquad L1602(R1602)$	55003219	#220029
	91100008	Wrapping terminal C			
	91100008	Wrapping terminal C			
	91100008	Wrapping terminal C		91100008	Wrapping terminal

					IC. TRANSISTOR
			Q1801	25000074	IC TA7089
			Q1804	22106390	Transistor 2SA639
		<b>†</b>	Q1803	22107330	Transistor 2SA733
	FIN	AL BOARD	Q1805, 1806	22318155	Transistor 2SC181
Symbol No.	Parts No.	Description	Q100 <b>0</b> , 1000		200101
	017152AZ	Final board with components			
PB-1715B	60417152	P.C. Board			
101/100	00417132	110, 2011	<b>+</b>		DIODE
+			D1801, 1802	21090019	Silicon 10D10
			D1803~1808	21015550	Silicon
<del>-</del>		VACUUM TUBE	D1003~1000	21013330	Sincon 191999
V1701, 1702	10000026	6146B			
V1701, 1702	10000020	0140B			
		DIODE			RESISTOR
D1701	21090019	Silicon 10D10	R1810	40143479	Carbon film 1/4W VJ 4.7
D1701	21090019	VACUUM TUBE SOCKET	R1815	40143471	" " " 47
VS1701, 1702	68080006	SB-3606	R1812	40143471	" " " 4.
V31701, 1702	0 80 80 00 0	3B-3000	R1813, 1814	40143103	" " " 10
			4 1	40143103	10
			1817, 1818 R1816	40143223	" " " 22
		RESISTOR	R1801, 1802,	40143223	Carbon composition 1/2W GK
D1701 1702	42124560		1	42124474	<u>-</u>
R1701, 1702 (L1702, 1703)	42124300	Carbon composition 1/2W GK 56Ω	1804, 1805 R1803, 1809	43204471	Metallic film 2W 470
R1 703, 1704,	42124101	" " " 100Ω	R1808	43304332	" " 3W 3.3k
1705			R1806	43304153	" " " 15k
R1706		Meter shunt	R1807	43304473	" " 47k
R1707	43304153	Metallic film 3W 15kΩ			
	*				
4					
01704 1710		CAPACITOR	WD 1001	40015500	POTENTIOMETER
C1704, 1710	30830103	Ceramic disc 500WV 0.01µF	VR1801	49915502	V10K-8-1-2 5kΩB
C1705~1709,	30820473	" 50WV 0.047μF			·
1711, 1712 C1703	20020102	" 500WV 1000PF			
	30830102				
C1701	33147101	Moulded mica 1kWV 100PF	G1001 1007 1010		CAPACITOR
C1702	33831050	Dipped mica 500WV 5PF	C1801,1807,1812		Ceramic disc 500WV 0.0047
			C1810	36825223	Mylar 50WV 0.022µ
			C1811	34220106	Electrolytic 16WV TW 10μ
			C1806	35330106	" 250WV TW_ 10μ
			C1808, 1809	34350226	" 350WV TW 22μ
			C1802~1805	34330476	" 250WV TW 47μ
			I		
		<del> </del>	<del> </del>	<del> </del>	
	52020012	INDUCTOR			
L1701	53020013	Micro inductor 150µH			
L1 704	53020015	Micro inductor 150μH Micro inductor 560μH			
L1 704 L1 702, 1 703		Micro inductor 150µH			
L1 704	53020015	Micro inductor 150μH Micro inductor 560μH		THE RESERVE OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE	SWITCH BOARD
L1 704 L1 702, 1703	53020015	Micro inductor 150μH Micro inductor 560μH	Symbol No.	Part No.	Description
L1 704 L1 702, 1 703	53020015 53003220	Micro inductor 150μH Micro inductor 560μH RF choke #220307		Part No. 017183AZ	Description Select switch board with compo
L1 704 L1 702, 1 703	53020015	Micro inductor 150μH Micro inductor 560μH	Symbol No. PB-1718C	Part No.	Description
L1 704 L1 702, 1 703	53020015 53003220	Micro inductor 150μH Micro inductor 560μH RF choke #220307		Part No. 017183AZ	Description Select switch board with compo
L1 704 L1 702, 1703	53020015 53003220	Micro inductor 150μH Micro inductor 560μH RF choke #220307		Part No. 017183AZ	Description Select switch board with compo
L1 704 L1 702, 1 703	53020015 53003220	Micro inductor 150μH Micro inductor 560μH RF choke #220307	PB-1718C	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board TRANSISTOR
L1 704 L1 702, 1 703	53020015 53003220 91100008	Micro inductor 150μH Micro inductor 560μH RF choke #220307  Wrapping terminal C		Part No. 017183AZ	Description Select switch board with compo
L1 704 L1 702, 1703 (R1701, 1702)	53020015 53003220 91100008	Micro inductor 150µH Micro inductor 560µH RF choke #220307  Wrapping terminal C	PB-1718C	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board TRANSISTOR
L1 704 L1 702, 1 703	53020015 53003220 91100008 REC Part. No.	Micro inductor 150µH Micro inductor 560µH RF choke #220307  Wrapping terminal C  CT. C UNIT  Description	PB-1718C	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board TRANSISTOR
L1 704 L1 702, 1703 (R1701, 1702)	\$3020015 \$3003220 91100008 REC Part No. 017171AZ	Micro inductor 150µH Micro inductor 560µH RF choke #220307  Wrapping terminal C  CT. C UNIT  Description  Rect. C unit with components	PB-1718C	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board  TRANSISTOR  Transistor 2SC181
L1704 L1702, 1703 (R1701, 1702)	53020015 53003220 91100008 REC Part. No.	Micro inductor 150µH Micro inductor 560µH RF choke #220307  Wrapping terminal C  CT. C UNIT  Description	PB-1718C Q1901, 1902	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board  TRANSISTOR Transistor 2SC181
L1704 L1702, 1703 (R1701, 1702)	\$3020015 \$3003220 91100008 REC Part No. 017171AZ	Micro inductor 150µH Micro inductor 560µH RF choke #220307  Wrapping terminal C  CT. C UNIT  Description  Rect. C unit with components	PB-1718C	Part No. 017183AZ 60417183	Description Select switch board with compound P.C. Board  TRANSISTOR  Transistor 2SC181

Т		RESISTOR			<u> </u>
R1901, 1902	40143103	Carbon film 1/4W VJ 10kΩ			DIODE
		<u> </u>	D2101~2103	20900140	LED GD4-203SRD
			D2104, 2108	21090011	Silicon 10D1
			D2105~2107,	21015550	Silicon 1S1555
			2109~2112		
		CAPACITOR			
C1901	34220106	Electrolytic 16WV TW 10μF			RESISTOR
			R2105, 2107	40143560	Carbon film 1/4W VJ 56Ω
-			R2106	40143221	" " " 220Ω
		·	R2111	40143821	" " " 820Ω
			R 2102	40143102	" " " 1kΩ
			R2101, 2104,	40143152	" " " 1.5kΩ
		RELAY	2108		
RL1901, 1902	70000031	FBR211AD012M 12V	R2103	40143472	" " " 4.7kΩ
			R2112, 2113	40143103	" " " 10kΩ
			R2109	40143123	" " " 12kΩ
			R2110	40143223	" " " 22kΩ
		SWITCH			
S1901~1906	65000039	6B0002CC2060			
	91100008	Wrapping terminal C			
		FFG		<del> </del>	POTENTIOMETER
			VR2101	49912471	V10K-8-1-2 470ΩB
				1	1
		-			
	1				
		SWITCH BOARD		1	CAPACITOR
Symbol No.	Part No.	Description	C2102	30820473	Ceramic disc 50WV 0.047μF
	017191AZ	Lever switch board with components	C2101	34220107	Electrolytic 16WV TW 100μF
PB-1719B	60417191	P.C. Board		-	
					+
		RESISTOR			
R2001	41143821	Carbon film 1/4W TJ 820Ω		İ	RELAY
			RL2101, 2102	70000031	FBR211AD012M 12V
					*
					SWITCH
		SWITCH	S2101~2105	65000035	5B0001FC2060
S2001	64000103	SLE 62251			,
S2002	64000102	SLE 64301			
S2003, 2004,	64000101	SLE 62301		91100008	Wrapping terminal C
2005					
					1
				1	-
				I E	D A BOARD.
	TUNE S	WITCH BOARD	Symbol No.	Contract of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the last of the la	D A BOARD  Description
Symbol No.	TUNE S	WITCH BOARD  Description	Symbol No.	Part No. 017212AZ	Description
Symbol No.			Symbol No.	Part No.	
Symbol No. PB-1720B	Part No.	Description		Part No. 017212AZ	Description LED A board with components
	Part No. 017202AZ	Description Tune switch board with components		Part No. 017212AZ	Description LED A board with components
	Part No. 017202AZ	Description Tune switch board with components		Part No. 017212AZ	Description LED A board with components P.C. Board
	Part No. 017202AZ	Description Tune switch board with components P.C. Board	PB-1721B	Part No. 017212AZ 60417212	Description  LED A board with components  P.C. Board  DIODE
PB-1720B	Part No. 017202AZ 60417202	Description Tune switch board with components P.C. Board TRANSISTOR		Part No. 017212AZ	Description LED A board with components P.C. Board
PB-1720B  Q2102, 2103	Part No. 017202AZ 60417202 22107330	Description Tune switch board with components P.C. Board  TRANSISTOR Transistor 2SA733	PB-1721B	Part No. 017212AZ 60417212	Description  LED A board with components  P.C. Board  DIODE
PB-1720B	Part No. 017202AZ 60417202	Description Tune switch board with components P.C. Board TRANSISTOR	PB-1721B	Part No. 017212AZ 60417212	Description LED A board with components P.C. Board  DIODE

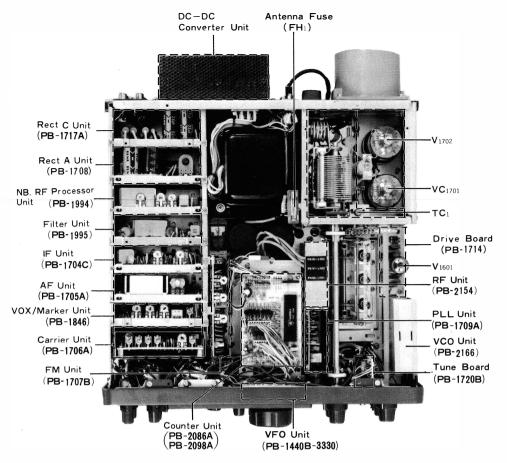
		RESISTOR				
R 2203	41143271	Carbon film 1/4W TJ 270Ω			CAPACITOR	
R2202	41143821	" " " 820Ω	C2407	30820103		.01µF
R2201	41143152	" " " 1.5kΩ	C2409	33824100		0PF
			C2405	33824120		2PF
			C2403, 2404	33824680		8PF
			C2402	33824271		70PF
			C2401	33824821		20PF
			C2406	34220336	Electrolytic 16WV TW	
	REJECT	SWITCH BOARD		0.22000		
Symbol No.	Part No.	Description				
	017222AZ	Reject switch board with				
		components				
PB-1722B	60417222	P.C. Board				
101/220	00,11,222	710.20014	,		TRIMMER CAPACITOR	
			TC2401	39000018		20PF
			TC2407	39000001		10PF
		DIODE	TC2406	39000002		20PF
D2301	20900140	LED GD4-203SRD	TC2402~2405	39000005		50PF
		RESISTOR			TRANSFORMER	
R2301	40143152	Carbon film 1/4W VJ 1.5kΩ	T2401	55002202		‡220303A
112301	70173132	Caroon min 1/4 w v J 1.3K32	T2401	55003292 55003222		#220303A
			12402	33003222		220201
		POTENTIOMETER				
VR2301	49915502	V10K-8-1-2 5kΩB			MER B BOARD	
			Symbol No.	Part No.	Description	
		,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	PB-1724C	017243AZ 60417243	Trimmer B board with co	omponents
	-		PB-1/24C	6041/243	P.C. Board	
00001	65000024	SWITCH				
S2301	65000034	1B0001AC2060		-		
	<del> </del>			<b>†</b>	RESISTOR	
			R2501, 2502	40143682	Carbon film 1/4W VJ	6.8kΩ
	+		I K Z 3 U I . Z 3 U Z	40143062	Carbon IIIII 1/4 w v J	0.0K32
		VER A BOARD				
Symbol No.	Part No.	Description				
	Part No. 017233AZ	Description Trimmer board A with components				
Symbol No. PB-1723C	Part No.	Description			CAPACITOR	
	Part No. 017233AZ	Description Trimmer board A with components	C2503	33824330	Dipped mica 50WV	
	Part No. 017233AZ	Description Trimmer board A with components	C2503 C2504	33824680	Dipped mica 50WV	68PI
	Part No. 017233AZ	Description Trimmer board A with components P.C. Board	C2503 C2504 C2502	33824680 33824271	Dipped mica 50WV	68PI 270PI
PB-1723C	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board TRANSISTOR	C2503 C2504	33824680	Dipped mica 50WV	68PI 270PI
PB-1723C Q2401	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 2SC735Y	C2503 C2504 C2502	33824680 33824271	Dipped mica 50WV	68PI 270PI
PB-1723C	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board TRANSISTOR	C2503 C2504 C2502	33824680 33824271	Dipped mica 50WV	68PI 270PI
PB-1723C Q2401	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 2SC735Y	C2503 C2504 C2502	33824680 33824271	Dipped mica 50WV	68PI 270PI
PB-1723C Q2401	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y	C2503 C2504 C2502	33824680 33824271	Dipped mica 50WV	68PI 270PI
PB-1723C  Q2401 Q2402	Part No. 017233AZ 60417233 22307354 22318154	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y  DIODE	C2503 C2504 C2502 C2501	33824680 33824271 33824821	Dipped mica 50WV  " " "  " " "  " " "  TRIMMER CAPACITOR	68PI 270PI 820PI
PB-1723C Q2401	Part No. 017233AZ 60417233	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y	C2503 C2504 C2502 C2501	33824680 33824271 33824821	Dipped mica 50WV  " " "  " " "  " " "  TRIMMER CAPACITOR  B7P	68PI 270PI 820PI
PB-1723C  Q2401 Q2402	Part No. 017233AZ 60417233 22307354 22318154	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y  DIODE	C2503 C2504 C2502 C2501 TC2501 TC2506, 2507	33824680 33824271 33824821 39000018 39000002	Dipped mica 50WV  """"  """  """  TRIMMER CAPACITOR  B7P  ECV-1ZW 10x32	68PI 270PI 820PI 420PF 10PF
PB-1723C  Q2401 Q2402	Part No. 017233AZ 60417233 22307354 22318154	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y  DIODE	C2503 C2504 C2502 C2501	33824680 33824271 33824821	Dipped mica 50WV  " " "  " " "  " " "  TRIMMER CAPACITOR  B7P	68PJ 270PJ 820PJ
PB-1723C  Q2401 Q2402	Part No. 017233AZ 60417233 22307354 22318154	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 28C735Y Transistor 28C1815Y  DIODE	C2503 C2504 C2502 C2501 TC2501 TC2506, 2507	33824680 33824271 33824821 39000018 39000002	Dipped mica 50WV  """"  """  """  TRIMMER CAPACITOR  B7P  ECV-1ZW 10x32	68PI 270PI 820PI 420PF 10PF
PB-1723C  Q2401 Q2402	Part No. 017233AZ 60417233 22307354 22318154	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 2SC735Y Transistor 2SC1815Y  DIODE Silicon 1S1555	C2503 C2504 C2502 C2501 TC2501 TC2506, 2507	33824680 33824271 33824821 39000018 39000002	Dipped mica 50WV  " " "  " " "  TRIMMER CAPACITOR B7P ECV-1ZW 10x32 ECV-1ZW 50x32	68PI 270PI 820PI 420PF 10PF
PB-1723C  Q2401 Q2402  D2402	Part No. 017233AZ 60417233 22307354 22318154 21015550	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 2SC735Y Transistor 2SC1815Y  DIODE Silicon 1S1555  RESISTOR	C2503 C2504 C2502 C2501 TC2501 TC2506, 2507 TC2502~2505	33824680 33824271 33824821 39000018 39000002 39000005	TRIMMER CAPACITOR B7P ECV-1ZW 10x32 ECV-1ZW 50x32  TRANSFORMER	68PF 270PF 820PF 420PF 10PF 50PF
PB-1723C  Q2401 Q2402  D2402	Part No. 017233AZ 60417233 22307354 22318154 21015550	Description Trimmer board A with components P.C. Board  TRANSISTOR Transistor 2SC735Y Transistor 2SC1815Y  DIODE Silicon 1S1555  RESISTOR Carbon film 1/4W VJ 10kΩ	C2503 C2504 C2502 C2501 TC2501 TC2506, 2507	33824680 33824271 33824821 39000018 39000002	Dipped mica 50WV  " " "  " " "  " " "  TRIMMER CAPACITOR  B7P  ECV-1ZW 10x32  ECV-1ZW 50x32	10PF

		V				
	TRIM	MER C BOARD			POTENTIOMETE	
Symbol No.	Part No.	Description	VR2702	49905104	SR 19R	100kΩB
Symbol No.	010920BZ	Trimmer C board with components	V K 2 / U 2	49905104	SR19R	1ΜΩΒ
PB-1092-3330	60610920	P.C. Board		47703103	SKIJK	11/12/1
T D-1072-3330	00010720	1.C. Doard				
					CAPACITOR	
		RESISTOR	C2703	30820473	Ceramic disc 50	VV 0.047μF
R2601	42124333	Carbon composition $1/2W TJ 33k\Omega$		36825104	Mylar 50V	
R2001	12121333	carbon composition 1/2W 13 33KG	C2705	36526204	Tantalum 35V	
			C2706, 2707	36526334	" "	
			C2704	34220226	Electrolytic 16	
	22024100	CAPACITOR				
C2605	33834100	Dipped mica 500WV 10PF				
C2603 C2604	33834300 33834500	" " 30PF " " 50PF			MINI CONNECTO	ıR
C2604 C2602	33834500	" " " 50PF " " 220PF	J2701	67080006	5048-8A	'11
C2602	33834821	" " 820PF	J 2 / 01	0700000	3046-6A	
				ME	MODY LINE	
		TRIMMER CAPACITOR	Symbol No.	Part No.	MORY UNIT  Desc	ription
TC2603~2605	39000017	B-1P1 40PF	,	017872AZ	Memory board w	ith components
TC2602	39000016	B-2PY 100PF	PB-1787B	60417872	P.C. Board	
TC2601	39000018	B-7P 420PF				
					IC, FET & TRANS	SISTOR
			Q2820	25000149	IC	LM308
			Q2821	25000135	IC	MC4044P
	KE	YER UNIT				(µPC1008C)
Symbol No.	Part No.		Q2822~2826	25000090	IC	MC14042B
	017281AZ	Keyer unit with components	Q2812	25000147	IC	MM74C90
PB-1728A	60417281	P.C. Board	Q2811	25000146	IC ,	MSM5562
			Q2818	25000172	IC	NJM78L05
			Q2816, 2817	25000175	IC	NJM78L08
			Q2813	25000140	IC	SN74LS00N
		IC & TRANSISTOR	Q2814, 2833	25000141	IC	SN74LS04N
Q2701	25000203	IC 8044	Q2832	25000151	IC	SN74LS123N
Q2702	22318154	Transistor 2SC1815Y	Q2827~2831	25000150	IC	SN74LS192N
			Q2815	25000148	IC	TC5032P
			Q2819, 2834	25000109	IC	μPC14305
		DIODE	Q2801, 2802, 2805, 2806	22890017	FET	JF1033B
D2701~2706	21090115	Germanium 1N60	Q2809	23800401	FET	3SK40M
			Q2807	22303724	Transistor	2SC372Y
		,	Q2803, 2804,	22307853	Transistor	2SC785O
		RESISTOR	2810 Q2808	22390001	Transistor	MPS A13
R2705	40143102	Carbon film 1/4W VJ 1kΩ	1 2000			
R2704	40143332	" " " 3.3kΩ				
R	40143472	" " " 4.7kΩ				
R2709, 2710	40143103	" " " 10kΩ	1		DIODE	
	40143393	" " " 39kΩ	D2804, 2805	21001880	Germanium	1S188FM
R2703						
R2703 R2706	40143473	" " •" " 47kΩ	D2801~2803	21015550	Silicon	1S1555
	40143473 40143563	" " *" " 47kΩ	D2801~2803 D2806, 2807	21015550 21090141	Silicon Varactor	1S1555 MV104

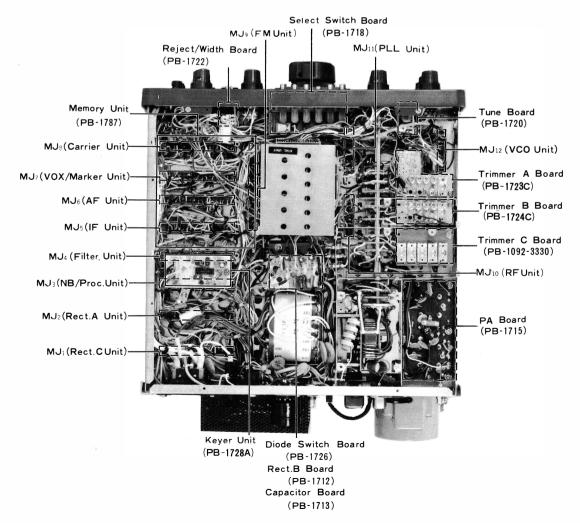
				C2802	31827271	Ceramic disc 50WV 2	70PF UJ
-				C2821, 2823	38820471		70PF
-			i		1	(2222-660	0-02-471)
				C2822	38820102		.001µF
-		CRYSTAL				(RD200Y	
X2801	71800092	HC-18/U	3276.8kHz	C2801, 2806,	38820103	" " " 0	.01μF
				2808, 2811,	1	(RD204Y	
			i	2813~2815,		•	•
				1818~2820,			
		RESISTOR		2829~2832,			
R2863	40143279	Carbon film RD 1/4F	2.7Ω	2839, 2856,			
R2860	40143339	" " " "	3.3Ω	2859, 2867			
R2825	40143339	" " " "	22Ω	C2868,2869,2871	30820473	" " " 0	.047μF
R2805, 2808,	40143101	" " " "	100Ω	C2810	33821050	Dipped mica "	5PF
2822, 2824	40143101		10032	C2860	33824150		15PF
R2813	40143121	" " " "	120Ω	C2816	33824470		47PF
R2809, 2821		" " " "	220Ω	C2812, 2817	33824470		51PF
R2804, 2817	40143221	" " " "	390Ω	C2612, 2617			82PF
	40143391	" " " "	470Ω	C2834	33824820 36825332		.0033µF
R2826, 2831, 2840	40143471		4/032	C2837	36825473		.047μF
R2835	40142102	" " " "	1kΩ	C2847, 2848,	36825104		.1μF
-	40143102	" " " "		2853	30023104	0	.1μ1
R2815	40143122	" " "	1.2kΩ	C2861	36526334	Tantalum 35WV 0	.33μF
R2818, 2834,	40143152	" " " "	1.5kΩ	C2842, 2843,	36526105		μF
2849	40142272	" " " "	2.71.0	2852	30320103	I	μ1
R2842, 2855	40143272		2.7kΩ	C2844	36526255	" " 2	.2μF
R2832, 2837	40143332	" " " "	3.3kΩ	C2851	36526335		.2μΓ .3μF
D2010 2012	10112150			C2850	36916337		.3μΓ 30μF
R2810, 2843,	40143472	" " " "	4.7kΩ	C2862~2865			
2857, 2861					32821102		.001µF 30PF
R2853	40143562	" " " "	5.6kΩ	C2833, 2835,	36824331	Styrol " 3	SUPF
R2827, 2848	40143822	" " " "	8.2kΩ	2836	24420026	T1 . 1 .: 400077 # 2	2 F
R2844, 2846,	40143103	" " " "	10kΩ	C2825	34120336		3μF
2847, 2850~			ļ	C2824	34120476	" 10WV TW 4	
2852				C2845	34220475	" 16WV TW 4	
R2811	40143123	" " " "	1 2kΩ	C2826	34220106		0μF
R2828, 2829	40143153	" " "	15kΩ	C2809, 2838,	34220337		30μF
R2838	40143223	" " " "	22kΩ	2841, 2854,		(CE04 RVC 16W	V 330μF)
R2812, 2858,	40143333	" " "	33kΩ	2855, 2857,			
2859				2858, 2866			
R2836	40143473	" " " "	47kΩ	C2870	34220108	" " 1	000μF
R2803, 2806,	40143563	" " "	56kΩ				
2820						- 12	
R2854, 2862	40143823	" " " "	82kΩ _				
R2801, 2802,	40143104	" " " "	100kΩ				
2814, 2816,							
2823, 2830,						TRIMMER CAPACITOR	
2833, 2839,				TC2801	39000073	ECV-1ZW 40x53 4	OPF
2841, 2856							
R2807,2819	40143334	" " " "	330kΩ				
R2845	40143394	" " " "	390kΩ				
R2864	41143102	" " 1/4P	lkΩ			INDUCTOR	
R2865	41143472	" " 1/4P	4.7kΩ	L2802,2805,2807	53020001	Micro inductor FL-5H 1	mH
-				L2803, 2804	53020014	" " FL-4H 1	.8μΗ
		POTENTIOMETER		L2801	53020027	" " FL-5H 2	70μH
VR2801, 2802	49800093	PN822H103H	10kΩB	L2806	55003069	" " 35μH #	‡220012
× .							
		CAPACITOR					
C2849	31829101	Ceramic disc 50WV	100PF SL			TRANSFORMER	
C2807	31820240	" " "	24PF CH	T2801	55003223		#220332A
C2828	31820390	" " "	39PF CH	1			
	31820470	" " "	47PF CH				
C2827	1 21020770			<b>+</b>	<b>—</b>	<u> </u>	
C2827 C2805	31820820	" " "	82PF CH	1			
C2827 C2805 C2804	31820820 31827100	n n n	82PF CH 10PF UJ				

			R2931	40143473	Carbon film RD 1/4F 47kΩ
	,		R2901, 2905,	40143104	" " " 100kΩ
			2927		*
			R2929	40143105	" " " 1ΜΩ
			R2930	40143225	" " " 2.2ΜΩ
		NTER UNIT			
Symbol No.	Part No.	Description			
	017291AZ	Counter/Display unit assembly			
PB-1729A	60417291	P.C. Board			
					BLOCK RESISTOR
			RB2901	47000004	RK1/16B8R $4.7k\Omega \times 8$
		IC, FET & TRANSISTOR			
Q2920, 2921	25000144	IC F40192			
Q2919	25000143	IC MC1416P			
Q2916	25000114	IC MC14011B			CAPACITOR
Q2911	25000138	IC MSL980-Y7	C2901	31829080	Ceramic disc 50WV 8PF SL
Q2910	25000139	IC MSL980-Y4	C2903, 2911	31829330	" " " 33PF SL
Q2917, 2922,	25000085	IC MSM561	C2916, 2919	31827820	" " " 82PF UJ
2923			C2922, 2923	31820510	" " 51PF CH
Q2918	25000084	IC MSM5501	C2905, 2915,	31820101	" " 100PF CH
Q2912	25000080	IC MSM5564	2918	1	
Q2925	25000175	IC NJM78L08	C2902, 2904,	30820103	" " $0.01\mu\mathrm{F}$
Q2913	25000140	IC SN74LS00N	2906~2910,		
Q2914	25000141	IC SN74LS04N	2912, 2913,		
Q2915	25000072	IC SN74LS90N	2917, 2920,		
Q2903	25000104	IC SN76514N	2947, 2948		
Q2924	25000109	IC μPC14305	C2929, 2931	30820473	" " " 0.047μF
Q2902	22890017	FET JF1033B	2952		
Q2901	23800401	FET 3SK40M	C2926	33824331	Dipped mica " 330PF
Q2909	22107330	Transistor 2SA733	C2927	36825332	Mylar " 0.0033μF
Q2904, 2905	22307853	Transistor 2SC785O	C2950	36825102	" " 0.001μF
Q2906~2908	22309450	Transistor 2SC945	C2924	36825473	" " 0.047μF
			C2914, 2930.	36226106	Tantalum 16WV 10µF
			2949		
			C2932~2945	32821102	Feed thru 50WV 0.001µF
D2001 2007		DIODE	C2925, 2928	36324331	Styrol 25WV 330PF
D2901~2907	21015550	Silicon	C2946	36326685	Noise limiter 20WV 6.8µF
	i i		C2951	34220477	Electrolytic 16WV 470μF
			C2953, 2954	36526105	Tantalum 35WV 1μF
		CRYSTAL	<u> </u>		
X2901	71800105	HC-18/U 18.5MHz #210045-2			
X2902	71800103	HC-18/U 18.0MHz #210045-1			
X2903	71400001	HC-14/W 655.36kHz #210045	<u> </u>		
A2703	/1400001				RECEPTACLE
			J2901	67160002	Pin connector 5049-16A 16P
			J2902	68020001	CN 7017
		RESISTOR	1 22,52	00020001	CITIOIT
R2954	42124100	Carbon composition $1/2W = 10\Omega$			1
R2932~2953	40143101	Carbon film RD 1/4F $100\Omega$			
R2909, 2912	40143221	" " " 220Ω			VARIABLE CAPACITOR
R2915, 2918	40143331	" " " 330Ω	VC2901	39000072	TSN-120SX 10PF×2
R2903, 2906,	40143471	" " " 470Ω		1.000072	1011/2
2928		1,332		+	
R2904	40143152	" " " 1.5kΩ	t		<u> </u>
R2907, 2910	40143222	" " " 2.2kΩ	<u> </u>	+	TRANSFORMER
R2919, 2920,	40143332	" " " 3.3kΩ	T2901, 2902	52000064	8X377004 13MHz #220306
2922, 2925		3.5865		1200007	1220000
R2911	40143472	" " " 4.7kΩ	<b>†</b>	+	
R2908	40143562	" " " 5.6kΩ	†	+	1.
R2902, 2913,	40143153	" " " 15kΩ	<b>†</b>	+	INDUCTOR
2914, 2916,	10113133	13832	L2901	55020025	Micro inductor FL-5H 33µH
		1	L2902	55003370	
2917	1				Noise filter coil SFT840D

				1	INDUCTOR
			L3101, 3102	<b>1</b> .	Micro inductor FL-4H 22µH
			L3103	53020027	Micro inductor FL-5H 270µH
	DISP	LAY BOARD			
Symbol No.	Part No.	Description		91100008	Wrapping terminal C
PB-1730	60417300	P.C. Board			
		DISPLAY LED			
DS3001~3006	21090135	HP5082-7740			
			ļ		
	-			DO DO 00	NAME OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY
		SOCKET	Symbol No.	Part No.	DNVERTER UNIT  Description
QS3001~3006	68140005	314-AG-37D	Cymbol 140.	Tart IVO.	TRANSISTOR
Q33001 3000	08140003	314-AG-37D	Q3201, 3202	22290020	T20A6 with insulator
			Q3201, 3202	22290020	120710 With histiator
	67200003	Board joint 163740		1	
			,		
					RESISTOR
			R3202	43104332	Wire wound 1W 3.3Ω
			R3201	43504221	Metallic film 5W 220Ω
	THE RESERVE OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE PARTY OF THE	SWITCH BOARD		1	
Symbol No.	Part No.	Description	ļ	-	
DD 17264	017261AZ	Diode switch board with component		-	
PB-1726A	60417261	P.C. Board		-	CARACITOR
			C3202	38235473	CAPACITOR  Metallized paper 150WV 0.047µF
			C3202	34320227	Electrolytic 25WV 220 $\mu$ F
		FET	C3201	34320221	Electrolytic 25W V 220µ1
Q3101, 3102	22800195	2SK19GR		+	
				1	
		DIODE			CONNECTOR
D3102 •	2,1010070	Germanium 1S1007	P3201	68090038	AC9M
D3101, 3103	21015550	Silicon 1S1555			
		DECISION			
R3101	40143151	RESISTOR  Carbon film 1/4W VJ 150Ω			
R3105~3107	40143131	" " " 560Ω		AC(	CESSORIES
R3110	40143102	" " " 1kΩ	Symbol No.	Part No.	Description
R3108	40143222	" " " 2.2kΩ	Symbol 140.	77000008	Microphone YE7A
R3109	40143332	" " " 3.3kΩ	1		with Microphone hanger screws.
R3102~3104	40143103	" " " 10kΩ		67040001	Microphone plug FM-144P
				96000033	AC Power cord #240036B
				T9003680	2 wire, 2 prong plug
				T9003681	3 wire, without plug
				T9003682	3 wire, 3 prong UL plug
				T9003683	3 wire, 3 prong Australia plug
	20020102	CAPACITOR		9003684	3 wire, 2 prong EU plug
	30820103	Ceramic disc 50WV 0.01µF	-	67120009	Power plug QS-A-P1 2FL
				T9003720	DC Power cord #240037
3109~3112	20020472	,, ,, ,, ,, ,, ,, ,, ,, ,, ,, ,, ,, ,,	-		D 1 00 : 51257
3109~3112 .C3113	30820473	" " " 0.047µF		67120009	Power plug QS-A-P12FL
3109~3112 C3113 C3101, 3103	33824471	Dipped mica 50WV 470PF		67120009 69000002	Fuse holder SN1102
3109~3112 C3113 C3101, 3103 C3102	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007	Fuse holder SN1102 Fuse 20A
3109~3112 C3113 C3101, 3103 C3102 C3106, 3107,	33824471	Dipped mica 50WV 470PF		67120009 69000002 73000007 67030001	Fuse holder SN1102 Fuse 20A Key plug SH3603
3109~3112 C3113 C3101, 3103 C3102	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007 67030001 67020002	Fuse holder SN1102 Fuse 20A Key plug SH3603 Phone plug SH3001
3109~3112 C3113 C3101, 3103 C3102 C3106, 3107,	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007 67030001 67020002 67020003	Fuse holder SN1102 Fuse 20A Key plug SH3603 Phone plug SH3001 External speaker plug P2240
3109~3112 C3113 C3101, 3103 C3102 C3106, 3107,	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007 67030001 67020002 67020003 67020005	Fuse holder SN1102 Fuse 20A Key plug SH3603 Phone plug SH3001 External speaker plug P2240 Antenna plug SO259
C3113 C3101, 3103 C3102 C3106, 3107,	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007 67030001 67020002 67020003 67020005 67110007	Fuse holder SN1102 Fuse 20A Key plug SH3603 Phone plug SH3001 External speaker plug P2240 Antenna plug SO259 ACC plug PA-602B 0-
3109~3112 C3113 C3101, 3103 C3102 C3106, 3107,	33824471 33824102	Dipped mica 50WV 470PF " " 1000PF		67120009 69000002 73000007 67030001 67020002 67020003 67020005	Fuse holder SN1102 Fuse 20A Key plug SH3603 Phone plug SH37001 External speaker plug P2240 Antenna plug SO259



Top View

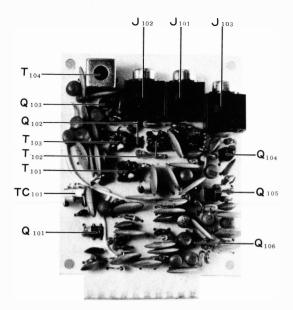


Bottom View

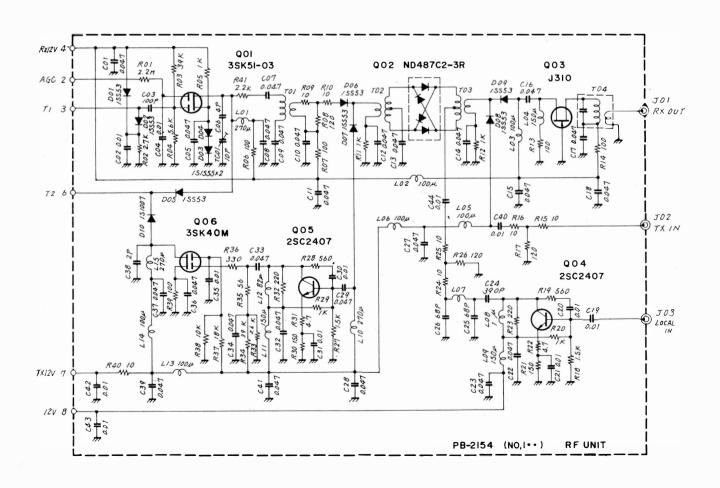
#### **RF UNIT (PB-2154)**

The incoming signal is amplified by the RF amplifier  $Q_{101}$  (3SK51-03), a dual gate MOSFET which has superior rejection against cross modulation. The amplified signal is then fed to the first mixer  $Q_{102}$  (ND487C2-3R), a Schottky-barrier double-balanced mixer, for excellent intercept characteristics. The RF signal is mixed with a local signal delivered from the LOCAL UNIT, resulting in a 8.9875 MHz first IF. The IF signal is then amplified by  $Q_{103}$  (J310) and delivered to the FILTER. UNIT.

The input and output of the RF amplifier are permeability tuned circuits, resulting in high sensitivity with excellent rejection of unwanted out-of-band signals.



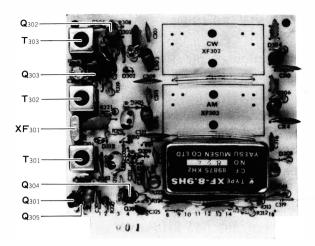
RF unit (PB-2154)



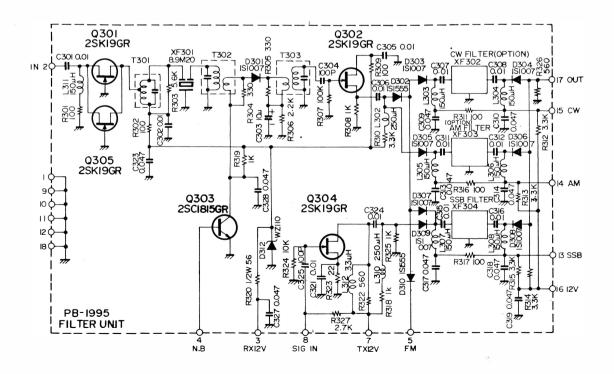
#### FILTER UNIT (PB-1995)

The IF signal received at pin 2 of the FILTER UNIT (PB-1995) is amplified by parallel-connected  $Q_{301}$  and  $Q_{305}$  (both 2SK19GR), and fed through a monolithic filter XF₃₀₁ (8.9M-20A), which has a  $\pm 10$  kHz bandwidth, providing additional selectivity and enough delay time to match the noise blanker gating pulses. The signal is then fed to the second IF amplifier,  $Q_{302}$  (2SK19GR).

The noise blanker diode  $D_{301}$  (1S1007) is placed between  $T_{302}$  and  $T_{303}$ , and it functions as an ON/OFF switch which is controlled by the noise blanker driver  $Q_{303}$  (2SC1815GR). The output from the source of  $Q_{302}$  is passed through the SSB filter  $XF_{304}$  (or the optional AM or CW filters). Selection of the filter to be used is performed by one of the diode switches  $D_{303}$  -  $D_{308}$  (1S1007), depending on the mode of operation. The IF signal is then transferred to the IF UNIT. In the FM mode, the IF signal is coupled directly through  $D_{310}$  (1S1555) to pin 5 of the IF UNIT.



Filter unit (PB-1995)



#### NB UNIT (PB-1994)

A portion of the 8987.5 kHz IF signal is fed to pin 4 of the noise blanker unit and appears at noise blanker mixer  $Q_{209}$  (3SK40M), where the 8532.5 kHz signal generated by  $Q_{211}$  (2SC1815Y) is mixed with the incoming signal to produce a 455 kHz signal. The 455 kHz signal is then amplified by  $Q_{210}$  (3SK40M).

When a carrier or a noise-free modulated signal is received, the 455 kHz signal (with its corresponding strength) is rectified by  $D_{202}$  and  $D_{203}$  (both 1N270) to charge  $C_{235}$ . There is no discharge loop for  $C_{235}$ ; therefore, signals which exceed the charged voltage established by the reference voltage on  $C_{235}$  will not pass through  $D_{202}$  and  $D_{203}$ . Accordingly, there will be no voltage drop across  $R_{247}$ , and  $Q_{212}$  (3SK51-03) will conduct as the gate voltage approaches zero potential. When  $Q_{212}$  conducts, the drain voltage at pin 2 of the printed board will drop.

The drain of  $Q_{212}$  is directly connected to the base of  $Q_{303}$  (2SC1815GR) in the FILTER UNIT. As the drain voltage of  $Q_{212}$  drops, the base voltage of  $Q_{303}$  drops, turning off  $Q_{303}$ . The collector voltage will then increase, producing

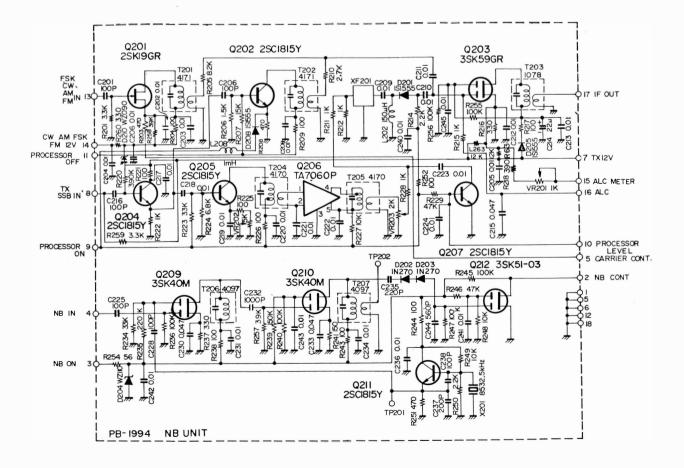
a forward bias to  $D_{301}$  (1S1007). As  $D_{301}$  conducts, the signals will pass normally through the circuit.

When pulse-type noise is received which exceeds the charged reference voltage established by  $C_{235}$ ,  $D_{202}$  and  $D_{203}$  will permit negative-going pulses to turn  $Q_{212}$  off. The drain voltage will rapidly increase as it turns off.

As the drain voltage increases,  $Q_{303}$  will turn on and the collector voltage will decrease. Accordingly,  $D_{301}$  will be biased to block the signal. Thus, when pulse-type noise is received, the signal passage will be blanked off momentarily.

#### **IF UNIT (PB-1704C)**

The IF signal from pin 14 is fed to the gate of the IF first mixer,  $Q_{401}(3SK51-03)$ , where the IF signal is heterodyned with a 19.7475 MHz  $\pm \Delta f$  local signal delivered from crystal oscillator  $Q_{405}$  (2SC535A) and buffer amplifier  $Q_{406}$  (2SC1815Y), resulting in a signal of 10.76 MHz  $\pm \Delta f$ .



The new 10.76 MHz  $\pm$   $\Delta$  f signal is fed through filter XF₄₀₁ to the IF first mixer Q₄₀₁ (3SK51-03), where the filtered signal is heterodyned with a 19.7475 MHz  $\pm$   $\Delta$ f signal, producing an 8.9875 MHz signal, the same as the original IF. This process moves the IF signal across the passband of XF₄₀₁. The combination of filters XF₃₀₄ and XF₄₀₁ provides continuously variable width of the IF passband.

The frequency of crystal oscillator  $Q_{405}$  is varied by varactor diode  $D_{410}$  (1S2209).

On the AM and FM modes, the IF signal is passed through diode switches  $D_{402}$  and  $D_{403}$  (1S1007), and does not pass through filter  $XF_{401}$ .

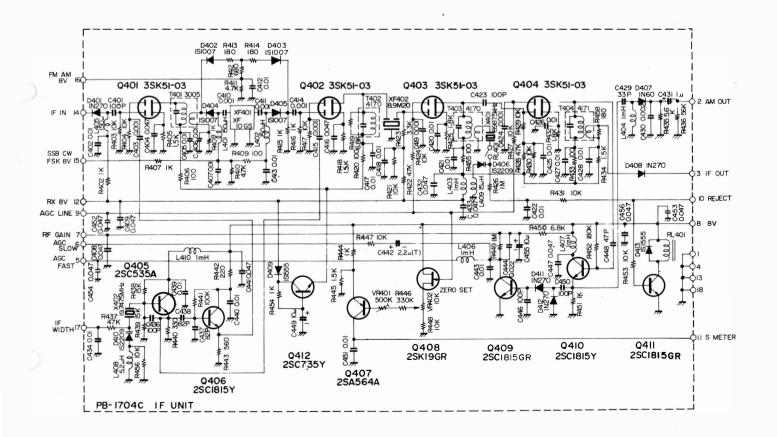
The output from the IF second mixer is fed through a monolithic filter  $XF_{402}$  to the two-stage IF amplifier consisting of  $Q_{403}$  and  $Q_{404}$  (both 3SK51-03). The output from  $Q_{403}$  is coupled to the rejection tuning circuit which eliminates interference within the IF passband. This rejection function is accomplished by varying the resonant frequency of a crystal with varactor diode  $D_{406}$  (1S2209) on the SSB, CW, and FSK modes.

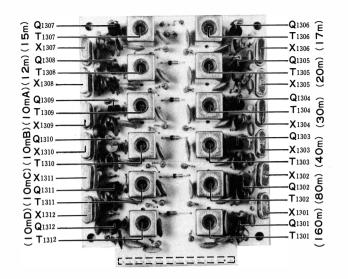
The amplified IF signal is fed to the CARRIER UNIT. In the AM mode, the signal is fed through a buffer amplifier  $Q_{410}$  (2SC1815Y) to the AM detector  $D_{407}$  (1N60). The signal is then fed to the AF UNIT.

A portion of the output from  $Q_{410}$  is rectified by  $D_{411}$  and  $D_{412}$  (1N270) to produce AGC voltage. The AGC voltage is amplified by DC amplifier  $Q_{409}$  (2SC1815GR) and fed to the gate of RF amplfier  $Q_{101}$  and to IF amplifiers  $Q_{403}$  and  $Q_{404}$  to control the gain of these stages for AGC purposes. The time constant of the AGC voltage decay is selectable (FAST/SLOW) by switch  $S_{2003}$ . The AGC voltage is further amplified by  $Q_{408}$  (2SK19GR) and  $Q_{407}$  (2SA564A) for signal strength indication on the front panel S-meter.

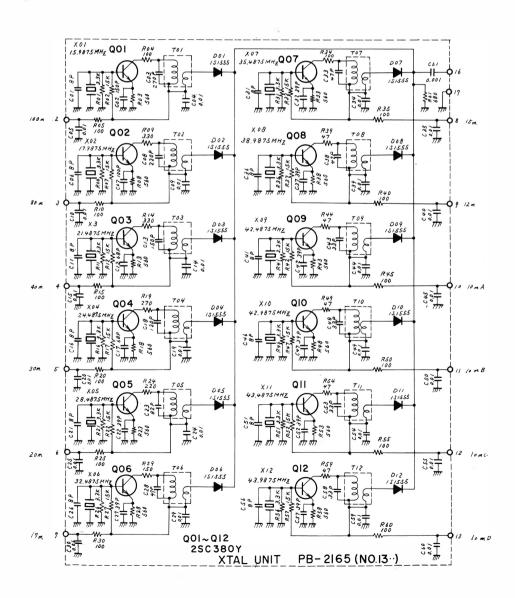
The RF GAIN control on the front panel varies the AGC voltage level, providing manual control of the gain of the RF and IF stages.

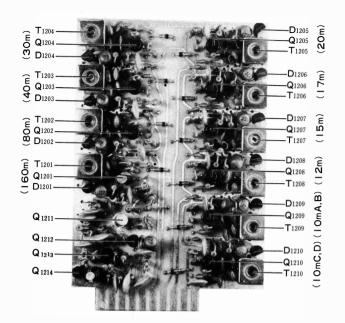
 $Q_{411}(2SC1815GR)$  works as a relay driver for the IF rejection tuning circuit. Delay transistor  $Q_{412}$  (2SC735Y) supplies the voltage to the drain of  $Q_{401}$  and  $Q_{402}$  when the transceiver returns to the receive mode after transmission.



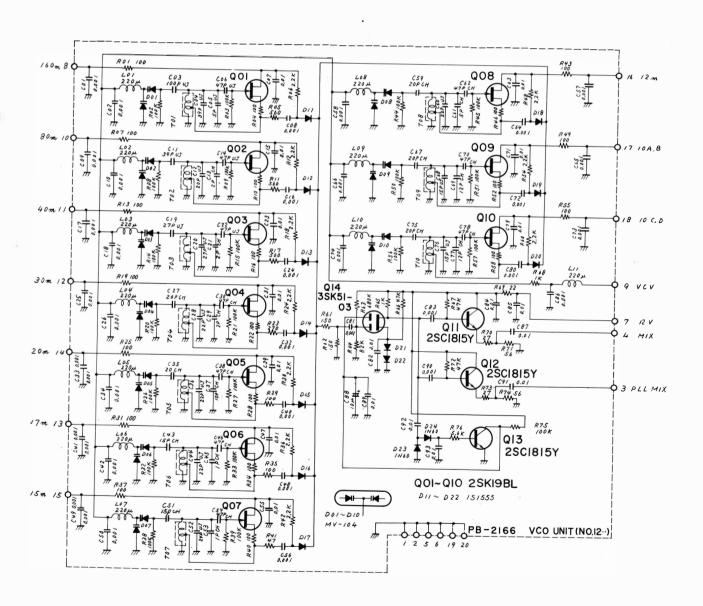


Crystal unit (PB-2165)





VCO unit (PB-2166)



#### COUNTER UNIT (PB-2086A-3430/PB-2098)

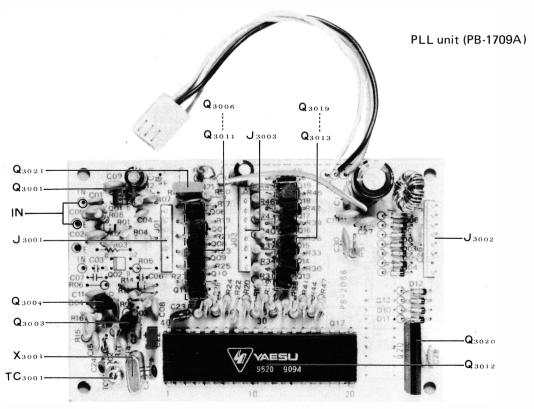
The local oscillator signal is applied to Large-Scale Integrated Circuit (LSI) chip for display on the front panel digital display.

The premix signal as shown in Table 2 from the LOCAL Unit, is amplified by  $Q_{3001}$  (3SK73). The amplified signal is further amplified by  $Q_{3003}$  (2SC 1674) and delivered to the LSI counter chip,  $Q_{3012}$  (MSM9520RS). of the output from  $Q_{3003}$  is amplified by  $Q_{3004}$  (2SC1815Y) and fed to gate 2 of  $Q_{3001}$  controlling the gain of those amplifiers.

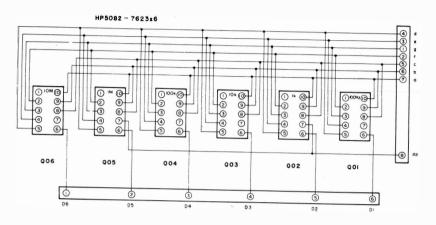
The output from the LSI is fed to the display. The output from pins 24 through 30 is delivered to segment drivers  $Q_{3013}-Q_{3019}$  (2SA952L) and digit drivers  $Q_{3006}-Q_{3011}$  (2SA952L) through a dynamic drive configuration. Display is performed by  $D_{2901}-D_{2906}$  (HP5082-7623), seven-segment light-emitting diodes.

	Nominal Premix Local Frequency	L S B	U S B	CW, AM
160m	10.4875—10.9875(MHz)	10.486-10.986(MHz)	10.489-10.989(MHz)	10.4883—12.9883(MHz)
80m	12.4875—12.9875	12.486-12.986	12.489-12.989	12.4883-12.9883
40m	15.9875—16.4875	15.986-16.486	15.989-16.489	15.9883-16.4883
30m	18.9875—19.4875	18.986-19.486	18.989-19.489	18.9883-19.4883
20m	22.9875-23.4875	22.986-23.486	22.989-23.489	22.9883-23.4883
17 m	26.9875-27.4875	26.986-27.486	26.989-27.489	26.9883-27.4883
15 m	29.9875-30.4875	29.986-30.486	29.989-30.489	29.9883-30.4883
12 m	33.4875-33.9875	33.486-33.986	33.489-33.989	33.4883-33.9883
10m A	36.9875-37.4875	36.986-37.486	36.989-37.489	36.9883-37.4883
10m B	37.4875-37.9875	37.486-37.986	37.489-37.989	37.4883-37.9883
10m C	37.9875—38.4875	37.986-38.486	37.989-38.489	37.9883-38.4883
10m D	38.4875—38.9875	38.486 — 38.986	38.489-38.989	38.4883-38.9883

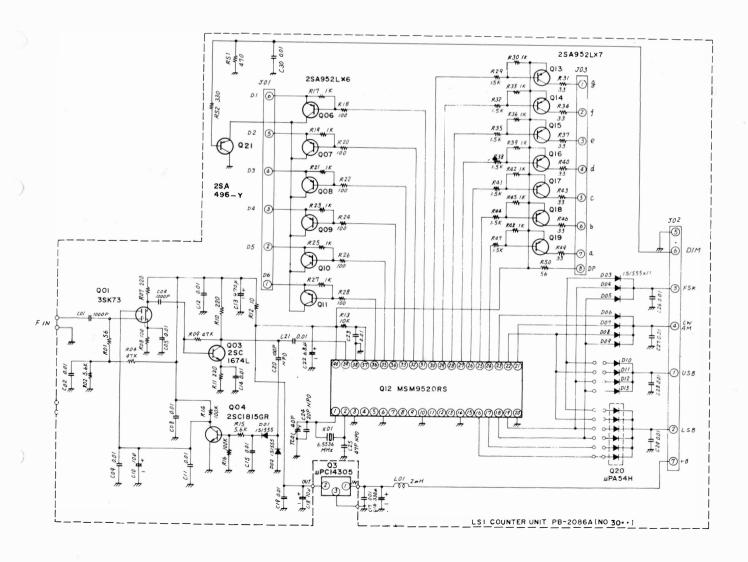
Table 2



Counter unit (PB-2086A)



DISPLAY UNIT PB-2098 (NO.29..)



		CHASSIS	C29,59,60,89.90.104,			0.01µF
Symbol No.	Part No.	Description	105~107,109		(DB201YF103Z5L5)	
		IC .	C17, 18, 19, 37, 38, 46,	K13170473	Ceramic disc 50WV	$0.047\mu$
Q1,2	G1090070	μPC14308	48~50,52,~56,58,75		$(\mathrm{DB207YF473Z5L5})$	
Q3	G1090114	μPC14312	59,62~68,71~73,81,			
			82,88,91,96,98,99,			
		TRANSISTOR	101,102,112,93			
Q5	G3107150C	2SA715C	C110	K02175121	Ceramic disc 50WV	120pF
		DIODE				
1)10,16,18,19,31	G2090118	Germanium 1SS97	C35,36	K12279004	Ceramic disc 500WV	0.0047μF
1)1~3,9,11~15,17,27		Silicon 1S1555	Ì		(ECKD2H472PE)	
~30			C77,79,80,83,106	K12279002	Ceramic disc 500WV	0.01µF
D5~7,20,26	G2090001	″ 10D1			(ECKD2H103PE)	
. , , . , , . ,			C40	K00309002	Ceramic disc 1KWV	100pF
	J01245562	Carbon film ¼W TJ 5.6kΩ			(CC45SL3A101KY)	
	701210002	941.000 11.00 91.000	C14,15	K12329002	Ceramic disc 1.4KV	0.0047µF
		RESISTOR	011,10		(ECKDAL472PE)	0.0011,
R5	J01245821	Carbon film ¼W TJ 820Ω	C12, 13, 44, 78, 92	K12329001	Ceramic disc 1.4KV	0.01µF
10	J00245102	" " VJ 1kΩ	012, 13, 11, 10, 32	112023001	(ECKDAL103PE)	0.0141
R6		" " TJ 3.3kΩ	C41	K30176201		200pF
R19,43	J01245332 J01245472	4.7kΩ	741	1.50170201	Dipped mica 50WV (Z17D201K05)	200hr
R19,43	J01245472 J00245273	" " " V.J 27kΩ	C31	K30273010	Dipped mica 500WV	1pF
			[ (31	K30273010	• •	lpr
R1	J01245104	" " T.J 100kΩ		1/20072075	(LCQ11010D5)	. F
R4,16	J10276100	" composition ½W GK10Ω	C11	K30273050	Dipped mica 500WV	5pF
R39	J30356150	Cement 3W * 15Ω			(LCQ11050D5)	
R37	J01245681	Carbon film ¼W TJ 680Ω	C87	K30276100	Dipped mica 500WV	10pF
R3,18,30	J10276101	* Composition ½W * 100Ω			(LCQ11100D5)	
R22	J10276221	″ ″ 220Ω	C1,42	K30276271	Dipped mica 500WV	270pF
R7,9,17	J10276102	″ ″ ″ 1kΩ			(LCQ1721K5)	
R20	J10276152	" " 1.5kΩ	C39	K30275361	Dipped mica 500WV	360pF
R8	J10276222	″ ″ ″ 2.2kΩ			(LCQ17361J5)	
R25	J10276272	″ ″ ″ 2.7kΩ	C3	K30276471	Dipped mica 500WV	470pF
R33	J10276103	" " 10kΩ			(LCQ17471K5)	
R14	J10276123	" " " 12kΩ	C9	K30276511	Dipped mica 500WV	510pF
R13,29	J10276223	" " 22kΩ			(LCQ18651K5)	
R44	J01245471	Carbon film ¼W T.J 470Ω	C8	K30279048	Dipped mica 500WV	750pF
R40	J10276279	* * 2.7Ω			DM19D102K5)	
R <b>36</b>	J20306222	Metallic film 1 W 2.2kΩ	C2	K30306391	Dipped mica 1KWV	390pF
R35	J20356332	" " 3 W 3.3kΩ	_		(DM15D391K10)	
R41,42	J01245562	Carbon film ¼W TJ 5.6kΩ	C7	K30306222	Dipped mica 1KWV	2200pF
R38	J01245182	″ ″ ″ 1.8kΩ	1		(DM19D222K10)	
		POTENTIOMETER	C47,70	K31306800	Moulded mica 1KWV	80pF
VR1	J60800021	VM11AA41A5M1112 10kΩA	1		(CML1-800K10)	
VR2	J62800035	DM11A743A5M1222 10kΩB/500kΩC	C84	K50247473	Mylar 250WV	0.047μF
VR3	J62800020	DM10A039A 5kΩB/5kΩB	1		(250F2U473M)	
VR4	J61800007	GM70A619A 50kΩB×2	C20~28,51	K21270002	Feed thru 500WV	0.001µF
VR5	J62800034	DM70A039A $5k\Omega B/5k\Omega A$			(ECKL2H-102PE)	
VR7	J60800064	VM10A654C 1kΩB	C61	K40120106	Electrolytic 16WV	10μF
VR8	J62800026	DM10E553A $5k\Omega B/5k\Omega B$	1 "	1113123100	(16RL10)	/
VR9	J60800039	VM10AB08A 5kΩB	C57	K40120336	Electrolytic 16WV	33μF
VR6	J62800047	DM10A042A $5k\Omega B/5k\Omega B$	† 30.	11.10120000	(16RL33)	
VICO	302000047	DM10/1042/1 Sk221)/ Sk221)	C34,43	K41120227	Electrolytic 16WV	220µ F
		`	- 034,43	K41120221	(16TL220)	220μ1
			0111	V21206201		200-E
		01710707	C111	K31306201	Dipped mica 1KV	200pF
C20	V00175 152	CAPACITOR 50WW 47.F	C108	K41140227	Electrolytic 25WV	220µF
C30	K02175470	Ceramic disc 50WV 47pF	WOI	Macaacaa	VARIABLE CAPACITOR	
CF	L'access : :	(DD106CH470J50V02)	VC1	K90000035	RT-18B-300	
C5	K00329001	Ceramic disc 1.5KV 300pF	VC2	K90000016	C134E125	
	ļ	(MD40JSL301K1.5KV)				
C16	K00359003	Ceramic disc 3KV 3pF				
		(CC45SL3F030KY)				
C4	K12359001	Ceramic disc 3KV 1000pF			TRIMMER CAPACITOR	
		(CK45E3F102KY)	TC1	K91000007	120C 10×2 1.5KV	5pF
C103	K14179003	Ceramic disc 25WV 0.1 $\mu$ F				
		(DB209YZ104Z5L0)				

		INDUCTOR			CONNECTOR
L1	L0020304C		J1	P1090001	SG-7701
L2	L0020305A	·	J2	P0090009	FM-144-S
L4	L1190017	FL-5H 102K 1mH	J3	P1090004	SG-7814
L11,12,14	L1190001	EL0710 - 251K 250 \( \mu \) H	J10,11	P1090025	CN-7017
L8	L1020064	300µH	J12~18	R7040620A	Jack Ass'y Board
L6,7(R11,R12)	L0020308		J19	P1090005	SG-8050
L9	L0020009		J4	P0090046	QS-A-DB12ML
L10	L1020690	500μH	J5	P1090033	D6-701B00
L13	L0020705	0007:11	J6	P1090034	D7-701B00
LI:9	L0020703		J8	P1090028	M -BR -06B(D)
			J20	P1090045	AC9-PF
		TRANSFORMER		P1090014	SI-7501-1
		TRANSFORMER	J7		SA602B00
T1	L0020073		J9	P1090040	SA002D00
T2,T3	L0020074			-	
					AALH TI LAGIC
				Discourse	MULTI JACK
		METER	MJ1~8	P4090003	121S-18B-105A
M1(With PL3,4)	M0090007A	500 μ A	MJ9	P4090004	121S -22B - 105A
			MJ10	P4090001	121S -10B-105A
			MJ11,12	P4090007	220D-20B-205A
		SPEAKER			
SP1	M4090031	SA-77K-Y 4Ω 3W			COOLING FAN
			FAN1	M2090001	2SB10A
		POWER TRANSFORMER			
PT1	L3030013A				FUSE
1 11	L3030013A		F1	Q0000005	5A(100~117V)
			111	_	3A(200~234V)
				Q0000004	3A(200 234V)
		RELAY			
RL1	M1090006	AE3244			
RL2	M1090002	MX2P 12V			FUSE HOLDER
			FH1	P2000003	F3265
			FH2	P2000001	SN1001 #2
					,
	1	RELAY SOCKET			
RLS1	M1490004	AE3840			3
RLS2	M1490001	PX08			PILOT LAMP
			PL1	Q1000039	BF311-04071A 14V0.12A
			PL2,3	Q1000040	BQ-044-22839A 8V 100mA
			PL4(M1)	_	Meter lamp 8V0.055A
		SWITCH			
C1	NIOOFOOFF	RS-9-9-12	<u> </u>		
S1	N0050055A		PB-1390	F0001390	LED B BOARD
S2	N0050054	GS-4-8-6B			LED GD4-203-SRD
S3	N7090004	W D9216	D8	G2090060	LED GD4-203-3KD
S4	N7090005	W D9223			
S5	N 0190090	CS-3,5,12			
		PLUG			x 1
P1(with Wire)	T9200320C	5047 -08			UNIT
P2(with Wire)	T9200520E	5047 - 07	Symbol <b>N</b> o.	Part No.	Description
P3(with Wire)	T9200340C	5047 - 17		C0021540	RF unit with components
P8(with Wire)	T9203640	5047 -07	PB-2154A	F0002154A	P. C. Board
P4,5,6	P0090045	SQ4052			
P10	P0090009	SQ4152			FET
	P0090002	SI5908 4P	Q101	G4800510C	
P7	1 0000002	U10000 11	4101	- 10000100	
P7	DOOOOOE	S17502 2D	0106	G4800400M	3SK40M
P7 P9	P0090005	SI7502 2P	Q106	G4800400M	
	P0090005	S17502 2P	Q106 Q103 Q102	G4800400M G3090019 G2090135	3SK40M J310 ND487C2-3R

0104 105	C0004070	TRANSISTOR				INDUCTOR	
Q104,105	G3324070	2SC2407		L107	L0020491		0.32µH
			\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	L108	L1190005	FL-4H 1R0M	1 <i>µ</i> H
				L112	L1190033	FL-5H 820K	82µH
				L102,103.105.106,113	L1190016	FL-5H 101K	100µH
				114			
		DIODE		L104,109,111	L1190020	FL-5H 151K	150µH
D101,102,105~109	G2090027	Si 1SS53		L101,110,115	L1190038	FL-5H 271K	270µH
D103,104	G2015550	Si 1S1555					
D110	G2090093	Ge(GB) 1N270				TRANSFORMER	_
5110	02030033	Gerob, INZIO		T101~103	L0020788A	TRAISI ORIVIER	
				T104	L0020733A		
				1104	L002022171		
		RESISTOR					
R122,131	J00245479	Carbon film 1/4WVJ	4.7Ω				
R109,110,115,116,124	J00245100	" " "	10Ω			JACK	
140				J101~103	P1090018	SQ-3081	
R135	J00245223	" " "	22kΩ				
R106,107,113,114,139	J00245101	" "	100Ω				
R108,117,126	J00245121	" " "	120Ω				
R121,130	J00245151	0 0 0	150Ω				
R123,132	J00245221	" " "	220Ω				
R136	J00245331	" " "	330Ω		NB	UNIT	
R119,128	J00245561	" " "	560Ω	Symbol <b>N</b> o.	Part No.	Description	
R105,111,112,120,129	J00245102	" " "	1kΩ		C0019940	NB unit with components	3
R125	J00245271	" " "	270Ω	PB-1994	F0001994	P. C. Board	
R118,127	J00245152	" " "	1.5kΩ				
R141	J00245222	" " "	2.2kΩ				
R102	J00245272	" " "	$2.7 \mathrm{k}\Omega$				
R104,133	J00245562	" " "	5.6kΩ			IC, FET & TRANSISTOR	
R138	J00245103	" " "	10kΩ	Q206	G1090063	IC TA7060P	
R137	J00245183	" " "	18 kΩ	Q201	G3801680D	FET 2SK168D	
R134	J00245393	" " "	$39k\Omega$	Q209,210	G4800400M	FET 3SK40M	
R101	J00245225	" " "	2.2ΜΩ	Q212	G4800510C	FET 3SK51-03	
R103	J00245473	" " "	$47k\Omega$	Q203	G4800590G	FET 3SK59GR	
		CAPACITOR		Q202,204,205,207,211	G3318150Y	Transistor 2SC1815Y	
C124	K30176391	Dipped mica 50WV	390pF				
		(Z18D391K05)					
C138	K02179003	Ceramic disc 50WV	2pF				
		(DD104CK020C50V02)					
C106	K02172040	Ceramic disc 50WV	4pF			DIODE	
	*	(DD104CH040C50V02)		D202,203	G2090029	Germanium 1N60	
C125,126	K00175680	Ceramic disc 50WV	68pF	D201,205,208	G2015550	Silicon 1S1555	
		(DD104SL680J50V02)		D210	G2090010	Zener W Z090	
C103	K00175101	Ceramic disc 50WV	100pF	D204	G2090012	Zener WZ110	
		(DD105SL101J50V02)					
C102,104,116,130,119	K13170103		$0.01 \mu  \mathrm{F}$				
$\sim$ 121,131,135,140		(DB201YF103Z5L5)					
144,145					-	CRYSTAL	
C101,105,107~115,	K13170473	Ceramic disc 50WV	$0.047 \mu F$	X201	H0100431A	HC-18/U 8533.3kHz	
117,118,122,123,		(DB <b>207</b> YF <b>473</b> Z <b>5</b> L <b>5</b> )					
127~129,132~134,				,			
136.137, 142, 143,							
139						CRYSTAL FILTER	
C141	K40120336	Electrolytic 16WV	33μF	XF201	H1100890	XF-8.9HP	
		(16RL33)					
		*					
		TOWARD CARRET			1	1	
TOTAL	V01000010	TRIMMER CAPACITOR	10 E			DESISTOR	
TC101	K91000019	TRIMMER CAPACITOR ECV-1ZW 10×40	10pF	D954	100245560	RESISTOR	/ I 560
TC101	K91000019		10pF	R254	J00245560	Carbon film 1/4W V	
TC101	K91000019		10pF	R254 R204,209,221,225 226,238,243,244	J00245560 J00245101	Carbon film 1/4W V	/J 56Ω // 100Ω

R252	J01245101	Carbon film 1/4 W TJ	100Ω			TRANSFORMER						
R241	J00245151	" " " VJ	150Ω	T206,207	L0020101	R12-4097						
R216,237,260	J00245331	" " " "	330Ω	T201,202,204,205	L0020140	R12-4170						
R203,208,251	J00245471	*, , , , ,	470Ω	T203	L0020221A	R12-1078						
R211,212,215,217,	J00245102	" " " "	1kΩ									
222,228	1											
R206	J00245152	" " " "	1.5kΩ		Q5000011	Wrapping Terminal C						
R214,250	J00245222	. , , , , ,	2.2kΩ			11 0						
R210	J00245272	" " " "	2.7kΩ									
R201,259	J00245332	" " "	3.3kΩ									
R224	J00245682	" " "	6.8kΩ									
R205	J00245822	" " " "	8.2kΩ									
R227,248,249	J00245022 J00245103	" " " "	10kΩ		- T-11 575	R UNIT						
				Symbol No.	Part No.	Description						
R263 R207	J01245123	, , TJ	12kΩ 15kΩ	Symbol 140.	C0019950	Filter unit with components						
	J00245153			DD 1005	F0001995	P. C. Board						
R223,234	J00245333	" " "	33kΩ	PB-1995	1.0001993	r. C. Board						
R257,258	J00245393	" " " "	39kΩ									
R229,246	J00245473	" " " "	47kΩ	`								
R236,240,245,247,	J00245104	" " "	$100 \mathrm{k}\Omega$									
255,256,257				0001 000 001	G0000000	FET & TRANSISTOR						
R239	J00245154	<i>"</i> " " " "	150kΩ	Q301,302,304,305	G3090035	FET 2SK19TM-GR						
R235	J00245224	" " "	220kΩ	Q303	G3318150G	Transistor 2SC1815GR						
R220	J00245394	" " " "	390kΩ									
R262	J01245225	" " TJ	2.2ΜΩ									
						DIODE						
				D301,303~309	G2090093	Germanium 1N270						
				D302,310	G2015550	Silicon 1S1555						
				D312	G2090012	Zener WZ110						
		POTENTIOMETER		D315~321	G2090118	Germanium 1SS97						
VR201,203	J50710202	V10KB-1-2	$2 \mathrm{k} \Omega \mathrm{B}$									
VR202	J50711502	TR11R100	$5 \mathrm{k}\Omega \mathrm{B}$									
						CRYSTAL FILTER						
				XF301	H1100470	8.9M -20						
				XF304	H1100860	XF-8.9HS						
		CAPACITOR		XF303	H1100870	XF-8.9GA (OPTION)						
C201,206,216,238,	K00175101	Ceramic disc 50WV	100pF	XF302	H1100880	XF-8.9HC (OPTION)						
225,228	1	(DD40001 404 (001100)										
		(DD105SL101J50V02)										
C237	K00179019	(DD105SL101J50V02)  Ceramic disc 50WV	200pF	_		_						
C237	K00179019		200pF									
C237	K00179019 K00175221	Ceramic disc 50WV	200 _p F 220 _p F			RESISTOR						
		Ceramic disc 50WV (DD106SL201J50V02)		R323	J00245220	RESISTOR Carbon film ¼W VJ 22Ω						
		Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV	220pF		J00245220 J00245101							
C235	K00175221	Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV (DD107SL221J50V02)		R323 R301,302,309 R311,316,317		Carbon film ½W VJ 22Ω						
C235	K00175221	Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV (DD107SL221J50V02) Ceramic disc 50WV	220pF	R301,302,309 R311,316,317	J00245101	Carbon film   ½W VJ   22Ω     2Ω     C235 C232 C202,203,205,208~	K00175221 K13170102	Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV (DD107SL221J50V02) Ceramic disc 50WV (DB200YF102Z5L2)	220pF 0.001μF	R301,302,309	J00245101 J01245101	Carbon film         ¼W         VJ         22Ω           ""         "         "         100Ω           ""         "         TJ         100Ω
C235 C232 C202,203,205,208~ 213,217,219~224,	K00175221 K13170102	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV	220pF 0.001μF	R301,302,309 R311,316,317 R304,305 R322,326	J00245101 J01245101 J00245331 J00245561	Carbon film         ¼W         VJ         22Ω           φ         φ         φ         100Ω           φ         φ         TJ         100Ω           φ         φ         VJ         330Ω						
C235 C232 C202,203,205,208~ 213,217,219~224, 218,231,246,234,	K00175221 K13170102	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV	220pF 0.001μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325	J00245101 J01245101 J00245331 J00245561 J00245102	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245	K00175221 K13170102 K13170103	Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV (DD107SL221J50V02) Ceramic disc 50WV (DB200YF102Z5L2) Ceramic disc 50WV (DB201YF103Z5L5)	220pF 0.001μF 0.01μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235 C232 C202,203,205,208~ 213,217,219~224, 218,231,246,234,	K00175221 K13170102	Ceramic disc 50WV (DD106SL201J50V02) Ceramic disc 50WV (DD107SL221J50V02) Ceramic disc 50WV (DB200YF102Z5L2) Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV	220pF 0.001μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215	K13170102  K13170103  K13170473	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV (DB207YF473Z5L5)	220pF 0.001μF 0.01μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272 J00245332	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245	K00175221 K13170102 K13170103	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB207YF473Z5L5)     Dipped mica   50WV	220pF 0.001μF 0.01μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245332 J00245562	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244	K13170102  K13170103  K13170473  K30176561	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV (DB207YF473Z5L5)  Dipped mica 50WV (LCQ18-561K05)	220 _p F 0.001μF 0.01μF 0.047μF 560 _p F	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245332 J00245562 J00245103	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215	K13170102  K13170103  K13170473	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB207YF473Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV	220pF 0.001μF 0.01μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307	J00245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245272 J00245332 J00245103 J00245104	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214	K13170102  K13170103  K13170473  K30176561  K40120226	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV (DB207YF473Z5L5)  Dipped mica 50WV (LCQ18-561K05)  Electrolytic 16WV (16RL22)	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245332 J00245562 J00245103	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244	K13170102  K13170103  K13170473  K30176561	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB207YF473Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV	220 _p F 0.001μF 0.01μF 0.047μF 560 _p F	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307	J00245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245272 J00245332 J00245103 J00245104	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214	K13170102  K13170103  K13170473  K30176561  K40120226	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV (DB207YF473Z5L5)  Dipped mica 50WV (LCQ18-561K05)  Electrolytic 16WV (16RL22)	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307	J00245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245272 J00245332 J00245103 J00245104	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214	K13170102  K13170103  K13170473  K30176561  K40120226	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB207YF473Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307	J00245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245272 J00245332 J00245103 J00245104	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214	K13170102  K13170103  K13170473  K30176561  K40120226	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB207YF473Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307 R320	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272 J00245332 J00245562 J00245103 J00245104 J10276560	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214	K13170102  K13170103  K13170473  K30176561  K40120226	Ceramic disc 50WV (DD106SL201J50V02)  Ceramic disc 50WV (DD107SL221J50V02)  Ceramic disc 50WV (DB200YF102Z5L2)  Ceramic disc 50WV (DB201YF103Z5L5)  Ceramic disc 50WV (DB201YF103Z5L5)  Dipped mica 50WV (LCQ18-561K05)  Electrolytic 16WV (16RL22)  Mylar 50WV (50F2U473M)	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307	J00245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245272 J00245332 J00245103 J00245104	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214  C230,233	K13170102 K13170103 K13170473 K30176561 K40120226 K50177473	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB201YF103Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV     (50F2U473M)	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307 R320	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272 J00245332 J00245562 J00245103 J00245104 J10276560	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214  C230,233	K13170102 K13170103 K13170473 K30176561 K40120226 K50177473	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB201YF103Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV     (50F2U473M)     INDUCTOR     FL-5H   151K	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307 R320	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272 J00245332 J00245562 J00245103 J00245104 J10276560	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214  C230,233	K13170102 K13170103 K13170473 K30176561 K40120226 K50177473	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB201YF103Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV     (50F2U473M)	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307 R320  C304	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245222 J00245332 J00245562 J00245103 J00245104 J10276560 K00175101	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						
C235  C232  C202,203,205,208~ 213,217,219~224, 218,231,246,234, 236,240~243,245  C215  C244  C214  C230,233	K13170102 K13170103 K13170473 K30176561 K40120226 K50177473	Ceramic disc   50WV     (DD106SL201J50V02)     Ceramic disc   50WV     (DD107SL221J50V02)     Ceramic disc   50WV     (DB200YF102Z5L2)     Ceramic disc   50WV     (DB201YF103Z5L5)     Ceramic disc   50WV     (DB201YF103Z5L5)     Dipped mica   50WV     (LCQ18-561K05)     Electrolytic   16WV     (16RL22)     Mylar   50WV     (50F2U473M)     INDUCTOR     FL-5H   151K	220pF 0.001μF 0.01μF 0.047μF 560pF 22μF 0.047μF	R301,302,309 R311,316,317 R304,305 R322,326 R308,318,319,325 R306 R327 R310,312~315 R303 R324 R307 R320	J00245101 J01245101 J00245331 J00245561 J00245102 J00245222 J00245272 J00245332 J00245562 J00245103 J00245104 J10276560	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$						

					;						
C301,306,307,308,	K13170103	Ceramic disc	50WV	0.01µF			RESIST	DR			
311,312,315,316		(DB201YF103	Z5L5)		R406,420,433,455	J00245101	Carbor		1/4 W	VJ	100Ω
321					R409	J01245101	4	"	"		100Ω
C309,310,313,314,	K13170473	Ceramic disc	50WV	0.047μF	R413	J01245181	,,	,	"		180Ω
317,318,319,323,	1	(DB207YF473)		0.011,7-1	R414	J00245181	"		,		
327,328		(DB20111413)	ZULU /				,	",			180Ω
	V4010010C	Fl . l .:	101111	10 F	R442	J00245221			"		220Ω
C303	K40120106	Electrolytic	16WV	10μF	R440	J00245331	"	"	"		330Ω
		(16RL10)			R443	J00245561	"	"	"		560Ω
					R412	J00245681	"	"	"	"	680Ω
	1				R402,407,408,415,418	J00245102	"	"	"	"	$1 \mathrm{k} \Omega$
					416,444,451,454						
		INDUCTOR			R405,434,445,418	J00245152	"	"	"	"	1.5kΩ
L312	L1190025	FL-5H 330K		33μH	R425,432	J00245182	"	"	"	"	1.8kΩ
L303~308,311	L1190020	FL-5H 151K		150µH	R423	J00245332	"	"	,	·	3.3kΩ
L302,310	L1190001	EL0710 251K		250µH	R410,411	J00245472	,	"	,		4. 7kΩ
1.502,510	L1130001	ELOTTO 23TK		230,411	R435	J00245472 J00245562	,	"	"		5.6kΩ
											~
					R419,450	J00245682	"	"	"		6.8kΩ
					R403,404,417,421,	J00245103	"	"	"	"	$10$ k $\Omega$
		TRANSFORMER	₹		424,427,429~431,						
T301~303	L0020141	R12-4171			447,448,453,456						
					R438,439	J00245153	"	"	"	"	$15k\Omega$
					R422,428,437	J00245473	*	"	"	"	47kΩ
					R436	J00245563	"	"	"	"	56kΩ
					R441	J00245104	"	"	"		100kΩ
					R452	J00245184	"	"	"		180kΩ
		UNIT					,	,	,		
					R446	J00245334					330kΩ
Symbol No.	Part No.		scription		R426,449	J00245105	"	"	"	"	1ΜΩ
	C0017040	IF unit with	components	•							
PB-1704C	F0001704C	P. C. Board									
							POTENT	IOMETE	R		
		FET & TRANS	SISTOR	-	VR402	J50710103	V10K -	8-1-2			10kΩB
Q408	G3090035	FET	2SK19T	CM CD	VR401	J50710504		,			500kΩB
Q401~404	G4800510C	"				J50705501		1A-A00	DEO		
			3SK51-		VR403	350705501	EVIN-A	11A-A00.	D <b>3</b> 2		500ΩΒ
Q407	G3105641	Transistor	2SA564								
Q409,411	G3318150G	"	2SC181								
Q405	G3305350A	"	2SC535	A	_		CAPACI	TOR			
Q412	G3319590Y	"	2SC195	9Y	C401,423,446,450	K00175101	Ceram	ic disc	50W	V	100pF
Q406,410	G3318150Y	*	2SC181	5Y			(DD10	5SL101J	50V02)		
					C448	K02175470	Ceram	ic disc	50W	V	47pF
							(DD10	6CH470J	50V02)		
		<u> </u>			C429	K02179013		ic disc	50W	V	33pF
	-	DIODE			1 0.20	1102110010	1	5CH330J			оорг
D407	G2090029		1200		C42C	V0C175101	+			1.7	100 F
	-	Germanium	1N60		C436	K06175101	-	ic disc	50W	V	100pF
D401,408,411,412	G2090093	+	GB)1N270				-	6UJ101J			
D402~405,414~417	G2090118	"	1SS97		C437,438	K06175820	Ceram	ic disc	50W	V	·82pF
D409,413	G2015550	Silicon	1S1555				(ECC-	D1H820	JU2)		
D406,410	G2022090	Varactor	1S2209		C402,405~407,412,	K10177103	Ceram	i c disc	50W	V	$0.01 \mu F$
					413,417,418,421,		(DB20	5YB103N	15L5)		
	1				425,427,428						
											0.001µF
					C403 410 411 414	K13170102	Ceram	ic disc	50W	V	
		CRYSTAI		1000	C403,410,411,414,	K13170102		ic disc	50W	V	
V402	<b>ПОТООЧ</b>	CRYSTAL	7475MLI_		415,419,424		(DB20	0YF102Z	5L2)		
	H0100433	HC-18/U 19.			<b>-</b>	K13170102 K13170222	(DB20 Ceram	0YF102Z ic disc	50W		
	H0100433 H0100432	HC-18/U 19.	7475MHz 9875MHz		415,419,424 C430	K13170222	(DB20 Ceram (DB20	0YF102Z ic disc 1YF222Z	50W 50W	V	0.0022μF
X402 X401		HC-18/U 19.			415,419,424 C430 C420,422,426,434,		(DB20 Ceram (DB20 Ceram	0YF102Z ic disc 1YF222Z ic disc	50W 50W 55L5) 50W	V	
		HC-18/U 19.			415,419,424 C430	K13170222	(DB20 Ceram (DB20 Ceram	0YF102Z ic disc 1YF222Z	50W 50W 55L5) 50W	V	0.0022μF
		HC-18/U 19.			415,419,424 C430 C420,422,426,434,	K13170222	(DB20 Ceram (DB20 Ceram (DB20	0YF102Z ic disc 1YF222Z ic disc	50W 50W 55L5) 50W 55L5)	V	0.0022μF
		HC-18/U 19.	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416,	K13170222 K13170103	(DB20 Ceram (DB20 Ceram (DB20 Ceram	0YF102Z ic disc 1YF222Z ic disc 1YF103Z	50W 50W 55L5) 50W 55L5) 50W	V	0.0022μ F 0.01μ F
X401	H0100432	HC-18/U 19.	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416, 432,433,441,447,	K13170222 K13170103	(DB20 Ceram (DB20 Ceram (DB20 Ceram	OYF102Z ic disc 1YF22ZZ ic disc 1YF103Z ic disc	50W 50W 55L5) 50W 55L5) 50W	V	0.0022μ F 0.01μ F
X401 XF402	H0100432	HC-18/U 19. « 8. CRYSTAL FIL 8.9M20A	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416, 432,433,441,447, 456,452~454	K13170222 K13170103 K13170473	(DB20 Ceram (DB20 Ceram (DB20 Ceram (DB20	OYF102Z ic disc 1YF222Z ic disc 1YF103Z ic disc 7YF473Z	55L2) 50W 55L5) 50W 55L5) 50W 55L5)	V	0.0022μF 0.01μF 0.047μF
X401	H0100432	HC-18/U 19.	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416, 432,433,441,447,	K13170222 K13170103	(DB20 Ceram (DB20 Ceram (DB20 Ceram (DB20	0YF102Z ic disc 1YF22ZZ ic disc 1YF103Z ic disc 7YF473Z	50W 50W 55L5) 50W 55L5) 50W	V	0.0022μ F 0.01μF
X401 XF402	H0100432	HC-18/U 19. « 8. CRYSTAL FIL 8.9M20A	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416, 432,433,441,447, 456,452~454 C444	K13170222  K13170103  K13170473  K50177223	(DB20 Ceram (DB20 Ceram (DB20 Ceram (DB20 Mylar (50F2	0YF102Z ic disc 1YF222Z ic disc 1YF103Z ic disc 7YF473Z	55L2) 50W 55L5) 50W 55L5) 50W 55L5)	v v	0.0022μF 0.01μF 0.047μF 0.022μF
X401 XF402	H0100432	HC-18/U 19. « 8. CRYSTAL FIL 8.9M20A	9875MHz		415,419,424 C430 C420,422,426,434, 439,440,443,451 C404,408,409,416, 432,433,441,447, 456,452~454	K13170222 K13170103 K13170473	(DB20 Ceram (DB20 Ceram (DB20 Ceram (DB20 Mylar (50F2 Tantal	0YF102Z ic disc 1YF222Z ic disc 1YF103Z ic disc 7YF473Z	55L2) 50W 55L5) 50W 55L5) 50W 55L5) 60W 55L5)	v v	0.0022μF 0.01μF 0.047μF

		· <i>'</i>	AKIS					
C431	K40170105	Electrolytic 16WV 14 (50RL1)	μF	R505	J00254151	Carbon film 1	4W VJ	150Ω
C445,449	K40120106	Electrolytic 16WV 10	0μF					
		(16RL10)				POTENTIOMETER	₹	
				VR501	J61800006	GM -70R	$1M\Omega B \times$	2
		INDUCTOR						
L409	L1190019	FL-5H 150K 15	5 <i>μ</i> Η			CAPACITOR		
L401,402,405	L1190020	FL-5H 151K 15	50μH	C512,519	K02179016	Ceramic disc	50W V	51pF
L403,404,406,407,	L1190017	FL-5H 102K 1n	mH			(DD106CH510J50	)V02)	
410				C535	K13170102	Ceramic disc	50WV	0.001µF
L408	L0020145	VXO coil 5.	. 2µH			(DB200YF102Z5	L2)	
				C501,534	K13170103	Ceramic disc	$50 \mathrm{WV}$	$0.01 \mu\mathrm{F}$
						(DB201YF103Z5	L5)	
				C521	K13170473	Ceramic disc	50WV	$0.047\mu\mathrm{F}$
		TRANSFORMER				(DB207YF473Z5		
T401	L0020187			C514	K30176391	Dipped mica	$50 \mathrm{WV}$	390pF
T402,403	L0020140	R12-4170				(Z18D391K05)		
T404	L0020141	R12-4171		C507	K50177472	Mylar	50W V	$0.0047 \mu  \mathrm{F}$
					<u> </u>	(50F2U472M)		
	1			C523,524	K50177682	Mylar	50W V	$0.0068\mu$
		DEL AV		CEOC	VEOLEGIAC	(50F2U682M)	E011/17	0.01. 5
DI 401	141100010	RELAY		C506	K50177103	Mylar	50W V	0.01µF
RL401	M 1190018	UFM -10208 8V	V	CEIC	VE0177470	(50F2U103M)	50W V	0.047E
				C516	K50177473	Mylar (50F2U473M)	50 W V	0.047μF
				C520,530,531,536	K50177104	Mylar	50WV	0.1μF
	+			C320,330,331,330	K30177104	(50F2U104M)	30 W V	$0.1\mu$ 1
	+			C502,503,509,511,	K40170105	Electrolytic	50W V	1μ F
	^	F UNIT		522,529,532,533	140170100	(50RL1)	30111	1,41
Symbol No.	Part No.	Description		C504	K40140475	Electrolytic	25W V	4.7μF
-,	C0017050	AF unit with components				(25RL4R7)		,
PB-1705A	F0001705A	P. C. Board		C528	K41120106	Electrolytic	16WV	10μ F
						(16TL10)		
				C513	K40100226	Electrolytic	10WV	22µ F
						(10RL22)		
		IC & TRANSISTOR		C505,508	K40120226	Electrolytic	16WV	22μ F
Q503	G1090110	IC TA7205AP				(16RL22)		
Q504	G1090077	″ MC3403P		C525	K40100336	Electrolytic	10WV	33μ F
Q506	G1090123	″ 78L08				(10RL33)		
Q501,502,505,507	G330732G	Transistor 2SC732TM	-GR	C517	K40100476	Electrolytic	$10 \mathrm{WV}$	47μ F
						(10RL47)		
			<u> </u>	C515	K40100107	Electrolytic	$10 \mathrm{W}  \mathrm{V}$	100µ F
						(10RL100)		
				C518	K40100477	Electrolytic	10W V	470μ F
D-00 -00	700017101	RESISTOR				(10RL470)		
R523,536	J00245101	Carbon film 1/4 W VJ 10						
R516	J00245561		Ω000					
R506	J00245681 J00245102		80Ω kΩ			HEAT SINK		
R512	J00245102 J00245222				D0043800A	(TA-7205)		
R504,539	J00245222 J00245332		2.2kΩ 3.3kΩ		R0042800A	(1A-1200)	-	
R513,514,537,538	J00245332 J00245472		1. 7kΩ	×				
R510,511	J00245472 J00245822		3.2kΩ					
R543	J00245103		0kΩ	-				
R503	J00245153		5kΩ					
R530,545	J00245333		3kΩ		VOX/MA	RKER UNIT		
R508	J00245393		39kΩ	Symbol No.	Part No.		cription	
R502,509,515	J00245473		17kΩ	-,	C0018460	VOX/Marker u		components
R534,540	J00245823		32kΩ	PB-1846B	F0001846B	P. C. Board		
R517,520,522,525,	J00245104		.00kΩ					
526,528,535,541			t					
R519,524,527	J00245124	* * * 12	20kΩ	,				
R518,521,529	J00245224	<i>"</i> " " " " 2:	220kΩ					

		IC & TRANSIST	OR		C634	V00175101	Constitution	FOWN	100 F
Q604	G1090068	IC & TRANSIST	MC14011	В	C034	K00175101	Ceramic disc (DD105SL101J50	50WV V02)	100pF
Q612	G1090064	IC	4024PC		C613	K13170102	Ceramic disc	50W V	0.001μF
Q603	G3105641R	Transistor	2SA564A			110110102	(DB200YF102Z5I		0.001,41
Q602,608~610,615	G3318150G	Transistor	2SC18150	GR	C603,620,626,629,	K13170103	Ceramic disc	50W V	0.01µF
Q607	G3319590Y	Transistor	2SC1959		636	1	(DB201YF103Z5I		*****
(2601,605,606,611	G3318150Y	Transistor	2SC1815	Υ .	C638	K13170473	Ceramic disc	50W V	0.047μF
Q613,614	G3303800Y	"	2SC380T	M - Y			(DB207YF473Z5I	_5)	
					C631	K30176271	Dipped mica	50W V	270pF
					İ	1	(Z17D271K05)		
					C630	K30176511	Dipped mica	50WV	510pF
		DIODE					(Z18D511K05)		
D601	G2090029	Germanium	1N60		C622~624	K50177223	Mylar	50W V	0.022μF
D603,607~609	G2015550	Silicon	1S1555				(50F2U223M)		
D602,606	G2090010	Zener	W Z090		C608,610,616	K50177473	Mylar	$50\mathrm{WV}$	$0.047\mu\mathrm{F}$
D <b>605</b>	G2090093	Ge(GB)	1N270				(50F2U473M)		
					C606	K70147105	Tantalum	25WV	1μF
							(CS15E1E010M)		
					C621	K70127225	Tantalum	16WV	$2.2\mu\mathrm{F}$
		CRYSTAL					(CS15E1C2R2M)		
X601	H0100260	HC-6W 3200kF	łz		C602,605	K70127106	Tantalum	16W V	10 <i>µ</i> F
					GC10, G10	I/gotogooo	(CS15E1C100M)	101111	00 5
					C612,618	K70127226	Tantalum	16W V	22μ F
		DECICTOR			C604 611 610	V40170105	(CS15E1C220M)	50W V	1
R616	J00245101	RESISTOR  Carbon film	¼W VJ	1000	C604,611,619	K40170105	Electrolytic (50RL1)	JUW V	1μF
R643	J00245101 J00245221	Carbon film	74 W VJ	220Ω	C627	K40170225	Electrolytic	50W V	2.2µF
R620,628	J00245221 J00245471		" "	470Ω	0027	K40170223	(50RL2R2)	3011 1	2.2μ1
R605,614,625,626,	J00245102	, ,	" "	1kΩ	C625	K40140475	Electrolytic	25W V	4.7μF
636,642,646~650	300243102			INU	0023	1140140415	(25RL4R7)	20	1.17.1
R615,630,640,	J00245222	" "	" "	2.2kΩ	C601,609,615,617	K40120106	Electrolytic	16WV	10μF
R <b>637</b>	J00245392	" "	" "	3.9kΩ	1		(16RL10)		,
R604,606,632~634	J00245472	" "	" "	4.7kΩ	C607,614	K40120106	Electrolytic	16W V	22μ F
R <b>627</b>	J00245562	* *	" "	5.6kΩ			(16RL22)		, -
R601,602,607,608,	J00245103	" "	" "	10kΩ	C637	K40120107	Electrolytic	16W V	100μ F
612,621						*	(16RL100)		
R623,641,652,653	J00245103	" "	" "	10kΩ					
R603,619,629,635,	J00245223	" "	" "	$22k\Omega$					
639,644,645							TRIMMER CAPA	CITOR	
R624	J00245393	" "	" "	39kΩ	TC601	K91000020	ECV-1ZW	$20{ imes}40$	20pF
R <b>638</b>	J00245473	" "	" "	$47 \mathrm{k}\Omega$		,			
R <b>613</b>	J00245563	" "	" "	$56 \mathrm{k}\Omega$					
R618,631	J00245683	" "	" "	68kΩ					
R <b>622</b>	J00245104	" "	" "	$100 k\Omega$			SWITCH		
R609,610	J00245105	<i>"</i>	" "	1ΜΩ	S601	N6090012	27S120		
R <b>651</b>	J10276181	∥ compositi							
R611	J10246335	" "	½ W ⋄	3.3ΜΩ			INDUCTOR		
					1.601	1.1190005	FL4H 1ROM		1μΗ
		DOTENTION	-D						
VDC02	IFOGICIOS	POTENTIOMETE	-K	101 00	6 1 1 5		IER UNIT		
VR603	J50710103	V10K-8-1-2		10kΩB	Symbol <b>N</b> o.	Part No.		ription	
VR601	J50710503	,		50kΩB	DD 1700 A	C0017060	Carrier unit wi	th compo	onents
VR <b>602</b>	J50710504	"		500kΩB	PB-1706A	F0001706A	P. C. Board		
		CAPACITOR					IC, FET & TRAI	NSISTOR	2
C632	K00172030	Ceramic disc	50WV	3pF	Q705,706	G1090086	IC	TA7063	
		(DD104SL0300	C50V02)		Q708	G1090068	IC	MC140	
C635	K00172040	Ceramic disc	50WV	4pF	Q702	G3090035	FET	2SK197	
		(DD104SL040C	C50V02)		Q704	G4800590Y	FET	3SK59	7
C628	K02179011	Ceramic disc	50WV	27pF	Q707	G3318150G	Transistor	2SC181	
		(DD104CH270J	(FOX/OO)		Q710	G3303720G	Transistor	200720	2TM-GR
		(1)D104C112103	50 V 02 )		Q710	033037200	Transistor	250132	THE GIV

	,	-		C705,713	K02179011	Ceramic disc 50WV	27pF
						(DD104CH270J50V02)	
				C704	K02179012	Ceramic disc 50WV	<b>30</b> pF
		DIODE		*		(DD105CH300J50V02)	
D705~708	G2090118	Germanium (GB) 1SS97		C703	K02175390	Ceramic disc 50WV	<b>39</b> pF
D702~704,709,~713,	G2015550	Silicon 1S1555				(DD105-275CH390J50V02	)
715,719,720,724				C721,730	K00172101	Ceramic disc 50WV	100pF
D716,718	G2090010	Zener WZ090				$(\mathrm{DD105SL101J50V02})$	
D721,722	G2090025	Zener WZ050		C718,719	K00179020	Ceramic disc 50WV	240pF
D701,723	G2090093	Germanium 1N270			1	(DD107SL241J50V02)	
				C701,702,706,707,	K13170103	Ceramic disc 50WV	0.01µF
				711,712,714,716,		(DB201YF103Z5L5)	
		CRYSTAL		717,735,740,746,			
X701	H0100421	HC-18/U 8986kHz		748,751			
X703	H0100422A	∥ 8988.3kHz		C739	K13170473	Ceramic disc 50WV	0.047μF
X702	H0100423	∞ 8989kHz				(DB207YF473Z5L5)	
			-	C708,709	K30176151	Dipped mica 50WV	150pF
		_				(Z17D151K05)	
				C723,732	K50177222	Mylar 50WV	0.0022µ1
		RESISTOR				(50F2U222M)	
R749,753,754	J00245680	Carbon film ¼W VJ	68Ω	C720,724,727,734	K50177473	Mylar 50WV	0.047µF
1(145,105,104	300243000	Carbon IIIII 74 W VO	0012	1 0120,124,121,104	1100111110	(50F2U473M)	0.011,
R747,752	J00245101	" " VJ	100Ω	C725,726,736,737,	K40170105	Electrolytic 50WV	1μF
1747,732	300243101	7 7 7	10022	741,749,752	140170103	(50RL1)	1,41
R729	100945191	" " VJ	1200		K40170225	Electrolytic 50WV	2.2µF
	J00245121	" " " VJ	120Ω 150Ω	C731,747	K40170225	(50RL2R2)	2.2μ1
R704,707	J00245151			C700 700 754 740	V40120106	Electrolytic 16WV	10µF
R755	J00245181		180Ω	C728,733,754,742~	K40120106	(16RL10)	10μ1
R708,709	J00245221	" " " "	220Ω	744	17.40100000		00
R721,735	J00245331	" " " "	330Ω	C722,738	K40120226	Electrolytic 16WV	$22\mu$ F
R710,738	J00245391	" " " "	390Ω		17.10100000	(16RL22)	00 13
R702	J00245471	" " " "	470Ω	C750,753	K40120336	Electrolytic 16WV	33μ F
					17	(16RL33)	
R701,718,727	J00245102	" " " "	1kΩ	C729	K40120476	Electrolytic 16WV	$47\mu\mathrm{F}$
R715	J00245222		2.2kΩ			(16RL47)	
R717,728,745	J00245332	" " "	3.3kΩ				
R705,706	J00245472	" " " "	4.7kΩ				
R751	J00245682	" " " "	6.8kΩ		_		
R720,731,734,737,	J00245103	" " " "	$10 \mathrm{k}\Omega$			TRIMMER CAPACITOR	_
741,756,757				TC701~704	K91000020	ECV-1ZW 20×40	20pF
R <b>723</b>	J00245153	" " "	15kΩ	TC705	K91000023	ECV-1ZW 50×40	50pF
R739,746,758	J00245223	" " "	$22k\Omega$		_		
R726	J00245333	" " "	$33k\Omega$				
R712,719,732	J00245393	4 4 4	$39 \mathrm{k}\Omega$				
R713,745	J00245473	" " " "	$47 \mathrm{k}\Omega$			INDUCTOR	
R <b>74</b> 2	J00245563	" " " "	$56 \mathrm{k}\Omega$	L705	L1190023	FL-5H 220K	22 <i>µ</i> H
R714,736	J00245823	" " " "	82kΩ	L706	L1190001	EL-0710 251K	250µH
R703,711,725	J00245104	, , , , ,	$100 \mathrm{k}\Omega$	L707	L1190038	FL-5H 271K	270µH
R722,733	J00245154	" " " "	$150 \mathrm{k}\Omega$	L701~704	L1190017	FL-5H 102K	1mH
R740,744	J00245105	" " " "	1ΜΩ				
R743	J10246335	"composition " GK	$3.3 M\Omega$				
					-	TRANSFORMER	
				T701	L0020141	R12-4171	
		POTENTIOMETER		T702	L0020140	R12-4170	
VR701	J50702201		200ΩΒ	1			
VR702	J50702504		00kΩB				
							_
	-			1			
						RELAY	
		CARACITOR		DI 701	M1100002		1917
	V00170000	CAPACITOR FOWV 9	) E	RL701	M1190002	FBR-211AD012M	12V
C715	K00172020	Ceramic disc 50WV 2	2pF				
C715		(DD104CI 000 CECTION)					
	Izon-Fried	(DD104SL020C50V02)	10 F				
C715	K02179008		20pF				

		O UNIT				
Symbol No.	Part No.	Description				
	C0014403	VFO assembly 3330				
		VFO chassis			RESISTOR	
		VFO board .	R809,811	J00245101		100Ω
	+		R807	J00245221		220Ω
			R805,808	J00245222		2.2kΩ
			R802	J00245332		3.3kΩ
			R801	J00245103		10kΩ
*	****VFO	CHASSIS * * * * *	R803	J00245183		18kΩ
			R804	J00245223		22kΩ
		CAPACITOR	R806,810	J00245104	" " "	100kΩ
C801	K06173080	Ceramic disc 50WV UJ 8pF (DD104UJ080D50V02)	*			
C803	K06175120	Ceramic disc 50WV UJ 12pF	1		-	
C003	100173120	(DD104UJ120D50V02)			CAPACITOR	
C804	K02175150	Ceramic disc 50WV CH 15pF (DD104CH150J50V02)	C807	K30173080	Dipped mica 50WV (LCQ11080D05)	8pF
C805	K02175330	Ceramic disc 50WV CH 33pF (DD105CH330J50V02)	C814	K30176330	Dipped mica 50W V (Z11C330K05)	33pF
C 824,826	K13170103	Ceramic disc 50WV 0.01µF	C809,810,812,815,	K13170103	Ceramic disc 50WV	0.01µF
		(DB201YF103Z5L5)	819,820		(DB201YF103Z5L5)	
C802	K30209001	Dipped mica 50WV 1000pF (DM19D102K1)	C811	K30176181	Dipped mica 50WV (Z17D181K05)	180pF
C825	K70167334	Tantalum 35WV 0.33μF (CS15E1VR33M)	C813	K30176431	Dipped mica 50WV (Z18D431K05)	430pF
		-	C808,818	K30176390	Dipped mica 50WV (Z11C390K05)	39pF
V(2001	Vocassa	VARIABLE CAPACITOR	C822	K30209001	Dipped mica 50WV	1000pF
VC801	K90000024	C521R-112	C821,823	K00175471	Ceramic 50WV SL	470pF
					(DD109SL471J50V02)	
		TRIMMER CAPACITOR	+			
TC801	K90000001	TSN-100D15 15pF				
		INDUCTOR			TRIMMER CAPACITOR	
L801	L0020268A		TC802	K91000016	ECV-1ZW 50×32	50pF
L806	L1190001	EL0710 -251K 250µH	1 3002	1101000010		
2000	ETTOGGT	BESTI BOTT				
		JACK				
J802	P1090012	SI-6303-1			INDUCTOR	
J 801	P1090022	STR-01	L804,805	L1190007	FL-4H 1R8M	1.8µH
	Q5000005	Lighthouse type terminal	L803	L1190001	EL0710-251K	250µH
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	- Summer Silve serminal	L802	L1190040	S4 102K	1mH
			1			
	* * * * * VF0	BOARD * * * * *				
			-			
PB-1440B	F0001440B	Printed circuit board				
·	C9014403	PCB with components				
		FET & TRANSISTOR				
Q802	G3090035	FET 2SK19TM-GR				
Q801,803	G3303800Y	Transistor 2SC380 TM-Y				
						T. A.
			-			
		DIODE				
D801	G2022360	Varactor 1S2236				

Symbol <b>N</b> o.		/ UNIT	R947,950	J00245103		VJ 10kΩ
-	Part No.	Description	R911	J00245183	" " "	√ 18kΩ
PB-1707B	C0017070 F0001707B	FM unit with components P. C. Board	R921,930,948,951 965,	J00245223	<i>"</i> "	22kΩ
	-		R955,964	J00245273	" " "	* 27kΩ
			R904,907,949,961	J00245473	" " "	″ 47kΩ
			R932,941,962	J00245563	" " "	″ 56kΩ
		IC, FET & TRANSISTOR	R924,925	J00245104	" " "	″ 100kΩ
Q904,909	G1090059	IC TA7061AP	R931	J00245154	" " "	* 150kΩ
Q914	G1090123	IC 78L08	R927	J01245332	" " "	TJ 3.3kΩ
Q911	G3800340E	FET 2SK34E	R966	J01245152	" " "	* 1.5kΩ
Q901	G4800510C	FET 3SK51-03	1.000	001240102		1.00.
Q902,903,905,906,	G3318150Y	Transistor 2SC1815Y	+	*	THERMISTOR	
907,908,910,912,			TH901	G9090001	SDT-250	
913						
					POTENTIOMETER	
		DIODE	VR903	J50710202	V10-K8-1-2	2KB
D902,903,905,906	G2001880F	Germanium 1S188FM	VR901	J50710203	"	20kΩB
D901,907,910	G2015550	Silicon 1S1555	VR902	J50710503	,,	50kΩB
D908	G9090006	Varistor MV-13				
D909	G2090040	Varactor FC-63				
		CRYSTAL			CAPACITOR	
X902	H0100440A	HC-18/U 8988.3kHz	C968	K02179008	Ceramic disc 50WV	20pF
X901	H0102275	HC-18/U 9442.5kHz			(DD104CH200J50V02)	
		CRYSTAL FILTER(OPTION)	C901,902,903,913, 963	K13170102	Ceramic disc 50WV (DB200YF102Z5L2)	0.001µF
XF901	H1102020	XF-8.9GF	C904,905,909,910,	K13170103	Ceramic disc 50WV	0.01µF
•		CERAMIC FILTER	956,961,962,964, 966,971		(DB201YF473Z5L5)	
CF901,902	H3900030	LFB-15	C926,928,973	K13170473	Ceramic disc 50WV	0.047μF
		Eal	1		(DB207YF473Z5L5)	
		CERAMIC DISCRIMIMNATOR	C960	K30176200	Dipped mica 50WV (Z11C200K05)	20pF
CFD901	H7900060	SFD-455-S4	C907	K30176470	Dipped mica 50WV	47pF
					(Z11C470K05)	
			C930	K30176101	Dipped mica 50WV (Z12D101K05)	100pF
		RESISTOR	C958,959	K30176121	Dipped mica 50WV	120pF
R959	J00245100	Carbon film ½W VJ 10Ω			( Z17D121K05)	
R958 R914,916,917,937,	J00245560 J00245101	, , , , , 56Ω , , , , 100Ω	C906,908	K30176151	Dipped mica 50WV (Z17D151K05)	150pF
938,953,957 R923	J01245101	" " TJ 100Ω	C955	K30176221	Dipped mica 50WV	220pF
	J01245101 J00245221		C011 000 040	VEOLOGIAC	(Z17D221K05)	0.001 F
R922			C911,922,940	K50177102	Mylar 50WV	0.001µF
R915 R956	J00245331	" " " 330Ω	C040	VE0177222	(50F2U102M)	0.0000
	J00245471	, , , 470Ω , , , , 560Ω	C949	K50177332	Mylar 50WV	0.0033μF
R936,944,952	J00245561 J00245681	% % % 560Ω % % % 680Ω	C944	VE0177470	(50F2U332M) Mylar 50WV	7 0 0047
Rana	J00245681 J00245102	" " " " 680Ω		K50177472	Mylar 50WV (50F2U472M)	0.0047μF
	000240102	7 7 7 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	C929,931,933,965		Mylar 50WV	0.01μF
R909 R913,933,939,943					(50F2U103M)	υ.υιμΓ
R913,933,939,943 963	100245152	// // // // 1 5l-O		1	L VOUL AUTUOINT	
R913,933,939,943 963 R906,918,929,934	J00245152	4 4 1.5kΩ	C923 924 925 920	K50177999		7 0 022E
R913,933,939,943 963 R906,918,929,934 R905	J00245182	" " 1.8kΩ	C923,924,925,938,	K50177223	Mylar 50WV	0.022μF
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960	J00245182 J00245222	*	950,952		Mylar 50WV (50F2U223M)	
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960 R910,935	J00245182 J00245222 J00245272	$\begin{array}{cccccccccccccccccccccccccccccccccccc$		K50177223 K50177333	Mylar 50WV (50F2U223M) Mylar 50WV	
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960 R910,935 R903,926,927,946,	J00245182 J00245222	*	950,952 C941	K50177333	Mylar 50WV (50F2U223M) Mylar 50WV (50F2U333M)	0.033μF
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960 R910,935 R903,926,927,946,	J00245182 J00245222 J00245272 J00245332	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	950,952 C941 C912,914,915,916,		Mylar 50WV (50F2U223M)  Mylar 50WV (50F2U333M)  Mylar 50WV	0.033μF
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960 R910,935 R903,926,927,946, 954 R912	J00245182 J00245222 J00245272 J00245332 J00245392	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	950,952 C941 C912,914,915,916, 918,919,932,951	K50177333	Mylar 50WV (50F2U223M) Mylar 50WV (50F2U333M)	0.033μF
R913,933,939,943 963 R906,918,929,934 R905 R901,902,945,960 R910,935 R903,926,927,946,	J00245182 J00245222 J00245272 J00245332	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	950,952 C941 C912,914,915,916,	K50177333	Mylar 50WV (50F2U223M)  Mylar 50WV (50F2U333M)  Mylar 50WV	7 0.033μF 7 0.047μF

			KICIO LIST		
C936,939,947	K40170105	Electrolytic 50W 1µ	F		CAPACITOR
		(50RL1)	C1011,1012	K12279004	Ceramic disc 50WV 0.0047µH
C934,935	K40140475		7μF		(ECKD2H472PE)
		(25RL4R7)	C1009,1010	K12279002	Ceramic disc 50WV 0.01µF
C937,942,953	K40120106	Electrolytic 16WV 10A	-		(ECKD2H103PE)
G0.15.0.10		(16RL10)	C1013	K13170473	Ceramic disc 50WV 0.047μF
C945,946	K40120226	Electrolytic 16WV 22µ			(DB207YF473Z5L5)
	************	(16RL22)	C1008	K30279059	Dipped mica 50WV 2200pF
C921,943,948	K40120476	Electrolytic 16WV 47,	·		(DM19D222K5)
	1/10150000	(16RL47)	C1003~1006	K40240226	Electrolytic 250WV 22μF
C972	K13170680	Celamic disc 50WV 681		17.411.40000	(250RH22)
			C1001,1002	K41140338	Electrolytic 25WV 3300µF (25TL3300)
			C1007	K70167224	Tantalum 35WV 0.22μF
			C1007	K70107224	(CS15E1VR22M)
		TRIMMER CAPACITOR			(OSIGET VILLENT)
TC901	K91000019	ECV-1ZW 10×40 10 ₁	oF		
					AF CHOKE
			CH1001	L2030064	
		INDUCTOR			
L904,905	L1190020	FL-5H 151K 150	) <i>μ</i> Η		
L901,902,903,906	L1190017	FL-5H 102K 1m	Н		
*					
		10.	,		
				_	UNIT
T001	1.0100000	TRANSFORMER	Symbol No.	Part No.	Description
T901	L0190002		DD 17004	C0017090	PLL unit with components
T902	L0020319	D10 4170	PB-1709A	F0001709A	P. C. Board
T903 T904	L0020140 L0020210	R12-4170			
1904	L0020210				
					IC, FET & TRANSISTOR
			Q1102	G1090081	IC TA7310P
			Q1106	G1090082	IC SN75450B
			Q1107	G1090111	IC MC4044P
	REC	T.A UNIT			(μPC1008C)
Symbol No.	Part No.	Description	Q1111	G1090120	IC 78L05
	C0017080	Rect. A unit with components	Q1110	G1090123	IC 78L08
PB-1708	F0001708	P. C. Board	Q1104	G3090035	FET 2SK19TM-GR
			Q1108	G3318150G	Transistor 2SC1815GR
			Q1101,1103,1105,110	9 G3318150Y	Transistor 2SC1815Y
		DIODE			
D1001,1002	G2090003	Silicon V06B			
D1003,1004	G2090002	/ 10D10			DIODE
D1005,1006	G2015550	/ 1S1555	D1101~1103	G2015550	Silicon 1S1555
· ·		RESISTOR			RESISTOR
R1009,1012	J00245472	Carbon film 1/4W VJ 4.	7kΩ R1126	J00245100	Carbon film ½W VJ 10Ω
R1009,1012	J00245472 J00245103	/ / / / / / 10l		J00245100 J00245560	Carbon 111m /4 W VJ 1012
R1001	J10276102	composition ½W GK 1kg		J00245680	
	J10276473	" " " 471		J00245101	" " " 100Ω
R1008	J00245563	Carbon film 1/4W VJ 56		J00245151	" " 150Ω
R1011	J00245225		2MΩ R1105,1114,1121	J00245102	" " 1kΩ
R1003	J20306471		0Ω R1122	J00245152	" " 1.5kΩ
R1002	J20306562		6kΩ R1110,1112,1115,111		" " " 2.2kΩ
R1013	J20336473		kΩ 1118		
			R1119,1120,1123,112	4 J00245472	″ ″ ″ 4.7kΩ
			1127		
		POTENTIOMETER	R1111,1125	J00245223	" " " 22kΩ"
VR1001	J50708103	<del>-</del>	R1111,1125 kΩB R1104	J00245223 J00245473	" " " 22kΩ " " 47kΩ

J00245104	Carbon film 1/4 W VJ	100kΩ	*		TRANSISTOR
			Q1211~1213	G3318150Y	2SC1815Y
	CARACITOR				
V00175270		07. 5			
KUU175270		27pF	D1001 1010		DIODE
K00175330		22. E			MV104
K00173330		33pr			1S1555
K00175390		39nF	D1223,1224	G2090029	1N60
100113330		ОЗРІ			
K00175470		47pF			·
	(DD104SL470J50V02)				RESISTOR
K00175560	Ceramic disc 50WV	56pF	R1269	J00245220	Carbon film ¼W VJ 22Ω
	(DD104SL560J50V02)		R1270,1273	J00245270	ν ν ν 27Ω
K00175101	Ceramic disc 50WV	100pF	R1241	J00245470	″ ″ ″ 47Ω
	(DD105SL101J50V02)		R1271,1274	J00245560	″ ″ ″ 56Ω
K00175151	Ceramic disc 50WV	150pF	R1201,1204,1207,1210	J00245101	″ ″ ″ 100Ω
	(DD14SL151J50V02)		1213,1216,1219,1222		
K13170102	Ceramic disc 50WV	$0.001 \mu\mathrm{F}$	1225,1228,1229,1231		·
5	(DB200YF102Z5L2)		1234,1235,1237,1240		
K13170103	Ceramic disc 50WV	0.01µF			
	(DB201YF103Z5L5)		1255,1258		
1750-55-			· · · · · · · · · · · · · · · · · · ·	J00245151	" " 150Ω
K50177104		0.1µF			, , , , 270Ω , , , , , , , , , , , , , , , , , , ,
V71107005		C 0F			" " " 560Ω
K71137685		6.8µ F			$\begin{array}{cccccccccccccccccccccccccccccccccccc$
V 40120106		10E	1 ' ' '	J00245222	2.2K11
K40120100	-	10μ Γ	1		
	(TORELO)			.100245472	, , , , 4.7kΩ
			+		" " 5.6kΩ
					ν ν ν ν 47kΩ
	INDUCTOR		R1264	J00245823	" " " 82kΩ
L1190015	FL-4H 120J	12 <i>µ</i> H	R1202,1203,1208,1209	J00245104	" " " 100kΩ
L1190021	FL-5H 180K	18µH	1214,1215,1220,1221		
L1190023	FL-5H 220K	22 <i>µ</i> H	1226,1227,1232,1233		
L1190024	FL-5H 221K	220µH	1238,1239,1244,1245		
L1190017	FL-5H 102K	1mH	1250,1251,1256,1257		
			1275		
					″ ″ ″ 680kΩ
			R1277	J01245560	" " TJ 56Ω
T 0000100					
L0020169	R12-4184				CARACITOR
			C1945 1959	K02170001	CAPACITOR  Ceramic disc 50WV 1pF
			1245,1255	V05113001	(DD104CK010C50V02)
Q5000011	Wranning terminal C		C1213 1221 1220	K02179003	Ceramic disc 50WV 2pF
-40000011	mapping terminal O			1102110000	(DD104CK020C50V02)
	30		C1261	K02172050	Ceramic disc 50WV 5pF
			31201	3102112000	(DD104CH050C50V02)
	-		C1237	K02173100	Ceramic disc 50WV 10pF
			1		(DD104CH100D50V02)
			24000 4000	V00175100	Ceramic disc 50WV 12pF
VC	O UNIT		C1269,1277	K02175120	Ceramic disc 50WV 12pF
VC(	O UNIT  Description	2	C1269,1277	K02175120	(DD104CH120J50V02)
		s	C1243,1251	K02175120	•
Part No.	Description	s	2		(DD104CH120J50V02)
Part No. C0021660	Description VCO unit with component	s	2		(DD104CH120J50V02)  Ceramic disc 50WV 15pF
Part No. C0021660	Description VCO unit with component	S	C1243,1251  C1227,1235,1259,1267 1275	K02175150	(DD104CH120J50V02)  Ceramic disc 50WV 15pF (DD104CH150J50V02)
Part No. C0021660	Description VCO unit with component	s	C1243,1251 C1227,1235,1259,1267	K02175150	(DD104CH120J50V02)  Ceramic disc 50WV 15pF (DD104CH150J50V02)  Ceramic disc 50WV 20pF
Part No. C0021660 F0002166A	Description VCO unit with component P. C. Board FET	S	C1243,1251  C1227,1235,1259,1267 1275  C1230,1238,1246,1254 1262,1270,1278	K02175150 K02179008 K02175470	(DD104CH120J50V02)  Ceramic disc 50WV 15pF (DD104CH150J50V02)  Ceramic disc 50WV 20pF (DD104CH200J50V02)  Ceramic disc 50WV 47pF (DD106CH470J50V02)
Part No. C0021660 F0002166A  G4800510C	Description VCO unit with component P. C. Board  FET 3SK51-03	s	C1243,1251  C1227,1235,1259,1267 1275  C1230,1238,1246,1254	K02175150 K02179008	(DD104CH120J50V02)  Ceramic disc 50WV 15pF (DD104CH150J50V02)  Ceramic disc 50WV 20pF (DD104CH200J50V02)  Ceramic disc 50WV 47pF (DD106CH470J50V02)  Ceramic disc 50WV 5pF
Part No. C0021660 F0002166A	Description VCO unit with component P. C. Board FET	S	C1243,1251  C1227,1235,1259,1267 1275  C1230,1238,1246,1254 1262,1270,1278	K02175150 K02179008 K02175470	(DD104CH120J50V02)  Ceramic disc 50WV 15pF (DD104CH150J50V02)  Ceramic disc 50WV 20pF (DD104CH200J50V02)  Ceramic disc 50WV 47pF (DD106CH470J50V02)
	K00175560  K00175101  K00175151  K13170102  K13170103  K50177104  K71137685  K40120106  L1190015  L1190021  L1190023  L1190024	CAPACITOR	CAPACITOR	CAPACITOR	

			1 7111	LIST				
C1212	K06179004	Ceramic disc 50WV	20pF	X1303	H0100413	21.4875MHz		
		(DD104UJ 200J50V02)		X1304	H0102321	24.4875MHz		
C1228, 1236, 1244, 1260	K06175220	Ceramic disc 50WV	22pF	X1305	H0100414	28.4875MHz		
		(ECC-D1H220JU)		X1306	H0102322	32.4875MHz		
C1252	K06179005	Ceramic disc 50WV	24pF	X1307	H0100415	35.4875MHz		
		(DD104UJ240J50V02)	· · · · · ·	X1308	H0102323	38.9875MHz		
C1219,1220	K06175270	Ceramic disc 50WV	27pF	X1309	H0100416	42.4875MHz		
		(ECC-D1H270JU)		X1310	H0100417	42.9875MHz		
C1204,1211	K06175390	Ceramic disc 50WV	39pF	X1311	H0100418	43.4875MHz		
		(DD104UJ390J50V02)		X1312	H0100419	43.9875MHz	_	
C1206,1214,1222	K06175470	Ceramic disc 50WV	47pF	4				¥
		(ECC-D1H470JU2)						
C1201,1202,1208~	K13170102	†	$0.001\mu\mathrm{F}$					
1210,1216~1218,		(DB200YF102Z5L2)			_	RESISTOR		
1224~1226,1232~				R1339,1344,1349,1354	J00245470	Carbon film 1/4 V	VVJ	47Ω
1234,1240~1242,				1359	100015101			1000
1248~1250,1256~				R1304,1305,1310,1315	J00245101	, , ,	"	$100\Omega$
1258, 1264~1266,				1320, 1325, 1330, 1334				
1272~1274,1280,				1335,1340,1345,1350				
1281,1283,1286,1290	V19170100	Committee to the control	0.01 5	1355,1360	100045151	, , , ,		1500
C1207,1215,1223,1231		1	$0.01\mu\mathrm{F}$	R1329	J00245151	, , , , ,		$\frac{150\Omega}{220\Omega}$
1239, 1247, 1255, 1263		(DB201YF103Z5L5)		R1324	J00245221	0 0 0		
1271,1279,1282,1284				R1319	J00245271	, , , ,		270Ω 330Ω
1285,1287,1289,1291				R1309,1314	J00245331 J00245561	, , ,		330Ω 560Ω
1292,1293,	V 401 0000 4	Ceramic disc 16WV	10E	R1303, 1308, 1313, 1318	J00245561		"	20077
C1288	K40129004	+	10μ F	1323,1328,1333,1338				
C1294	V7010710C	(16RE10) Tantalum 16WV	10 <i>μ</i> F	1343,1348,1353,1358	J00245681	, , ,		680Ω
C1294 C1203	K70127106		10μr 100pF	R1361		* * *		3.3kΩ
C1203	K06175101	Ceramic disc 50WV	100pr	R1301, 1306, 1311, 1316	J00245332		,	3.3K11
		TRANSFORMER		1321,1326,1331,1336				
T1201,1202	L0020294	TRAINSFORMER		1341,1346,1351,1356 R1302,1307,1312,1317	J00245153	, , ,	"	15kΩ
T1201,1202	L0020294			1322,1327,1332,1337	300243133			13842
T1205,1204	L0020295			1342,1347,1352,1357				
T1207~1210	L0020296			1342,1347,1332,1337				
	2002020							
						CAPACITOR		
		INDUTOR		C1301, 1306, 1311, 1316	K02173080	Ceramic disc 50	)WV	8pF
L1201~1211	L1190024	FL5H 221K	220µ H	1321,1326,1331,1336		(DD104CH080D50V02	2)	
				1341,1346,1351,1356				
				C1343,1348,1353,1358	K02179013	Ceramic disc 50 (DD105CH330J50V02		33 _p F
				C1322,1327,1332,1337	K02175390			39pF
				1342,1347,1352,1357		(DD105-257CH390J5		4
	XTA	AL UNIT		C1328,1333,1338	K02175470		)WV	47pF
Symbol No.	Part No.	Description		, ,		(DD106CH470J50V02		•
	C0021650	XTAL unit with compone	ents	C1312,1317	K02175680			68pF
PB-2165	F0002165	P. C. Board				(DD107CH680J50V02		
				C1323	K02175820	Ceramic disc 50	OWV	82pF
						DD107CH820J50V02)		
				C1307	K02175101	Ceramic disc 5	0W V	100pF
		TRANSISTOR				(DD107CH101J50V02	?)	
Q1301~1312	G3303800Y	2SC380Y		C1318	K02175121	Ceramic disc 5	0WV	120pF
						(DD109CH121J50V02	?)	
				C1302,1313	K02175151	Ceramic disc 5	0WV	150pF
						(DD109CH151J50V02		
		DIODE		C1361	K13170102	Ceramic disc 5	0WV	0.001µ
D1301~1312	G2015550	1S1555				(DB200YF102Z5L5)		
				C1304,1305,1309,1310	K03170103	Ceramic disc 5	0WV	0.01µF
				1314,1315,1319,1320	,	(DB201YF103Z5L5)		
	1			1324,1325,1329,1330				
				1 , , , , , , , , , , , , , , , , , , ,	+			
		CRYSTAL		1334,1335,1339,1340				
X1301 X1302	H0100411 H0100412	CRYSTAL 15.9875MHz 17.9875MHz		+ ' ' '				

C1308	K30176221	Dipped mica 50WV 220pF		BDIVE	D. DOADD
01000	100170221	(Z17D221K05)	Symbol No.	Part No.	R BOARD  Description
C1303	K30176271	Dipped mica 50WV 270pF (Z17D271K05)		C0017141	Driver board with components
		(BIIBBIINO)	PB-1714A	F0001714A	(without vacuum tube) P. C. Board
				1 000171111	1. C. Bourd
		TRANSFORMER			
Γ1301~1312	L0020017				VACUUM TUBE
			V1601	G6090002	12BY7A
		CONNECTOR			
J1301	P0090056	5048 - 17A			VACUUM TUBE SOCKET
			VS1601	P3090022	SB-9403
		CDVCTAL COCKET			
KS1301~1312	P3090002	CRYSTAL SOCKET S2-101P-00			RESISTOR
1012	1 3030002	52 1011 00	R1605	J10276470	Carbon composition ½W GK47Ω
			R1062(L1602),1604	J10276560	" " " 56Ω
	-		R1603	J10276101	" " 100Ω
			R1601	J10276473	″ ″ ″ 47kΩ
		B BOARD			,
Symbol No.	Part No. C0017120	Description  Rect. B board with components			CAPACITOR
PB-1712A	F0001712A	P. C. Board	C1601,1602	K12279002	Ceramic disc 500WV 0.01μF (ECKD2H103PE)
			C1603,1604,1606	K13170473	Ceramic disc 50WV 0.047μF (DB207YF473Z5L5)
		DIODE.	C1605	K30279051	Dipped mica 500WV 1000pF
D1401~1404	G2090002	Silicon 10D10			(DM19D102K5)
		RESISTOR			INDUCTOR
R1401~1406	J10276474	Carbon composition ½W GK 470kΩ	L1601	L1190020	FL-5H 151K 150µH
			L1602(R1602)	L1020307	
	Q5000011	Wrapping terminal C			
	4000011				
8				Q5000011	Wrapping terminal
		TOR BOARD			
Symbol No.	Part No. C0017130	Description  Capacitor board with components		FINAL	BOARD
PB-1713	F0001713	P. C. Board	Symbol No.	Part No.	Description
				C0017152	Final board with components (without vacuum tube)
			PB-1715B	F0001715B	P. C. Board
		CAPACITOR			
C1501,1502	K43270002	Electrolytic 500WV 100µF (CE-62L500L100)		1	VACUUM TUBE
			V1701,1702	G6090001	6146B
					DIODE
	-		D1701	G2090002	Silicon 10D10
					VACUUM TUBE SOCKET
			VS1701,1702	P3090024	SB- <b>3606</b>

		I AIXIX	5 6151		
			R1816,1820	J00245223	Carbon film ¼W VJ 22kΩ
			R1801,1802,1804,1805	J10276184	Carbon composition ½W GK 180kC
	4	-	R1819	J20306390	Metallic film 1 W GK 39Ω
		RESISTOR	R1803	J20336391	" " 2 W 390Ω
R1701,1702	J10276560	Carbon composition	R1809	J20336471	
(L1702,1703)	310270300	½W GK 56Ω			
	110050101		R1808	J20356332	" " 3 W 3.3kΩ
R1703,1704,1705	J10276101	″ ″ ″ 100Ω	R1806	J20356153	″ ″ ″ 15kΩ
R1706	J32009007	Meter shunt $0.847\Omega \pm 3\%$	R1807	J20356473	″ ″ ″ 47kΩ
R1707	J20356153	Metallic film 3 W 15kΩ			
		CAPACITOR			POTENTIOMETER
C1703	K12279001	Ceramic disc 500WV 0.001μF (ECKD2H102PE)	VR1801	J50711502	V10K -8-1-2 5kΩB
C1704,1710	K12279002	Ceramic disc 500WV 0.01μF (ECKD2H103PE)			
C1705~1709,1711,	K13170473	Ceramic disc 50WV 0.047μF			CAPACITOR
1712		(DB207YF473Z5L5)	C1801,1807,1812	K12279004	Ceramic disc 500WV 0.0047µ
C1702	K30273050	Dipped mica 500WV 5pF			(ECKD2H472PE)
C1701	K31306101	(LCQ11050D5)  Moulded mica 1kWV 100pF	C1810	K50177223	(50F2U223M)
		(CML1-101K10)	C1811	K40120106	Electrolytic 16WV 10μF (16RL10)
			C1806	K41240106	Electrolytic 250WV 10µF (250TL10)
L1701	L1190020	INDUCTOR FL-5H 151K 150 <i>µ</i> H	C1808,1809	K40260226	Electrolytic 350WV 22μF (350RH22)
L1704	L1190020		C1802~1805	K40240476	Electrolytic 250WV 47µF
		FL-5H 561K 560µH	C1802~1805	N40240476	†
L1702,1703 (R1701,1702)	L1020307				(250RH47)
\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	_				
	Q5000011	Wrapping terminal C			
			SEI	ECT SW	ITCH BOARD
		,	Symbol No.	Part No.	Description
			Symbol No.		Select switch board with
				C0017180	Select switch board with
					components
	REC	T.C UNIT	PB-1718C	F0001718C	P. C. Board
Symbol <b>N</b> o.	Part No.	Description			
	C0017170	Rect. C unit with components			4
PB-1717A	F0001717A	P. C. Board			
					TRANSISTOR
			Q1901,1902	G3318150Y	Transistor 2SC1815Y
			<u> </u>		
		IC. TRANSISTOR			
Q1801	G1090036	IC TA7089M	× ****		
Q1804	G3106390	Transistor 2SA639	+		DIODE
Q1803	G3100330	/ 2SA733	D1901,1902	G2090001	Silicon 10D1
Q1805,1806	G3107330 G3318150G	% 2SC1815GR	D1301,1302	G2030001	Sincon 10D1
		BIODE	Diggs con	100015:	RESISTOR 1/W WILLIAM
		DIODE	R1901,1902	J00245103	Carbon film ¼W VJ 10kΩ
D1802,1809	G2090002	Silicon 10D10	*		
D1803~1808	G2015550	√ 1S1555			
I)1801	G2090081	SM1-12			
					CAPACITOR
			C1901	K40120106	Electrolytic 16WV TW 10μF
		RESISTOR	†		(16RL10)
R1810	J00245479	Carbon film ¼W VJ 4.7Ω			,201220/
R1815	J00245471	// // // 470Ω			
R1812					
	J00245472	-,,,,,			
R1813, 1814, 1817, 181	18 J00245103	″ ″ ″ 10kΩ		1	

		RELAY	R2112,2113	J00245103	Carbon film ½W VJ 10kΩ
RL1901,1902	M1190002	FBR211AD012M 12V	R2109	J01245123	Carbon film ¼W VJ 10kΩ  " " TJ 12kΩ
			R2110	J00245223	" " VJ 22kΩ
			162110	300243223	V J ZZKIZ
			7		-
		SWITCH			
S1901~1906	N4090014	6B0002CC2060			POTENTIOMETER
			VR2101	J50710471	V10K -8-1-2 470ΩB
			V102101	330710471	VION 0 1 2 47022B
	Q5000011	Wrapping terminal C			
	QUUUUII	Wrapping terminar o			
					CAPACITOR
			C2102	K13170473	Ceramic disc 50WV 0.047µF
			1 02102	111111111	(DB207YF473Z5L5)
•			C2101	K40120107	Electrolytic 16WV 100µF
	FVFR SV	VITCH BOARD	02101	1110120101	(16RL100)
Symbol No.	Part No.	Description			(10NB200)
	C0017190	Lever switch board with			
	00011130	components			
PB-1719B	F0001719B	P. C. Board			RELAY
		·	RL2101,2102	M1190002	FBR211AD012M 12V
			.,		
		RESISTOR	y		
R2001	J01245821	Carbon film ½W TJ 820Ω			SWITCH
			S2101~2105	N4090007	5B0001FC2060
					,
			,		
		SWITCH		Q5000011	Wrapping terminal C
S2001	N3090004	SLE62251			
S2002	N3090006	SLE64301			
S2003,2004,2005	N3090002	SLE62301			
			· ·		
				LED.	A BOARD
			Symbol No.	Part No.	Description
·				C0017210	LED A board with components
	TIME CW	ITCH BOARD	PB <b>-1721</b> B	F0001721B	P. C. Board
	TONE SW				
Symbol No.	Part No.				
Symbol No.		Description Tune switch board with components			
	Part No.				
	Part No. C0017200	Tune switch board with components			DIODE
	Part No. C0017200	Tune switch board with components	D2201~2206	G2090060	DIODE  LED GD4-203SRD
	Part No. C0017200	Tune switch board with components	D2201~2206	G2090060	
	Part No. C0017200	Tune switch board with components	D2201~2206	G2090060	
PB- <b>1720</b> B	Part No. C0017200	Tune switch board with components P. C. Board	D2201~2206	G2090060	
PB-1720B Q2102,2103	Part No. C0017200 F0001720B	Tune switch board with components P. C. Board TRANSISTOR	D2201~2206	G2090060	LED GD4-203SRD  RESISTOR
PB-1720B Q2102,2103	Part No. C0017200 F0001720B	Tune switch board with components P. C. Board  TRANSISTOR  Transistor 2SA733	R2203	J01245271	LED GD4-203SRD  RESISTOR  Carbon film ¼W TJ 270Ω
PB-1720B Q2102,2103	Part No. C0017200 F0001720B	Tune switch board with components P. C. Board  TRANSISTOR  Transistor 2SA733	R2203 R2202		LED GD4-203SRD           RESISTOR           Carbon film         ½W         TJ 270Ω           μ         μ         κ         820Ω
PB-1720B Q2102,2103	Part No. C0017200 F0001720B	Tune switch board with components P. C. Board  TRANSISTOR  Transistor 2SA733  2SC1815Y	R2203	J01245271	LED GD4-203SRD  RESISTOR  Carbon film ¼W TJ 270Ω
PB-1720B  Q2102,2103  Q2101	Part No. C0017200 F0001720B G3107330 G3318150Y	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  2SC1815Y  DIODE	R2203 R2202	J01245271 J01245821	LED GD4-203SRD           RESISTOR           Carbon film         ½W         TJ 270Ω           "         "         "         820Ω
PB-1720B  Q2102,2103  Q2101  D2101~2103	Part No. C0017200 F0001720B  G3107330 G3318150Y	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD	R2203 R2202	J01245271 J01245821	LED GD4-203SRD           RESISTOR           Carbon film         ½W         TJ 270Ω           "         "         * 820Ω
PB-1720B  Q2102,2103  Q2101  D2101~2103  D2104,2108	G3107330 G3318150Y  G2090060 G2090001	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1	R2203 R2202	J01245271 J01245821	LED GD4-203SRD           RESISTOR           Carbon film         ½W         TJ 270Ω           "         "         "         820Ω
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~	Part No. C0017200 F0001720B  G3107330 G3318150Y	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD	R2203 R2202	J01245271 J01245821	LED GD4-203SRD           RESISTOR           Carbon film         ½W         TJ 270Ω           "         "         * 820Ω
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108	G3107330 G3318150Y  G2090060 G2090001	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1	R2203 R2202 R2201	J01245271 J01245821 J01245152	LED   GD4-203SRD
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~	G3107330 G3318150Y  G2090060 G2090001	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1	R2203 R2202 R2201	J01245271 J01245821 J01245152	LED   GD4-203SRD
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~	G3107330 G3318150Y  G2090060 G2090001	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1	R2203 R2202 R2201	J01245271 J01245821 J01245152 REJECT S	RESISTOR
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~	G3107330 G3318150Y  G2090060 G2090001	Tune switch board with components P. C. Board  TRANSISTOR  Transistor 2SA733  * 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  * 1S1555	R2203 R2202 R2201	J01245271 J01245821 J01245152	RESISTOR  Carbon film ¼W TJ 270Ω  γ γ γ 820Ω  γ γ γ 1.5kΩ  WITCH BOARD  Description  Reject switch board with
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~ 2112	G3107330 G3107330 G32090060 G2090001 G2015550	Tune switch board with components P. C. Board  TRANSISTOR Transistor 2SA733  " 2SC1815Y  DIODE LED GD4-203SRD Silicon 10D1  " 1S1555	R2203 R2202 R2201	J01245271 J01245821 J01245152 BEJECT S Part No. C0017220	RESISTOR  Carbon film ¼W TJ 270Ω  γ γ γ 820Ω  γ γ γ 1.5kΩ  WITCH BOARD  Description  Reject switch board with  component
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~ 2112  R2105,2107	G3107330 G3107330 G32090060 G2090001 G2015550  J00245560	Tune switch board with components  P. C. Board  TRANSISTOR  Transistor 2SA733  " 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  " 1S1555  RESISTOR  Carbon film ¼W VJ 56Ω	R2203 R2202 R2201	J01245271 J01245821 J01245152 REJECT S	RESISTOR  Carbon film ¼W TJ 270Ω  γ γ γ 820Ω  γ γ γ 1.5kΩ  WITCH BOARD  Description  Reject switch board with
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~ 2112  R2105,2107 R2106	G3107330 G3107330 G3318150Y  G2090060 G2090001 G2015550  J00245560 J00245221	Tune switch board with components  P. C. Board  TRANSISTOR  Transistor 2SA733  " 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  " 1S1555  RESISTOR  Carbon film ¼W VJ 56Ω  " " 220Ω	R2203 R2202 R2201	J01245271 J01245821 J01245152 BEJECT S Part No. C0017220	RESISTOR  Carbon film ¼W TJ 270Ω  γ γ γ 820Ω  γ γ γ 1.5kΩ  WITCH BOARD  Description  Reject switch board with  component
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~ 2112  R2105,2107 R2106 R2111	G3107330 G3107330 G3318150Y  G2090060 G2090001 G2015550  J00245560 J00245221 J00245821	Tune switch board with components  P. C. Board  TRANSISTOR  Transistor 2SA733  " 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  " 1S1555  RESISTOR  Carbon film ¼W VJ 56Ω  " " " 220Ω  " " " 820Ω	R2203 R2202 R2201	J01245271 J01245821 J01245152 BEJECT S Part No. C0017220	RESISTOR  Carbon film ¼W TJ 270Ω  γ γ γ 820Ω  γ γ γ 1.5kΩ  WITCH BOARD  Description  Reject switch board with components
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~ 2112  R2105,2107 R2106 R2111 R2102	G3107330 G3107330 G3318150Y  G2090060 G2090001 G2015550  J00245560 J00245221 J00245821 J00245102	Tune switch board with components  P. C. Board  TRANSISTOR  Transistor 2SA733  " 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  " 1S1555  RESISTOR  Carbon film ¼W VJ 56Ω  " " " 220Ω  " " " 820Ω  " " " 1kΩ	R2203 R2202 R2201	J01245271 J01245821 J01245152 BEJECT S Part No. C0017220	RESISTOR  Carbon film ¼W TJ 270Ω  " " " 820Ω  " " " 1.5kΩ  WITCH BOARD  Description  Reject switch board with  components
PB-1720B  Q2102,2103 Q2101  D2101~2103 D2104,2108 D2105~2107,2109~	G3107330 G3107330 G3318150Y  G2090060 G2090001 G2015550  J00245560 J00245221 J00245821	Tune switch board with components  P. C. Board  TRANSISTOR  Transistor 2SA733  " 2SC1815Y  DIODE  LED GD4-203SRD  Silicon 10D1  " 1S1555  RESISTOR  Carbon film ¼W VJ 56Ω  " " " 220Ω  " " " 820Ω	R2203 R2202 R2201	J01245271 J01245821 J01245152 BEJECT S Part No. C0017220	RESISTOR  Carbon film ¼W TJ 270Ω  A A 820Ω A A 1.5kΩ  WITCH BOARD  Description  Reject switch board with components

					TRIMMER CAPACITOR
			TC2401	K91000078	BW6P-1 420pF
			TC2406	K9000030	ECV-1ZW 20×53 20pF
		RESISTOR	TC2402~2405	K91000016	ECV-1ZW $50\times32$ $50pF$
R2301	J00245152	Carbon film ¼W VJ 1.5kΩ	TC2408,2409,2410	K91000030	ECV-1ZW 40×53 40pF
			, , ,		
VR <b>2301</b>	150710500	POTENTIOMETER	70401	T 0000000	TRANSFORMER
V K2301	J50710502	V10K-8-1-2 5kΩB	T2401 T2402	L0020303A	
			1 2402	L0020545	
C0201	Nagonog	SWITCH			
S2301	N4090008	1B0001AC2060			
				TRIMME	R.B BOARD
			Symbol No.	Part No.	Description
				C0021910	Trimmer B board with components
			PB-2191	F00021910	P. C. Board
	TRIMME	R.A BOARD			
Symbol <b>N</b> o.	Part No.	Description			
	C0021900	Trimmer board A with component	ts		
PB-2190	F0002190	P. C. Board			RESISTOR
		TRANSISTOR			
Q2401	G3319590Y	Transistor 2SC1959Y			CAPACITOR
Q2402	G3318150Y	∥ 2SC1815Y	C2503,2508,2509	K30176330	Dipped mica 50WV 33pF (Z11C330K05)
			C2504,2506	K30176680	Dipped mica 50WV 68pF (Z11D680K05)
D2402	G2015550	DIODE Silicon 1S1555	C2502	K30176271	Dipped mica 50WV 270pF (Z17D271K05)
			C2501	K30176821	Dipped mica 50WV 820pF (LCQ18821K05)
		RESISTOR	C2507	K30176101	Dipped mica 50WV 100pF
R2401,2402	J00245103	Carbon film ¼W VJ 10kΩ	C2507	V2011.0101	Dipped mica 50WV 100pF
102101,2102	000240100	Out 5011 111111 74 11 1 0 1 10 10 10 10 10 10 10 10 10 10			TRIMMER CAPACITOR
			TC2501	K91000078	BW6P-1 420pF
			TC2502~2505	K91000016	ECV-1ZW 50×32 50pF
	* *		TC2506,2508	K91000028	ECV-1ZW 10×53 10pF
		CAPACITOR	TC2509,2510	K91000030	ECV-1ZW 40×53 40pF
C2407	K13170103	Ceramic disc 50WV 0.01µ (DB201YF103Z5L5)	F		
C2409	K30176100	Dipped mica 50WV 10pF			TRANSFORMER
		(Z11C100K05)	T2501	L0020303A	
C2405,2412	K30176120	Dipped mica 50WV 12pF (Z11C120K05)		,	
C2403,2404,2411	K30176680	Dipped mica. 50WV 68pF (Z11D680K05)			
C2402	K30176271	Dipped mica 50WV 270pF (Z17D271K05)			,
C240 <b>1</b>	K301768 <b>2</b> 1	Dipped mica 50WV 820pF (LCQ18821K05)	Symbol No.	Part No.	R.C BOARD  Description
C2406	K40120336	Electrolytic 16WV 33μF (16RL33)	PB-1092-3330	C0010922 F2001092	Trimmer C board with components P. C. Board
C2410	K30209001	Dipped mica 50WV 1000pl	7		
					RESISTOR
			R2601	J10276333	Carbon composition ½W 33kΩ

		PARIS	D LIST			
		CAPACITOR	C2705	K70167224	Tantalum	35WV 0.22μF
C26O5	K30276100	Dipped mica 500WV 10pF (LCQ11100D5)	C970C 9707	×	(CS15E1VR22M	)
C26O3	K30276300	Dipped mica 500WV 30pF	C2706,2707	K70167334	(CS15E1VR33M	″ 0.33μF
C26O4	K30276510	(LCQ12300K5) Dipped mica 500WV 50pF	C2704	K40120226	Electrolytic (16RL22)	16WV 22μF
C26O2	K30276221	(LCQ12510K5)				
C2002	K30276221	Dipped mica 500WV 220pF (LCQ17221K5)				
C2601	K30276821	Dipped mica 500WV 820pF (LCQ18821K5)	J2701	P0090037	MINI CONNECTO	PR
C2607	K30276330	Dipped mica 500WV 33pF	92.01	1 000000	0010 011	
C2606	K30276101	// // // 100pF				
		TRIMMER CAPACITOR				
TC2603~2605	K91000031	B-1P1 40pF				
TC2 <b>6</b> 02	K91000032	B-2PY 100pF		MEMO	RY UNIT	
TC2 <b>6</b> 01	K91000078	BW 6 P-1 420pF	Symbol No.	Part No.		ription
	1131000010	BW 01 1		C0017870		with components
			PB-1787E	F0001787E	P. C. Board	with components
1						
	KEY	FR UNIT			IC, FET & TRA	
Symbol No.	Part No.	Description	Q2820	G1090099	IC ,	LM308
PB-1728A	C0017280 F0001728A	Keyer unit with components P. C. Board	Q2821	G1090087	IC	MC4044P (μPC1008C)
			Q2822~2826	G1090051	IC	MC14042B
			Q2812	G1090097	IC	MM74C90
					IC	
		10.4 = 7.11010707	Q2811	G1090096		M SM 5562
		IC & TRANSISTOR	Q2818	G1090120	IC	NJM78L05
Q2701	G1090233	IC 8044	Q2816,2817	G1090123	IC	NJM78L08
Q2702	G3318150Y	Transistor 2SC1815Y	Q2813	G1090092	IC	SN74LS00N
			Q2814,2833	G1090093	IC	SN74LS04N
			Q2832	G1090100	IC	SN74LS123N
			Q2827~2831	G1090019	IC	SN74LS192N
		DIODE	Q2815	G1090098	IC	TC5032P
D2701~2706	G2090029	Germanium 1N60	Q2819,2834	G1090065	IC	μPC14305
			Q2801,2802,2805,2806	G3090020	FET	JF1033B
			Q2809	G4800510C	FET	3SK51-03
			Q2807	G3318150Y	Transistor	2SC1815Y
		RESISTOR	Q2803,2804,2810	G3307850O	Transistor	2SC7850
R2 <b>7</b> 0 <b>5</b>	J00245102	Carbon film ¼W VJ 1kΩ			Transistor	MPS A13
			Q2808	G3090005	Transistor	MI 5 AI3
R2 <b>7</b> 0 <b>4</b>	J00245332	// // // 3.3kΩ				
	J00245472	// // // 4.7kΩ				
R2709,2710	J00245103	/ / / 10kΩ				
R2701,2702,2707	J00245104	″ ″ ″ 100kΩ			DIODE	
	_	,	D2804,2805	G2001880F	Germanium	1S188FM
			D2801~2803	G2015550	Silicon	1S1555
			D2806,2807	G2090043	Varactor	MV104
			D2808	G2090047	Zener	W Z060
				,		
VR2702	J51723104	POTENTIOMETER SR19R 100k $\Omega$ B				
	001120104	TOUR 42D			CRYSTAL	
			X2801	H0100570	HC-18/U	3276.8kH
C2703	K13170473	CAPACITOR  Ceramic disc 50WV 0.047μF	*		RESISTOR	
		(DB207YF473Z5L5)	R2863	J00245279	Carbon film	½ W VJ 2.7Ω
C2701,2702	K50177104	Mylar 50WV 0.1μF	R2860	J00245339	" "	" " 3.3Ω
02101,2102	130177104	(50F2U104M)	R2825	J00245220	* *	" " 22Ω
		(501° 20 1041/1)				
			R2805,2808,2822,2824	J00245101	" "	″ ″ 100Ω

				PARIS					
R2813 R2809, 2821	J00245121 J00245221	Carbon film	½ W V.	J 120Ω 220Ω	C2860	K30176150	Dipped mica (Z11C150K05)	50W V	15pF
R2804,2817	J00245221 J00245391	* *		390Ω	C2816	K30176470	Dipped mica	50W V	47pF
R2826,2831,2840	J00245471	, , ,	" "	470Ω	C2810	K30170470	(Z11C470K05)	50 W V	47pr
R2835	J00245102	" "		1 kΩ	C2812,2817	K30176510	Dipped mica	50W V	51pF
R2815	J00245122	" "		1.2kΩ	G0004	1/50155000	(Z11D510K05)		
R2818,2834,2849	J00245152	, ,		1.5kΩ	C2834	K50177332	Mylar	50W V	0.0033μF
R2842,2855	J00245272	" "		2.7kΩ	G0005	1/50155450	(50F2U332M)	5011/1/	
R2832,2837	J00245332	" "		3.3kΩ	C2837	K50177473	Mylar	50W V	0.047μF
R2810,2843,2857,2861	J00245472	" "		4.7kΩ	G0045 0040 0050	1/50155104	(50F2U473M)	5011/17	
R2853	J00245562	" "		5.6kΩ	C2847,2848,2853	K50177104	Mylar	50W V	$0.1\mu\mathrm{F}$
R2827,2848	J00245822	" "		8.2kΩ	C00C1	V70107004	(50F2U104M)	35WV	0.00 F
R2844,2846,2847,2850 ~2852	J00245103	, , ,	<i>,</i> ,	· 10kΩ	C2861	K70167334	Tantalum (CS15E1VR33M		0.33μF
R2811	J00245123	" "==		12kΩ	C2842,2843,2852	K70147105	Tantalum	$25 \mathrm{W}\mathrm{V}$	1μF
R2828,2829	J00245153	" "		15kΩ			(CS15E1E010M		
R2838	J00245223	" "		$22k\Omega$	C2844	K70167225	Tantalum	$35 \mathrm{WV}$	2.2 <b>µ</b> F
R2812,2858,2859	J00245333	" "		· 33kΩ			(CS15E1V2R2M		
R2836	J00245473	" "		47kΩ	C2851	K70127335	Tantalum	16WV	3.3µF
R2803,2806,2820	J00245563	" "		56kΩ			(CS15E1C3R3M		
R2854,2862	J00245823	" "		· 82kΩ	C2850	K40089006	Electrolytic	6.3WV	330μF
R2801,2802,2814,2816	J00245104	" "	" "	· 100kΩ		*****	(6.3RE330)	05***	
2823,2830,2833,2839 2841,2856					C2845	K40140475	Electrolytic (25RL4R7)	25WV	4.7μF
R2807,2819 1	J00245334	" "	" "	≻ 330kΩ	C2826	K40120106	Electrolytic	16WV	10µ F
R2845	J00245394	" "	4 1	√ 390kΩ		•	(16RL10)		
R2864	J01245102	" "	″ T	J 1kΩ	C2825	K40120336	Electrolytic	$16 \mathrm{WV}$	$33\mu$ F
R2865	J01245472	" "	4	4.7kΩ	2000	**********	(16RL33)		
					C2824	K40100476	Electrolytic (10RL47)	10W V	47μF
				ş-	C2809,2838,2841,2854	1	Electrolytic	16WV	330 <b>µ</b> F
		POTENTIOMETE	:R		2855,2857,2858,2866		(16RL330)		
VR2801,2802	J51724103	PN822H103H		10kΩB	C2870	K41120108	Electrolytic (16TL1000)	16WV	1000µF
					C2862~2865	K31170002	Feed thru	50W V	0.001µF
					,		(ECKY1H-102W	/E)	
		CAPACITOR			C2833,2835,2836	K51176331	Styrol	50W V	330pF
C2804	K06173100	Ceramic disc (ECC-D1H100I	50WV OU)	10pF			(50SU331K)		
C2807	K02179010	Ceramic disc	50W V	24pF					
		(DD104CH240J		•					
C2828	K02175390	Ceramic disc	50WV	39pF			TRIMMER CAPA	CITOR	
		(DD105-257CH	390J50V02	-	TC2801	K91000030	ECV-1ZW 40		40pF
C2827	K02175470	Ceramic disc	50WV	47pF					-
		(DD106CH470J	50V02)						
C2803	K06175470	Ceramic disc	50W V	47pF					
		(ECC-D1H470J	U2)	,			INDUCTOR		
C2805	K02175820	Ceramic disc	50WV	82pF	L2802,2805,2807	L1190017	FL-5H 102K		1mH
					L2803,2804	L1190007	FL-4H 1R8M		1.8µH
C2849	K00175101	Ceramic disc	$50\mathrm{WV}$	100pF	L2801	L1190038	FL-5H 271K		270µH
		(DD105SL101J	50V02)		L2806	L1020012			35 <i>µ</i> H
C2802	K06175271	Ceramic disc	50WV	270pF					
		(ECC-D1H271J							
C2821,2823	K10179011	Ceramic disc (2222-660-0247	50W V 71)	470pF					
C2822	K14179001	Ceramic disc	50WV	0.001µF			TRANSFORMER		
		(RD200YZ102P			T2801	L0020332A			
C2801,2806,2808,2811	K14179002	Ceramic disc	50WV	0.01µF					
2813~2815,2818~		(RD204YM103Z	Z50V)						
2820,2829~2832,									
2839,2856,2859,2867									
C2868,2869,2871	K13170473	Ceramic disc (DB207YF473Z	50W V	0.047μF					
C2810	K30173050	Dipped mica	50WV	5pF					
		(LCQ11050D05							
		<b></b>			<del></del>	1	L		

	COUN	TER UNIT	R3016	J00245104	Carbon film ¼W VJ 100kΩ
Symbol No.	Part No.	Description	R3014	J01245104	" " T.J 100kΩ
	C0020863	3330 Counter unit Assembly			19 1008-
PB-2086A	C9020863	Main P.C. Board			
PB-2098A	C9020983	Display P. C. Board			
					CAPACITOR
****	COUNTER	MAIN BOARD ****	C3024	K02179008	Ceramic disc 50WV 20pF
	C9020863	Main board with components		1102110000	(DD104CH200J50V02)
PB-2086A	F0002086A	Counter main Board	C3025	K02175820	Ceramic disc 50WV 82pF
		IC		1102110020	(DD107CH820J50V02)
Q3012	G1090249	MSM9520RS	C3020	K02175101	Ceramic disc 50WV 100pF
Q3005	G1090065	μPC14305	-		(DD107CH101J50V02)
Q3020	G1090079	μРА54Н	C3001,3004	K13170102	Ceramic disc 50WV 0.001µF
		711011			(DB200YF102Z5L2)
			C3002,3005,3008,3009	K13170103	Ceramic disc 50WV 0.01µF
		FET	3011,3012,3014,3015		(DB201YF103Z5L5)
Q3001	G3800730	3SK73	3017,3019,3026~		
			3030,3021		
			C3010,3013,3018	K40120106	Electrolytic 16WV 10µF
					(16RL10)
	~	TRANSISTOR	C3016	K40129001	Electrolytic 16WV 330µF
Q3003	G331674L	2SC1674L			(16RE330)
Q3004	G3318150G	2SC1815GR	C3023	K50177103	Mylar 50WV 0.01μF
Q3006~3011,3013	G3109520L	2SA952L			(50F2U103M)
~3019			C3022	K71137685	Noiselimiter 20WV 6.8µF
Q3021	G3104960Y	2SA496Y			(CC99E1D6R8M)
				***************************************	
		DIODE			
D3001~3013	G2015550	1S1555			
					TRIMMER CAPACITOR
			TC3001	K91000030	ECV1ZW 40×53 40pF
					INDUCTOR
			L3001	1.2030068	
		CRYSTAL			
X3001	H0102272	6. 5536MHz			
					CONNECTOR
			J3001	P0090051	5048-06A
		RESISTOR	J3002	P0090054	5048-07A
R3012	J00245100	Carbon film ¼W VJ 10Ω	J3003	P0090037	5048-08A
R3031,3034,3037,3040	J00245330	″ ″ ″ 33Ω	P3003	T9201380A	3021 -03
3043,3046,3049					
R3050	J00245560	″ ″ ″ 56Ω			
R3001	J01245560	* * TJ 56Ω	4		
R3008,3018,3020,3022	J00245101	* * VJ 100Ω			
3024,3026,3028					
R3007,3010,3011	J00245221	" " 220Ω			AY BOARD ****
R3052	J00245331	* * * 330Ω	PB-2098A	F0002098A	P. C. Board
R3051	J00245471	" " 470Ω		C9020983	P.C.B with components
R3017,3019,3021,3023	J01245102	" " TJ 1kΩ			
3025,3027	100015:00				
R3036,3039,3042,3045	J00245102	" " " \" \" \" \" \" \" \" \" \" \" \" \			DISDLAY LES
3048,3030,3033	100045150		1,0001 0002	C0000000	DISPLAY LED
R3029, 3032, 3035, 3038	J00245152	" " " 1.5kΩ	1)2901~2906	G2090069	5082 -7623
3041,3044,3047	100045500				
R3002,3015	J00245562	" " 5.6kΩ			
R3013	J00245103	" " 10kΩ			COMPLECTOR
R3009	J00245473	" " 47kΩ	120000	magaggg	CONNECTOR
R3004	J01245473	″ ″ ″ TJ 47kΩ	P2902	Т9202440В	5047 -08

P2901	T9202430B	5047 - 06	D	C-DC CON	VERTER UNIT
		, ,	Symbol No.	Part No.	Description
					TRASISTOR
			Q3201,3202	G3090002	T20A6 with insulator
			× .		
					RESISTOR
			R3202	J31306339	Wire wound 1 W 3.3Ω
			R3201	J20376221	Metallic film 5 W 220Ω
	DIODE SW	ITCH BOARD			
Symbol No.	Part No.	Description			
•	C0017260	Diode switch board with components			
PB-1726A	F0001726A	P. C. Board			CAPACITOR
		,	C3202	K52247474	Metallized paper 250WV 0.47μF
			C3201	K41140227	Electrolytic 25WV 220µF
					(25TL220)
		FET			
Q3101,3102	G3090035	2SK19TM-GR			
·					*
					CONNECTOR
			P3201	P0090066	AC9M
		DIODE			
D3102	G2090093	Germanium 1N270			
D3101,3103	G2090093 G2015550	Silicon 1S1555		5	
	G2010000	101000		,	
				ACCES	SORIES
		RESISTOR	Symbol No.	Part No.	Description
R3101	J00245151	Carbon film ¼W VJ 150Ω	Symbol 140.	M3090004	Microphone YE7A
R3105~3107	J00245151	* * * 560Ω	-	1013030004	with Microphone hanger screws.
	J00245301 J00245102	" " ' 1kΩ		P1090020	Microphone plug FM -144P
R3110	J00245102 J00245222	* * * 2.2kΩ		1 1030020	Microphone plug 1 M 1441
R3108	J00245222 J00245332	" " " 3.3kΩ		_	AC Power cord
		" " " 10kΩ		T0002C00	2 wire, 2 prong plug
R3102~3104	J00245103	10812		T9003680	3 wire, 3 prong UL plug
				T9003682	3 wire, 3 prong OL plug
				T9003683	
		CARACITOR		T9003684	3 wire, 2 porong EU plug
G0104 0105 0100	1710050100	CAPACITOR		P1090092	power plug QS-A-P12FL
C3104,3105,3109~	K13070103	Ceramic disc 50WV 0.01µF	*	T0002700	DC D
3112	1/10150450	(DB201YF103Z5L5)		T9003720	DC Power cord
C3113	K13170473	Ceramic disc 50WV 0.047µF	-	P1090092	power plug QS-A-P12FL
		(DB207YF473Z5L5)		Q0000009	DC Fuse 20A
C3101,3103	K30176471	Dipped mica 50WV 470pF			- Chieses
19.		(Z18D471K05)		P0090008	Key plug SH3603
C3102	K30209001	Dipped mica 50WV 1000pF	*	P0090007	Phone plug SH3001
		(DM19D102K1)	,	P0090034	External speaker plug P2240
C3106,3107,3108	K40120106	Electrolytic 16WV TW 10µF		P0090019	Antenna plug SO259
		(16RL10)		P0090035	ACC plug PA-602B04
				P0090018	RCA pin plug CN7017
				Q0000005	AC Fuse 5A(100V~117V)
				Q0000004	3A(200V~234V)
		INDUCTOR			
L3101,3102	L1190008	FL-4H-2R8M 2.2µH	*		
L3103	L1190038	FL-5H 271K 270µH			
	Q5000011	Wrapping terminal C	1		
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